# MILITARY HANDBOOK 

## RELIABILITY PREDICTION OF ELECTRONIC EQUIPMENT



## DEPARTMENT OF DEFENSE WASHINGTON DC 20301

## RELIABILITY PREDICTION OF ELECTRONIC EQUIPMENT

1. This standardization handbook was developed by the Department of Defense with the assistance of the military departments, federal agencies, and industry.
2. Every effort has been made to reflect the latest information on reliability prediction procedures. It is the intent to review this handbook periodically to ensure its completeness and currency.
3. Beneficial comments (recommendations, additions, deletions) and any pertinent data which may be of use in improving this document should be addressed to: Commander, Rome Laboratory, AFSC, ATTN: ERSS, Griffiss Air Force Base, New York 13441-5700, by using the self-addressed Standardization Document Improvement Proposal (DD Form 1426) appearing at the end of this document or by letter.
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## MIL-HDBK-217F

This revision to MIL-HDBK-217 provides the following changes based upon recently completed studies (see Ref. 30 and 32 listed in Appendix C):

1. New failure rate prediction models are provided for the following nine major classes of microcircuits:

- Monolithic Bipolar Digital and Linear Gate/Logic Array Devices
- Monolithic MOS Digital and Linear Gate/Logic Array Devices
- Monolithic Bipolar and MOS Digital Microprocessor Devices (Including Controllers)
- Monolithic Blpolar and MOS Memory Devices
- Monolithic GaAs Digital Devices
- Monolithic GaAs MMIC Devices
- Hybrid Microcircuits
- Magnetic Bubble Memories
- Surface Acoustic Wave Devices

This revision provides new prediction models for bipolar and MOS microcircuits with gate counts up to 60,000 , linear microcircuits with up to 3000 transistors, bipolar and MOS digital microprocessor and coprocessors up to 32 bits, memory devices with up to 1 million bits, GaAs monolithic microwave integrated circuits (MMICs) with up to 1,000 active elements, and GaAs digital ICs with up to 10,000 transistors. The $C_{1}$ factors have been extensively revised to reflect new technology devices with improved reliability, and the activation energies representing the temperature sensitivity of the dice ( $\pi_{T}$ ) have been changed for MOS devices and for memories. The $\mathrm{C}_{2}$ factor remains unchanged from the previous Handbook version, but inctudes pin grid arrays and surface mount packages using the same model as hermetic, solder-sealed dual in-line packages. New vahues have been included for the quality factor ( $\pi_{\mathrm{Q}}$ ), the learning factor ( $\pi_{\mathrm{L}}$ ), and the environmental factor ( $\pi_{E}$ ). The model for hybrid microcircuits has been revised to be simpler to use, to delete the temperature dependence of the seal and interconnect failure rate contributions, and to provide a method of calculating chip junction temperatures.
2. A new model for Very High Speed Integrated Circuits (VHSICNHSIC Like) and Very Large Scale integration (VLSI) devices (gate counts above 60,000).
3. The reformatting of the entire handbook to make it easier to use.
4. A reduction in the number of environmental factors ( $\pi_{E}$ ) from 27 to 14.
5. A revised failure rate model for Network Resistors.
6. Revised models for TWTs and Klystrons based on data supplied by the Electronic Industries Association Microwave Tube Division.

MIL-HDBK-217F
1.1 Purpose - The purpose of this handbook is to establish and maintain consistent and uniform methods for estimating the inherent reliability (i.e., the reliability of a mature design) of military electronic equipment and systems. It provides a common basts tor rellability predictions curing acquisition programs for military electronic systems and equipment. It atso establishes a common basis for comparing and evaluating reliability predictions of related or compethive designs. The handoook is intended to be used as a tool to increase the reliablity of the equipment being designed.
1.2 Appllcation - This handbook contains two methods of rellability prediction - -Part Stress Analysis" in Sections 5 through 23 and "Parts Count" in Appendix A. These methods vary in degree of information needed to apply them. The Part Stress Analysis Method requires a greater amount of detailed information and is applicable during the later design phase when actual hardware and circults are being designed. The Parts Count Method requires less information, generally part quandities, quality level, and the application environment. This method is applicable during the earty design phase and during proposal formulation. In general, the Parts Count Method will usually result in a more conservative estimate (i.e., higher faiture rate) of system reltabinty than the Parts Stress Method.
1.3 Computerized Rollablity Prediction - Rome Laboratory - ORACLE is a computer program developed to aid in applying the part stress analysis procedure of MIL-HDBK-217. Based on environmental use characteristics, piece part count, thermal and electrical stresses, subsystem repair rates and system configuration, the program calculates piece part, assembly and subassembly failure rates. It also flags overstressed parts, allows the user to perform tradeoff analyses and provides system mean-time-to-failure and availability. The ORACLE computer program software (available in both VAX and IBM compatible PC versions) is available at replacement tape/disc cost to all DoD organizations, and to contractors for application on specific DoD contracts as government fumished property (GFP). A statement of terms and conditions may be obtained upon written request to: Rome Laboratory/ERSR, Grffiss AFB, NY 13441-5700.

This handbook cites some specifications which have been cancelled or which describe devices that are not to be used for new design. This information is necessary because some of these devices are used in so-called "off-the-sherr equipment which the Department of Defense purchases. The documents cited in this section are for guidance and information.

| SPECIFICATION | SECTION * | time |
| :---: | :---: | :---: |
| Mn-C-5 | 10.7 | Capmenors, Fired, Mica-Dieloctric, General Spocification for |
| MIL-R-11 | 9.1 | Presintor, Fixed, Composition (Insutated) General Specitication for |
| MIL-R-19 | 9.11 | Resktor, Variable, Wirewound (Low Operating Temperature) General Spectifcation for |
| MHL-C-20 | 10.11 | Ceppecior. Foxed, Ceramic Diolectric (Ternperature Compeneming) Established and Nonestablished Reliability, General Specification for |
| MIL-R-22 | 9.12 | Resistor, Wirowound, Power Type. General Specification for |
| MIL-C-25 | 10.1 | Capectior, Fixed, Paper-Dielectric, Direct Current (Hermeticalty Sealed in Metal Cases), General Specification for |
| MIL-R-26 | 9.6 | Resistor, Fixed, Wirewound (Power Type), General Specification for |
| AIIL $=$ T -27 | 11.1 | Transionmor and induator (Aludio, Power, High Power, Higi Power Pulse). General Specification for |
| M14-C-62 | 10.15 | Capactior, Fixed Electrolyic (DC. Aluminum. Dry Electrolyte, Polarized), General Specification for |
| MiL-C-81 | 10.16 | Capacitor, Variable, Coramic Dielectric (Trimmer), General Specification for |
| MIL-C-92 | 10.18 | Capactior, Variable, Air Dielectric (Trimmer). General Specitication for |
| MIL-R-93 | 9.5 | Resistor, Fixed, Wirowound (Accurate), General Specification for |
| MIL-R-94 | 9.14 | Resistor, Variable, Composition, General Specitication for |
| MIL-V-95 | 23.1 | Vibrator, Interrupter and Sell-Rectitying. General Specification for |
| w-111! | 20.1 |  |
| W-C-375 | 14.5 | Cinovit Breaker, Molded Case, Branch Circuit and Service |
| W-F-1726 | 22.1 | Fuse, Cartridge, Class H (This covers renewable and nonrenewable) |
| W-F-1ิิı4 | $\underline{20.1}$ | Fuse, Cartridge, High Internupting Capacity |
| MM-C-3098 | 19.1 | Crystal Unit. Quartz. General Specification for |
| Mil-C-3607 | 15.1 | Connector, Coaxial Radio Frequency, Series Putse, General Spectications for |
| MIL-C-3643 | 15.1 | Connector, Coaxial, Radio Frequency, Series NH, Associated Fitings, General Spectication for |
| MIL-C-3650 | 15.1 | Connector, Coaxial, Radio Frequency, Series LC |


| SPECAFICATION | SECTION: | TITE |
| :---: | :---: | :---: |
| M12-C-3655 | 15.1 | Connector, Phy and Pecoptacle, Ebotrical (Coaxial Series Twin) and Associated Fittings, General Specification for |
| MH-C-3767 | 15.1 | Cormoctor, Phig and Recoptacion (Power, Bladod Type) General Specification for |
| MIL-S3786 | 14.3 | Swich, Potary (Circuit Selector, Low-Current (Capacity)), General Specification for |
| Miti-Coss50 | 14.1 | Swich, Toggio, Environmentaliy Seaied, Generai Specificmion for |
| MIL-C-3965 | 10.13 | Capecitor, Fixed, Electrolytic (Nonsolid Electrolyte). Tantalum, General Specilication for |
| MIL-C-5015 | 15.1 | Connector, Electrical, Circular Threaded, AN Type, General Specillication for |
| MIL-F-5372 | 22.1 | Fuse, Current Limiter Type, Aircraft |
| MIL-R-5757 | 13.1 | Relay. Electrical (For Electronic and Communication Type Equipment). General Specification for |
| MIL-R-6106 | 13.1 | Relay, Electromagnetic (Including Established Reliability (ER) Types). General Specificution for |
| MIL-L-6363 | 20.1 | Lamp, Incandescent, Aviation Service, General Requirement for |
| MIL-S-8805 | 14.1. 14.2 | Switches and Switch Assomblies, Sensitive and Push, (Snap Action) General Specification for |
| MIL-S-8834 | 14.1 | Switches, Toggle, Positive Break, General Specification for |
| MİL-M-10304 | 18.1 | inieter, Electrical indicaling, Panei Type, Ruggedized, Generai Spectication for |
| MIL-R-10509 | 9.2 | Resistor, Fbed Fum (High Stability), General Specitication ior |
| MIL-C-10950 | 10.8 | Capacitor, Fixed, Mica Dielectric, Button Style, General Specification for |
| MIL-C-11015 | 10.10 | Cepecitor, Fixed, Ceramic Dielectric (General Purpose), General Spectication for |
| MIL-C-11272 | 10.9 | Capactior, Fred, Glass Dielectric, General Spectication for |
| M MiL-C-11693 | 10.2 | Capacior, Feed Through. Radio interierence Reduction AC and DC. (Hermetically Sealod in Motol Ceses) Established and Nonestablished Reliability, General Specification for |
| Nㅐ는ํ-11804 | 8.3 | Resiator, Fixed, Film (Power Type), General Spectication for |
| MIL-C-12889 | 10.1 | Capuctior, By-Pass', Radio - Interference Reduction, Paper Dielectric. AC and DC. (Hermetically Sealed in Metallic Cases), General Specilication for |
| Mili-F-12934 | 9.10 | Fesistor, Variabie, Wirewound, Precision, Generai Specitication ior |

### 2.0 REFERENCE DOCUMENTS

| SPECAFKATIION | SECTION * |
| :---: | :---: |
| MR-C-14157 | 10.3 |
| MKL-C-14409 | 10.17 |
| Mill-F-15160 | 22.1 |
| Mu-C-15305 | 11.2 |
| M1L-F-15733 | 21.1 |
| MKL-C-18312 | 10.4 |
| MK-F-18327 | 21.1 |
| MIL-R-18546 | 9.7 |
| Mill-S-19500 | 6.0 |
| MHL-R-19523 | 13.1 |
| MRL-R-19648 | 13.1 |
| MIL-C-19978 | 10.3 |
| MIL-T-21038 | 11.1 |
| MIL-C-21097 | 15.2 |
| M1L-R-22097 | 9.13 |
| MK-R-22684 | 9.2 |
| MRL-S-22710 | 14.4 |
| MRL-S-22885 | 14.1 |
| Mil-C-22992 | 15.1 |
| M1L-C-23183 | 10.19 |
| M1L-C-23269 | 10.9 |
| MIL-R-23285 | 9.15 |

## TITLE

Cenpectior, Pxed, Peper (Paper Plastic) or Plestic Dielectric, Direct Current (Hermetically Sealod in Metal Cases) Established Reliability, General Specficication for

Capacitor, Variable (Piston Type, Tubular Trimmer), General Specticication for

Fuse, instrument, Power and Telephone
Coll, Frued and Variable, Radio Frequency, General Specification for
Filer, Radio Interierence, General Specification for
Cepectior, Fixed, Motallzed (Paper, Paper Plastic or Plastic Film) Dielectric, Direct Current (Hermetically Sealed in Metal Cases), General Specification for

Filter, High Pass, Low Pass, Band Pass, Band Suppression and Dual Functioning, General Specification for

Resistor, Fixed, Wirewound (Power Type, Chassis Mounted), General Speclfication for

Semiconductor Device, General Specification for
Rolay, Control. Naval Shipboard
Retay, Time, Detay, Thermal, General Specification for
Capactor, Fixed Plastic (or Paper-Plastic) Dielectric (Hermetically Sealed in Metal, Ceramic or Glass Cases), Established and Nonestablished Reliability, General Specification for

Transformer, Pulse, Low Power, General Specification for
Connector, Electrical, Printed Wiring Board, General Purpose, General Spectication for

Resistor, Variable, Nonwirewound (Adjustment Types), General Specification for

Reststor, Fixed, Film, Insulated, General Specification for
Swhch, Rotary (Printed Circuit), (Thumbwheel, In-line and Pushbution), General Specification for

Switches, Pushbutton, Illuminated, General Specification for
Connector, Cylindrical, Heavy Duty, General Specification for
Cepechtor, Fxed or, Variable, Vacuum Dielectric, General Specification for

Capscitor, Fixed, Glass Dielectric, Established Reliablity, General Spectification for

Resistor, Variable, Nonwirewound, General Specification for

| SPECIFICATION | SECTION: | TITE |
| :---: | :---: | :---: |
| MIL-F-23419 | 22.1 | Fuse, Instrument Type, General Specification for |
| MIL-T-23648 | 9.8 | Thermistor, (Thermally Sensitive Resistor), Insulated, General Specallication for |
| MIL-C-24308 | 15.1 | Connector, Electric, Rectangular, Miniature Polarized Shell, Rack and Panel, General Spectication for |
| MIL-C-25516 | 15.1 | Connector, Electrical, Miniature, Coaxial, Environment Pesistant Type. General Spectication for |
| Mil-C-26482 | 15.1 | Connector, Electrical (Circular, Minieture, Cuick Disconnect. Environment Resisting) Receptacles and Phigs, General Specification for |
| MIL-R-27208 | 9.9 | Resistor, Variable, Wirewound, (Lead Screw Activated) General Specification for |
| MIL-C-28748 | 15.1 | Connector, Electrical, Rectangular, Rack and Panel, Solder Type and Crimp Type Contacts, General Specification for |
| MIL-R-28750 | 13.2 | Relay, Solid State, General Specification for |
| M1L-C-28804 | 15.1 | Connector, Electric Rectangular, High Density, Polarized Central Jackscrow, General Specification for, Inactive for New Designs |
| MIL-C-28840 | 15.1 | Connector, Electrical, Circular Threaded, High Density. High Shock Shipboard, Class D, General Specification for |
| MIL-M-38510 | 5.0 | Microcircuits, General Specification for |
| MIL-H-38534 | 5.0 | Hybrid Microcircuits, General Specification for |
| MIL-I-38535 | 5.0 | Integrated Circuits (Microcircuits) Manufacturing, General Spectication for |
| MIL-C-38999 | 15.1 | Connector, Electrical, Circular, Miniature, High Density, Quick Disconnect, (Bayonet, Threaded, and Breech Coupling) Environment Resistant, Removable Crimp and Hermetic Solder Contacts, General Specification for |
| MIL-C-39001 | 10.7 | Capactior, Fbred, Mica Dielectric, Established Reliability, General Specification for |
| MIL-R-39002 | 9.11 | Reststor, Variable, Wirewound, Semi-Precision, General Spectication for |
| MIL-C-39003 | 10.12 | Capacitor, Fixed, Electrolytic. (Solid Electrolyte), Tantalum, Eatablished Reliability, General Specificution for |
| MIL-R-39005 | 9.5 | Resistor, Fured, Wirewound, (Accurate) Establishod Rollability, General Specitication for |
| MIL-C-39006 | 10.13 | Capacitor, Fixed, Electrolytic (Nonsolid Electrolyte) Tantalum Established Reliability, General Specification for |
| MIL-R-39007 | 9.6 | Resistor, Fixed, Wirewound (Power Type) Established Reliability. General Specification for |


| SPECIFICATION | SECTION* | TIIE |
| :---: | :---: | :---: |
| MIL-R-39008 | 9.1 | Resistor, Fered, Composition, (Insulated) Established Reliability, General Specification for |
| MLI-R39009 | 9.7 | Restator, Fued, Wrowound (Power Type, Chassis Moumed) Established Reliability, General Specification for |
| MIL-C-39010 | 11.2 | Coll, Fired, Radio Frequency, Moided, Established Reliability, General Specification for |
| M ${ }^{\text {L }}$-C-39012 | 15.1 | Connector, Coaxial, Radio Frequency, General Specification for |
| M1-C-39014 | 10.10 | Capacitor, Fbeed, Ceramic Dielectric (General Purpose) Established Reliability, General Specification for |
| MR-C-39015 | 9.9 | Resietor, Variable, Wirewound (Lead Screw Actuated) Established Reliability, General Specification for |
| MUL-R-39016 | 13.1 | Relay, Electromagnetic, Established Reliability, General Specification for |
| MIL-R-39017 | 9.2 | Reeistor, Fixed, Film (Insulated), Established Reliability, General Specification for |
| MIL-C-39018 | 10.14 | Capacitor, Fixed, Electrohytic (Ahuminum Oxide) Established Reliability and Nonestablished Reliability, General Specification for |
| MHL-C-39019 | 14.5 | Cricult Breakers, Magnetic, Low Power, Seated, Trip-Free, General Specilication for |
| MIL-C-39022 | 10.4 | Capecitor, Fixed, Metallized Paper, Paper-Plastic Film, or Plastic Film Dieloctric, Direct and Ahernating Current (Hermetically Sealed in Metal Cases) Established Reliability, General Specification for |
| MIL-R-39023 | 9.15 | Resistor, Variable, Nonwirewound, Precision, General Specification for |
| MIL-R-39035 | 9.13 | Resistor, Variable, Nonwirewound, (Adjustment Type) Established Reliability, General Spectfication for |
| MIL-C-49142 | 15.1 | Connector, Triaxial, RF, General Specification for |
| MR.P-55110 | 15.2 | Printed Wiring Boards |
| MIL-R-55182 | 9.2 | Resistor, Fixed, Fint, Established Reliability, General Specification for |
| MIL-C-55235 | 15.1 | Connector, Coaxial, RF. General Specification for |
| MIL-C-55302 | 15.2 | Connector, Printed Circuit, Subassembly and Accessories |
| M 1 L-C-55339 | 15.1 | Adapter, Cosoxial, RF, General Specification for |
| M1L-C-55514 | 10.5 | Cepecthor, Fixed, Plestic (or Motallized Plastic) Dielectric, Direct Current, In Non-Métal Cases, General Specification for |
| MIL-C-55629 | 14.5 | Circuit Breaker, Magnetic, Unsealed, Trip-Free, General Specification for |
| MRL-T-55631 | 11.1 | Transformer, Intermediate Frequency, Radio Frequency, and Discriminator, General Specification for |


| SPECIFICATION | SECTION* | IITLE |
| :---: | :---: | :---: |
| MHL-C-55681 | 10.11 | Capacitor, Chip, Multiple Layer, Fixed, Ceramic Dielectric, Established Reliability, General Specification for |
| MRL-C-81511 | 15.1 | Connector, Electrical, Circular, High Density, Quick Dieconnect, Environment Resisting, and Accessories, General Spectication for |
| MIL-C-83383 | 14.5 | Circuit Breaker, Remote Control. Thermal, Trip-Free. General Specirication for |
| MKL-R-83401 | 9.4 | Pesistor Networks, Fixed, Film. General Spectication for |
| MIL-C-83421 | 10.6 | Capacitor, Fixed Supermetallized Plastic Film Dielectric (DC, AC or DC and AC) Hermeticaliy Sealed in Metal Cases, Estabtished Reliability. General Epecilication for |
| MIL-C-83513 | 15.1 | Connector, Electrical, Rectangular, Microminiature, Polarized Shell. General Specticmation for |
| MLL-C-83723 | 15.1 | Connector, Electrical (Circular Environment Resisting). Receptades and Plugs, General Specification for |
| MLL-R-83725 | 13.1 | Relay, Vacuum, General Specitication for |
| MIL-R-83726 | $\begin{array}{r} 13.1 .13 .2 \\ 13.3 \end{array}$ | Relay, Time Delay, Electric and Electronic. General Spectication for |
| MIL-S-83731 | 14.1 | Switch. Toggle, Unsealed and Sealed Toggle, General Specification for |
| Mn_C-83733 | 15.1 | Connector, Electrical, Miniature, Rectangular Type, Rack to Panel, Environment Resisting, 200 Degrees C Total Continuous Operating Temperature, General Specification for |
| MIL-S-83734 | 15.3 | Socket, Plug-in Electronic Components, General Specification for |
| STANDARD |  | TITLE |
| MILSTD-756 | Relin | ty Modeling and Prediction |
| MIL-STD-883 | Test | thods and Procedures for Microelectronics |
| MLL-STD-975 | NAS | Standand Electrical. Electronic and Electromechanical Parts Liet |
| MM.-8TD-1547 |  | Materials and Processes for Space Launch Vehicies, Technical ments for |
| MIL-STD-1772 | Cert | ation Requtroments for Myorid Microcirculi Factilies and Lines |

Copies of specifications and standards required by contractors in connection with specific acquisition functions should be obtalned from the contracting activity or as directed by the contracting officer. Single copies are also available (without charge) upon written request to:

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Standardization Document Order Desk
700 Robins Ave.
Building 4, Section D
Philadelphia, PA 19111-5094
(215) 697-2667
```

3.1 Rellablity EngIneering - Reliability is currently recognized as an essential need in military electronic systems. It is looked upon as a means for reducing costs from the tactory, where rework of defective components adds a non-productive overhead expense, to the field, where repair costs inctude not only parts and labor but also transportation and storage. More importantly, reliability directly impacts force effectiveness, measured in terms of availability or sortie rates, and determines the stze of the "logistics tail" inhibiting force utilization.

The achievement of rellability is the function of reliability engineering. Every aspect of an electronic system, from the purty of materials used in is component devices to the operators interface, has an impact on reliability. Reliability engineering must, therefore, be applied throughout the system's development in a diligent and timely fashion, and integrated whith other engineering disciplines.

A variety of reliability engineering tools have been developed. This handbook provides the modets supporting a basic tool, reliability prediction.
3.2 The Role of Rellablity Prediction - Reliabillty prediction provides the quantitative baseline needed to assess progress in reliability engineering. A prediction made of a proposed design may be used in several ways.

A characteristic of Computer Aided Design is the ability to rapidly generate alternative solutions to a particular problem. Reliability predictions for each design ahernative provide one measure of relative worth which, combined with other considerations, will aid in selecting the best of the available options.

Once a design is seiecied, tune reliability prediction may be used as a guide io improvement by sinowing the highest contributors to failure. If the part stress analysis method is used, it may also reveal other frultul areas tor change (e.g., over stressed parts).

The impact of proposed design changes on reliability can be determined only by comparing the reliability predictions of the existing and proposed designs.

The ability of the design to maintain an acceptable reliability level under environmental extremes may be assessed through reliability predictions. The predictions may be used to evaluate the need for environmental control systems.

The effects of complexity on the probability of mission success can be evaluated through reliability predictions. The need for redundant or back-up systems may be determined with the aid of reliability predictions. A tradeoff of redundancy against other reliability enhancing techniques (e.g.: more cooling, higher part quality, etc.) must be based on reliability predictions coupled with other pertinent considerations such as cost, spece lifritations, etc.

The prediction will also help evahuate the sionlicance of reported fallures. For example, h several fallures of one type or component occur in a system, the predicted fallure rate can be used to determine whether the number of fallures is commensurate with the number of components used in the system, or, that it indicates a problom area.

Finally, rellability predictions are usetul to various other engineering analyses. As examples, the location of built-in-test circuitry should be influenced by the predicted failure rates of the circuliry monitored, and maintenance strategy planners can make use of the relative probability of a fallure's location, based on predictions, to minimize downtime. Reliability predictions are also used to evaluate the probabilities of failure events described in a failure modes, effects and criticality analysis (FMECAs).
3.3 Limitations of Rellability Predictions - This handbook provides a common basis for reliability predictions, based on analysis of the best available data at the time of lssue. It is intended to make reliability prediction as good a tool as possible. However, 隹e any tool, reliability prediction must be used intelligently, with due consideration of its limitations.

The first limitation is that the failure rate models are point estimates which are based on available data. Hence, they are valid for the condifions under which the data was obtained, and for the devices covered. Some extrapolation during model development is possible, but the inherently empirical nature of the modeis can be severely resiricive. For exampie, none oi the modeis in this handibook predict nuciear survivability or the effects of ionizing radiation.

Even when used in similar environments, the differences between system applications can be significant. Predicted and actieved rellability have aways been closer for ground electronic systems than for avionic systems, because the environmental stresses vary less from system to system on the ground and hence the field conditions are in general closer to the environment under which the data was collected for the prediction model. However, failure rates are also impacted by operational scenarios, operator characteristics, maintenance practices, measurement tectniques and differences in deftintion of talture. Hence, a rellabllity prediction should nover be assumed to represent the expected fiald rellability as measured by the user (i.e., Mean-Time-Between-Maintenance, Mean-Time-Between-Removals, etc.). This does not negate its value as a reliability engineering tool; note that none of the applications discussed above requires the predicted reliability to match the field measurement.

Electronic technology is noted for its dynamic nature. New types of devices and new processes are continually introduced, compounding the difficulties of predicting reliability. Evolutionary changes may be handled by extrapolation from the existing models; revolutionary changes may dety analysis.

Another limitation of rellabilty predictions is the mechanics of the process. The part stress analysis method requires a signilicant amount of design detail. This naturally imposes a time and cost penalty. More significantly, marry of the detalis are not avaliable in the earty design stages. For this reason this handbook contains both the part stress anabyets mothod (Soctions 5 through 23) and a simpler parts coumt method (Appendix A) which can be used in earty design and bid formulation stages.

Finally, a basic limitation of reliability prediction is its dependence on correct application by the user. Those who correctly apphy the modets and use the information in a conscientious reliability program will find the prediction a usetul tool. Those who view the prediction only as a number which must exceed a specified value can usually find a way to achieve their goal without any impact on the system.

### 3.4 Part Stress Analysis Prediction

3.4.1 Appicability - This method is applicabie when most of the design is completed and a detailed parts list including part stresses is avallable. It can also be used during later design phases for rellability trade-offs vs. part selection and stresses. Sections 5 through 23 contain failure rate modets for a broad variety of parts used in electronic equipment. The parts are grouped by major categorles and, where appropriate, are subgrouped whin categories. For mechanical and electromechanical parts not covered by this Handboos, reffer to Dibliographyy Hems 20 and 36 (Appendix C).
The failure rates presented apply to equipment under normal operating conditions, i.e., with power on and performing its intended functions in is intended environment. Extrapolation of amy of the base fallure rate models beyond the tabulated values such as high or sub-zero temperature, electrical stress values above 1.0, or extrapolation of any associated model modifiers is completely invalid. Base fallure rates can be interpolated between electrical stress values from 0 to 1 using the undertying equations.

The general procedure for determining a board level (or system level) failure rate is to sum individually calculated fallure rates for each component. This summation is then added to a failure rate for the circuit board (which inchudes the effects of soldering parts to ti) using Section 16, Interconnection Assemblies.

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For parts or wires soldered together (e.g., a jumper wire between two parts), the connections model appearing in Section 17 is used. Finally, the effects of connecting circuit boards together is accounted for by adding in a failure rate for each connector (Section 15, Connectors). The wire between connectors is assumed to have a zero failure rate. For various service use profiles, duty cycles and redundancies the procedures described in MIL-STD-756, Reliability Modeling and Prediction, should be used to determine an effective system level faikre rate.
3.4.2 Part Quality - The qualty of a part has a direct effect on the part fallure rate and appears in the part models as a factor, $\pi_{Q}$. Many parts are covered by specifications that have several quality levels, hence, the part models have vabues of $\pi_{Q}$ that are keyed to these quality levels. Such parts with their quality designators are shown in Table 3-1. The detalled requirements for these levels are clearty defined in the applicable specification, except for microcircults. Microcircuits have quality levels which are dependent on the number of MiL-STD-883 screens (or equivatent) to which they are subjected.

Table 3-1: Parts with Multi-Level Quallty Specifications

| Part | Quality Designators |
| :--- | :--- |
| Microcircuits | S, B, B-1, Other: Quality Judged by |
| Screening Level |  |
| Discrete Semiconductors | JANTXV, JANTX, JAN |
| Capacitors, Established <br> Reliability (ER) | D, C, S, R, B, P, M, L |
| Resistors, Established <br> Rellability (ER) | S, R, P, M |
| Coils, Molded, R.F., <br> Reliability (ER) | S, R, P, M |
| Relays, EStablished <br> Reliability (ER) | R, P, M, L |

Some parts are covered by older specifications, usually referred to as Nonestablished Reliability (Non-ER), that do not have multi-levels of quality. These part models generally have two quality levels designated as "MIL-SPEC.", and "Lower". If the part is procured in complete accordance with the applicable specification, the $\pi_{Q}$ value for MIL-SPEC should be used. If any requirements are waived, or if a commercial part is procured, the $\pi_{Q}$ value for Lower should be used.

The foregoing discussion involves the "as procured" part quality. Poor equipment design, production, and testing facilities can degrade part quality. The use of the higher quality parts requires a total equipment design and quality control process commensurate with the high part quality. It would make little sense to procure high quality parts only to have the equipment production procedures damage the parts or introduce latent defects. Total equipment program descriptions as they might vary with different part quality mixes is beyond the scope of this Handbook. Reliability management and quality control procedures are described in other DOD standards and publications. Nevertheless, when a proposed equipment development is pushing the state-of-the-art and has a high reliability requirement necessitating high quality parts, the iotal equipment program should be given careful scrutiny and not just
the parts quality. Otherwise, the low faikre rates as predicted by the models for high quality parts will not be realized.
3.4.3 Use Environment - All part reliability models include the effects of environmental stresses through the environmentai iactor, $\pi_{E}$, excepi for tine eifecis of ionizing radiation. The descriptions of these emvironments are shown in Table 3-2. The $x_{E}$ factor is quantified within each part tailure rate model.
These environments encompass the major areas of equipment use. Some equipment will experience more than one environment during its normal use, e.g., equipment in spacecraft. In such a case, the reliability analysis should be segmented, namely, missile launch $\left(M_{L}\right)$ conditions during boost into and return from orbit, and space filight $\left(S_{F}\right)$ while in orbit.

Table 3-2: Environmental Symbol and Description

| Environment | ${ }^{\text {E E S S }}$ Smbol | Equivatom MIL-HDBK-217E. Notice 1 $\pi_{E}$ Symioui | Description |
| :---: | :---: | :---: | :---: |
| Ground, Benign | $G_{B}$ | $G_{B}$ $G_{M S}$ | Nonmobile, temperature and humidity controlled environments readily accessible to maintenance; inciudes iacoratory insiruments and tost equipment, medical electronic equipment, business and scientific computer complexes, and missiies and suppori equipment in ground silos. |
| Ground, Fixad | $G_{F}$ | $G_{F}$ | Noderately controllod environmente such as installation in permanent racks with adequate cooling air and possible installation in unheated buildings; includes permanent installation of air traffic control radar and communications facilities. |
| Ground, Mobile | $G_{M}$ | $\begin{aligned} & G_{M} \\ & M_{P} \end{aligned}$ | Equipment instalied on wheeled or tracked vohicles and equipment manually transported; includes tactical missile ground support equipment, mobile communication equipment, tactical fire direction sysiems, handineid communications equipment, laser designations and range finders. |
| Naval, Sheltered | $\mathbf{N}_{S}$ | $\mathrm{N}_{\mathbf{S}}$ <br> $N_{\text {SB }}$ | Includes sheltered or below deck conditions on surface ships and equipment instalied in submarines. |
| Naval, Unstentered | N | ${ }^{\mathrm{N}}$ <br> $\mathrm{N}_{\mathrm{N}}$ <br> $\mathrm{N}_{\mathrm{H}}$ | Unprotected surface shipborme equipment exposed to weather conditions and equipment immersed in salt water. Inctudes sonar equipment and equipment installod on hydrofoil vessels. |

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Table 3-2: Environmental Symbol and Description (cont'd)

| Environment | $\pi_{E}$ Syimbol | Equivalent MIL-HDBK-217E. Notice 1 $\pi_{E}$ Symbol | Description |
| :---: | :---: | :---: | :---: |
| Aitbome, Inhabited. Cargo | $A_{i C}$ | $\begin{aligned} & A_{I C} \\ & A_{I T} \\ & A_{I D} \end{aligned}$ | Typical conditions in cargo compartments which can be occupied by an alicrew. <br> Environment extremes of pressure, temperature, shock and vibration are minimad. Examples inctude long mission atrorafl such as the C130, C5, B52, and C141. This category alo applise to inhahined areae in iown performance smaller aircraft such as the T38. |
| Airborne, Inhabited. Fighter | $\mathrm{A}_{\text {IF }}$ | $\begin{aligned} & A_{I F} \\ & A_{i A} \end{aligned}$ | Same as $A_{I C}$ but installed on high performance aircraft such as fighters and interceptors. Examples include the F15, F16, F111, F/A 18 and A10 aircratt. |
| Airborne, Uninhabited, Cargo | Auc | Auc <br> AUT <br> AUB | Environmentally uncontrolled areas which cannot be inhebuited by an aircrew during flight. Environmental extremes of pressure. temperature and shock may be severe. Cxamples includs uninhatited areas of long mission aircraft such as the C130, C5, B52 and C141. This category also applies to uninhabited area of lower periormance smatler aircraft such as the T38. |
| Airborne. Uninhabited, Fighter | ALF | AuF <br> A UA | Same as AUC but installed on high performance aircraft such as fighters and interceptors. Examples include the F15, F16, F111 and A10 aircratt. |
| Airborne, Rotary Winged | $A_{\text {AW }}$ | ${ }^{\text {A PWW }}$ | Equipment instalied on helicopters. Applies to both internally and externally mounted equipment such as laser designators, fire control systems, and communications equipment. |
| Space, Flight | $S_{F}$ | $S_{F}$ | Eäth ortùal. Approactes benign ground conditions. Vehicle nelther under powered flight nor in atmospheric reentry; includes sateilites and shutties. |

### 3.0 INTRODUCTION

Table 3-2: Environmental Symbol and Description (cont'd)

| Environment | $\pi_{E}$ Symbol | Equivalent MILHDBK-217E, Notice 1 $\pi_{E}$ Symbol | Description |
| :---: | :---: | :---: | :---: |
| Missile, Flight | $M_{F}$ | $\begin{aligned} & M_{F F} \\ & M_{F A} \end{aligned}$ | Conditions related to powered flight of air breathing missiles, cruise missiles, and missiles in unpowered free flight. |
| Missile, Launch | $M_{L}$ | $\begin{aligned} & M_{L} \\ & U_{S L} \end{aligned}$ | Severe conditions related to missilie launch (air, ground and sea), space vehicle boost into orbit, and vehicle re-entry and landing by parachute. Also applies to solid rocket motor propulston powered tigit. and torpedo and missile launch from submarines. |
| Cannon, Launch | $C_{L}$ | $C_{L}$ | Extremely severe conditions related to cannon launching of 155 mm . and 5 inch guided projectiles. Conditions apply to the projectile from launch to target impact. |

3.4.4 Part Fallure Rate Models - Part failure rate models for microelectronic parts are significantly different from those for other parts and are presented entirely in Section 5.0. A typical example of the type of model used for most other part types is the following one for discrete semiconductors:

$$
\lambda_{\mathrm{P}}=\lambda_{\mathrm{B}} \pi_{\mathrm{T}} \pi_{\mathrm{A}} \pi_{\mathrm{R}} \pi_{\mathrm{S}} \pi_{\mathrm{C}} \pi_{\mathrm{Q}} \pi_{\mathrm{E}}
$$

where:
$\lambda_{p}$ is the part failure rate,
$\lambda_{\mathrm{b}}$ is the base failure rate usually expressed by a model relating the influence of electrical and temperature stresses on the part,
$\pi_{E}$ and the other $\pi$ factors modify the base failure rate for the category of environmental application and other parameters that affect the part reliability.

The $\pi_{E}$ and $\pi_{Q}$ factors are used in most all models and other $\pi$ factors apply only to specific models. The applicability of $\pi$ factors is identified in each section.

The base failure rate $\left(\lambda_{b}\right)$ models are presented in each part section along with identification of the applicable model factors. Tables of calculated $\lambda_{\mathrm{b}}$ values are also provided for use in manual calculations. The model equations can, of course, be incorporated into computer programs for machine processing. The tabulated values of $\lambda_{\mathrm{b}}$ are cut off at the part ratings with regard to temperature and stress, hence, use of parts beyond these cut off points will overstress the part. The use of the $\lambda_{b}$ models in a computer

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program should take the part rating limits into account. The $\lambda_{\mathrm{b}}$ equations are mathematically continuous beyond the part ratings but such failure rate values are invalid in the overstressed regions.

Al the part modets inctude failure data from both catastrophic and permanent drift failures (e.g., a resistor permanently falling out of rated tolerance bounds) and are based upon a constant failure rate, except for motors which show an increasing failure rate over time. Faikures associated with connection of parts into circuit assemblies are not included within the part failure rate models. Information on connection reliability is provided in Sections 16 and 17.
3.4.5 Thermal Aspects - The use of this prediction method requires the determination of the temperatures to which the parts are subjected. Since parts reliability is sensitive to temperature, the thermal anahysis of any design should faity accuratety provide the ambient temperatures noedod in using the part models. Of course, lower temperatures produce better reliability but also can produce increased penatties in terms of added loads on the environmental control system, unless achieved through improved thermal design of the equipment. The thermal analysis shouid be part of the design process and included in all the trade-off studies covering equipment pertormance, reliability, weight, volume, environmental control systems, etc. References 17 and 34 listed in Appendix C may be used as guides in determining component temperatures.
 For completeness, the chacklist inctudes catogories for roliability modeling and alfocation, which are sometimes delivered as part of a prediction report. It should be noted that the scope of any reliability analysis depends on the specific requirements called out in a statement-of-work (SOW) or system specification. The inclusion of this checklist is not intended to change the scope of these requirements.

Table 4-1: Rellabillty Analysis Checklist

| Major Concerns | Comments |
| :---: | :---: |
| MODELS <br> Are all functional elements included in the reliability block diagram /model? <br> Are all modes of operation considered in the math modet? <br> Do the math model results show that the design achioves the reliability requiremeni? | System design drawings/diagrams must be reviowed to be sure that the reliability modeVdiagrem agrees with the hardware. <br> Duty cycles, ahernate paths, degraded conditions and redundant units must be defined and modeted. <br> Unit failure rates and redundancy equations are used from tine detaiied pari predictions in the system math model (Soe MIL-STD-756, Reliability Prediction and Modeling). |
| ALLOCATION <br> Are system reliability requirements allocated (subdivided) to useful levels? <br> Does the allocation process consider complexity, design tiexioility, and safeity margins? | Useful levels are defined as: equipment for subcontractors, assemblies for sub-subcontractors, circuil boards for designers. <br> Conservative values are needed to prevent reallocation at every desigñ change. |
| PREDICTION <br> Does the sum of the parts equal the value of the module or unit? <br> Are environmental conditions and part quality representative of the requirements? <br> Are the circuit and part temperatures defined and do they represent the design? <br> Are equipment, assembly, subassembly and part reliability drivers identified? <br> Are alternate (Non MIL-HDBK-217) failure rates higniigited aiong with the rationaie for their use? <br> Is the level of detail for the part failure rate models sufficient to reconstruct the result? <br> Are critical components such as VHSIC, Monolithic Microwave Integrated Circults (MMIC), Application Specific Integrated Circuits (ASIC) or Hybrids highlighted? | Many predictions neglect to include all the parts producing optimistic results (check for solder connections, connectors, circuit boards). <br> Optimistic quality lovels and favorable onvironmental conditions are often assumed causing optimistic results. <br> Temperature is the biggest driver of part failure rates; low temperature assumptions will cause optimistic res̃ults. <br> Identification is needed so that corrective actions for reliability improvement can be considered. <br> Use of altemate failure rates, if deemed necessary, require submission of backup data to provide credence in the values. <br> Each component type should be sampled and failure rates completely reconstructed for accuracy. <br> Prediction methods for advanced technology parts should be carefully evaluated for impact on the module and system. |

This section presents fallure rate prediction models for the following ten major classes of microelectronic devices:

| $\frac{\text { Section }}{5.1}$ | Monolithic Pipolar Digital and Linear Gate/Logic Array Devices |
| :--- | :--- |
| 5.1 | Monolithic MOS Digital and Linear Gate/Logic Array Devices |
| 5.1 | Monolithic Bipolar and MOS Digital Microprocessor Devices |
| 5.2 | Monolithic Bipolar and MOS Memory Devices |
| 5.3 | Very High Speed integraied Circuit (VHSICNHSiC-Like and VLSi) CMOS Devices is <br> Gates) |
| 5.4 | Monolithic GaAs Digital Devices |
| 5.4 | Monolithic GaAs MAMIC |
| 5.5 | Hybrid Microcircuits |
| 5.6 | Suriace Acoustic Wave Devices |
| 5.7 | Magnetic Bubble Memories |

in the titie description of each monolithic device type, Bipolar represerts all TTL, ASTTL, DTL, ECL, CMA, ALSTTL, HTTL, FTTL, F, LTTL, STTL, BICMOS, LSTTL, IIL, I ${ }^{3}$ L and ISL devices. MOS represents all metal-oxide microcircuits, which includes NMOS, PMOS, CMOS and MNOS tabricated on various substrates such as sapphire, polycrystalline or single crystal silicon. The hybrid model is structured to accommodate all of the monolthic chip device types and various complexity levels.

Monolithic memory complexity factors are expressed in the number of bits in accordance with JEDEC STD 21A. This standard, which is used by all government and industry agencies that deal with microcircuit memories, states that memories of 1024 bits and greater shall be expressed as K bits, where $1 \mathrm{~K}=1024$ bits. For example, a 16 K memory has 16,384 bits, a 64 K memory has 65,536 bits and a 1 M memory has $1,048,576$ bits. Exact numbers of bits are not used for memories of 1024 bits and greater.

For devices having both linear and digital functions not covered by MIL-M-38510 or MIL-I-38535, use the linear modiei. Line drivers and line receivers are considered linear devices. For linear devices not covered by MIL-MI-38510 or MIIL=-38535, use the transistor count from the schematic diagram of the device to determine circuit complexity.

For dightal devices not covered by MIL-M-38510 or MIL-I-38535, use the gate count as determined from the logic diagram. A J-K or R-S flip flop is equivalent to 6 gates when used as part of an LSI circuit. For the purpose of this Handbook, a gate is considered to be any one of the following functions; AND, OR, exclusive OR, NAND, NOR and inverter. When a logic diagram is unavailable, use device transistor count to determine gate count using the following expressions:

| Technology | Gate Approximation |
| :--- | :--- |
| Bipolar | No. Gates $=$ No. Transistors/3.0 |
| CMOS | No. Gates $=$ No. Transistors/4.0 |
| All other MOS except CMOS | No. Gates $=$ No. Transistors/3.0 |

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### 5.0 MICROCIRCUITS, INTRODUCTION

A detailed form of the Section 5.3 VHSICNHSIC-Like model is inctuded as Appendix B to allow more detalled trade-ofis to be performed. Reference 30 should be consulted for more information about this model.

Reference 32 should be consulted for more Information about the modols appearing in Sections 5.1, 5.2, 5.4,5.5, and 5.6. Reference 13 should be consulted for additional information on Section 5.7.

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5.1 MICROCIRCUITS, GATE/LOGIC ARRAYS AND MICROPROCESSORS

DESCRIPTION

1. Bipolar Devices, Dighal and Linear Gate/Logic Arrays
2. MOS Devices, Digtal and Linear Gate/Logic Arrays
3. Field Programmable Logic Array (PLA) and Programmable Array Logic (PAL)
4. Microprocessors

$$
\lambda_{p}=\left(C_{1} \pi_{T}+C_{2} \pi_{E}\right) x_{Q} \sigma_{L} \quad \text { Faikres/10 }{ }^{6} \text { Hours }
$$

Bipolar Digital and Linear Gate/Logic Array Die Complexily Faihre Rate - $\mathrm{C}_{1}$

| Digital |  | Linear |  |  |  | PLAMPAL |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| No. Gates | $C_{1}$ | No. | Tran | cistors | $\mathrm{C}_{1}$ | No. Gates | $\mathrm{C}_{1}$ |
| 1 to 100 | . 0025 | 1 | to | 100 | . 010 | Up to 200 | . 010 |
| 101 to 1,000 | . 0050 | 101 | to | 300 | . 020 | 201 to 1,000 | . 021 |
| 1,001 to 3,000 | . 010 | 301 | to | 1.000 | . 040 | 1,001 to 5,000 | . 042 |
| 3,001 to 10,000 | . 020 | 1,001 |  | 10,000 | . 060 |  |  |
| 10,001 to 30,000 | . 040 |  |  |  |  |  |  |
| 30,001 to 60,000 | . 080 |  |  |  |  |  |  |

MOS Digital and Linear Gate/Logic Array Die Complexily Fallure Rate - $\mathrm{C}_{1}{ }^{\text {* }}$

*NOTE: For CMOS gate counts above $\mathbf{6 0 , 0 0 0}$ use the VHSICNHSIC-Like model in Section 5.3

Microprocessor
Die Complexity Failure Rate - $\mathrm{C}_{1}$

| No. Bits | Bipolar $_{1}$ | MOS |
| :--- | :---: | :---: |
|  | .060 | .14 |
| Up to 16 | .12 | .28 |
| Up to 32 | .24 | .56 |

All Other Model Parameters

| Parameter | Refer to |
| :--- | :--- |
| $\pi_{\mathrm{T}}$ | Section 5.8 |
| $C_{2}$ | Section 5.9 |
| $\pi_{\mathrm{E},} \pi_{\mathrm{Q}}, \pi_{\mathrm{L}}$ | Section 5.10 |

## DESCRIPTION

1. Read Only Memories (ROM)
2. Programmable Read Only Memories (PROM)
3. Ukraviolet Eraseable PROMs (UVEPROM)
4. "Flash," MNOS and Floating Gate Electrically Eraseable PROMs (EEPROM). Includes both floating gate tunnel oxide (FLOTOX) and textured polysilicon type EEPROMs
5. Static Random Access Memories (SRAM)
6. Dynamic Random Access Memories (DRAM)
$\lambda_{p}=\left(C_{1} \pi_{T}+C_{2} \pi_{E}+\lambda_{\text {cyc }}\right) \pi_{Q} \pi_{L}$. Failures $/ 10^{6}$ Hours

Die Complexity Failure Rate - $\mathrm{C}_{1}$

| Memory Size, B (Bits) | MOS |  |  |  | Bipolar |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | ROM | PROM, UVEPROM, EEPPROM, EAPROM | DRAM | SRAM (MOS \& BiMOS) | ROM, PROM | SRAM |
| Up to 16 K | . 00065 | . 00085 | . 0013 | . 0078 | . 0094 | . 0052 |
| 16 K < $\mathrm{B} \leq 64 \mathrm{~K}$ | . 0013 | . 0017 | . 0025 | . 016 | . 019 | . 011 |
| $64 \mathrm{~K}<\mathrm{B} \leq 256 \mathrm{~K}$ | . 0026 | . 0034 | . 0050 | . 031 | . 038 | . 021 |
| $256 \mathrm{~K}<\mathrm{B} \leq 1 \mathrm{M}$ | . 0052 | . 0068 | . 010 | . 062 | . 075 | . 042 |


| A $_{1}$ Factor for $\lambda_{\text {cyc }}$ Calculation |
| :---: |
| Total No. of <br> Programming <br> Cycles Over <br> EEPROM Life, Flotox ${ }^{1}$ Textured- <br> Poly <br> Up to 100 .00070 .0097 <br> $100<C \leq 200$ .0014 .014 <br> $200<C \leq 500$ .0034 .023 <br> $500<C \leq 1 K K$ .0068 .033 <br> $1 K<C \leq 3 K$ .020 .061 <br> $3 K<C \leq 7 K$ .049 .14 <br> $7 K<C \leq 15 K$ .10 .30 <br> $15 K<C \leq 20 K$ .14 .30 <br> $20 K<C \leq 30 K$ .20 .30 <br> $30 K<C \leq 100 K$ .68 .30 <br> $100 K<C \leq 200 K$ 1.3 .30 <br> $200 K<C \leq 400 K$ 2.7 .30 <br> $400 K<C \leq 500 K$ 3.4 .30 |

1. $A_{1}=6.817 \times 10^{-6}$ (C)
2. No underlying equation for TexturedPoly.
$\mathrm{A}_{2}$ Factor for $\lambda_{\text {cyc }}$ Calculation

| Total No. of Programming <br> Cycles Over EEPROM <br> Llfe, C | Textured-Poly $A_{2}$ |
| :--- | :---: |
| Up to 300 K | 0 |
| $300 \mathrm{~K}<\mathrm{C} \leq 400 \mathrm{~K}$ | 1.1 |
| $400 \mathrm{~K}<\mathrm{C} \leq 500 \mathrm{~K}$ | 2.3 |

All Other Model Parameters

| Parametor | Refer to |
| :--- | :--- |
| $\pi_{T}$ | Section 5.8 |
| $C_{2}$ | Section 5.9 |
| $\pi_{E}, \pi_{Q}, \pi_{L}$ | Section 5.10 |
| $\lambda_{\text {cyc }}$(EEPROMS <br> only | Page 5-5 |
| $\lambda_{\text {cyc }}=0 \quad$ For all other devices |  |




NOTES: 1. See Reference 24 for modeling off-chip error detection and correction scinemes at tine memory sysiem ievei.
2. If EEPROM type is unknown, assume Flotox.
3. Error Correction Code Options: Some EEPROM manuiaciurers have incorporaied on-chip error correction circuitry into their EEPPOM devices. This is represented by the on-chip hamming code entry. Other manufacturers have taken a redundant cell approach which incorporates an extra storage transistor in every memory cell. This is represented by the two-needs-one redundiant celi entry.
4. The $A_{1}$ and $A_{2}$ factors shown in Section 5.2 were developed based on an assumed system life of 10,000 operating hours. For EEPROMs used in systems wh signiticantly longer or shorter expected lifetimes the $A_{1}$ and $A_{2}$ factors should be multiplied by:

10,000
System Lifetime Operating Hours

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5.2 MICROCIRCUITS, MEMORIES
$\mathrm{B}_{1}$ and $\mathrm{B}_{2}$ Factors for $\lambda_{\text {cyc }}$ Calculation


## DESCRIPTION

CMOS greater than $\mathbf{6 0 , 0 0 0}$ gates

Die Base Falture Rate - $\lambda_{\mathrm{gD}}$

| Part Type | $\lambda_{\mathrm{BD}}$ |
| :--- | :--- |
| Logic and Custom | 0.16 |
| Cote Array | 0.24 |

Manuracturing Process Correction Faotor - $\bar{\pi}_{\text {MFG }}$

| Mânufacturing Process | MMFG |
| :--- | :---: |
| QML or QPL | .55 |
| Non QML or Non QPL | 2.0 |

All Other Model Parameters

| Parameter | Refer to |
| :--- | :--- |
| $\pi_{T}$ | Section 5.8 |
| $\pi_{E}, \pi_{\mathrm{Q}}$ | Section 5.10 |

Package Type Correction Factor - IpT

|  | $\pi$ TPT |  |
| :--- | :---: | :---: |
| Package Trpe | Hermetic | Nontrormetic |
| DIP | 1.0 | 1.3 |
| Pin Grid Array | 2.2 | 2.9 |
| Chip Carrier | 4.7 | 6.1 |
| (Surface Mount |  |  |
| Technology) |  |  |

Die Complexity Correction Factor $-\pi_{C D}$

| Feature Size <br> (Microns) | $A \leq .4$ | $.4<A \leq .7$ | $.7<A \leq 1.0$ | $1.0<A \leq 2.0$ | $2.0<A \leq 3.0$ |
| :---: | :---: | :---: | :---: | :---: | :---: |
| .80 | 8.0 | 14 | 19 | 38 | 58 |
| 1.00 | 5.2 | 8.9 | 13 | 25 | 37 |
| 1.25 | 3.5 | 5.6 | 8.2 | 16 | 24 |
| $\left.\pi_{C D}=\left(\frac{A}{.21}\right)\left(\frac{2}{X_{s}}\right)^{2}(.64)\right)+.36$ | $A=$ Total Scribed Chip Die Area in $\mathrm{cm}^{2}$ | $X_{3}=$ Feature Size (microns) |  |  |  |
| Die Area Conversion: $\mathrm{cm}^{2}=\mathrm{MIL}^{2}+155,000$ |  |  |  |  |  |



## MIL-HDBK-217F

5.4 MICROCIRCUITS, GAAS MWIC AND DIGITAL DEVICES

## DESCRIPTION

Gallium Arsenide Microwave Monolithic Integrated Circuit (GaAs MMIC) and GaAs Digital Integrated Circults using MESFET Transistors and Gold Based Metallization

$$
\lambda_{p}=\left[C_{1} \pi_{T} \pi_{A}+C_{2} \pi_{E}\right] \pi_{L} \pi_{Q} \text { Falures } 110^{6} \text { Hours }
$$

## MMIC: Die Complexily Failure Rates - $\mathrm{C}_{1}$

| Complexity <br> (No. of Elements) | $C_{1}$ |
| :---: | :---: |
| 1 to 100 | 4.5 |
| 101 to 1000 | 7.2 |

1. $\mathrm{C}_{1}$ accounts for the following active elements: transistors, diodes.

Dioital: Die Complexity Fallure Rates - $\mathrm{C}_{1}$

| Complexity <br> (No. of Elements) | $\mathrm{C}_{1}$ |
| :---: | :---: |
| 1 to 1000 | 25 |
| 1,001 to 10,000 | 51 |

1. $C_{1}$ accounts for the following active elements: transistors, diodes.

# DESCRIPTION <br> Hyourd Microcircuins <br> $\lambda_{P}=\left[\Sigma N_{C} \lambda_{C}\right]\left(1+.2 \pi_{E}\right) \pi_{F} \pi_{O} \pi_{L}$ Failures $/ 10^{6}$ Hours 

$N_{c}=$ Number of Each Patticular Component
$\lambda_{c}=$ Faikre Rate of Each Particular Component
The general procedure for developing an overall hybrid failure rate is to calculate an individual failure rate for each component type used in the hybrid and then sum them. This summation is then modtried to
 failure rate is a function of the active component failure modified by the environmental factor (i.e., ( $1+.2$ $\pi_{\mathrm{E}}$ ) ). Only the component types listed in the following table are considered to contribute significantly to
the overall failure rate of most hybrids. All other component types (e.g., resistors, inductors, etc.) are constdered to contribute insignificantly to the overal hybrid fallure rate, and are assumed to have a lallure rate of zero. This simplification is valid for most hybrids; however, if the hybrid consists of mostly passive components then a failure rate should be caiculated for these devices. it facioring in other component types, assume $\pi_{Q}=1, \pi_{E}=1$ and $T_{A}=$ Hybrid Case Temperature for these calculations.

| $\begin{gathered} \hline \text { Determine } \lambda_{c} \text { for These } \\ \text { Component Types } \\ \hline \end{gathered}$ | Handbook Section | Make These Assumptions When Determining $\lambda_{c}$ |
| :---: | :---: | :---: |
| Microcircuits | 5 | $C_{2}=0, \pi_{Q}=1, \pi_{L}=1, T_{J}$ as Determined from Section 5.12, $\lambda_{\mathrm{BP}}=0$ (for VHSIC). |
| Discrete Semiconductors | 6 | $\pi_{Q}=1, T_{J}$ as Determined from Section 6.14, $\pi_{E}=1$. |
| Capactors | 10 | $\begin{aligned} & \pi_{\mathrm{Q}}=1, T_{\mathrm{A}}=\text { Hybrid Case Temperature, } \\ & \pi_{\mathrm{E}}=1 . \end{aligned}$ |
| NOTE: If maximum rated stress for a die is unknown, assume the same as for a discrototy package die of the same type. If the same die has several ratings based on the discrete packaged type, assume the lowest rating. Power rating used should be based on case temperature for discrete semiconouctors. |  |  |
| Circuit Function Factor - $\pi_{F}$ |  | All Other Hybrid Model Parameters |
| Circuit Type | $\pi_{\text {F }}$ | Refer to Section 5.10 |
| Digital | 1.0 |  |
| Video, 10 MiHz < i < i GHz | 1.2 |  |
| Microwave, $1>1 \mathrm{GHz}$ | 2.6 |  |
| Linear, $\mathrm{i}<10 \mathrm{MHz}$ | 5.8 |  |
| Power | 21 |  |

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### 5.6 MCROCIRCUITS, SAW DEVICES

## DESCRIPTION Surface Acoustic Wave Devices

$$
\lambda_{P}=2.1 \pi_{Q} \pi_{E} \text { Failures/10 }{ }^{6} \text { Hours }
$$


Environmental Factor $-\pi_{E}$

| Environment | $\pi_{E}$ |
| :---: | :---: |
| $\mathrm{G}_{\mathrm{B}}$ | .5 |
| $\mathrm{G}_{\mathrm{F}}$ | 2.0 |
| $\mathrm{G}_{\mathrm{M}}$ | 4.0 |
| $\mathrm{~N}_{\mathrm{S}}$ | 4.0 |
| $\mathrm{~N}_{\mathrm{U}}$ | 6.0 |
| $\mathrm{~A}_{\mathrm{I}}$ | 4.0 |
| $\mathrm{~A}_{\mathrm{IF}}$ | 5.0 |
| $\mathrm{~A}_{\mathrm{UC}}$ | 5.0 |
| $\mathrm{~A}_{\mathrm{UF}}$ | 8.0 |
| $\mathrm{~A}_{\mathrm{RW}}$ | 8.0 |
| $\mathrm{~S}_{\mathrm{F}}$ | .50 |
| $\mathrm{M}_{\mathrm{F}}$ | 5.0 |
| $\mathrm{M}_{\mathrm{L}}$ | 12 |
| $\mathrm{C}_{\mathrm{L}}$ | 220 |

### 5.7 MICROCIRCUITS, MAGNETIC BUBBLE MEMORIES

The magnetic bubble memory device in its present form is a non-hermetic assembly consisting of the following two major structural segments:

1. A basic bubble chip or die consisting of memory or a storage area (e.g., an array of minor loops), and required comtrol and detection elements (e.g., generators, various gates and detectors).
2. A magnetic structure to provide controlled magnetic fields consisting of permanent magnets, coils, and a housing.

These two structural segments of the device are interconnected by a mechanical substrate and lead frame. The interconnect substrate in the present technology is normally a printed circuit board. It should be noted that this model does not include extemal support microelectronic devices required for magnetic bubble memory operation. The model is based on Reference 33. The general form of the fallure rate model is:

$$
\lambda_{p}=\lambda_{1}+\lambda_{2} \text { Failures/ } 10^{6} \text { Hours }
$$

where:
$\lambda_{1}=$ Failure Rate of the Control and Detection Structure
$\lambda_{1}=\pi_{\mathrm{Q}}\left[N_{\mathrm{C}} \mathrm{C}_{11} \pi_{\mathrm{T} 1} \pi_{\mathrm{W}}+\left(\mathrm{N}_{\mathrm{C}} \mathrm{C}_{21}+\mathrm{C}_{2}\right) \pi_{\mathrm{E}}\right] \pi_{\mathrm{D}} \pi_{\mathrm{L}}$
$\lambda_{2}=$ Failure Rate of the Memory Storage Area
$\lambda_{2}=\pi_{Q} N_{C}\left(C_{12} \pi_{T 2}+C_{22} \pi_{E}\right) \pi_{L}$


Device Complexity Failure Rates for Control and Detection Structure - $\mathrm{C}_{11}$ and $\mathrm{C}_{21}$

$$
\begin{aligned}
& C_{11}=.00095\left(N_{1}\right) \cdot 40 \\
& C_{21}=.0001\left(N_{1}\right) .226
\end{aligned}
$$

$N_{1}=$ Number of Dissipative Elements on a Chip (gates, detectors, generators, etc.), $\mathrm{N}_{1} \leq 1000$

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### 5.7 MICROCIRCUIT, MAGNETIC BUBBLE MEMORIES



Device Complexity Failure Rates for Memory Storage Stnucture - $\mathrm{C}_{12}$ and $\mathrm{C}_{22}$
$C_{12}=.00007\left(N_{2}\right)^{3}$
$C_{22}=.00001\left(\mathrm{~N}_{2}\right)^{3}$
$N_{2}=$ Number of Bits, $N_{2} \leq 9 \times 10^{6}$

All Other Model Parameters

| Parameter | Section |
| :--- | :--- |
| $\mathrm{C}_{2}$ | 5.9 |
| $\pi_{E}, \pi_{\mathrm{Q}}, \pi_{\mathrm{L}}$ | 5.10 |


| Temperature Factor For All Microcircuits - $\pi$ T $T$ |  |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | TIL ASTM. CML HTLL FTM OTL, ECL, ALSTLL | F. LTTL, STTL | $\begin{aligned} & \text { BiCMOS, } \\ & \text { LSTR } \end{aligned}$ | III, I'L, ISL | Drgita MOSS, Vhsic cmios | Linear (Bipolar \& MOS) | Mamories (Bipoter 1 mos. MMOS | Gade manc Acifve <br> Denices, TTA | Galle Dightal Active <br> Devices, $\mathrm{K}_{\mathrm{TA}}$ |
| $\begin{aligned} & \mathrm{Ea}(\mathrm{eV}) \rightarrow \\ & \left.\mathrm{T}_{\mathrm{f}}{ }^{\circ} \mathrm{C}\right) \end{aligned}$ | . 4 | . 45 | . 5 | . 6 | . 35 | . 65 | . 6 | - 1.6 | - 1.4 |
| 25 | . 10 | 10 | .10 | 10 | . 10 | . 10 |  |  |  |
| 30 35 | . 13 | . 13 | 14 | . 15 | . 13 | . 15 | . 15 | 3. $0.40 E-09$ | 1.00E-08 |
| 35 40 | . 17 | . 18 | . 19 | 21 | . 16 | . 23 | . 21 | 2.10E-00 | 5. $20 \mathrm{E}-08$ |
| 45 | . 21 | ${ }^{23}$ | . 24 | . 31 | . 19 | . 34 | . 31 | 6.20E00 | 1.40E-07 |
| 50 | . 33 | . 39 | . 34 | . 43 | . 24 | 49 | . 43 | 1.30E-07 | $3.105-07$ |
| 55 | . 42 | . 50 | . 45 | 8.61 | 28 35 | . 71 | . 61 | 2.00E-07 | 6. 60 E-07 |
| 60 | . 51 | . 63 | . 77 | 1.2 | . 42 | 1.0 | 1.8 | 6.70EE07 | 1.50E.06 |
| 65 | . 63 | . 80 | 1.0 | 1.6 | . 50 | 2.0 | 1.2 | 1.50E-08 | 3.10E-08 |
| 70 | . 77 | 1.0 | 1.3 | 2.1 | . 60 | 2.8 | 2.1 | C.COE-05 | 1.30E-05 |
| 75 | . 94 | 1.2 | 1.6 | 2.0 | . 71 | 3.8 | 2.9 | 1.40E-08 | 2.50E-05 |
| 80 85 | 1.1 | 1.5 | 2.1 | 3.8 | . 84 | 5.2 | 3.0 | 2.90E-06 | $4.00 \mathrm{E}-05$ |
| 90 | 1.6 | 2.3 | 2.15 | 5.0 | . 98 | 7.0 | 5.0 | 6.70E-08 | 9.40E.05 |
| ${ }^{\circ}$ | 1.0 | 2.8 | 4.1 | 6.6 8.5 | 1.1 | ${ }_{12} 9$ | 8.6 8.5 | 1.10E-04 | 1.70E-04 |
| 100 | 2.3 | 3.4 | 5.0 | 11 | 1.5 | 16 | $1{ }^{8.5}$ | 2.10E-04 4.00E-04 | 3. $3.20 \mathrm{E}-04$ |
| 105 | 2.7 | 4.1 | 6.2 | 14 | 1.8 | 21 | 14 | 7.50E-04 | 8.00E-03 |
| 110 | 3.2 | 4.8 | 7.5 | 18 | 2.1 | 28 | 18 | $1.40 \mathrm{E}-03$ | $1.60 \mathrm{E}-03$ |
| 115 <br> 120 | 3.7 | 5.8 | 0.2 | 23 | 2.4 | 35 | 23 | $2.40 \mathrm{E}-03$ | 3.10E-03 |
| 120 125 | 1.3 | 6.9 | 11 | 28 | 2.7 | 45 | 28 | 4.30E-03 | 5.30E-03 |
| 130 | 15.8 | 0.2 0.6 | 13 | 35 | 3.1 | 50 | 35 | $7.50 \mathrm{E}-03$ | $0.00 E^{-03}$ |
| 135 | 6.7 | 11 | 19 | 54 | 3.5 | 73 | 4 | 1.30E-02 | 1.50E-02 |
| 140 | 7.7 | 13 | 23 | 67 | 4.4 | 120 | ${ }_{6}^{4}$ | $2.20 \mathrm{E}-02$ | $2.40 \mathrm{E}-02$ |
| 145 | 10.8 | 15 | 27 | 82 | 8.0 | 140 |  | S.10E-02 | 3.00E-02 |
| 150 | 110 | 18 | 32 | 100 | 8.6 | 180 | 100 | 6.10EE02 $1.00 E-01$ | 6.30EE-02 $1.00 \mathrm{E}-01$ |
| 155 | 11 | 20 | 37 | 120 | 6.3 | 220 | 120 | $1.60 \mathrm{E}-01$ | 1.60E-01 |
| 160 165 | 13 | 24 24 | 43 50 | 150 | 7.0 | 270 | 150 | $2.60 \mathrm{E}-01$ | $2.40 \mathrm{E}-01$ |
| 170 | 113 | 31 | 59 | 210 | 8.7 | 330 400 | 180 | 4.10 E .01 | 3.70E-01 |
| 175 | 11 | 35 | 60 | 250 | 0.6 | 480 | 250 250 | S.40EE1 | S.70E-01 |

### 5.9 MICROCIRCUITS, $C_{2}$ TABLE FOR ALL

Package Failure Rate for all Microcircuits - $\mathrm{C}_{2}$

| Package Type |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Number of Functional Pins, $N_{p}$ | Hermetic: DIPs w/Solder or Weld Seal, Pin Grid Array (PGA) ${ }^{1}$, SMT (Leaded and Nonleaded) | DIPs with Glass Seal ${ }^{2}$ | Flatpacks with Axial Leads on 50 Mil Centers ${ }^{3}$ | Cans ${ }^{4}$ | Nonhermetic: DIPs, PGA, SMT (Leaded and Nonleaded) ${ }^{5}$ |
| 3 | . 00092 | . 00047 | . 00022 | . 00027 | . 0012 |
| 4 | . 0013 | . 00073 | . 00037 | . 00049 | . 0016 |
| 6 | . 0019 | . 0013 | . 00078 | . 0011 | . 0025 |
| 8 | . 0026 | . 0021 | . 0013 | . 0020 | . 0034 |
| 10 | . 0034 | . 0029 | . 0020 | . 0031 | . 0043 |
| 12 | . 0041 | . 0038 | . 0028 | . 0044 | . 0053 |
| 14 | . 0048 | . 0048 | . 0037 | . 0060 | . 0062 |
| 16 | . 0056 | . 0059 | . 0047 | . 0079 | . 0072 |
| 18 | . 0064 | . 0071 | . 0058 |  | . 0082 |
| 22 | . 0079 | . 0096 | . 0083 |  | . 010 |
| 24 | . 0087 | . 011 | . 0098 |  | . 011 |
| 28 | . 010 | . 014 |  |  | . 013 |
| 36 | . 013 | . 020 |  |  | . 017 |
| 40 | . 015 | . 024 |  |  | . 019 |
| 64 80 | . 025 | . 048 |  |  | . 032 |
| 128 | . 053 |  |  |  | . 068 |
| 180 | . 076 |  |  |  | . 098 |
| 224 | . 097 |  |  |  | . 12 |

1. $C_{2}=2.8 \times 10^{-4}\left(\mathrm{~N}_{\mathrm{p}}\right)^{1.08}$
2. $C_{2}=3.0 \times 10^{-5}\left(N_{D}\right)^{1.82}$
3. $C_{2}=3.6 \times 10^{-4}\left(N_{p}\right)^{1.08}$
4. $\quad C_{2}=9.0 \times 10^{-5}\left(\mathrm{~N}_{\mathrm{p}}\right)^{1.51}$
5. $\quad \mathrm{C}_{2}=3.0 \times 10^{-5}\left(\mathrm{~N}_{\mathrm{p}}\right)^{2.01}$

## NOTES:

1. SMT: Surface Mount Technology
2. DIP: Dual In-Line Package
3. If DIP Seal type is unknown, assume glass
4. The package failure rate $\left(\mathrm{C}_{2}\right)$ accounts for failures associated only with the package itself.

Failures associated with mounting the package to a circuit board are accounted for in Section 16, Interconnection Assemblies.

### 5.10 MACROCIRCUITS, $\pi_{E}, \lambda_{L}$ AND $\pi_{Q}$ TABLES FOR ALL

| Environment Factor - $\pi_{E}$ |  |
| :---: | :---: |
| Environment $\pi_{E}$ <br> $G_{B}$ .50 <br> $G_{F}$ 2.0 <br> $G_{M}$ 4.0 <br> $N_{S}$ 4.0 <br> $N_{U}$ 6.0 <br> $A_{I C}$ 4.0 <br> $A_{M F}$ 5.0 <br> $A_{U C}$ 5.0 <br> $A_{U F}$ 8.0 <br> $A_{\text {RW }}$ 8.0 <br> $S_{F}$ .50 <br> $M_{F}$ 5.0 <br> $M_{L}$ 12 <br> $C_{L}$ 220 |  |

Learning Factor - $\pi_{L}$

| Years in Production, $Y$ | $\pi_{\mathrm{L}}$ |
| :--- | :---: |
| 5.1 | 2.0 |
| .5 | 1.8 |
| 1.0 | 1.5 |
| 1.5 | 1.2 |
| $\geq 2.0$ | 1.0 |

$\pi_{L}=.01 \exp (5.35-.35 Y)$
$\mathrm{Y}=$ Years generic device type has been in production

| Quality Factors - $\pi_{0}$ |  |
| :---: | :---: |
| Description | $\pi_{0}$ |
| Clans SCatecorios: <br> 1. Procured in full accordance with MIL-M-38510, Class S requirements. <br> 2. Procured in tull accordance with Mil-1-38535 and Appendix B therewo (Class U). <br> 3. Hytrids: (Procured to Class S requirements (Cuality Lovel K) of Mull-H38534. | . 25 |
| Class B Categories: <br> 1. Procured in full accordance with MIL-M-38510, Class B requirements. <br> 2. Procured in full accordance with MIL-I-38535, (Class Q). <br> 3. Hybrids: Procured to Class B requirements (Quality Level H) of MIL-H-38534. | 1.0 |
| Class B-1Categon: <br> Fully compliant with all requirements of paragraph 1.2.1 of MiL-STD-883 and procured to a MiL drawing. DESC drawing or other govemment approved documentation. (Does not include hybrids). For hybrids use custom screening section below. | 2.0 |

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### 5.10 MICROCIRCUITS, $\pi_{E}, \pi_{L}$ AND $\pi_{Q}$ TABLES FOR ALL

Cually Factors (cont'd): $\pi_{Q}$ Calculation for Custom Screening Programs


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### 5.11 MICROCIRCUITS, T」 DETERMINATION, (ALL EXCEPT HYBRIDS)

Ideally, device case temperatures should be determined from a detailed thermal analysis of the equipment. Device junction temperature is then calculated with the following relationship:

$$
T_{J}=T_{C}+\theta_{J C} P
$$

$T_{J}=$ Worst Case Junction Temperature ${ }^{\circ} \mathrm{C}$ ).
$T_{C}=$ Case Temperature $\left({ }^{\circ} \mathrm{C}\right)$. In not avallable, use the following defaull table.

Default Case Temperature ( $T_{C}$ ) for all Environments

| Environment | $G_{B}$ | $G_{F}$ | $G_{M}$ | $N_{S}$ | $N_{U}$ | $A_{1 C}$ | $A_{I F}$ | $A_{U C}$ | $A_{U F}$ | $A_{P W}$ | $S_{F}$ | $M_{F}$ | $M_{L}$ | $C_{L}$ |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- |
| $T_{C}\left({ }^{\circ} C\right)$ | 35 | 45 | 50 | 45 | 50 | 60 | 60 | 75 | 75 | 60 | 35 | 50 | 60 | 45 |

$\theta_{\mathrm{JC}}=$ Junction-to-case thermal resistance $\left({ }^{\circ} \mathrm{C}\right.$ watt) for a device soldered into a printed circuit board. If $\theta_{J C}$ is not available, use a value contained in a specification for the closest equivalent device or use the following table.

| Package Type <br> (Ceramic Only) | Die Area $>14,400$ mil $^{2} \theta_{\mathrm{JC}}$ <br> $\left({ }^{\circ} \mathrm{CN}\right)$ | Die Area $\leq 14,400 \mathrm{mil}^{2}$ <br> $\theta_{\mathrm{JC}}\left({ }^{\circ} \mathrm{CM}\right)$ |
| :--- | :---: | :---: |
| Dual-In-Lime | 11 | 28 |
| Flat Package | 10 | 22 |
| Chip Carrier | 10 | 20 |
| Pin Grid Array | 10 | 20 |
| Can | - | 70 |

$P=$ The maximum power dissipation realized in a system application. If the applied power is not available, use the maximum power dissipation from the specification for the closest equivalent device.

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### 5.12 MICROCIRCUITS, TJ DETERMINATION, (FOR HYBRIDS)

This section describes a method for estimating junction temperature ( $T_{j}$ ) for integrated circuit dice mounted in a hybrid package. A hybrid is normally made up of one or more substrate assemblies mounted within a sealed package. Each substrate assembly consists of active and passive chips with thick or thin film metallization mounted on the substrate, which in turn may have multiple layers of metallization and dielectric on the surface. Figure $5-1$ is a cross-sectional view of a hybrid with a single multi-layered substrate. The layers within the hybrid are made up of various materials with different thermal characteristics. The table following Figure 5-1 provides a list of commonly used hybrid materials with typical thicknesses and corresponding thermal conductivtiles ( $K$ ). If the hybrid imemal structure cannot be determined, use the following defaut vabues for the temperature rise from case to junction: microcircuits, $10^{\circ} \mathrm{C}$; transistors, $25^{\circ} \mathrm{C}$; diodes, $20^{\circ} \mathrm{C}$. Assume capacitors are at $\mathrm{T}_{\mathrm{C}}$.


Figure 5-1: Cross-sectional View of a Hybrid with a Single Mult-Layered Substrate

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### 5.12 MICROCIRCUITS, TJ DETERMINATION, (FOR HYBRIDS)

Typical Hyprid Characteristics

| Material | Typical Usage | Typical Thickness, $L_{i}$ (in.) | Feature From Figure 5-1 | $\begin{aligned} & \text { Thermal } \\ & \text { Conductivity, } \\ & K_{i} \\ & \left(\frac{W / i^{2}}{{ }^{\circ} \mathrm{C} / \mathrm{in}}\right) \end{aligned}$ | $\begin{gathered} \left(\frac{1}{K_{i}}\right)\left(L_{i}\right) \\ \left(i n^{2}{ }^{\circ} \mathrm{C} / \mathrm{W}\right) \end{gathered}$ |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Silicon | Chip Device | 0.010 | A | 2.20 | . 0045 |
| GaAs | Chip Device | 0.0070 | A | . 76 | . 0092 |
| Aut Eutectic | Chip Attach | 0.0001 | B | 6.9 | . 000014 |
| Solder | Chip/Substrate Attach | 0.0030 | B/E | 1.3 | . 0023 |
| Epoxy (Dieleciric) | Chip/Substrate Âtiach | 0.00035 | B/E | . 0060 | . 58 |
| Epoxy (Conductive) | Chip Attach | 0.0035 | B | . 15 | . 023 |
| Thick Firm Dielectric | Glass Insulating Layer | 0.0030 | C | . 66 | . 0045 |
| Alumina | Substrate, MHP | 0.025 | D | . 64 | . 039 |
| Beryllium Oxide | Substrate, PHP | 0.025 | D | 6.6 | . 0038 |
| Kovar | Case, mip | 0.020 | F | . 42 | . 048 |
| Aluminum | Case, MHP | 0.020 | F | 4.6 | . 0043 |
| Copper | Case, PHP | 0.020 | F | 9.9 | . 0020 |

NOTE: MHP: Multichip Hybrid Package, PHP: Power Hybrid Package (Pwr: $\mathbf{2} \mathbf{2 W}$, Typically)

$$
\theta_{J C}=\frac{\sum_{i=1}^{n}\left(\frac{1}{K_{i}}\right)\left(L_{i}\right)}{A}
$$

$n=$ Number of Material Layers
$K_{i}=$ Thermal Conductivity of $i^{\text {ith }}$ Material $\left(\frac{\mathrm{W} / \mathrm{in}^{2}}{{ }^{\circ} \mathrm{C} / \mathrm{in}}\right)$ (User Provided or From Table)
$L_{i}=$ Thickness of $i^{\text {th }}$ Material (in) (User Provided or From Table)
$\mathrm{A}=$ Die Area ( $\mathrm{in}^{\mathbf{2}}$ ). If Die Ârea cannot be readily determined, estimate as follows:
$A=\left[.00278\right.$ (No. of Die Active Wire Terminals) $+.0417^{2}{ }^{2}$
Estimate $T_{J}$ as Follows:

$$
T_{J}=T_{C}+.9\left(\theta_{J C}\right)\left(P_{D}\right)
$$

$T_{C}=$ Hybrid Case Temperature $\left({ }^{\circ} \mathrm{C}\right)$. If unknown, use the $T_{C}$ Default Table shown in Section 5.11.
$\theta_{\mathrm{JC}}=$ Junction-to-Case Thermal Resistance ( ${ }^{\circ} \mathrm{C} / \mathrm{W}$ ) (As determined above)
$P_{D}=$ Die Power Dissipation (W)

## MIL-HDBK-217F

### 5.13 MUCROCIRCUITS, EXAMPLES

## Example 1: CMOS Digital Gate Array

Given: A CMOS digital timing chip (4046) in an airbome inhabited cargo application, case temperature $48^{\circ} \mathrm{C}, 75 \mathrm{~mW}$ power dissipation. The device is procured with normal manufacturers screening consisting of temperature cyciling, constant acceleration, electrical testing, seal test and extemal visual inspection, in the sequence given. The component manufacturer also pertorms a B-tevel bum-in followed by electrical testing. All screens and tests are periormed to the applicable MIL-STD-883 screening method. The package is a 24 pin ceramic DIP with a glass seal. The device has been manufactured for several years and has 1000 transistors.

$$
\lambda_{p}=\left(C_{1} \pi_{T}+C_{2} \pi_{E}\right) \pi_{Q} \pi_{L} \quad \text { Section } 5.1
$$

| $C_{1}$ | $=.020$ | 1000 Transistors $\boldsymbol{\sim} 250$ Gates, MOS C ${ }_{1}$ Table, Digital Column |
| :---: | :---: | :---: |
| $\pi_{T}$ | $=.29$ | Determine $T_{J}$ from Section 5.11 |
|  |  | $\mathrm{T}_{J}=48^{\circ} \mathrm{C}+\left(28^{\circ} \mathrm{C} M(.075 \mathrm{~W})=50^{\circ} \mathrm{C}\right.$ |
|  |  | Determine $\pi_{\mathrm{T}}$ from Section 5.8, Digital MOS Column. |
| $\mathrm{C}_{2}$ | $=.011$ | Section 5.9 |
| $\pi_{\mathrm{E}}$ | $=4.0$ | Section 5.10 |
| $\pi_{Q}$ | $=3.1$ | Section 5.10 |
|  |  | Group 1 Tests 50 Points <br> Group 3 Tests (B-level) 30 Points |
|  |  | TOTAL 80 Points |
|  |  | $\pi_{Q}=2+\frac{87}{80}=3.1$ |
|  | $=1$ | Section 5.10 |

$$
\lambda_{p}=[(.020)(.29)+(.011)(4)](3.1)(1)=.15 \text { Failure } / 10^{6} \text { Hours }
$$

## Example 2: EEPROM

Given: A 128 K Flotox EEPROM that is expected to have a $T_{J}$ of $80^{\circ} \mathrm{C}$ and experience 10,000 read/write cycles over the life of the system. The part is procured to all requirements of Paragraph 1.2.1, MIL-STD-883, Class B screening level requirements and has been in production for three years. It is packaged in a 28 pin DIP with a glass seal and will be used in an airborne uninhabited cargo application.

$$
\pi_{\mathrm{P}}=\left(C_{1} \pi_{T}+C_{2} \pi_{E}+\lambda_{\text {cyc }}\right) \pi_{Q} \pi_{L} \quad \text { Section } 5.2
$$

| $C_{1}=.0034$ | Section 5.2 |
| :--- | :--- |
| $\pi_{T}=3.8$ | Section 5.8 |
| $C_{2}=.014$ | Section 5.9 |

$\pi_{E}=5.0$
$\pi_{Q}=2.0$
$\pi_{\mathrm{L}}=1.0$
$\lambda_{\text {cyc }}=.38$

Section 5.10
Section 5.10
Section 5.10
Section 5.2:
$\lambda_{c y c}=\left[A_{1} B_{1}+\frac{A_{2} B_{2}}{\pi_{Q}}\right] \pi_{E C C}$
$A_{2}=B_{2}=0$ for Flotox
Assume No ECC, $\pi$ ECC $=1$
$A_{1}=.1,7 \mathrm{~K} \leq \mathrm{C} \leq 15 \mathrm{~K}$ Entry
$\mathrm{B}_{1}=3.8 \quad$ (Use Equation 1 at bottom of $\mathrm{B}_{1}$ and $\mathrm{B}_{2}$ Table)
$\lambda_{\text {cyc }}=A_{1} B_{1}=(.1)(3.8)=.38$

$$
\lambda_{P}=[(.0034)(3.8)+(.014)(5.0)+.38](2.0)(1)=.93 \text { Failures } / 10^{6} \text { Hours }
$$

## Example 3: GaAs MMIC

Given: A MA4GM212 Single Pole Double Throw Switch, DC - 12 GHz, 4 transistors, 4 inductors, 8 resistors, maximum input $P_{D}=30 \mathrm{dbm}, 16$ pin hermetic flatpack, maximum $T_{C H}=145^{\circ} \mathrm{C}$ in a ground benign environment. The part has been manutactured for 1 year and is screened to Paragraph 1.2.1 of MIL-STD-883, Class B equivalent screen.

$$
\lambda_{P}=\left[C_{1} \pi_{T} \pi_{A}+C_{2} \pi_{E}\right] \pi_{L} \pi_{Q} \quad \text { Section } 5.4
$$

| $C_{1}=4.5$ |  | Section 5.4, MMIC Table, 4 Active Elements (See Footnote to |
| ---: | :--- | ---: |
| $\pi_{T}=.061$ |  | Table) |
| $\pi_{A}=3.0$ | Section 5.8, $T_{J}=T_{C H}=145^{\circ} \mathrm{C}$ |  |
| $C_{2}=.0047$ | Section 5.4, Unknown Application |  |
| $\pi_{E}=.50$ | Section 5.9 |  |
| $\pi_{\mathrm{L}}=1.5$ | Section 5.10 |  |
| $\pi_{\mathrm{Q}}=2.0$ | Section 5.10 |  |
|  |  |  |
|  |  |  |
| $\lambda_{P}=[(4.5)(.061)(3.0)+(.0047)(.5)](1.5)(2.0)=2.5$ Failures $/ 10^{6} \mathrm{Hours}$ |  |  |

NOTE: The passive elements are assumed to contribute negligibly to the overall device failure rate.

## Example 4: Hybrid

Given: A linear multichip hybrid driver in a hermetically sealed Kovar package. The substrate is alumina and there are two thick film dielectric layers. The die and substrate attach materials are conductive epoxy and solder, respectively. The application environment is naval unsheltered, $65^{\circ} \mathrm{C}$ case temperature and the device has been in production for over two years. The device is

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### 5.13 MICROCIRCUITS, EXAMPLES

screened to MIL-STD-883, Method 5008, in accordance with Table VIII, Class B requirements. The hybrid contains the following components:

Active Components: 1 - LM106 Bipolar Comparator/Buffer Die (13 Transistors)
1 - LM741A Bipolar Operational Amplifier Die (24 Transistors)
2 - Si NPN Transistor
2 - Si PNP Transistor
2 - Si General Purpose Diodes
Passive Components: 2 - Ceramic Chip Capacitors
17 - Thick Film Resistors

$$
\lambda_{P}=\left[\sum N_{C} \lambda_{C}\right]\left(1+.2 \pi_{E}\right) \pi_{F} \pi_{Q} \pi_{L} \quad \text { Section } 5.5
$$

1. Estimate Active Device Junction Temperatures

If limited information is available on the specific hybrid materials and construction characteristics the default case-to-junction temperature rises shown in the introduction to Section 5.12 can be used. When detailed information becomes available the following Section 5.12 procedure should be used to determine the junction-to-case ( $\theta_{\mathrm{JC}}$ ) thermal resistance and $\mathrm{T}_{\mathrm{J}}$ values for each component.
$\theta_{J C}=\frac{\sum_{i=1}^{n}\left(\frac{1}{K_{i}}\right)\left(L_{i}\right)}{A}$
(Equation 1)

| Layer | Figure 5-1 Feature | $\left(\begin{array}{l}\left.\frac{1}{K_{i}}\right)\left(L_{i}\right) \\ \left(\mathrm{in}^{2}{ }^{\circ} \mathrm{C} / \mathrm{W}\right)\end{array}\right.$ <br> Silicon Chip <br> Conductive Epoxy <br> Two Dielectric Layers <br> Alumina Substrate <br> Solder Substrate Attachment <br> Kovar Case <br> $\quad \mathrm{B}$ |
| :--- | :---: | :---: |

$A=$ Die Area $=[.00278 \text { (No. Die Active Wire Terminals) }+.0417]^{2}$
(Equation 2)
$T_{J}=T_{C}+\theta_{J C} P_{D} \quad$ (Equation 3)

|  | LM106 | LM741A | Si NPN | Si PNP | Si Diode | Source |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| No. of Pins | 8 | 14 | 3 | 3 | 2 | Vendor Spec. Sheet |
| Power Dissipation, $P_{D}(W)$ | . 33 | . 35 | . 6 | . 6 | . 42 | Circuit Analysis |
| Area of Chip (in. ${ }^{2}$ ) | . 0041 | . 0065 | . 0025 | . 0025 | . 0022 | Equ. 2 Above |
| $\theta^{\text {JC }}$ ( ${ }^{\circ} \mathrm{CM}$ ) | 30.8 | 19.4 | 50.3 | 50.3 | 56.3 | Equ. 1 Above |
| $\mathrm{T}_{\mathbf{j}}\left({ }^{\circ} \mathrm{C}\right)$ | 75 | 72 | 95 | 95 | 89 | Equ. 3 Above |

2. Calculate Failure Rates for Each Component:
A) LM106 Die, 13 Transistors (from Vendor Spec. Sheet)

$$
\lambda_{P}=\left[C_{1} \pi_{T}+C_{2} \pi_{E}\right] \pi_{Q} \pi_{L}
$$

Section 5.1
Because $\mathrm{C}_{2}=0$;
$\lambda_{\mathrm{P}}=\mathrm{C}_{1} \pi_{\mathrm{T}} \pi_{\mathrm{Q}} \pi_{\mathrm{L}} \quad \pi_{\mathrm{T}}:$ Section $5.8 ; \pi_{\mathrm{Q}}, \pi_{\mathrm{L}}$ Default to 1.0
$=(.01)(3.8)(1)(1)=.038$ Failures $/ 10^{6}$ Hours
B) LM741 Die, 23 Transistors. Use Same Procedure as Above.

$$
\lambda_{p}=C_{1} \pi_{T} \pi_{Q} \pi_{L}=(.01)(3.1)(1)(1)=.031 \text { Failures } / 10^{6} \text { Hours }
$$

C) Silicon NPN Transistor, Rated Power $=5 \mathrm{~W}$ (From Vendor Spec. Sheet), $\mathrm{V}_{\text {CE }}{ }^{\mathcal{N}_{\text {CEO }}}=.6$, Linear Application

$$
\begin{aligned}
\lambda_{P} & =\lambda_{b} \pi_{T} \pi_{A} \pi_{R} \pi_{S} \pi_{Q} \pi_{E} \quad \text { Section 6.3; } \pi_{Q}, \pi_{E} \text { Default to } 1.0 \\
& =(.00074)(3.9)(1.5)(1.8)(.29)(1)(1) \\
& =.0023 \text { Faihures } / 10^{6} \text { Hours }
\end{aligned}
$$

D) Silicon PNP Transistor, Same as C.

$$
\lambda_{p}=.0023 \text { Failures } / 10^{6} \text { Hours }
$$

E) Silicon General Purpose Diode (Analog), Voltage Stress $=60 \%$, Metallurgically Bonded Construction.

$$
\begin{aligned}
\lambda_{P} & =\lambda_{D} \pi_{T} \pi_{S} \pi_{C} \pi_{Q} \pi_{E} \\
& =(.0038)(6.3)(.29)(1)(1)(1) \\
& =.0069 \text { Failures } / 10^{6} \text { Hours }
\end{aligned}
$$

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5.13 MICROCIRCUITS, EXAMPLES
F) Ceramic Chip Capacinor, Voltage Stress $=50 \%$,
$T_{A}=T_{\text {CASE }}$ for the Hybrid, $1340 \mathrm{pF}, 125^{\circ} \mathrm{C}$ Rated Temp.

$$
\begin{aligned}
\lambda_{P} & =\lambda_{D} \pi_{C V} \pi_{Q} \pi_{E} \\
& =(.0028)(1.4)(1)(1) \\
& =.0039 \text { Failures } / 10^{6} \text { Hours }
\end{aligned}
$$

G) Thick Film Resistors, per instuctions in Section 5.5, the contribution of these devices is considered insignificant relative to the overall mybrid faiture rate and they may be ignored.

## Oyerall Hytrid Part Faikure Rate Calculation:

$$
\begin{array}{ll}
\lambda_{P}=\left[\sum N_{C} \lambda_{C}\right]\left(1+.2 \pi_{E}\right) \pi_{F} \pi_{Q} \pi_{L} & \\
\pi_{E}=6.0 & \text { Section } 5.10 \\
\pi_{F}=5.8 & \text { Section } 5.5 \\
\pi_{Q}=1 & \text { Section } 5.10 \\
\pi_{L}=1 & \text { Section } 5.10 \\
\lambda_{P}= & \\
& \\
& +(1)(.038)+(1)(.0069)+(2)(.0039)](1+.2(6.0))(5.8)(1)(1) \\
\lambda_{p}= & 1.3 \text { Failures } / 10^{6} \text { Hours }
\end{array}
$$

## MIL-HDBK-217F

### 6.0 DISCRETE SEMICONDUCTORS, INTRODUCTION

The semiconductor transistor, diode and opto-electronic device sections present the fallure rates on the basis of device type and construction. An analytical model of the failure rate is also presented for each device category. The various types of discrete semiconductor devices require different falure rate models that vary to some degree. The modets apply to single devices unless otherwise noted. For mulliple devices in a single package the hybrid model in Section 5.5 should be used.

The applicable MIL specification for transistors, and optoelectronic devices is MIL-S-19500. The quality levels (JAN, JANTX, JANTXV) are as defined in MIL-S-19500.

The temperature factor ( $x_{T}$ ) is based on the device junction temperature. Junction temperature should be computed based on worse case power (or maximum power dissipation) and the device function to case thermal resistance. Determination of junction temperatures is explained in Section 6.14.

Reference 28 should be consulted for further detailed information on the models appearing in this section.

MIL-HDBK-217F

### 6.1 DIODES, LOW FREQUENCY

| SPECIFICATION | DESCRIPTION |
| :--- | :--- |
| MIL-S-19500 | Low Froquency Diodes: General Puppose Anabog, Suitching, |
|  | Fast Recovery, Power Rectifier, Transient Suppressor, Currem |
|  | Regulator, Vokage Regulator, Voltage Reference |

$$
\lambda_{p}=\lambda_{b} \pi_{T} \pi_{S} \pi_{C} \pi_{Q} \pi_{E} \text { Failures/ } 10^{6} \text { Hours }
$$

| Base Failure Rate $-\lambda_{\mathrm{b}}$ |  |
| :--- | :--- |
| Diode Type/Application $\lambda_{\mathrm{b}}$ <br> General Purpose Analog .0038 <br> Switching .0010 <br> Power Recitijier, Fast Recovery .069 <br> Power Rectifier/Schottky .0030 <br> Fower Diode $.0050 /$ <br> Power Rectitier with Junction <br> High Voltage Stacks .0013 <br> Transient SuppressorNaristor Current Regulator <br> Vothage Regulator and Voltage .0034 <br> Reference (Avalanche  <br> and Zener)  |  |

Temperature Factor - $\pi_{T}$
(General Purpose Ânaiog, Switching, Fast Recovery.
Powor Rectifier, Transient Suppressor)

| $\mathrm{T}_{\mathrm{J}}\left({ }^{\circ} \mathrm{C}\right)$ | $\pi_{\text {T }}$ | $\left.\mathrm{T}_{\mathrm{J}}{ }^{\circ} \mathrm{C}\right)$ | $\pi_{T}$ |
| :---: | :---: | :---: | :---: |
| 25 | 1.0 | 105 | 9.0 |
| 30 | 1.2 | 110 | 10 |
| 35 | 1.4 | 115 | 11 |
| 40 | 1.6 | 120 | 12 |
| 45 | 1.9 | 125 | 14 |
| 50 | 2.2 | 130 | 15 |
| 55 | 2.6 | 135 | 16 |
| 60 | 3.0 | 140 | 18 |
| 65 | 3.4 | 145 | 20 |
| 70 | 3.9 | 150 | 21 |
| 75 | 4.4 | 155 | 23 |
| 80 | 5.0 | 160 | 25 |
| 85 | 5.7 | 165 | 28 |
| 90 | 6.4 | 170 | 30 |
| 95 | 7.2 | 175 | 32 |
| 100 | 8.0 |  |  |
| $\pi_{T}=\exp \left(\cdot 3091\left(\frac{1}{T_{J}+273} \cdot \frac{1}{298}\right)\right)$ |  |  |  |
| $\mathrm{T}_{\mathrm{J}}=$ Junction Temperature $\left({ }^{\circ} \mathrm{C}\right.$ ) |  |  |  |

Temperature Factor - $\pi_{T}$
(Vohage Regulator, Voltage Reference,

| $T_{j}\left({ }^{\circ} \mathrm{C}\right)$ | $\pi_{T}$ | $T_{J}\left({ }^{\circ} \mathrm{C}\right)$ | $\pi_{T}$ |
| :---: | :---: | :---: | :---: |
| 25 | 1.0 | 105 | 3.9 |
| 30 | 1.1 | 110 | 4.2 |
| 35 | 1.2 | 115 | 4.5 |
| 40 | 1.4 | 120 | 4.8 |
| 45 | 1.5 | 125 | 5.1 |
| 50 | 1.6 | 130 | 5.4 |
| 55 | 1.8 | 135 | 5.7 |
| 60 | 2.0 | 140 | 6.0 |
| 65 | 2.1 | 145 | 6.4 |
| 70 | 2.3 | 150 | 6.7 |
| 75 | 2.5 | 155 | 7.1 |
| 80 | 2.7 | 160 | 7.5 |
| 85 | 3.0 | 165 | 7.9 |
| 90 | 3.2 | 170 | 8.3 |
| 95 | 3.4 | 175 | 6.7 |
| 100 | 3.7 |  |  |


| Electrical Stress Factor - $\pi_{S}$ |  |
| :---: | :---: |
| Stress | $\pi_{\text {S }}$ |
| Transient Suppressor, Voltage Regulator, Voltage Reference, Current Regulator | 1.0 |
| All Others: $\begin{aligned} & V_{\mathrm{s}} \leq .30 \\ & .3<V_{\mathrm{s}} \leq .40 \\ & .4<V_{\mathrm{s}} \leq .50 \\ & .5<V_{\mathrm{s}} \leq .60 \\ & .6<V_{\mathrm{s}} \leq .70 \\ & .7<V_{\mathrm{s}} \leq .80 \\ & .8<V_{\mathrm{s}} \leq .90 \\ & .9<V_{\mathrm{s}} \leq 1.00 \end{aligned}$ | 0.054 0.11 0.19 0.29 0.42 0.58 0.77 1.0 |
| For All Except Transient Suppressor, Voltage <br> Regulator, VoHage Reference, or Current Regulator $\begin{array}{ll} \pi_{s}=.054 & \left(V_{s} \leq .3\right) \\ \pi_{s}=V_{s} 2.43 & \left(.3<V_{s} \leq 1\right) \end{array}$ $v_{s}=\text { Voltage Stress Ratio }=\frac{\text { Voltage Applied }}{\text { Voltage Rated }}$ <br> Voltage is Diode Reverse Voltage |  |

Contact Construction Factor $-\pi_{\mathrm{C}}$

| Contact Construction | $\pi_{\mathrm{C}}$ |
| :--- | :---: |
| Metallurgically Bonded | 1.0 |
| Non-Metallurgically Bonded and <br> Spring Loaded Contacts | 2.0 |


| Quality Factor $-\pi_{\mathrm{Q}}$ |  |
| :--- | :---: |
| Quality $\pi_{\mathrm{Q}}$ <br> JANTXV 0.7 <br> JANTX 1.0 <br> JAN 2.4 <br> Lower 5.5 <br> Plastic 8.0 |  |

Environment Factor $-\pi_{E}$

| Environment | $\pi_{E}$ |
| :---: | :---: |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 6.0 |
| $G_{M}$ | 9.0 |
| $N_{S}$ | 9.0 |
| $N_{U}$ | 19 |
| $A_{I C}$ | 13 |
| $A_{I F}$ | 29 |
| $A_{U C}$ | 20 |
| $A_{U F}$ | 43 |
| $A_{R W}$ | 24 |
| $S_{F}$ | .50 |
| $M_{F}$ | 14 |
| $M_{L}$ | 32 |
| $C_{L}$ | 320 |

MIL-HDBK-217F
6.2 DIODES, HIGH FREQUENCY (WICROWAVE, RF)

SPECIFICATION MIL-S-19500

## DESCRIPTION

Si mipatt; Bum Effect, Gunn; Tunnel, Back; Mixer, Detector, PIN, Schottky; Varactor, Step Recovery

$$
\lambda_{p}=\lambda_{D} \pi_{T} \pi_{A} \pi_{R} \pi_{Q} \pi_{E} \quad \text { Failures } / 10^{6} \text { Hours }
$$

| Base Failure Rate - $\lambda_{\mathrm{t}}$ |  |
| :---: | :---: |
| Diode Type | $\lambda_{b}$ |
| Si MPATT ( 335 GH (z) | . 22 |
| Gunn/Bulk Etfoct | . 18 |
| Tunnel and Back (including | 0023 |
| PIN | . 0081 |
| Schottky Barrier (Including |  |
| Detectors) and Point Contact (200 NHzz S Frequency 35 GHz ) |  |
|  | $.027$ |


| Temperature Factor - $\pi_{T}$ (All Typos Excopt IMPATT) |  |  |  |
| :---: | :---: | :---: | :---: |
| $\mathrm{T}_{\mathrm{J}}\left({ }^{\circ} \mathrm{C}\right)$ | $\pi_{T}$ | $\mathrm{T}_{\mathrm{J}}\left({ }^{\circ} \mathrm{C}\right)$ | ${ }^{\pi}$ T |
| 25 | 1.0 | 105 | 4.4 |
| 30 | 1.1 | 110 | 4.8 |
| 35 | 1.3 | 115 | 5.1 |
| 40 | 1.4 | 120 | 5.5 |
| 45 | 1.6 | 125 | 5.9 |
| 50 | 1.7 | 130 | 6.3 |
| 55 | 1.9 | 135 | 6.7 |
| 60 | 2.1 | 140 | 7.1 |
| 65 | 2.3 | 145 | 7.6 |
| 70 | 2.5 | 150 | 8.0 |
| 75 | 2.8 | 155 | 8.5 |
| 80 | 3.0 | i60 | 9.0 |
| 85 | 3.3 | 165 | 9.5 |
| 90 | 3.5 | 170 | 10 |
| 95 | 3.8 | 175 | 11 |
| 100 | 4.1 |  |  |
|  |  | $\frac{1}{+27}$ | )) |
|  | on | ${ }^{(\circ}{ }^{\circ} \mathrm{C}$ |  |


| Temperature Factor- $\pi_{T}$ (MPPATI) |  |  |  |
| :---: | :---: | :---: | :---: |
| $\mathrm{T}_{\mathrm{J}}\left({ }^{\circ} \mathrm{C}\right)$ | $\pi_{\text {T }}$ | $\left.\mathrm{T}_{\mathrm{j}}{ }^{\circ} \mathrm{C}\right)$ | $\pi_{T}$ |
| 25 | 1.0 | 105 | 42 |
| 30 | 1.3 | 110 | 50 |
| 35 | 1.8 | 115 | 60 |
| 40 | 2.3 | 120 | 71 |
| 45 | 3.0 | 125 | 84 |
| 50 | 3.9 | 130 | 99 |
| 55 | 5.0 | 135 | 120 |
| 60 | 6.4 | 140 | 140 |
| 65 | 8.1 | 145 | 160 |
| 70 | 10 | 150 | 180 |
| 75 | 13 | 155 | 210 |
| 80 | 16 | 160 | 250 |
| 85 | 19 | 165 | 288 |
| 90 | 24 | 170 | 320 |
| 95 | 29 | 175 | 370 |
| 100 | 35 |  |  |
|  | (-5 | $\frac{1}{+273}$ | $\frac{1}{98}$ )) |
| ${ }^{\top} \mathrm{J}$ | cion | ( ${ }^{\circ} \mathrm{C}$ ) |  |


| Application Factor $-\pi_{\mathrm{A}}$ |  |
| :--- | :---: |
| Diodes Application $\pi_{\mathrm{A}}$ <br> Varactor, Vohage Control .50 <br> Varactor, Multiplier 2.5 <br> All Other Diodes 1.0 |  |

MI-HDBK-217F
6.2 DIODES, HIGH FREQUENCY (MICROWAVE, RF)

| Power Rating Factor $\cdot \pi_{R}$ |  |
| :---: | :---: |
| Rated Power, Pr (Watts) | $\pi_{R}$ |
| $\begin{aligned} & \text { PIN Diodes } \\ & \qquad \begin{array}{l} \operatorname{Pr} \leq 10 \\ 10<\operatorname{Pr} \leq 100 \\ 100<P_{r} \leq 1000 \\ 1000<P_{r} \leq 3000 \end{array} \end{aligned}$ | $\begin{gathered} .50 \\ 1.3 \\ 2.0 \\ 2.4 \end{gathered}$ |
| All Other Diodes | 1.0 |
| PIN Diodes $\pi_{R}=$ <br> All Other Diodes $\pi_{R}=$ | $\left(P_{r}\right)-.25$ |


| Quality Factor - $\pi_{Q}$ (Schotrky) |  |
| :---: | :---: |
| Quality* | $\pi$ |
| JANTXV | . 50 |
| JANTX | 1.0 |
| JAN | 1.8 |
| Lower | 2.5 |
| Plastic | - |
| For high frequ MIL-S-195 defined as requiremen | ot specified to lasses are me |


| Quality Factor $-\pi_{Q}$ <br> (All Types Except Schottky) |  |
| :---: | :---: |
| Quality ${ }^{\text {* }}$ | $\pi_{\text {a }}$ |
| JANTXV | . 50 |
| JANTX | 1.0 |
| JAN | 5.0 |
| Lower | 25 |
| Plastic | 50 |
| For high fr MIL-S. 195 requireme | pectified to as are |


| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\pi_{E}$ |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 2.0 |
| $G_{M}$ | 5.0 |
| $N_{S}$ | 4.0 |
| $N_{U}$ | 11 |
| $A_{1}$ | 4.0 |
| $A_{I F}$ | 5.0 |
| $A_{U C}$ | 7.0 |
| $A_{U F}$ | 12 |
| $A_{R W}$ | 16 |
| $S_{F}$ | .50 |
| $M_{F}$ | 9.0 |
| $M_{L}$ | 24 |
| $C_{L}$ | 250 |

### 6.3 TRANSISTORS, LOW FREQUENCY, BIPOLAR

## SPECIFICATION MIL-S-19500

DESCRIPTION
NPN (Frequency <200 MHz)
PNP (Frequency < 200 MHz )

$$
\lambda_{P}=\lambda_{D} \pi_{T} \pi_{A} \pi_{R} \pi_{S} \pi_{Q} \pi_{E}
$$

Failures $/ 10^{6}$ Hours
Base Fallure Rate $-\lambda_{\mathrm{B}}$

| Type | $\lambda_{\mathrm{b}}$ |
| :--- | :---: |
| NPN and PNP | .00074 |

Application Factor $-\pi_{\mathrm{A}}$

| Application | $\pi_{\mathrm{A}}$ |
| :--- | :---: |
| Linear Amplification | 1.5 |
| Switching | .70 |


| $\mathrm{T}_{\mathrm{J}}\left({ }^{\circ} \mathrm{C}\right)$ | $\pi_{\text {T }}$ | $\left.\mathrm{T}^{(10}{ }^{\circ} \mathrm{C}\right)$ | $\pi_{T}$ |
| :---: | :---: | :---: | :---: |
| 25 | 1.0 | 105 | 4.5 |
| 30 | 1.1 | 110 | 4.8 |
| 35 | 1.3 | 115 | 5.2 |
| 40 | 1.4 | 120 | 5.6 |
| 45 | 1.6 | 125 | 5.9 |
| 50 | 1.7 | 130 | 6.3 |
| 55 | 1.9 | 135 | 6.8 |
| 60 | 2.1 | 140 | 7.2 |
| 65 | 2.3 | 145 | 7.7 |
| 70 | 2.5 | 150 | 8.1 |
| 75 | 2.8 | 155 | 8.6 |
| 80 | 3.0 | 160 | 9.1 |
| 85 | 3.3 | 165 | 9.7 |
| 90 | 3.6 | 170 | 10 |
| 95 | 3.9 | 175 | 11 |
| 100 | 4.2 |  |  |
| $\pi_{T}=\exp \left(-2114\left(\frac{1}{T_{J}+273} \cdot \frac{1}{298}\right)\right)$ |  |  |  |
| $\mathrm{T}_{\mathrm{J}}=$ Junction Temperature ( ${ }^{\circ} \mathrm{C}$ ) |  |  |  |


| Rated Power ( $\mathrm{Pr}_{\text {r }}$, Watts) | $\pi_{\text {R }}$ |
| :---: | :---: |
| Pr $\leq .1$ | . 43 |
| $\mathrm{P}_{\mathrm{r}}=.5$ | . 77 |
| $\mathrm{Pr}_{\mathrm{r}}=1.0$ | 1.0 |
| $\mathrm{Pr}_{\mathrm{r}}=5.0$ | 1.8 |
| $\mathrm{Pr}_{\mathrm{r}}=10.0$ | 2.3 |
| $\mathrm{Pr}_{\mathrm{r}}=50.0$ | 4.3 |
| $\mathrm{Pr}_{\mathrm{r}}=100.0$ | 5.5 |
| $\mathrm{Pr}_{\mathrm{r}}=500.0$ | 10 |
| $\pi_{R}=.43 \quad R a$ | Rated Power 5.1W |
| $\pi_{R}=\left(P_{r}\right)^{37} \quad R a$ | Rated Power > . 1 W |

6.3 TRANSISTORS, LOW FREQUENCY, BIPOLAR

Voltage Stress Factor - $\pi_{S}$

| Applied $V_{C E} /$ Rated $V_{C E O}$ | $\pi_{\mathrm{S}}$ |
| :--- | :---: |
| $0<\mathrm{V}_{\mathrm{S}} \leq .3$ | .11 |
| $.3<\mathrm{V}_{\mathrm{S}} \leq .4$ | .16 |
| $.4<\mathrm{V}_{\mathrm{S}} \leq .5$ | .21 |
| $.5<\mathrm{V}_{\mathrm{S}} \leq .6$ | .29 |
| $.6<\mathrm{V}_{\mathrm{S}} \leq .7$ | .39 |
| $.7<\mathrm{V}_{\mathrm{S}} \leq .8$ | .54 |
| $.8<\mathrm{V}_{\mathrm{S}} \leq .9$ | .73 |
| $.9<\mathrm{V}_{\mathrm{S}} \leq 1.0$ | 1.0 |

$\pi_{S} \quad=.045 \exp \left(3.1\left(V_{s}\right)\right) \quad\left(0<V_{S} \leq 1.0\right)$
$\mathrm{V}_{\mathrm{s}}=$ Applied $\mathrm{V}_{\mathrm{CE}} /$ Rated $\mathrm{V}_{\text {CEO }}$
$\mathrm{V}_{\mathrm{CE}}=$ Voltage, Collector to Emitter
$V_{\text {CEO }}=$ Vottage, Collector to Emitter, Base Open

Environment Factor $-\pi_{E}$

| Environment | $\pi_{\mathrm{E}}$ |
| :---: | :---: |
| $\mathrm{G}_{\mathrm{B}}$ | 1.0 |
| $\mathrm{G}_{\mathrm{F}}$ | 6.0 |
| $\mathrm{G}_{\mathrm{M}}$ | 9.0 |
| $\mathrm{~N}_{\mathrm{S}}$ | 9.0 |
| $\mathrm{~N}_{\mathrm{U}}$ | 19 |
| $\mathrm{~A}_{\mathrm{K}}$ | 13 |
| $A_{I F}$ | 29 |
| $A_{U C}$ | 20 |
| $A_{U F}$ | 43 |
| $A_{R W}$ | 24 |
| $\mathrm{~S}_{\mathrm{F}}$ | .50 |
| $M_{\mathrm{F}}$ | 14 |
| $M_{\mathrm{L}}$ | 32 |
| $\mathrm{C}_{\mathrm{L}}$ | 320 |


| Quality Factor $-\pi_{\mathrm{Q}}$ |  |
| :--- | :---: |
| Quality | $\pi_{\mathrm{Q}}$ |
| JANTXV | .70 |
| JANTX | 1.0 |
| JAN | 2.4 |
| Lower | 5.5 |
| Plastic | 8.0 |

MIL-HDBK-217F

### 6.4 TRANSISTORS, LOW FREQUENCY, SI FET

## SPECIFICATION

MIL-S-19500

DESCRIPTION
N -Channel and P-Channel Si FET (Frequency $\leq 400 \mathrm{MHz}$ )

$$
\lambda_{D}=\lambda_{b} \pi_{T} \pi_{A} \pi_{Q} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

Base Failure Rate $-\lambda_{\mathrm{b}}$

| Transistor Type | $\lambda_{\mathrm{b}}$ |
| :--- | :--- |
| MOSFET | .012 |
| JFET | .0045 |

Temperature Factor $-\pi_{T}$
$\pi_{T}-\exp \left(-1925\left(\frac{1}{T_{J}+273} \cdot \frac{1}{298}\right)\right)$
$T_{J}=$ Junction Temperature ( ${ }^{\circ} \mathrm{C}$ )

| Quality Factor $-\pi_{\mathrm{Q}}$ |  |
| :--- | :---: |
| Quality | $\pi_{\mathrm{Q}}$ |
| JANTXV | .70 |
| JANTX | 1.0 |
| JAN | 2.4 |
| Lower | 5.5 |
| Plastic | 8.0 |


| Application (Pr, Rated Output Power) | $\pi_{\text {A }}$ |
| :---: | :---: |
| Linear Amplification $\left(P_{r}<2 W\right)$ <br> Small Signal Switching | $\begin{array}{r} 1.5 \\ .70 \\ \hline \end{array}$ |
| Power FETs <br> (Non-linear, $\mathrm{P}_{\mathrm{r}} \geq 2 \mathrm{~W}$ ) $\begin{aligned} & 2 \leq \mathrm{Pr}_{\mathrm{r}}<5 \mathrm{~W} \\ & 5 \leq \mathrm{Pr}<50 \mathrm{~W} \\ & 50 \leq \mathrm{Pr}_{\mathrm{r}}<250 \mathrm{~W} \\ & \mathrm{Pr}_{\mathrm{r}} \geq 250 \mathrm{~W} \end{aligned}$ | $\begin{gathered} 2.0 \\ 4.0 \\ 8.0 \\ 10 \end{gathered}$ |

Environment Factor - $\pi_{\mathrm{E}}$

| Environment | $\pi_{E}$ |
| :---: | :---: |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 6.0 |
| $G_{M}$ | 9.0 |
| $N_{S}$ | 9.0 |
| $N_{U}$ | 19 |
| $A_{I C}$ | 13 |
| $A_{I F}$ | 29 |
| $A_{U C}$ | 20 |
| $A_{U F}$ | 43 |
| $A_{R W}$ | 24 |
| $S_{F}$ | .50 |
| $M_{F}$ | 14 |
| $M_{L}$ | 32 |
| $C_{L}$ | 320 |

SPECIFICATION
MIL-S-19500

## DESCRIPTION

Unijunction Transistors

$$
\lambda_{\mathrm{P}}=\lambda_{\mathrm{b}} \pi_{\mathrm{T}} \pi_{\mathrm{Q}} \pi_{E} \text { Failures/ } 10^{6} \text { Hours }
$$

Base Failure Rate $-\lambda_{\mathrm{b}}$

| Type | $\lambda_{\mathrm{b}}$ |
| :---: | :---: |
| All Unijunction | .0083 |


| Temperature Factor $-\pi_{T}$ |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
| $\mathrm{~T}_{J}\left({ }^{\circ} \mathrm{C}\right)$ | $\pi_{T}$ | $T_{J}\left({ }^{\circ} \mathrm{C}\right)$ | $\pi_{T}$ |  |
|  |  |  |  |  |
| 25 | 1.0 | 105 | 5.8 |  |
| 30 | 1.1 | 110 | 6.4 |  |
| 35 | 1.3 | 115 | 6.9 |  |
| 40 | 1.5 | 120 | 7.5 |  |
| 45 | 1.7 | 125 | 8.1 |  |
| 50 | 1.9 | 130 | 8.8 |  |
| 55 | 2.1 | 135 | 9.5 |  |
| 60 | 2.4 | 140 | 10 |  |
| 65 | 2.7 | 145 | 11 |  |
| 70 | 3.0 | 150 | 12 |  |
| 75 | 3.3 | 155 | 13 |  |
| 80 | 3.7 | 160 | 13 |  |
| 85 | 4.0 | 165 | 14 |  |
| 90 | 4.4 | 170 | 15 |  |
| 95 | 4.9 | 175 | 16 |  |
| 100 | 5.3 |  |  |  |
|  |  |  |  |  |

$\pi_{T}=\exp \left(-2483\left(\frac{1}{T_{J}+273} \cdot \frac{1}{298}\right)\right)$
$\mathrm{T}_{J}=$ Junction Temperature $\left({ }^{\circ} \mathrm{C}\right)$

| Quality Factor $-\pi_{\mathrm{Q}}$ |  |
| :--- | :---: |
| Quality | $\pi_{\mathrm{Q}}$ |
| JANTXV | .70 |
| JANTX | 1.0 |
| JAN | 2.4 |
| Lower | 5.5 |
| Plastic | 8.0 |


| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\pi_{E}$ |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 6.0 |
| $G_{M}$ | 9.0 |
| $N_{S}$ | 9.0 |
| $N_{U}$ | 19 |
| $A_{I C}$ | 13 |
| $A_{I F}$ | 29 |
| $A_{U C}$ | 20 |
| $A_{U F}$ | 43 |
| $A_{R W}$ | 24 |
| $S_{F}$ | .50 |
| $M_{F}$ | 14 |
| $M_{L}$ | 32 |
| $C_{L}$ | 320 |

## MIL-HDBK-217F

6.6 TRANSISTORS, LOW NOISE, HIGH FREQUENCY, BIPOLAR

## SPECIFICATION

M!L-S-19500

## DESCRIPTION

Bipolar, Microwave RF Transistor
(Frequency > 200 MHz , Power < 1 W )

$$
\lambda_{P}=\lambda_{b} \pi_{T} \pi_{R} \pi_{S} \pi_{Q} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

Application Note: The model applies to a single die (for multipte die use the hybrid model). The model does apply to ganged transistors on a single die.

| Base Failure Rate $-\lambda_{b}$ |  |
| :--- | :---: |
| Type | $\lambda_{b}$ |
| All Types | .18 |


| $\mathrm{T}_{\mathrm{J}}\left({ }^{\circ} \mathrm{C}\right)$ | $\pi_{T}$ | $\mathrm{T}_{J}\left({ }^{\circ} \mathrm{C}\right)$ | $\pi_{T}$ |
| :---: | :---: | :---: | :---: |
| 25 | 1.0 | 105 | 4.5 |
| 30 | 1.1 | 110 | 4.8 |
| 35 | 1.3 | 115 | 5.2 |
| 40 | 1.4 | 120 | 5.6 |
| 45 | 1.6 | 125 | 5.9 |
| 50 | 1.7 | 130 | 6.3 |
| 55 | 1.9 | 135 | 6.8 |
| 60 | 2.1 | 140 | 7.2 |
| 65 | 2.3 | 145 | 7.7 |
| 70 | 2.5 | 150 | 8.1 |
| 75 | 2.8 | 155 | 8.6 |
| 80 | 3.0 | 160 | 9.1 |
| 85 | 3.3 | 165 | 9.7 |
| 90 | 3.6 | 170 | 10 |
| 95 | 3.9 | 175 | 11 |
| 100 | 4.2 |  |  |
| $\pi_{T}=\exp \left(-2114\left(\frac{1}{T_{J}+273} \cdot \frac{1}{298}\right)\right)$ |  |  |  |
| $T_{j}=$ dunction Temperature ( ${ }^{\circ} \mathrm{C}$ ) |  |  |  |


| Power Rating Factor - $\boldsymbol{\pi}_{\mathbf{R}}$ |  |
| :---: | :---: |
| Rated Power ( $\mathrm{P}_{\mathrm{r}}$, Watts) | $\pi_{\text {R }}$ |
| Pr $\leq .1$ | . 43 |
| . $1<\operatorname{Pr} \leq .2$ | . 55 |
| . $2<\operatorname{Pr} \leq .3$ | . 64 |
| . $3<\mathrm{Pr}_{\mathrm{r}} \leq .4$ | . 71 |
| . $4<\mathrm{Pr}_{\mathrm{r}} \leq .5$ | . 77 |
| . $5<\operatorname{Pr} \leqslant .6$ | . 83 |
| . $6<\operatorname{Pr} \leq .7$ | . 88 |
| . $7<\mathrm{Pr}^{5} \leq .8$ | . 92 |
| . $8<\operatorname{Pr} \leq .9$ | . 96 |
| $\pi_{R}=.43$ |  |
| $\pi_{R}=\left(P_{r}\right)^{37}$ |  |
| Voltage Stress Factor $-\pi_{\text {s }}$ |  |
| Applied VCE/Rated VCEO | $\pi_{\text {s }}$ |
| $0<V_{s} \leq .3$ | . 11 |
| . $3<\mathrm{V}_{\mathrm{s}} \leq .4$ | . 16 |
| $.4<V_{\text {s }} \leq .5$ | . 21 |
| . $5<\mathrm{V}_{\mathrm{s}} \leq .6$ | . 29 |
| . $6<\mathrm{V}_{\mathrm{s}} \leq .7$ | . 39 |
| . $7<\mathrm{V}_{\mathrm{s}} \leq .8$ | . 54 |
| . $8<\mathrm{V}_{5} \leq .9$ | . 73 |
| . $9<\mathrm{V}_{\mathrm{s}} \leq 1.0$ | 1.0 |
| $\pi_{s} \quad=.045 \exp \left(3.1\left(V_{s}\right)\right) \quad\left(0<V_{s} \leq 1.0\right)$ |  |
| $\mathrm{V}_{\mathrm{s}}=$ Applied $\mathrm{V}_{\text {CE }} /$ Ratod $\mathrm{V}_{\text {CEO }}$ |  |
| $V_{\text {CE }}$ - Vohage, Collector to Emitter |  |
| $V_{C E O}=$ Voltage, Collector to Emitter, Base Open |  |

## MIL-HDBK-217F

### 6.6 TRANSISTORS, LOW NOISE, HIGH FREQUENCY, BIPOLAR

| Quality Factor $-\pi_{\mathrm{O}}$ |  |
| :--- | :---: |
| Quality | $\pi_{\mathrm{Q}}$ |
| JANTXV | .50 |
| JANTX | 1.0 |
| JAN | 2.0 |
| Lower | 5.0 |

NOTE: For these devices, JANTXV quality class must inctude IR Scan for die attach and screen tor barrier: layer pinholes on gold metallized devices.

| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\pi_{E}$ |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 2.0 |
| $G_{M}$ | 5.0 |
| $N_{S}$ | 4.0 |
| $N_{U}$ | 11 |
| $A_{I C}$ | 4.0 |
| $A_{H F}$ | 5.0 |
| $A_{U C}$ | 7.0 |
| $A_{U F}$ | 12 |
| $A_{R W}$ | 16 |
| $S_{F}$ | .50 |
| $M_{F}$ | 9.0 |
| $M_{L}$ | 24 |
| $C_{L}$ | 250 |

### 6.7 TRANSISTORS, HIGH POWER, HIGH FREQUENCY, BIPOLAR

## SPECIFICATION

MIL-S-19500

DESCRIPTION
Power, Microwave, RF Bipolar Transistors (Average Power $\geq 1 \mathrm{~W}$ )

$$
\lambda_{P}=\lambda_{b} \pi_{T} \pi_{A} \pi_{M} \pi_{Q} \pi_{E}
$$

Failures $/ 10^{6}$ Hours
Base Failure Rate - $\lambda_{b}$

| $\begin{aligned} & \text { Frequency } \\ & (\mathrm{GHz}) \end{aligned}$ | Output Power (Watts) |  |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | 1.0 | 5.0 | 10 | 50 | 100 | 200 | 300 | 400 | 500 | 600 |
| $\leq 0.5$ | . 038 | . 039 | . 040 | . 050 | . 067 | . 12 | . 20 | . 36 | . 62 | 1.1 |
| 1 | . 046 | . 047 | . 048 | . 060 | . 080 | . 14 | . 24 | . 42 | . 74 | 1.3 |
| 2 | . 065 | . 067 | . 069 | . 086 | . 11 | . 20 | . 35 |  |  |  |
| 3 | . 093 | . 095 | . 098 | . 12 | . 16 | . 28 |  |  |  |  |
| 4 | . 13 | . 14 | . 14 | . 17 | . 23 |  |  |  |  |  |
| 5 | . 19 | . 19 | . 20 | . 25 |  |  |  |  |  |  |
|  |  |  |  |  |  |  |  |  |  |  |

NOTE: Output power refers to the power level for the overall packaged device and not to individual transistors within the package (if more than one transistor is ganged together). The output power represents the power output from the active device and should not account for any duty cycle in pulsed applications. Duty cycle is accounted for when determining $\pi_{A}$.

| Temperature Factor $-\pi_{T}$ (Gold Metallization) |  |  |  |  | Temperature Factor - $\pi_{T}$ (Aluminum Metallization) |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | $V_{s}\left(V_{C E} /{ }^{\text {PV }}\right.$ CES $) ~$ |  |  |  | $\mathrm{V}_{\mathrm{s}}\left(\mathrm{V}_{C E} / \mathrm{BV}_{\text {CES }}\right)$ |  |  |  |  |
| $\mathrm{T}_{\mathrm{j}}\left({ }^{\circ} \mathrm{C}\right)$ | $\leq .40$ | . 45 | . 50 | . 55 | $\mathrm{T}_{\mathrm{j}}\left({ }^{\circ} \mathrm{C}\right)$ | 5.40 | 45 | . 50 | . 55 |
| $\leq 100$ | . 10 | . 20 | . 30 | . 40 | $\leq 100$ | . 38 | 75 | 1.1 | 1.5 |
| 110 | . 12 | . 25 | . 37 | . 49 | 110 | . 57 | 1.1 | 1.7 | 2.3 |
| 120 | . 15 | . 30 | . 45 | . 59 | 120 | . 84 | 1.7 | 2.5 | 3.3 |
| 130 | . 18 | . 36 | . 54 | . 71 | 130 | 1.2 | 2.4 | 3.6 | 4.8 |
| 140 | . 21 | . 43 | . 64 | . 85 | 140 | 1.7 | 3.4 | 5.1 | 6.8 |
| 150 | . 25 | . 50 | . 75 | 1.0 | 150 | 2.4 | 4.7 | 7.1 | 9.5 |
| 160 | 29 | 59 | . 88 | 1.2 | 160 | 3.3 | 6.5 | 9.7 | 13 |
| 170 | . 34 | . 68 | 1.0 | 1.4 | 170 | 4.4 | 8.8 | 13 | 18 |
| 180 | 40 | 79 | 1.2 | 1.6 | 180 | 5.9 | 12 | 18 | 23 |
| 190 | 45 | . 91 | 1.4 | 1.8 | 190 | 7.8 | 15 | 23 | 31 |
| 200 | . 52 | 1.0 | 1.6 | 2.1 | 200 | 10 | 20 | 30 | 40 |
| $\begin{gathered} \pi_{T}=.1 \\ \pi_{T}=2( \end{gathered}$ $v_{s}$ <br> VCE $\mathrm{BVCE}$ | $\begin{aligned} & -29 \\ & \leq .40) \end{aligned}$ <br> 35) $\exp$ <br> $<V_{s} s$ | $\frac{1}{T_{J}+}$ <br> 903 <br> BVC <br> ting V <br> tor-E <br> e with <br> (Vol <br> Junctio | $\frac{1}{37^{\prime}}$ <br> 273 <br> (Volts) <br> reakd <br> Short <br> perat | )). <br> C) | $\pi_{T}=$. $\pi_{T}=7.55$ <br> $v_{s}$ <br> $V_{C E}$ <br> BVCE <br> $T_{J}$ | $\operatorname{xp}(-5$ <br> s $\leq .40$ ) <br> -.35) <br> $4<V_{S}$ <br> - <br> $=$ <br> $=$ | $\frac{1}{T_{J}+}$ <br> 5794 <br> BVCES <br> ting Vo <br> tor-Em <br> with <br> (Volts) <br> Junction | - $\frac{1}{37}$ <br> 273 <br> (Volts) <br> reakd <br> Shorte <br> peratu | ()). <br> C) |


| Application Factor $-\pi_{\mathrm{A}}$ |  |  |
| :--- | :---: | :---: |
| Application Duty Factor $\pi_{\mathrm{A}}$ <br> CW N/A 7.6 <br> Pulsed $51 \%$ .46 <br>  $5 \%$ 70 <br>  $10 \%$ 1.0 <br>  $15 \%$ 1.3 <br>  $20 \%$ 1.6 <br>  $25 \%$ 1.9 <br>  $\geq 30 \%$ 2.2 <br> $\pi_{\mathrm{A}}=7.6, \mathrm{CW}$   <br> $\pi_{\mathrm{A}}=.06$ (Duty Factor \%) +.40, Pulsed   |  |  |


| Quality Factor $-\pi_{\mathrm{Q}}$ |  |
| :--- | :---: |
| Quality | $\pi_{\mathrm{Q}}$ |
| JANTXV | .50 |
| JANTX | 1.0 |
| JAN | 2.0 |
| Lower | 5.0 |
| NOTE: For these devices, JANTXV quality class <br> must include IR Scan for die attach and screen for <br> barrier layer pinholes on gold metallized devices. |  |


| Matching Network Factor - $\pi_{M}$ |  | Environment Factor - $\pi_{E}$ |  |
| :---: | :---: | :---: | :---: |
|  |  | Environment | $\pi_{\text {E }}$ |
| Matching | $\pi_{M}$ | $\mathrm{G}_{\mathrm{B}}$ | 1.0 |
| Input and Output | 1.0 | $G_{F}$ | 2.0 |
| Input and Output | 1.0 | $\mathrm{G}_{\mathrm{M}}$ | 5.0 |
| Input | 2.0 | $\mathrm{N}_{S}$ | 4.0 |
| None | 4.0 | $\mathrm{N}_{\mathrm{u}}$ | 11 |
|  |  | $A_{1 C}$ | 4.0 |
|  |  | $A_{\text {IF }}$ | 5.0 |
|  |  | ${ }^{\text {A }}$ UC | 7.0 |
|  |  | ${ }^{\text {A }}$ UF | 12 |
|  |  | $A_{\text {RW }}$ | 16 |
|  |  | $\mathrm{S}_{\mathrm{F}}$ | 50 |
|  |  | $M_{F}$ | 9.0 |
|  |  | $M_{L}$ | 24 |
|  |  | $C_{L}$ | 250 |

MIL-HDBK-217F

### 6.8 TRANSISTORS, HIGH FREQUENCY, GAAS FET

## SPECIFICATION

MIL-S-19500

DESCRIPTION
GaAs Low Noise, Driver and Power FETs ( $\geq$ 1GHz)
Failures/ $10^{6}$ Hours

| $\begin{gathered} \text { Operating } \\ \text { Frequency (GHz) } \\ \hline \end{gathered}$ |  |  | Averag | Power |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | $<.1$ | . 1 | . 5 | 1 | 2 | 4 | 6 |
| 1 | . 052 | - | - | - | -- | -- | $\cdots$ |
| 4 | . 052 | . 054 | . 066 | . 084 | . 14 | . 36 | . 96 |
| 5 | . 052 | . 083 | . 10 | . 13 | . 21 | . 56 | 1.5 |
| 6 | . 052 | . 13 | . 16 | . 20 | . 32 | . 85 | 2.3 |
| 7 | . 052 | . 20 | . 24 | . 30 | . 50 | 1.3 | 3.5 |
| 8 | . 052 | . 30 | . 37 | . 47 | . 76 | 2.0 |  |
| 9 | . 052 | . 46 | . 56 | . 72 | 1.2 |  |  |
| 10 | . 052 | . 71 | . 87 | 1.1 | 1.8 |  |  |
| $\lambda_{b}=.052$ |  |  | $1 \leq F \leq$ |  |  |  |  |
| $\lambda_{\mathrm{b}}=$ | 429(F) |  | $4 \leq F \leq$ | $\leq P \leq 6$ |  |  |  |
| F | (GHz) |  | P | Outpu | er (W |  |  |

The average output power represents the power output from the active device and should not account for any duty cycle in pulsed applications.

| Temperature Factor - $\pi_{T}$ |  |  |  |
| :---: | :---: | :---: | :---: |
| ${ }^{\mathrm{T}} \mathrm{C}$ ( ${ }^{\circ} \mathrm{C}$ ) | $\pi_{T}$ | $\mathrm{T}_{\mathrm{C}}\left({ }^{\circ} \mathrm{C}\right)$ | ${ }_{T}$ |
| 25 | 1.0 | 105 | 24 |
| 30 | 1.3 | 110 | 28 |
| 35 | 1.6 | 115 | 33 |
| 40 | 2.1 | 120 | 38 |
| 45 | 2.6 | 125 | 44 |
| 50 | 3.2 | 130 | 50 |
| 55 | 4.0 | 135 | 58 |
| 60 | 4.9 | 140 | 66 |
| 65 | 5.9 | 145 | 75 |
| 70 | 7.2 | 150 | 85 |
| 75 | 8.7 | 155 | 97 |
| 80 | 10 | 160 | 110 |
| 85 | 12 | 165 | 120 |
| 90 | 15 | 170 | 140 |
| 95 | 18 | 175 | 150 |
| 100 | 21 |  |  |
|  |  | 273 | 8) |
| $T_{C}=$ | ne | lure ( ${ }^{\circ} \mathrm{C}$ ) |  |


| Application Factor $-\pi_{A}$ |  |
| :--- | :---: |
| Application (P $\leq 6 W$ ) | $\pi_{A}$ |
| All Low Power and Pulsed | 1 |
| CW | 4 |
| P $=$ Average Output Power (Watts) |  |

## MIL-HDBK-217F

6.8 TRANSISTORS, HIGH FREQUENCY, GaAs FET

| Matching Network Factor - $\pi_{\mathrm{M}}$ |  | Environment Factor - $\pi_{\mathrm{E}}$ |  |
| :---: | :---: | :---: | :---: |
| Matching | $\pi_{M}$ | Environment | $\pi_{\text {E }}$ |
| Input and Output Input Only |  | $\mathrm{G}_{\mathrm{B}}$ | 1.0 |
|  | 1.0 | $\mathrm{G}_{\mathrm{F}}$ | 2.0 |
|  | 2.0 | $G_{M}$ | 5.0 |
| None | 4.0 | $\mathrm{N}_{S}$ | 4.0 |
|  |  | $\mathrm{N}_{\mathrm{U}}$ | 11 |
| Quality Factor - $\pi_{Q}$ |  | $A_{1}$ | 4.0 |
|  |  | $A_{\text {IF }}$ | 5.0 |
| Quality | $\pi_{\mathrm{Q}}$ | ${ }^{\text {A }}$ UC | 7.0 |
| JANTXV | . 50 | ${ }^{\text {A }}$ UF | 12 |
|  |  | $A_{\text {RW }}$ | 16 |
| JANTX | 1.0 | $\mathrm{S}_{\mathrm{F}}$ | . 50 |
| JAN | 2.0 | $M_{F}$ | 7.5 |
| Lower | 5.0 | $M_{L}$ | 24 |
|  |  | $\mathrm{C}_{\mathrm{L}}$ | 250 |

### 6.9 TRANSISTORS, HIGH FREQUENCY, SI FET

## SPECIFICATION

MIL-S-19500

$$
\lambda_{p}=\lambda_{b} \pi_{T} \pi_{Q} \pi_{E}
$$

| Base Faiture Rate $-\lambda_{\mathrm{b}}$ |  |
| :--- | :---: |
| Transistor Type $\lambda_{\mathrm{b}}$ <br> MOSFET .060 <br> JFET .023 |  |


| Temperature Factor - $\pi_{T}$ |  |  |  |
| :---: | :---: | :---: | :---: |
| $\mathrm{T}_{J}\left({ }^{\circ} \mathrm{C}\right)$ | $\pi_{T}$ | $\mathrm{T}_{\mathrm{J}}\left({ }^{\circ} \mathrm{C}\right)$ | $\pi_{T}$ |
| 25 | 1.0 | 105 | 3.9 |
| 30 | 1.1 | 110 | 4.2 |
| 35 | 1.2 | 115 | 4.5 |
| 40 | 1.4 | 120 | 4.8 |
| 45 | 1.5 | 125 | 5.1 |
| 50 | 1.6 | 130 | 5.4 |
| 55 | 1.8 | 135 | 5.7 |
| 60 | 2.0 | 140 | 6.0 |
| 65 | 2.1 | 145 | 6.4 |
| 70 | 2.3 | 150 | 6.7 |
| 75 | 2.5 | 155 | 7.1 |
| 80 | 2.7 | 160 | 7.5 |
| 85 | 3.0 | 165 | 7.9 |
| 90 | 3.2 | 170 | 8.3 |
| 95 | 3.4 | 175 | 8.7 |
| 100 | 3.7 |  |  |
|  |  | $\frac{1}{+273}$ |  |
|  |  | ( ${ }^{\circ}$ |  |

Failures $/ 10^{6}$ Hours
DESCRIPTION
Si FETs (Avg. Power < 300 mW . Freq. > 400 MHz )
Quality Factor $-\pi_{\mathrm{Q}}$

| Quality | $\pi_{\mathrm{Q}}$ |
| :--- | :---: |
| JANTXV | .50 |
| JANTX | 1.0 |
| JAN | 2.0 |
| Lower | 5.0 |


| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\pi_{E}$ |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 2.0 |
| $G_{M}$ | 5.0 |
| $N_{S}$ | 4.0 |
| $N_{U}$ | 11 |
| $A_{I C}$ | 4.0 |
| $A_{I F}$ | 5.0 |
| $A_{U C}$ | 7.0 |
| $A_{U F}$ | 12 |
| $A_{R W}$ | 16 |
| $S_{F}$ | .50 |
| $M_{F}$ | 9.0 |
| $M_{L}$ | 24 |
| $c_{L}$ | 250 |

## SPECIFICATION <br> MIL-S-19500

DESCRIPTION
Thyristors
SCRs, Triacs

$$
\lambda_{p}=\lambda_{b} \pi_{T} \pi_{R} \pi_{S} \pi_{Q} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$



| Rated Forward Current (Ifrms ${ }^{\text {(Amps) }}$ ) | $\pi_{R}$ |
| :---: | :---: |
| $\begin{aligned} & .05 \\ & .10 \\ & .50 \\ & 1.0 \\ & 5.0 \\ & 10 \\ & 20 \\ & 30 \\ & 40 \\ & 50 \\ & 60 \\ & 70 \\ & 80 \\ & 90 \\ & 100 \\ & 110 \\ & 120 \\ & 130 \\ & 140 \\ & 150 \\ & 160 \\ & 170 \\ & 175 \end{aligned}$ | $\begin{gathered} .30 \\ .40 \\ .76 \\ 1.0 \\ 1.9 \\ 2.5 \\ 3.3 \\ 3.9 \\ 4.4 \\ 4.8 \\ 5.1 \\ 5.5 \\ 5.8 \\ 6.0 \\ 6.3 \\ 6.6 \\ 6.8 \\ 7.0 \\ 7.2 \\ 7.4 \\ 7.6 \\ 7.8 \\ 7.9 \end{gathered}$ |
| $\begin{aligned} & \pi_{\mathrm{R}}=\left(L_{\mathrm{rms}}\right)^{40} \\ & \text { frms }=\text { RMS Rated } F \end{aligned}$ | nt (Amps) |

## MIL-HDBK-217F

### 6.10 THYRISTORS AND SCRS

| Voltage Stress Factor $-\pi_{S}$ |  |
| :---: | :---: |
| $V_{S}$(Blocking Voltage Applied/ <br> Blocking Voltage Rated) | $\pi_{S}$ |
| $V_{S} \leq .30$ | .10 |
| $.3<V_{S} \leq .4$ | .18 |
| $.4<V_{S} \leq .5$ | .27 |
| $.5<V_{S} \leq .6$ | .38 |
| $.6<V_{S} \leq .7$ | .51 |
| $.7<V_{S} \leq .8$ |  |
| $.8<V_{S} \leq .9$ |  |
| $.9<V_{S} \leq 1.0$ | .65 |
|  | 1.0 |
| $\pi_{S}=.10$ | $\left(V_{s} \leq 0.3\right)$ |
| $\pi_{S}=\left(V_{S}\right)$ | $\left(V_{s}>0.3\right)$ |


| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\pi_{E}$ |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 6.0 |
| $G_{M}$ | 9.0 |
| $N_{S}$ | 9.0 |
| $N_{U}$ | 19 |
| $A_{I C}$ | 13 |
| $A_{I F}$ | 29 |
| $A_{U C}$ | 20 |
| $A_{U F}$ | 43 |
| $A_{R W}$ | 24 |
| $S_{F}$ | 14 |
| $M_{F}$ | 32 |
| $M_{L}$ | 320 |
| $C_{L}$ |  |


| Quality Factor $-\pi_{\mathrm{Q}}$ |  |
| :--- | :---: |
| Quality $\pi_{\mathrm{Q}}$ <br> JANTXV 0.7 <br> JANTX 1.0 <br> JAN 2.4 <br> Lower 5.5 <br> Plastic 8.0 |  |

6.11 OPTOELECTRONICS, DETECTORS, ISOLATORS, EMITTERS

## SPECIFICATION MIL-S-19500

## DESCRIPTION <br> Photodetectors, Opto-isoiaiors, Emitiers

$$
\lambda_{P}=\lambda_{b} \pi_{T} \pi_{Q} \pi_{E} \quad \text { Failures } / 10^{6} \text { Hours }
$$

Base Faiture Rate $-\lambda_{\mathrm{D}}$

| Opioeiectronic Type | $\lambda_{B}$ |
| :---: | :---: |
| Photodetectors |  |
| Photo-Transistor | . 0055 |
| Photo-Diode | . 0040 |
| Opto-Isolators Photodiade Output, Single Device | . 0025 |
| Photatransistor Output, Single Device | . 013 |
| Photodarlington Output, Single Device | . 013 |
| Light Sensitive Resistor, Single Device | . 0064 |
| Photodiode Output, Dual Device | . 0033 |
| Phototransistor Output, Dual Device | . 017 |
| Photodarlington Output, Dual Device | . 017 |
| Light Sensitive Resistor, Dual Device | . 0086 |
| Emitters inirared Light Eminting Diode (iRLD) | . 0013 |
| Light Emitting Diode (LED) | . 00023 |


| Temperature Facior - $\pi_{T}$ |  |  |  |
| :---: | :---: | :---: | :---: |
| $\mathrm{T}_{\mathrm{J}}\left({ }^{\circ} \mathrm{C}\right)$ | $\pi_{T}$ | $\mathrm{T}_{\mathrm{J}}\left({ }^{\circ} \mathrm{C}\right)$ | $\pi_{T}$ |
| $\begin{aligned} & 25 \\ & 30 \\ & 35 \\ & 40 \\ & 45 \\ & 50 \\ & 55 \\ & 60 \\ & 65 \\ & 70 \end{aligned}$ | $\begin{aligned} & 1.0 \\ & 1.2 \\ & 1.4 \\ & 1.6 \\ & 1.8 \\ & 2.1 \\ & 2.4 \\ & 2.7 \\ & 3.0 \\ & 3.4 \end{aligned}$ | $\begin{array}{r} 75 \\ 80 \\ 85 \\ 90 \\ 95 \\ 100 \\ 105 \\ 110 \\ 115 \end{array}$ | $\begin{aligned} & 3.8 \\ & 4.3 \\ & 4.8 \\ & 5.3 \\ & 5.9 \\ & 6.6 \\ & 7.3 \\ & 8.0 \\ & 8.8 \end{aligned}$ |
| $T_{1}$ | $(-2$ | $\frac{1}{\jmath+27}$ <br> ture | $\hat{y}$ |


| Quality Factor $-\pi_{\mathrm{Q}}$ |  |
| :---: | :---: |
| Quality $\pi_{\mathrm{Q}}$ <br> JANTXV .70 <br> JANTX 1.0 <br> JAN 2.4 <br> Lower 5.5 <br> Plastic 8.0 |  |


| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\pi_{E}$ |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 2.0 |
| $G_{M}$ | 8.0 |
| $N_{S}$ | 5.0 |
| $N_{U}$ | 12 |
| $A_{i C}$ | 4.0 |
| $\hat{A}_{I F}$ | 6.0 |
| $A_{U C}$ | 6.0 |
| $A_{U F}$ | 8.0 |
| $A_{R W}$ | 17 |
| $S_{F}$ | .50 |
| $M_{F}$ | 9.0 |
| $M_{L}$ | 24 |
| $C_{L}$ | 450 |

## MIL-HDBK-217F

## SPECIFICATION

MIL-S-19500

## DESCRIPTION <br> Alphanumeric Display

$$
\lambda_{P}=\lambda_{b} \pi_{T} \pi_{Q} \pi_{E} \text { Failures/10 } \text { Hours }
$$

| Base Failure Rate $-\lambda_{b}$ |  |  |
| :---: | :---: | :---: |
| Number <br> of <br> Characters | $\lambda_{b}$ <br> Segment <br> Display | $\lambda_{b}$ <br> Diode Array <br> Dispotay |
| 1 whogic Chip | .00043 | .00026 |
| 2 | .00047 | .00030 |
| 2 w/ogic Chip | .00086 | .00043 |
| 3 | .00090 | .00047 |
| 3 whogic Chip | .0013 | .00060 |
| 4 | .0013 | .00064 |
| 4 whogic Chip | .0017 | .00077 |
| 5 | .0022 | .00081 |
| 6 | .0026 | .00094 |
| 7 | .0030 | .0011 |
| 8 | .0034 | .0013 |
| 9 | .0039 | .0015 |
| 10 | .0043 | .0016 |
| 11 | .0047 | .0018 |
| 12 | .0052 | .0020 |
| 13 | .0060 | .0021 |
| 14 | .0065 | .0025 |
| 15 |  | .0026 |

$\lambda_{b}=.00043(C)+\lambda_{1 C}$, for Segment Displays
$\lambda_{\mathrm{b}}=.00009+.00017(\mathrm{C})+\lambda_{1 C}$. Diode Array Displays
C $=$ Number of Characters
$\lambda_{X C}=.000043$ for Displays with a Logic Chip
= 0.0 for Displays without Logic Chip
NOTE: The number of characters in a display is the number of characters contained in a single sealed package. For example, a 4 character display comprising 4 separately packaged single characters mounted together would be 4-one character displays, not 1 -four character display.

| Quality Factor $-\pi_{\mathrm{Q}}$ |  |
| :--- | :---: |
| Quality $\pi_{\mathrm{Q}}$ <br> JANTXV 0.7 <br> JANTX 1.0 <br> JAN 2.4 <br> Lower 5.5 <br> Plastic 8.0 |  |


| Temperature Factor $\cdot \pi_{T}$ |  |  |  |  |
| :--- | :---: | :---: | :---: | :---: |
| $T_{J}\left({ }^{\circ} \mathrm{C}\right)$ $\pi_{T}$ $T_{J}\left({ }^{\circ} \mathrm{C}\right)$ $\pi_{T}$ <br> 25 1.0 75 3.8 <br> 30 1.2 80 4.3 <br> 35 1.4 85 4.8 <br> 40 1.6 90 5.3 <br> 45 1.8 95 5.9 <br> 50 2.1 100 6.6 <br> 55 2.4 105 7.3 <br> 60 2.7 110 8.0 <br> 65 3.0 115 8.8 <br> 70 3.4   |  |  |  |  |
| $\pi_{T}=\exp \left(-2790\left(\frac{1}{T_{J}+273}-\frac{1}{298}\right)\right)$ |  |  |  |  |
| $T_{J}=$ |  |  |  |  |


| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\pi_{E}$ |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 2.0 |
| $G_{M}$ | 8.0 |
| $N_{S}$ | 5.0 |
| $N_{U}$ | 12 |
| $A_{1}$ | 4.0 |
| $A_{I F}$ | 6.0 |
| $A_{U C}$ | 6.0 |
| $A_{U F}$ | 8.0 |
| $A_{R W}$ | 17 |
| $S_{F}$ | .50 |
| $M_{F}$ | 9.0 |
| $M_{L}$ | 24 |
| $C_{L}$ | 450 |

```
SPECIFICATION
MIL-S-19500
```


## DESCRIPTION

Laser Diodes with Optical Fhx Densities
< 3 MW/cm ${ }^{2}$ and Fonward Current < 25 amps

$$
\lambda_{P}=\lambda_{b} \pi_{T} \pi_{Q} \pi_{1} \pi_{A} \pi_{P} \pi_{E} \text { Failures/106 Hours }
$$

Base Failure Rate $-\lambda_{\mathrm{t}}$

| Laser Diode Type | $\lambda_{\mathrm{b}}$ |
| :--- | :---: |
| GaAs/Al GaAs | 3.23 |
| In GaAs/In GaAsP | 5.65 |


| Temperature Factor $-\pi_{T}$ |  |
| :---: | :---: |
| $T_{J}\left({ }^{\circ} \mathrm{C}\right)$ |  |$\pi_{T}$


| Quality Factor - $\pi^{2} \mathrm{Q}$ |  |
| :--- | :---: |
| Quality | $\pi_{\mathrm{Q}}$ |
| Hermetic Package | 1.0 |
| Nonhermetic with Facet Coating | 1.0 |
| Nonhermetic without Facet Coating | 3.3 |

Forward Current Factor, $\pi_{1}$

| Forward Peak Current (Amps) | $\pi$ |
| :---: | :---: |
| .050 | 0.13 |
| .075 | 0.17 |
| .1 | 0.21 |
| .5 | 0.62 |
| 1.0 | 1.0 |
| 2.0 | 1.6 |
| 3.0 | 2.1 |
| 4.0 | 2.6 |
| 5.0 | 4.8 |
| 10 | 6.3 |
| 15 | 7.7 |
| 20 | 8.9 |
| 25 |  |

$\pi_{1}=(1)^{68}$
1 = Forward Peak Current (Amps), $1 \leq 25$
NOTE: For Variable Current Sources, use the Initial Current Value.
Application Factor $\pi_{A}$

| Application | Duty Cycle | $\pi_{A}$ |
| :--- | :---: | :---: |
| CW | - | 4.4 |
| Pulsed | .1 | .32 |
|  | .2 | .45 |
|  | .3 | .65 |
|  | .4 | .71 |
|  | .5 | .77 |
|  | .6 | .84 |
|  | .7 | .89 |
|  | .8 | .95 |
|  | .9 | 1.00 |
|  | 1.0 |  |
|  |  |  |
|  |  |  |
| $\pi_{A}=4.4$, CW |  |  |
| $\pi_{A}=$ Duty Cycle | 0.5, Putsed |  |

NOTE: A duty cycle of one in pulsed application represents the maximum amount it can be driven in a pulsed mode. This is different from continuous wave application which will not withstand pulsed operating levels on a continuous basis.

## MIL-HDBK-217F

### 6.13 OPTOELECTRONICS, LASER DIODE


Environment Factor $-\boldsymbol{\pi}_{E}$

| Environment | $\boldsymbol{\pi}_{\mathrm{E}}$ |
| :---: | :---: |
| $\mathrm{G}_{\mathrm{B}}$ | 1.0 |
| $\mathrm{G}_{\mathrm{F}}$ | 2.0 |
| $\mathrm{G}_{\mathrm{M}}$ | 8.0 |
| $\mathrm{~N}_{\mathrm{S}}$ | 5.0 |
| $\mathrm{~N}_{\mathrm{U}}$ | 12 |
| $\mathrm{~A}_{\mathrm{K}}$ | 4.0 |
| $\mathrm{~A}_{\mathrm{IF}}$ | 6.0 |
| $A_{U C}$ | 6.0 |
| $A_{U F}$ | 8.0 |
| $A_{\text {RW }}$ | 17 |
| $\mathrm{~S}_{\mathrm{F}}$ | .50 |
| $M_{F}$ | 9.0 |
| $M_{L}$ | 24 |
| $C_{L}$ | 450 |

### 6.14 DISCRETE SEMICONDUCTORS, $T_{J}$ DETERMINATION

Ideally, device case temperatures should be determined from a detailed thermal analysis of the equipmeni. Device juncion iemperaiure is then caiculâted with time íolowing relationsitip:

$$
T_{J}=T_{C}+\theta_{d C} P
$$

where:
$\mathrm{T}_{\mathbf{J}}=$ Junction Temperature ( ${ }^{\circ} \mathrm{C}$ )
$T_{C}=$ Case Temperature ( ${ }^{\circ} \mathrm{C}$ ). If no thermal analysis exists, the defauth case temperatures shown in Table 6-1 should be assumed.
${ }^{{ }_{J C}}=$ Junction-to-Case Thermal Resistance ( ${ }^{\circ} \mathrm{C} M$ ). This parameter should be determined from vendor, milliary specilication sheets or Table 6-2, whichever is greater. It may also be estimated by taking the reciprocal of the recommended derating level. For example, a device derating recommendation of .16 W/PC would
 $70^{\circ} \mathrm{CM}$.

P = Device Worse Case Power Dissipation (W)
The models are not applicable to devices at overstress conditions. If the calculated junction temperature is greater than the maximum rated junction temperature on the MIL slash sheets or the vendor's specifications, whichever is smalier, then the device is overstressed and these modeis ARE NOT APPLICABLE.

## Table 6-1: Default Case Temperatures ( $T_{C}$ ) for All Environments

| Environment | $\left.\mathrm{T}_{\mathrm{C}}{ }^{\circ} \mathrm{C}\right)$ |
| :---: | :---: |
| $\mathrm{G}_{\mathrm{B}}$ | 35 |
| $\mathrm{G}_{\mathrm{F}}$ | 45 |
| $\mathrm{G}_{\mathbf{M}}$ | 50 |
| $\mathrm{~N}_{\mathrm{S}}$ | 45 |
| $\mathrm{~N}_{\mathrm{U}}$ | 50 |
| $A_{\mathrm{K}}$ | 60 |
| $\mathrm{~A}_{\mathrm{IF}}$ | 60 |
| $A_{\mathrm{UC}}$ | 75 |
| $\mathrm{~A}_{\mathrm{UF}}$ | 75 |
| $A_{R W}$ | 60 |
| $\mathrm{~S}_{\mathrm{F}}$ | 35 |
| $M_{F}$ | 50 |
| $M_{\mathrm{L}}$ | 60 |
| $C_{\mathrm{L}}$ | 45 |

6.14 DISCRETE SEMICONDUCTORS, $T_{J}$ DETERMINATION

Table 6-2: Approximate Junction-to-Case Thermai Resistance ( $\theta_{J C}$ ) ior Semiconductor Devices in Various Package Sizes*

| Package Type | Ojc $\left({ }^{\circ} \mathrm{CM}\right)$ | Package Type | Ojc ( ${ }^{\circ} \mathrm{CNM}$ ) |
| :---: | :---: | :---: | :---: |
| TO-1 | 70 | TO-205AD | 70 |
| TO-3 | 10 | TO-205AF | 70 |
| TO-5 | 70 | TO-220 | 5 |
| TO-8 | 70 | DO-4 | 5 |
| TO-9 | 70 | DO-5 | 5 |
| TO-12 | 70 | DO-7 | 10 |
| TO-18 | 70 | DO-8 | 5 |
| TO-28 | 5 | DO-9 | 5 |
| TO-33 | 70 | DO-13 | 10 |
| TO-39 | 70 | DO-14 | 5 |
| TO-41 | 10 | DO-29 | 10 |
| TO-44 | 70 | DO-35 | 10 |
| TO-46 | 70 | DO-41 | 10 |
| TO-52 | 70 | DO-45 | 5 |
| TO-53 | 5 | DO-204MB | 70 |
| TO-57 | 5 | DO-205AB | 5 |
| TO-59 | 5 | PA-42A,B | 70 |
| TO-60 | 5 | PD-36C | 70 |
| TO-61 | 5 | PD-50 | 70 |
| TO-63 TO-66 | 5 10 | PD-77 PD-180 | 70 70 |
| TO-66 | 10 70 | PD-180 | 70 70 |
| TO-72 | 70 | PD-262 | 70 |
| TO-83 | 5 | PD-975 | 70 |
| TO-89 | 22 | PD-280 | 70 |
| TO-92 | 70 | PD-216 | 70 |
| TO-94 | 5 | PT-2G | 70 |
| TO-99 ${ }^{\text {TO-126 }}$ | 70 5 | PT-6B PH-13 | 70 70 |
| TO-127 | 5 | PH-16 | 70 |
| TO-204 | 10 | PH-56 | 70 |
| TO-204AA | 10 | PY-58 | 70 |
|  |  | PY-373 | 70 |

*When available, estimates must be based on military specification sheet or vendor values, whichever $\theta_{\mathrm{JC}}$ is higher.

MIL-HDBK-217F

### 6.15 DISCRETE SEMICONDUCTORS, EXAMPLE

## Example

Given: $\quad$ Silicon dual transistor (complementary), JAN grade, rated for 0.25 W at $25^{\circ} \mathrm{C}$, one side only, and 0.35 W at $25^{\circ} \mathrm{C}$, both sides, with $T_{\text {max }}=200^{\circ} \mathrm{C}$, operating in linear service at $55^{\circ} \mathrm{C}$ case temperature in a shehered naval environment. Side one, NPN, operating at 0.1 W and 50 percent of rated voltage and side two, PNP, operating at 0.05 W and 30 percent of rated voltage. The device operates at less than 200 MHz .

Since the device is a bipolar dual transistor operating at low frequency ( $<200 \mathrm{MHz}$ ), it falls into the Transistor, Low Frequency, Bipolar Group and the appropriate model is given in Section 6.3. Since the device is a dual device, it is necessary to compute the failure rate of each side separately and sum them together. Also, since $\theta_{\mathrm{JC}}$ is unknown, $\theta_{J C}=70^{\circ} \mathrm{CN}$ will be assumed.

Based on the given information, the following model factors are determined from the appropriate tables shown in Section 6.3.

| $\lambda_{b}=.00074$ |  |
| :--- | :--- |
| $\pi_{T 1}=2.2$ | Side $1, T_{J}=T_{C}+\theta_{J C} P=55+70(.1)=62^{\circ} \mathrm{C}$ |
| $\pi_{T 2}=2.1$ | Side $2, T_{J}=55+70(.05)=59^{\circ} \mathrm{C}$ |
| $\pi_{A}=1.5$ | Using equation shown with $\pi_{R}$ table, $P_{r}=.35 \mathrm{~W}$ |
| $\pi_{R}=.68$ | Side $1,50 \%$ Voltage Stress |
| $\pi_{S 1}=.21$ | Side $2,30 \%$ Voltage Stress |
| $\pi_{S 2}=.11$ |  |
| $\pi_{Q}=2.4$ |  |
| $\pi_{E}=9$ |  |

SIDE 1 SIDE 2
$\lambda_{\mathrm{P}}=\lambda_{\mathrm{B}} \pi_{\mathrm{T} 1} \pi_{\mathrm{A}} \pi_{\mathrm{R}} \pi_{\mathrm{S} 1} \pi_{\mathrm{Q}} \pi_{E}+\lambda_{\mathrm{B}} \pi_{\mathrm{T} 2} \pi_{A} \pi_{R} \pi_{S 2} \pi_{\mathrm{Q}} \pi_{\mathrm{E}}$
$\lambda_{\mathrm{p}}=(.00074)(2.2)(1.5)(.68)(.21)(2.4)(9)+(.00074)(2.1)(1.5)(.68)(.11)(2.4)(9)$
$=.011$ Failures $/ 10^{6}$ Hours

### 7.1 TUBES, ALL TYPES EXCEPT TWT AND MAGNETRON

## DESCRIPTION

All Types Except Traveling Wave Tubes and Magnetrons. Includes Receivers, CRT, Thyratron, Crossed Field Amplifier, Pulsed Gridded, Transmitting, Vidicons, Twystron, Pulsed Klystron, CW Klystron

$$
\lambda_{P}=\lambda_{D} \pi_{L} \pi_{E} \text { Failures/10 } 6 \text { Hours }
$$

Base Failure Rate $-\lambda_{b}$
(Includes Both Random and Wearout Fallures)

| Tube Type | $\lambda_{b}$ | Tube Type | $\lambda_{b}$ |
| :---: | :---: | :---: | :---: |
| Receiver <br> Triode, Tetrode, Pentode Power Rectifier | ${ }_{10}^{5.0}$ | Klystron, Low Power, (e.g. Local Oscillator) | 30 |
| CRT | 9.6 | Klystron, Continuous Wave* |  |
| Thyratron | 50 | 3K3000LQ | 9.0 |
| $\begin{aligned} & \text { Crossed Field Amplifier } \\ & \text { QK681 } \\ & \text { SFD261 } \\ & \hline \end{aligned}$ | $\begin{aligned} & 260 \\ & 150 \end{aligned}$ | 3K50000LF 3K210000LQ 3KM300LA | $\begin{array}{r} 54 \\ 150 \\ 64 \end{array}$ |
| Pulsed Gridded |  | 3KM3000LA | 19 |
| 2041 | 140 | 3KM50000PA | 110 |
| 6952 | 390 | $3 \mathrm{KM50000PA1}$ | 120 |
| 7835 | 140 | $3 \mathrm{KM50000PA2}$ | 150 |
| Transmitting |  | $4 \mathrm{K3CC}$ | 610 |
| Triode, Peak Pwr. $\leq 200$ KW, Avg. Pwr $\leq 2 \mathrm{KW}$ Freq $<200 \mathrm{MHz}$ | 75 | 4K50000LQ | 30 |
|  | 100 | 4 KM 50 LB | 28 |
| $\leq 200$ KW Avg Power $\leq 2 \mathrm{KW}$ |  | 4KM50LC | 15 |
| Freq. $\leq 200 \mathrm{~kW}$ |  | 4KM50SJ | 38 |
| If any of the above limits exceeded | 250 | 4KM50SK | 37 |
| Vidicon |  | 4KM5000020 | 140 79 |
| Antimony Trisulfide ( $\mathrm{Sb}_{2} \mathrm{~S}_{3}$ ) |  | 4KM50000LR | 57 |
| Photoconductive Material | 51 | 4KM170000LA | 15 |
| Silicon Diode Array Photoconductive Material | 48 | 8824 | 130 |
| Twystron |  | 8825 |  |
| VA144 | 850 | 8826 | 280 |
| VA145E | 450 | VA853 | 220 |
| VA145H | 490 | $\checkmark$ A856B | 65 |
| VA913A | 230 | VA888E | 230 |
| Klystron, Pulsed* 4KMP10000LF | 43 |  |  |
| 8568 | 230 | - It the CW Klystron of interest is not listed above, |  |
| L3035 | 66 | use the Alternate CW Klystron $\lambda_{b}$ Table on the |  |
| 13250 | 69 |  |  |

## MIL-HDBK-217F

### 7.1 TUBES, ALL TYPES EXCEPT TWT AND MAGGNETRÔN

Alternate* Base Failure Rate for Pulsed Klystrons - $\lambda_{\mathrm{o}}$

| P(MW) | F(GHz) |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | . 2 | 4 | . 6 | . 8 | 1.0 | 2.0 | 4.0 | 6.0 |
| 01 | 16 | 16 | 16 | 16 | 16 | 16 | 16 | 16 |
| . 30 | 16 | 16 | 17 | 17 | 17 | 18 | 20 | 21 |
| . 80 | 16 | 17 | 17 | 18 | 18 | 21 | 25 | 30 |
| 1.0 | 17 | 17 | 18 | 18 | 19 | 22 | 28 | 34 |
| 3.0 | 18 | 20 | 21 | 23 | 25 | 34 | 51 |  |
| 5.0 | 19 | 22 | 25 | 28 | 31 | 45 | 75 |  |
| 8.0 | 21 | 25 | 30 | 35 | 40 | 63 | 110 |  |
| 10 | 22 | 28 | 34 | 40 | 45 | 75 |  |  |
| 25 | 31 | 45 | 60 | 75 | 90 | 160 |  |  |
| $\lambda_{D}=2.94(F)(P)+i 6$ <br> $F=$ Operating Frequency in $\mathrm{GHz}, 0.2 \leq F \leq 6$ <br> $P=P e a k$ Output Power in MW, $01 \leq P \leq 25$ and $\mathrm{P} \leq 490 \mathrm{~F}^{-2.35}$ |  |  |  |  |  |  |  |  |
|  |  |  |  |  |  |  |  |  |
|  |  |  |  |  |  |  |  |  |
| -See previous page for other Klystron Base Fallure Rates. |  |  |  |  |  |  |  |  |

Alternate" Base Failure Rate for CW Klystrons - $\lambda_{\mathrm{B}}$

| P(KW) | F(MHz) |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | 300 | 500 | 8001000 | 2000 | 4000 | 6000 | 8000 |
| 0.1 | 30 | 31 | $33 \quad 34$ | 38 | 47 | 57 | 66 |
| 1.0 | 31 | 32 | $33 \quad 34$ | 39 | 48 | 57 | 66 |
| 3.0 | 32 | 33 | 3435 | 40 | 49 | 58 |  |
| 5.0 | 33 | 34 | $35 \quad 36$ | 41 | 50 |  |  |
| 8.0 | 34 | 35 | 3738 | 42 |  |  |  |
| 10 | 35 | 36 | $38 \quad 39$ | 43 |  |  |  |
| 30 | 45 | 46 | 4849 |  |  |  |  |
| 50 | 55 | 56 | 5859 |  |  |  |  |
| 80 | 70 | 71 | 73 |  |  |  |  |
| 100 | 80 | 81 |  |  |  |  |  |
| $\lambda_{\mathrm{b}}=0.5 \mathrm{P}+.00046 \mathrm{~F}+29$ |  |  |  |  |  |  |  |
| $\begin{aligned} & P=\text { Average Output Power in KW, } 0.1 \leq P \leq 100 \\ & \text { and } P \leq 8.0(10)^{6}(F)^{-1.7} \end{aligned}$ |  |  |  |  |  |  |  |
| $F=\begin{aligned} & \text { Oparating Frequency in } \mathrm{MHz}, \\ & 300 \leq F \leq 8000\end{aligned}$$300 \leq F \leq 8000$ |  |  |  |  |  |  |  |
| -See previous page for other Klystron Base Failure Rates. |  |  |  |  |  |  |  |

Learning Factor $-\pi_{L}$

| $T$ (years) | $\pi_{L}$ |
| :---: | :---: |
| $\leq 1$ | 10 |
| 2 | 2.3 |
| $\geq 3$ | 1.0 |
| $\pi_{L}$ | $=10(1)^{-2.1}, 1 \leq T \leq 3$ |
|  | $=10, T \leq 1$ |
| $T$ | $=1, T \geq 3$ |$\quad$| Number of Years since Introduction |
| :--- |
| to Fieid Use |


| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\pi_{E}$ |
| $G_{B}$ | .50 |
| $G_{F}$ | 1.0 |
| $G_{M}$ | 14 |
| $N_{S}$ | 8.0 |
| $N_{U}$ | 24 |
| $A_{I C}$ | 5.0 |
| $A_{I F}$ | 8.0 |
| $A_{U C}$ | 6.0 |
| $A_{U F}$ | 12 |
| $A_{\bar{R} W}$ | 40 |
| $S_{F}$ | .20 |
| $M_{F}$ | 22 |
| $M_{I}$ | 57 |
| $C_{L}$ | 1000 |

## MIL-HDBK-217F

## DESCRIPTION

Traveling Wave Tubes

$$
\lambda_{p}=\lambda_{b} \pi_{E} \quad \text { Failures } / 10^{6} \text { Hours }
$$

| Base Failure Rate - $\lambda_{b}$ |  |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Power M | $\mathrm{Frequency}_{6}{ }_{8} \mathrm{GHz}_{10}$ |  |  |  |  |  |  |  |  |
|  |  |  |  |  |  |  |  |  |  |
| 500 | 11 | 12 | 13 | 16 16 | 20 | 24 | 29 | 42 | 61 |
| 1000 | 11 | 12 | 14 | 16 | 20 | 24 | 29 | 43 | 62 |
| 3000 | 12 | 13 | 14 | 17 | 21 | 25 | 30 | 44 | 65 |
| 5000 | 12 | 13 | 15 | 18 | 22 | 26 | 32 | 46 | 68 |
| 8000 | 13 | 14 | 16 | 19 | 23 | 28 | 33 | 49 | 72 |
| 10000 | 14 | 15 | 18 | 20 | 24 | 29 | 35 | 51 | 75 |
| 15000 | 15 | 16 | 18 | 22 | 26 | 32 | 39 | 56 | 83 |
| 20000 | 17 | 18 | 20 | 24 | 29 | 35 |  | 62 | 91 |
| 30000 | 20 | 22 | 24 | 29 | 36 | 43 | 52 | 76 | 110 |
| 40000 | 25 | 27 | 30 | 36 | 43 | 53 | 64 | 93 | 140 |
| $\lambda_{\mathrm{b}}=11(1.00002)^{\mathrm{P}}(1.1)^{F}$ <br> $P=$ Rated Power in Wants (Peak, if Pulsed), $.001 \leq P \leq 40,000$ <br> $F=$ Operating Frequency in GHz, $3 \leq F \leq 18$. <br> It the operating frequency is a band, or two difterent values, use the geometric mean of the end point frequencies when using table. |  |  |  |  |  |  |  |  |  |
|  |  |  |  |  |  |  |  |  |  |
|  |  |  |  |  |  |  |  |  |  |
|  |  |  |  |  |  |  |  |  |  |


| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\pi_{E}$ |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 3.0 |
| $G_{M}$ | 14 |
| $N_{S}$ | 6.0 |
| $N_{U}$ | 21 |
| $A_{I C}$ | 10 |
| $A_{I F}$ | 14 |
| $A_{U C}$ | 11 |
| $A_{U F}$ | 18 |
| $A_{R W}$ | 40 |
| $S_{F}$ | .10 |
| $M_{F}$ | 22 |
| $M_{L}$ | 66 |
| $C_{L}$ | 1000 |

MIL-HDBK-217F
7.3 TUBES, MAGNETRON

> DESCRIPTION
> Magnetrons, Pulsed and Continuous Wave (CW)
> $\lambda_{P}=\lambda_{b} \pi_{U} \pi_{C} \pi_{E}$ Failures/10 Hours

Base Failure Rate - $\lambda_{b}$

| P(MW) | 510.20 Frequency (GHz) |  |  |  |  |  |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | 1 | . 5 | 1 | 5 | 10 | 20 | 30 | 40 | 50 | 60 | 70 | 80 | 90 | 100 |
| . 01 | 1.4 | 4.6 | 7.6 | 24 | 41 | 67 | 91 | 110 | 130 | 150 | 170 | 190 | 200 | 220 |
| . 05 | 1.9 | 6.3 | 10 | 34 | 56 | 93 | 120 | 150 | 180 | 210 | 230 | 260 | 280 | 300 |
| . 1 | 2.2 | 7.2 | 12 | 39 | 64 | 110 | 140 | 180 | 210 | 240 | 270 | 290 | 320 | 350 |
| . 3 | 2.8 | 9.0 | 15 | 48 | 80 | 130 | 180 | 220 | 260 | 300 | 330 | 370 | 400 | 430 |
| . 5 | 3.1 | 10 | 17 | 54 | 89 | 150 | 200 | 240 | 290 | 330 | 370 | 410 | 440 | 480 |
| 1 | 3.5 | 11 | 19 | 62 | 100 | 170 | 230 | 280 | 330 | 380 | 420 | 470 | 510 | 550 |
| 3 | 4.4 | 14 | 24 | 77 | 130 | 210 | 280 | 350 | 410 | 470 | 530 | 580 | 630 | 680 |
| 5 | 4.9 | 16 | 26 | 85 | 140 | 230 | 310 | 390 | 460 | 520 | 580 | 640 | 700 | 760 |
| Pulsed | Magnetrons: |  |  |  |  |  |  | CW Magnetrons (Rated Power < 5 KW): |  |  |  |  |  |  |
| $\lambda_{b}$ | 19(F) ${ }^{73}$ (P). 20 |  |  |  |  |  |  | $\lambda_{b}=18$ |  |  |  |  |  |  |
| F | Operating Frequency in GHz , |  |  |  | . $1 \leq 5 \leq 100$ |  |  |  |  |  |  |  |  |  |
| P | Output Power in MW, |  |  |  | . $01 \leq \mathrm{P} \leq 5$ |  |  |  |  |  |  |  |  |  |


| Utillization Factor $-\pi_{U}$ |
| :--- |
| Utilization (Radiate Hours/ <br> Filament Hours) $\pi_{U}$ <br> 0.0 .44 <br> 0.1 .50 <br> 0.2 .55 <br> 0.3 .61 <br> 0.4 .76 <br> 0.5 .78 <br> 0.6 .83 <br> 0.7 .89 <br> 0.8 .94 <br> 0.9 1.0 <br> 1.0  <br>   <br>   <br> $R=$ Radiate Hours/Filament Hours  |

Construction Factor $-\pi_{\mathrm{C}}$

| Construction | $\pi_{\mathrm{C}}$ |
| :--- | :---: |
| CW (Rated Power < 5 KW ) | 1.0 |
| Coaxial Pulsed | 1.0 |
| Conventional Pulsed | 5.4 |


| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\pi_{E}$ |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 2.0 |
| $G_{M}$ | 4.0 |
| $N_{S}$ | 15 |
| $N_{U}$ | 47 |
| $A_{I C}$ | 10 |
| $A_{I F}$ | 16 |
| $A_{U C}$ | 12 |
| $A_{U F}$ | 23 |
| $A_{R W}$ | 80 |
| $S_{F}$ | .50 |
| $M_{F}$ | 43 |
| $M_{L}$ | 133 |
| $C_{L}$ | 2000 |

The models and failure rates presented in this section apply to laser peculiar items only, i.e., those items wherein the lasing action is generated and controlled. In addition to laser peculiar hems, there are other assemblies used with lasers that contain electronic parts and mechanical devices (pumps, valves, hoses, etc.). The faikure rates for these parts should be determined with the same procedures as used for other electronic and mechanical devices in the equipment or system of whict the laser is a part.

The laser failure rate models have been developed at the "functional," rather than "piece part" level because the available data were not sufficient for "piece part" model development. Nevertheless, the iaser ínctionai models are inciuded in this hanatoók in the interest of completeness. These laser models will be revised to include piece part models and other laser types when the data become available.

Because each laser family can be designed using a variety of approaches, the failure rate models have been siructured on tîree Dasic iaser íunctions wivicil are common io mosi iaser families, but may difîer in the hardware implementation of a given function. These functions are the lasing media, the laser pumping mechanism (or pump), and the coupling method.

Examples of media-related hardware and reliability inftuencing factors are the solid state rod, gas, gas pressure, vacuum integrity, gas mix, outgassing, and tube diameter. The electrical discharge, the flashlamp, and energy level are examples of pump-related hardware and reliability influencing factors. The coupling function reliability influencing factors are the " $Q$ " switch, mirrors, windows, crystals, substrates, coatings, and level of dust protection provided.

Some of the laser models require the number of active optical surfaces as an input parameter. An active optical surface is one with which the laser energy (or beam) interacts. Internally reflecting surfaces are not counted. Figure 8-1 below illustrates examples of active optical surfaces and count.


Figure 8-1: Examples of Active Optical Surfaces

MIL-HDBK-217F

### 8.1 LASERS, HELIUM AND ARGON

DESCRIPTION
Helium Neon Lasers
Helium Cadmium Lasers
Argon Lasers

$$
\lambda_{P}=\lambda_{\text {MEDIA }} \pi_{E}+\lambda_{\text {COUPLING }} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

| Lasing Media Failure Rate $-\lambda_{\text {MEDIA }}$ |  |
| :--- | :---: |
| Type | $\lambda_{\text {MEDIA }}$ |
| $\mathrm{He} / \mathrm{Ne}$ | 84 |
| $\mathrm{He} / \mathrm{Cd}$ | 228 |
| Argon | 457 |


| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\pi_{E}$ |
| $G_{B}$ | .30 |
| $G_{F}$ | 1.0 |
| $G_{M}$ | 4.0 |
| $N_{S}$ | 3.0 |
| $N_{U}$ | 4.0 |
| $A_{I C}$ | 4.0 |
| $A_{I F}$ | 6.0 |
| $A_{U C}$ | 7.0 |
| $A_{U F}$ | 9.0 |
| $A_{R W}$ | 5.0 |
| $S_{F}$ | .10 |
| $M_{F}$ | 3.0 |
| $M_{L}$ | 8.0 |
| $C_{L}$ | $N / A$ |

mechanism is related to the gas media (as reflected in $\lambda_{\text {MEDIA }}$; however, when the tube is refilled periodically (preventive maintenance) the mirrors (as part of $\lambda$ COUPLING) can be expected to deteriorate after approximately 104 hours of operation if in contact with the discharge region.
$\lambda_{\text {COUPLING }}$ is negligible for helium lasers.

## MIL-HDBK-217F

8.2 LASERS, CARBON DIOXIDE, SEALED

DESCRIPTION
$\mathrm{CO}_{2}$ Sealed Continuous Wave Lasers

$$
\lambda_{\mathrm{P}}=\lambda_{\mathrm{MEDIA}} \pi_{\mathrm{O}} \pi_{\mathrm{B}} \pi_{E}+10 \pi_{\mathrm{OS}} \pi_{E} \quad \text { Failures } / 10^{6} \text { Hours }
$$

Lasing Media Failure Rate - $\lambda_{\text {MEDIA }}$

| Tube Current (mA) | $\lambda_{\text {MEDIA }}$ |  |
| :---: | ---: | :---: |
| 10 | 240 |  |
| 20 | 930 |  |
| 30 | 1620 |  |
| 40 | 2310 |  |
| 50 | 3000 |  |
| 100 | 6450 |  |
| 150 | 9900 |  |
|  |  |  |
| MEDIA - 69(1) - 450 |  |  |
| I = Tube Current (mA), $10 \leq 1 \leq 150$ |  |  |

Gas Overfill Factor $=\pi_{\mathrm{O}}$

| $\mathrm{CO}_{2}$ Overill Percent (\%) | $\pi_{\mathrm{O}}$ |
| :---: | :---: |
| 0 | 1.0 |
| 25 | .75 |
| 50 | .50 |

$\pi_{0}=1-.01$ (\% Overtill)
Overtill percent is based on the percent increase over the optimum $\mathrm{CO}_{2}$ partial pressure which is normally in the range of 1.5 to $3 \mathrm{~T}_{\text {or }}$ ( $1 \mathrm{~T}_{\text {orr }}=1$ mm Hg Pressure) for most sealed $\mathrm{CO}_{2}$ lasers.

| Ballast Factor $-\pi_{\mathrm{B}}$ |  |
| :---: | :---: |
| Percent of Ballast <br> Volumetric Increase $\pi_{\mathrm{B}}$ <br> 0 1.0 <br> 50 .58 <br> 100 .33 <br> 150 .19 <br> 200  <br> $\pi_{\mathrm{B}}=(1 / 3)$ (\% Vol. Inc./100)  |  |


| Optical Surface Factor $-\pi \mathrm{OS}$ |
| :--- |
| Active Optical Surfaces $\pi \mathrm{OS}$ <br> 1 1 <br> 2 2 <br> OS $=$ Number of Active Optical Surfaces  <br> NOTE: Only active optical surfaces are  <br> counted. An active optical surface is one with  <br> which the laser energy or bean intermcts.  <br> Internaly refiecting surfaces are not counted.  <br> See Figure 8-1 for examples on determining the  <br> number of optical surfaces.  |


| Environment Factor - $\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\pi_{E}$ |
| $\mathrm{G}_{\mathrm{B}}$ | . 30 |
| $\mathrm{G}_{\mathrm{F}}$ | 1.0 |
| $G_{M}$ | 4.0 |
| $\mathrm{N}_{S}$ | 3.0 |
| Nu | 4.0 |
| $A_{1 C}$ | 4.0 |
| $\mathrm{A}_{\text {IF }}$ | 6.0 |
| ${ }^{\text {A }}$ UC | 7.0 |
| ${ }^{\text {A }}$ UF | 9.0 |
| $A_{\text {RW }}$ | 5.0 |
| $S_{F}$ | . 10 |
| $M_{F}$ | 3.0 |
| $M_{L}$ | 8.0 |
| $C_{L}$ | N/A |

DESCRIPTION
$\mathrm{CO}_{2}$ Flowing Lasers
$\lambda_{p}=\lambda_{\text {coupling }} \pi_{O S} \pi_{E}$ Failures $/ 10^{6}$ Hours

| Coupling Failure Rate - $\lambda_{\text {coupling }}$ |  |
| :---: | :---: |
| Power (KW) | $\lambda^{\text {COUPLING }}$ |
| $\begin{gathered} .01 \\ .1 \\ 1.0 \end{gathered}$ | $\begin{array}{r} 3 \\ 30 \\ 300 \end{array}$ |
| ${ }^{\lambda}$ COUPLING $=$ <br> $\mathrm{P}=$ Average Po <br> Beyond the 1KW r <br> begin to predominat <br> It should also be no devices are the prim <br> A tailored optical cle program on optic d | $W . .01 \leq P \leq 1.0$ <br> falhure mechanisms <br> COUPLING values wing laser optical ailure occurrence. <br> $\theta$ maintenance tends laser life. |


| Optical Surface Factor $-\pi_{\mathrm{OS}}$ |
| :--- |
| Active Optical Surfaces $\pi_{\mathrm{OS}}$ <br> 1 1 <br> 2 2 |


| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\pi_{E}$ |
| $G_{B}$ | .30 |
| $G_{F}$ | 1.0 |
| $G_{M}$ | 4.0 |
| $N_{S}$ | 3.0 |
| $N_{U}$ | 4.0 |
| $A_{I C}$ | 4.0 |
| $A_{I F}$ | 6.0 |
| $A_{U C}$ | 7.0 |
| $A_{U F}$ | 9.0 |
| $A_{R W}$ | 5.0 |
| $S_{F}$ | .10 |
| $M_{F}$ | 3.0 |
| $M_{L}$ | 8.0 |
| $C_{L}$ | $N / A$ |

$\pi_{\mathrm{OS}}=$ Number of Active Optical Surfaces
NOTE: Only active optical surfaces are counted. An active optical surface is one with which the laser energy or beam interacts. Internally refiecting surfaces are not counted. See Figure 8.1 for examples on determining the number of optical surfaces.

DESCRIPTION<br>Neodymium-Yttrum-Aluminum-Gamet (ND:YAG) Rod Lasers

## Ruby Rod Lasers

$$
\lambda_{P}=\left(\lambda_{\text {PUMP }}+\lambda_{\text {MEDIA }}+16.3 \pi_{C} \pi_{O S}\right) \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

## Pump Pulse Failure Rate - $\lambda_{\text {PUMP }}$ <br> (Xenon Flashlamps)

The empirical formula used to determine $\lambda$ PUMP
(Failures/106 Hours) for Xenon lamps is:
$\lambda_{\text {PUMP }}=(3600)(P P S)\left[2000\left(\frac{E_{j}}{d L \sqrt{t}}\right)^{8.58}\right]\left[\pi_{\mathrm{COOL}}\right]$
$\lambda$ PUMP is the failure rate contribution of the Xenon flashlamp or flashtube. The flashlamps evaluated herein are linear types used for military solid state laser systems. Typical default model parameters are given below.

PPS is the repetition pulse rate in pulses per second. Typical values range between 1 and 20 pulses per second.
$\mathrm{E}_{\mathrm{j}} \quad$ is the flashlamp or flashtube input energy per pulse, in joules. Its value is determined from the actual or design input energy. For values less than 30 joules, use $E_{j}=30$. Defaut value: $\mathrm{E}_{\mathrm{j}}=40$.
d is the flashlamp or flashtube inside diameter, in millimeters.
Defaut value: $d=4$.
$L \quad$ is the flashlamp or flashtube arc length in inches. Default value: $L=2$.
$t$ is the truncated pulse width in microseconds. Use $t=100$ microseconds for any truncated pulse width exceeding 100 microseconds. For shorter duration pulses, pulse width is to be measured at 10 percent of the maximum current amplitude. Default value: $t=100$.
$\pi \mathrm{COOL}$ is the cooling factor due to various cooling media immediately surrounding the flashlamp or flashtube. $\pi_{\mathrm{COOL}}=1.0$ for any air or inert gas cooling. $\pi_{\mathrm{COOL}}=.1$ for all liquid cooled designs. Default value: $\pi_{\mathrm{COOL}}=.1$, liquid cooled.

## Pump Pulse Failure Rate - $\lambda_{\text {PUMP }}{ }^{3}$

(Krypton Flashiamps)
The empirical formula used to determine $\lambda_{\text {pUMP }}$ for Krypton lamp is:
$\lambda_{\text {PLMMP }}=[625]\left[10^{80.9} \stackrel{P}{\mathrm{~L}}\right]\left[x_{\text {coo }}\right]$ Failures $/ 10^{6}$ Hours
$\lambda_{\text {PUMP }}$ is the failure rate contribution of the krypton flashlamp or flashtube. The flashlamps evaluted herein are the continuous wave (CW) type and are most widely used for commercial solid state applications. They are approx-imately 7 mm in diameter and 5 to 6 inches long.
$P \quad$ is the average input power in kilowatts. Default value: $\mathrm{P}=4$.
$L \quad$ is the flashlamp or flashtube arc length in inches. Defaut value: $L=2$.
$\pi^{\mathrm{COOL}}$ is the cooling factor due to various cooling media immediately surrounding the flashlamp or flashtube. $\pi_{\mathrm{COOL}}=1$ for any air or inent gas cooling. $\pi_{\mathrm{COOL}}=.1$ for all liquid designs. Default value: $\pi_{\mathrm{COOL}}=.1$, liquid cooled.

Media Failure Rate - $\lambda$ MEDIA

| Laser Type | $\lambda_{\text {MEDIA }}$ |
| :--- | :---: |
| ND:YAG | 0 |
| Ruby | $(3600)$ (PPS) $\left[43.5 \mathrm{~F}^{2.52}\right]$ |

PPS is the number of pulses per second
F is the energy density in Joules per cm. $2 /$ pulse over the cross-sectional area of the laser beam, which is nominally equivalent to the cross-sectional area of the laser rod, and its value is determined from the actual design parameter of the laser rod utilized.

NOTE: $\lambda_{\text {MEDIA }}$ is negligible for ND:YAG lasers.

| Cleanliness Level | ${ }^{\pi} \mathrm{C}$ |
| :---: | :---: |
| Rigorous clearliness procedures and trained maintenance personnel. Bellows provided over optical train. <br> Minimal precautione during opening. maintenence, repair, and testing. Bellows provided over optical train. <br> Minimal precaustions during opening, maintenence, repair, and testing. No bellowe provided over optical train. | 30 <br> 60 |
| NOTE: Although sealed syetems tend to be rellable once compatible materials have been selected and proven, extreme care must still be taken to prevent the entrance of perticulates during manufacturing. field flashlamp replacement, or routine maintenance/ repair. Contamination is the major cause of solid state laser malfunction, and spectal provisions and vigilance must continually be provided to maintain the cleanliness level required. |  |


| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\pi_{E}$ |
| $\mathrm{G}_{\mathrm{B}}$ | .30 |
| $\mathrm{G}_{\mathrm{F}}$ | 1.0 |
| $\mathrm{G}_{\mathrm{M}}$ | 4.0 |
| $\mathrm{~N}_{\mathrm{S}}$ | 3.0 |
| $\mathrm{~N}_{\mathrm{U}}$ | 4.0 |
| $\mathrm{~A}_{\mathrm{IC}}$ | 4.0 |
| $\mathrm{~A}_{\mathrm{IF}}$ | 6.0 |
| $\mathrm{~A}_{\mathrm{UC}}$ | 7.0 |
| $\mathrm{~A}_{\mathrm{UF}}$ | 9.0 |
| $\mathrm{~A}_{\mathrm{RW}}$ | 5.0 |
| $\mathrm{~S}_{\mathrm{F}}$ | .10 |
| $\mathrm{M}_{\mathrm{F}}$ | 3.0 |
| $\mathrm{M}_{\mathrm{L}}$ | 8.0 |
| $\mathrm{C}_{\mathrm{L}}$ | $\mathrm{N} / \mathrm{A}$ |

Optical Surface Factor $-\pi_{\mathrm{OS}}$

| Active Optical Surfaces | $\pi_{\mathrm{OS}}$ |
| :---: | :---: |
| 1 | 1 |
| 2 | 2 |
| $\pi_{\mathrm{OS}}=$ Number of Active Optical Surfaces |  |
| NOTE: Only ective optical surfacas are counted. |  |
| An active optical surface is one with which ite laser |  |
| energy or beam interacts. Internally reflecting |  |
| surfaces are not counted. See Figure 8-1 for |  |
| examples on determining the number of optical |  |
| surfaces. |  |

This section includes the active resistor specifications and, in addition, some older/inactive specifications are inctuded because of the large number of equipments still in field use which contain these parts.

The Established Reliability (ER) resistor family generalty has four qualification failure rate levels when tested per the requirements of the applicable specification. These qualification failure rate levels differ by a factor of ten (from one level to the next). However, field data has shown that these failure rate levels differ by a factor of about only three, hence the $\pi_{Q}$ values have been set accordingly.

The use of the resistor models requires the calculation of the electrical power stress ratio, Stress = operating power/rated power, or per Section 9.16 for variable resistors. The models have been structured such that derating curves do not have to be used to find the base faiture rate. The rated power for the stress ratio is equal to the full nominal rated power of the resistor. For example, a MIL-R-39008 resistor has the following derating curve:


Figure 9-1: MIL-R-39008 Derating Curve

This particular resistor has a rating of 1 watt at $70^{\circ} \mathrm{C}$ ambient, or beiow. If it were being used in an ambient temperature of $100^{\circ} \mathrm{C}$, the rated power for the stress calculation would still be 1 watt, not $45 \%$ of 1 watt (as read off the curve for $100^{\circ} \mathrm{C}$ ). Of course, while the derating curve is not needed to determine the base failure rate, it must still be observed as the maximum operating condition. To aid in determining if a resistor is being used within rated conditions, the base failure rate tables show entries up to certain combinations of stress and temperature. If a given operating stress and temperature point falls in the blank pontion of the base faiture rate table, the resistor is overstressed. Such misapplication would require an analysls of the circuit and operating conditions to bring the resistor within rated conditions.

## MIL-HDBK-217F

9.1 RESISTORS, FIXED, COMPOSITION
SPECIFICATION
MIL-R-39008
MIL-R-11

STYLE DESCRIPTION RCR RC

Resistors, Fixed, Composition (Insulated), Established Reliability Resistors, Fixed, Composition (Insulated)

$$
\lambda_{\mathrm{P}}=\lambda_{\mathrm{b}} \pi_{\mathrm{R}} \pi_{\mathrm{Q}} \pi_{\mathrm{E}} \text { Failures } / 10^{6} \text { Hours }
$$

| $\mathrm{T}_{\mathrm{A}}\left({ }^{\circ} \mathrm{C}\right)$ | Stress |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | . 1 | . 3 | . 5 | . 7 | . 9 |
| 0 | . 00007 | . 00010 | . 00015 | . 00020 | . 00028 |
| 10 | . 00011 | . 00015 | . 00021 | . 00030 | . 00043 |
| 20 | . 00015 | . 00022 | . 00031 | . 00045 | . 00064 |
| 30 | . 00022 | . 00031 | . 00046 | . 00066 | . 00096 |
| 40 | . 00031 | . 00045 | . 00067 | . 00098 | . 0014 |
| 50 | . 00044 | . 00066 | . 00098 | . 0014 | . 0021 |
| 60 | . 00063 | . 00095 | . 0014 | . 0021 | . 0032 |
| 70 | . 00090 | . 0014 | . 0021 | . 0032 | . 0048 |
| 80 | . 0013 | . 0020 | . 0031 | . 0047 |  |
| 90 | . 0018 | . 0029 | . 0045 |  |  |
| 100 | . 0026 | . 0041 | . 0065 |  |  |
| 110 | . 0038 | . 0060 |  |  |  |
| 120 | . 0054 |  |  |  |  |
| $\lambda_{b}=4.5 \times 10^{-9} \exp \left(12\left(\frac{T+273}{343}\right)\right) \exp \left(\frac{S}{.6}\left(\frac{T+273}{273}\right)\right)$ |  |  |  |  |  |
| $T=$ Ambient Temperature ( ${ }^{\circ} \mathrm{C}$ ) |  |  |  |  |  |
| $S=$ Ratio of Operating Power to Rated Power |  |  |  |  |  |


| Quality Factor $-\pi_{Q}$ |  |
| :---: | :---: |
| Quality | $\pi_{Q}$ |
| S | .03 |
| R | 0.1 |
| P | 0.3 |
| M | 1.0 |
| MIL-R-11 | 5.0 |
| Lower | 15 |


| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\pi_{E}$ |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 3.0 |
| $G_{M}$ | 8.0 |
| $N_{S}$ | 5.0 |
| $N_{U}$ | 13 |
| $A_{I C}$ | 4.0 |
| $A_{I F}$ | 5.0 |
| $A_{U C}$ | 7.0 |
| $A_{U F}$ | 11 |
| $A_{R W}$ | 19 |
| $S_{F}$ | .50 |
| $M_{F}$ | 11 |
| $M_{L}$ | 27 |
| $C_{L}$ | 490 |


|  |  |
| :--- | :--- |
| SPECIFICATION | STYLE |
| MIL-R-39017 | RLR |
| MIL-R-22684 | RL |
| MIL-R-55182 | RN $(R, C, o r N)$ |
| MIL-R-10509 | RN |
|  | $\lambda_{D}=\lambda_{b} \pi_{R} \pi_{Q} \pi_{E}$ |

## DESCRIPTION

Fixed, Film, Insulated, Established Reliability
Fixed, Film, Insulated
Fixed, Film, Established Reliability Fixed, Film, High Stability

Failures $/ 10^{6}$ Hours

Base Failure Rate - $\lambda_{b}$ (MIL-R-22684 and MIL-R-39017)

| $\left.T_{A}{ }^{\circ} \mathrm{C}\right)$ | .1 | .3 | .5 | .7 | .9 |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 0 | .00059 | .00073 | .00089 | .0011 | .0013 |
| 10 | .00063 | .00078 | .00096 | .0012 | .0014 |
| 20 | .00067 | .00084 | .0010 | .0013 | .0016 |
| 30 | .00072 | .00090 | .0011 | .0014 | .0018 |
| 40 | .00078 | .00098 | .0012 | .0016 | .0019 |
| 50 | .00084 | .0011 | .0014 | .0017 | .0022 |
| 60 | .00092 | .0012 | .0015 | .0019 | .0024 |
| 70 | .0010 | .0013 | .0017 | .0021 | .0027 |
| 80 | .0011 | .0014 | .0018 | .0024 |  |
| 90 | .0012 | .0016 | .0021 | .0027 |  |
| 100 | .0013 | .0018 | .0023 |  |  |
| 110 | .0015 | .0020 | .0026 |  |  |
| 120 | .0017 | .0023 |  |  |  |
| 130 | .0019 |  |  |  |  |
| 140 | .0022 |  |  |  |  |
| 10 |  |  |  |  |  |
| 10 |  |  |  |  |  |

$\lambda_{\mathrm{D}}=3.25 \times 10^{-4} \exp \left(\frac{T+273}{343}\right)^{3} \exp \left(\mathrm{~S}\left(\frac{T+273}{273}\right)\right)$
$T=$ Ambient Temperature ( ${ }^{\circ} \mathrm{C}$ )
$S=$ Ratio of Operating Power to Rated Power

Base Failure Rate - $\lambda_{b}$
(MIL-R-10509 and MIL-R-55182)

| $T_{A}\left({ }^{\circ} \mathrm{C}\right)$ | Stress |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | . 1 | . 3 | . 5 | . 7 | . 9 |
| 0 | . 00061 | . 00074 | . 00091 | . 0011 | . 0014 |
| 10 | . 00067 | . 00082 | . 0010 | . 0012 | . 0015 |
| 20 | . 00073 | . 00091 | . 0011 | . 0014 | . 0017 |
| 30 | . 00080 | . 0010 | . 0013 | 0016 | . 0019 |
| 40 | . 00088 | . 0011 | . 0014 | . 0017 | . 0022 |
| 50 | . 00096 | . 0012 | . 0015 | . 0020 | . 0025 |
| 60 | . 0011 | . 0013 | . 0017 | . 0022 | . 0028 |
| 70 | . 0012 | . 0015 | . 0019 | . 0025 | . 0032 |
| 80 | . 0013 | . 0016 | . 0021 | . 0028 | . 0036 |
| 90 | . 0014 | . 0018 | . 0024 | . 0031 | . 0040 |
| 100 | . 0015 | . 0020 | . 0026 | . 0035 | . 0045 |
| 110 | . 0017 | . 0022 | . 0029 | . 0039 | . 0051 |
| 120 | . 0018 | . 0024 | . 0033 | . 0043 | . 0058 |
| 130 | . 0020 | . 0027 | . 0036 | . 0049 | . 0065 |
| 140 | . 0022 | . 0030 | . 0040 | . 0054 |  |
| 150 | . 0024 | . 0033 | . 0045 |  |  |
| 160 | . 0026 | . 0036 |  |  |  |
| 170 | . 0029 |  |  |  |  |
| $\lambda_{\mathrm{D}}=5 \times 10^{-5} \exp \left(3.5\left(\frac{T+273}{398}\right)\right) \exp \left(\mathrm{S}\left(\frac{T+273}{273}\right)\right)$ |  |  |  |  |  |
| $\mathrm{T}=$ Ambient Temperature ( ${ }^{\circ} \mathrm{C}$ ) |  |  |  |  |  |
| $s=$ Ratio of Operating Power to Rated Power |  |  |  |  |  |

NOTE: Do not use MIL-R-10509 (Characteristic B) below the line. Points below are overstressed.

## MIL-HDBK-217F

9.2 RESISTORS, FIXED, FILM

| Resistance Factor $-\pi_{R}$ |  |
| :--- | :---: |
| Resistance Range (ohms) | $\pi_{R}$ |
| $<.1 \mathrm{M}$ | 1.0 |
| $\geq 0.1 \mathrm{M}$ to 1 M | 1.1 |
| $>1.0 \mathrm{M}$ to 10 M | 1.6 |
| $>10 \mathrm{M}$ | 2.5 |


| Quality Factor $-\pi_{\mathrm{Q}}$ |  |
| :--- | :---: |
| Quality | $\pi_{\mathrm{Q}}$ |
| S | .03 |
| R | 0.1 |
| P | 0.3 |
| M | 1.0 |
| MIL-R-10509 | 5.0 |
| MIL-R-22684 | 5.0 |
| Lower | 15 |


| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\pi_{E}$ |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 2.0 |
| $G_{M}$ | 8.0 |
| $N_{S}$ | 4.0 |
| $N_{U}$ | 14 |
| $A_{I C}$ | 4.0 |
| $A_{I F}$ | 8.0 |
| $A_{U C}$ | 10 |
| $A_{U F}$ | 18 |
| $A_{R W}$ | 19 |
| $S_{F}$ | .20 |
| $M_{F}$ | 10 |
| $M_{L}$ | 28 |
| $C_{L}$ | 510 |

MIL-HDBK-217F
9.3 RESISTORS, FIXED, FILM, POWER

SPECIFICATION
MIL-R-11804

## STYLE <br> RD

## DESCRIPTION <br> Fixed, Film, Power Type

$$
\lambda_{p}=\lambda_{b} \pi_{R} \pi_{Q} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

| Base Failure Rate - $\lambda_{0}$ |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | Stress |  |  |  |  |
| $T_{A}\left({ }^{\circ} \mathrm{C}\right)$ | . 1 | . 3 | . 5 | . 7 | . 9 |
| 0 | . 0089 | . 0098 | . 011 | . 013 | . 015 |
| 10 | . 0090 | . 010 | . 011 | . 013 | . 015 |
| 20 | . 0092 | . 010 | . 012 | . 014 | . 016 |
| 30 | . 0094 | . 010 | . 012 | . 014 | . 017 |
| 40 | . 0096 | . 011 | . 012 | . 015 | . 017 |
| 50 | . 0098 | . 011 | . 013 | . 015 |  |
| 60 | . 010 | . 011 | . 013 | . 016 |  |
| 70 | . 010 | . 012 | . 014 | . 016 |  |
| 80 | . 010 | . 012 | . 014 | . 017 |  |
| 90 | . 011 | . 012 | . 015 |  |  |
| 100 | . 011 | . 013 | . 015 |  |  |
| 110 | . 011 | . 013 | . 016 |  |  |
| 120 | . 012 | . 014 | . 016 |  |  |
| 130 | . 012 | . 014 | . 017 |  |  |
| 140 | . 012 | . 014 |  |  |  |
| 150 | . 013 | . 015 |  |  |  |
| 160 | . 013 | . 016 |  |  |  |
| 170 | . 014 | . 016 |  |  |  |
| 180 | . 014 |  |  |  |  |
| 190 | . 015 |  |  |  |  |
| 200 | . 015 |  |  |  |  |
| 210 | . 016 |  |  |  |  |
| $\lambda_{h}$ | $\begin{aligned} & 7.33 x \\ & \exp ( \end{aligned}$ | $\begin{aligned} & 0^{-3} \exp \\ & \left.\frac{s}{.45}\right) \end{aligned}$ | $\begin{array}{r} 202(T \\ +273 \\ 273 \end{array}$ | $\begin{aligned} & \left.\frac{73}{8}\right)^{2} \\ & 9)^{1.3} \end{aligned}$ |  |
|  | Ambie | emper | $\theta\left({ }^{\circ} \mathrm{C}\right.$ |  |  |
|  | Ratio of | Operatin | Power | Rated |  |


| Quality Factor $-\pi_{\mathrm{Q}}$ |  |
| :---: | :---: |
| Quality | $\pi_{\mathrm{Q}}$ |
| MIL-SPEC | 1.0 |
| Lower | 3.0 |

Environment Factor - $\pi_{E}$

| Environment | $\pi_{\mathrm{E}}$ |
| :---: | :---: |
| $\mathrm{G}_{\mathrm{B}}$ | 1.0 |
| $\mathrm{G}_{\mathrm{F}}$ | 2.0 |
| $\mathrm{G}_{\mathrm{M}}$ | 10 |
| $\mathrm{~N}_{\mathrm{S}}$ | 5.0 |
| $\mathrm{~N}_{\mathrm{U}}$ | 17 |
| $\mathrm{~A}_{I C}$ | 6.0 |
| $\mathrm{~A}_{I F}$ | 8.0 |
| $\mathrm{~A}_{U C}$ | 14 |
| $\mathrm{~A}_{\mathrm{UF}}$ | 18 |
| $A_{R W}$ | 25 |
| $\mathrm{~S}_{F}$ | .50 |
| $M_{F}$ | 14 |
| $M_{L}$ | 36 |
| $C_{L}$ | 660 |

Resistance Factor $-\pi_{R}$

| Resistance Range (ohms) | $\pi_{R}$ |
| :--- | :---: |
| 1010100 | 1.0 |
| $>100$ to 100 K | 1.2 |
| $>100 \mathrm{~K} 101 \mathrm{M}$ | 1.3 |
| $>1 \mathrm{M}$ | 3.5 |

## MIL-HDBK-217F

### 9.4 RESISTORS, NETWORK, FIXED, FILM

| SPECIFICATION STYLE | DESCRIPTION <br> MIL-R-83401 | RESistor Networks, Fixed, Film |
| :--- | :--- | :--- |


| $\mathrm{T}_{\mathrm{C}}\left({ }^{\circ} \mathrm{C}\right)$ | $\pi_{T}$ | $\mathrm{T}_{\mathrm{C}}\left({ }^{\circ} \mathrm{C}\right)$ | $\pi_{T}$ |
| :---: | :---: | :---: | :---: |
| 25 | 1.0 | 80 | 8.3 |
| 30 | 1.3 | 85 | 9.8 |
| 35 | 1.6 | 90 | 11 |
| 40 | 1.9 | 95 | 13 |
| 45 | 2.4 | 100 | 15 |
| 50 | 2.9 | 105 | 18 |
| 55 | 3.5 | 110 | 21 |
| 60 | 4.2 | 115 | 24 |
| 65 | 5.0 | 120 | 27 |
| 70 | 6.0 | 125 | 31 |
| 75 | 7.1 |  |  |
| $\pi_{T}=\exp \left(-4056\left(\frac{1}{T_{C}+273}-\frac{1}{298}\right)\right.$ |  |  |  |
| $T_{C}=$ Case Temperature ( ${ }^{\circ} \mathrm{C}$ ) |  |  |  |

NOTE: $H T_{C}$ is unknown, it can be estimated as follows:
$T_{C}=T_{A}+55(S)$
$T_{A}=$ Ambient Temperature ( ${ }^{\circ} \mathrm{C}$ )
$S=\frac{\text { Operating Power }}{\text { Package Rated Power }}$

Any device operating at $T_{C}>125^{\circ} \mathrm{C}$ is overstressed.

| ${\text { Quality Factor }-\pi_{\mathrm{Q}}}^{\|c\| c \mid}$Quality 1 <br> MIL-SPEC 3 |  |
| :---: | :---: |


| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\pi_{E}$ |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 2.0 |
| $G_{M}$ | 8.0 |
| $N_{S}$ | 4.0 |
| $N_{U}$ | 14 |
| $A_{I C}$ | 4.0 |
| $A_{I F}$ | 8.0 |
| $A_{U C}$ | 9.0 |
| $A_{U F}$ | 18 |
| $A_{R W}$ | 19 |
| $S_{F}$ | .50 |
| $M_{F}$ | 14 |
| $M_{L}$ | 28 |
| $C_{L}$ | 510 |


| Number of Resistors Factor $-\pi$ NR |
| :---: |
| $\pi_{\text {NR }}=$ Number of Film Resistors in Use |
| NOTE: Do not include resistors that are not used. |


|  |  |  |
| :--- | :--- | :--- |
| SPECIFICATION | STYLE | DESCRIPTION |
| MIL-R-39005 | RBR | Fixed, Wirewound, Accurate, Established Reliability |
| MIL-R-93 | RB | Fixed, Wirewound, Accurate |

$$
\lambda_{p}=\lambda_{D} \pi_{R} \pi_{Q} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

| Base Faikre Rate - $\lambda_{D}$ |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $T_{A}\left({ }^{\circ} \mathrm{C}\right)$ | Stress |  |  |  |  |
|  | . 1 | . 3 | . 5 | . 7 | . 9 |
| , | . 0033 | . 0037 | . 0045 | . 0057 | . 0075 |
| 10 | . 0033 | . 0038 | . 0047 | . 0059 | . 0079 |
| 20 | . 0034 | . 0039 | . 0048 | . 0062 | . 0084 |
| 30 | . 0034 | . 0040 | . 0050 | . 0066 | . 0090 |
| 40 | . 0035 | . 0042 | . 0052 | . 0070 | . 0097 |
| 50 | . 0037 | . 0043 | . 0055 | . 0075 | . 011 |
| 60 | . 0038 | . 0046 | . 0059 | . 0081 | . 012 |
| 70 | . 0041 | . 0049 | . 0064 | . 0089 | . 013 |
| 80 | . 0044 | . 0053 | . 0070 | . 0099 | . 015 |
| 90 | . 0048 | . 0059 | . 0079 | . 011 | . 017 |
| 100 | . 0055 | . 0068 | . 0092 | . 013 | . 020 |
| 110 | . 0065 | . 0080 | . 011 | . 016 | . 025 |
| 120 | . 0079 | . 0099 | . 014 | . 021 | . 033 |
| 130 | . 010 | . 013 | . 018 | . 028 |  |
| 140 | . 014 |  |  |  |  |
| $\lambda_{b}=.0031 \exp \left(\frac{T+273}{398}\right)^{10} \exp \left(s\left(\frac{T+273}{273}\right)\right)^{1.5}$ |  |  |  |  |  |
|  |  |  |  |  |  |
| T - Ambient Temperature ( ${ }^{\circ} \mathrm{C}$ ) |  |  |  |  |  |
| $S=$ Ratio of Operating Power to Rated Power |  |  |  |  |  |

Resistance Factor $-\pi_{\mathrm{R}}$

| Resistance Range (ohms) | $\pi_{\mathrm{R}}$ |
| :--- | :--- |
| Up to 10 K | 1.0 |
| $>10 \mathrm{~K}$ to 100 K | 1.7 |
| $>100 \mathrm{~K} 101 \mathrm{M}$ | 3.0 |
| $>1 \mathrm{M}$ | 5.0 |


| Quality Factor $-\pi_{Q}$ |  |
| :---: | :---: |
| Quality | $\pi_{Q}$ |
| S | .030 |
| $R$ | .10 |
| $P$ | .30 |
| $M$ | 1.0 |
| MIL-R-93 | 5.0 |
| Lower | 15 |
| Environment $^{G_{B}}$ |  |
| $G_{F}$ | $\pi_{E}$ |
| $G_{M}$ | 1.0 |
| $N_{S}$ | 2.0 |
| $N_{U}$ | 11 |
| $A_{I C}$ | 5.0 |
| $A_{I F}$ | 18 |
| $A_{U C}$ | 15 |
| $A_{U F}$ | 18 |
| $A_{R W}$ | 28 |
| $S_{F}$ | 35 |
| $M_{F}$ | 27 |
| $M_{L}$ | 14 |
| $C_{L}$ | 38 |

## MIL-HDBK-217F

O.G RESISTORS, FIXED, WIREWOUND, POWER

| SPECIFICATION | STYLE | DESCRIPTION |
| :--- | :--- | :--- |
| MIL-R-39007 | RWR | Fixed, Wirewound, Power Type, Established Reliabilty |
| MIL-R-26 | RW | Fixed, Wirewound, Power Type |


| Base Failure Rate $-\lambda_{\mathrm{b}}$ |  |  |  |  |  |  |
| ---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $T_{A}\left({ }^{\circ} \mathrm{C}\right)$ | .1 | .3 | .5 | .7 | .9 |  |
| 0 | .0042 | .0062 | .0093 | .014 | .021 |  |
| 10 | .0045 | .0068 | .010 | .016 | .024 |  |
| 20 | .0048 | .0074 | .011 | .017 | .027 |  |
| 30 | .0052 | .0081 | .013 | .020 | .031 |  |
| 40 | .0056 | .0089 | .014 | .022 | .035 |  |
| 50 | .0061 | .0097 | .016 | .025 | .040 |  |
| 60 | .0066 | .011 | .017 | .028 |  |  |
| 70 | .0072 | .012 | .020 | .032 |  |  |
| 80 | .0078 | .013 | .022 | .037 |  |  |
| 90 | .0085 | .014 | .025 | .042 |  |  |
| 100 | .0093 | .016 | .028 | .048 |  |  |
| 110 | .010 | .019 | .031 | .055 |  |  |
| 120 | .011 | .020 | .036 | .063 |  |  |
| 130 | .012 | .022 | .040 |  |  |  |
| 140 | .014 | .025 | .046 |  |  |  |
| 150 | .015 | .028 | .052 |  |  |  |
| 160 | .017 | .032 | .060 |  |  |  |
| 170 | .019 | .036 | .068 |  |  |  |
| 180 | .021 | .040 | .078 |  |  |  |
| 190 | .023 | .046 |  |  |  |  |
| 200 | .026 | .052 |  |  |  |  |
| 210 | .029 | .059 |  |  |  |  |
| 220 | .033 | .066 |  |  |  |  |
| 230 | .037 | .077 |  |  |  |  |
| 240 | .042 | .088 |  |  |  |  |
| 250 | .047 | .10 |  |  |  |  |
| 260 | .054 |  |  |  |  |  |
| 270 | .061 |  |  |  |  |  |
| 280 | .06 |  |  |  |  |  |
| 290 | .079 |  |  |  |  |  |
| 300 | .091 |  |  |  |  |  |
| 310 | .10 |  |  |  |  |  |

$\left.\lambda_{\mathrm{b}}=00148 \exp \left(\frac{T+273}{298}\right)^{2} \exp \left(\frac{S}{.5}\right)\left(\frac{T+273}{273}\right)\right)$
$T=A m b i e n t$ Temperature $\left({ }^{\circ} \mathrm{C}\right)$
$\mathrm{S}=$ Ratio of Operating Power to Rated Power

NOTE: Do not use MIL-R-39007 Resistors below the line. Points below are overstressed.

MIL-HDBK-217F


## MIL-HDBK-217F

9.7 RESISTORS, FIXED, WIREWOUND, POWER, CHASSIS MOUNTED

## SPECIFICATION <br> M!L-R-39009

MIL-R-18546
style RER

RE

DESCRIPTION
Fixed, Wirewound, Power Type, Chassis Mounted, Established Reliability
Fixed, Wirewound, Power Type, Chassis Mounted

$$
\lambda_{P}=\lambda_{b} \pi_{R} \pi_{Q} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

| Base Failure Rate - $\lambda_{t}$ |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | Stress |  |  |  |  |
| $T_{A}\left({ }^{\circ} \mathrm{C}\right)$ | 1 | . 3 | . 5 | . 7 | . 9 |
| 0 | . 0021 | . 0032 | . 0049 | . 0076 | . 012 |
| 10 | . 0023 | . 0036 | . 0056 | . 0087 | . 014 |
| 20 | . 0025 | . 0040 | . 0064 | . 0100 | . 016 |
| 30 | . 0028 | . 0045 | . 0072 | . 012 | . 019 |
| 40 | . 0031 | . 0050 | . 0082 | . 013 | . 022 |
| 50 | . 0034 | . 0056 | . 0093 | . 016 | . 026 |
| 60 | 0037 | . 0063 | . 011 | . 016 |  |
| 70 | . 0041 | . 0070 | . 012 | . 021 |  |
| 80 | . 0045 | . 0079 | . 014 | . 024 |  |
| 90 | 0050 | . 0088 | 016 | . 028 |  |
| 100 | 0055 | 0098 | 018 | 032 |  |
| 110 | . 0060 | . 011 | . 020 |  |  |
| 120 | . 0066 | . 012 | . 023 |  |  |
| 130 | . 0073 | . 014 | . 026 |  |  |
| 140 | . 0081 | . 015 | . 030 |  |  |
| 150 | . 0089 | . 017 | . 034 |  |  |
| 160 | . 0098 | . 019 |  |  |  |
| 170 | . 011 | . 022 |  |  |  |
| 180 | . 012 | . 024 |  |  |  |
| 130 | . 013 | . 027 |  |  |  |
| 200 | . 014 | . 030 |  |  |  |
| 210 | . 016 |  |  |  |  |
| 220 | . 017 |  |  |  |  |
| 230 | . 019 |  |  |  |  |
| 240 | . 021 |  |  |  |  |
| 250 | . 023 |  |  |  |  |
| $\lambda_{b}=.00015 \exp \left(2.64\left(\frac{T+273}{298}\right)\right) \exp \left(\frac{S}{.466}\left(\frac{T+273}{273}\right)\right)$ |  |  |  |  |  |
| T | Ambie | Temper | ( $\left({ }^{\circ} \mathrm{C}\right)$ |  |  |
| S | Fatio | Operatio | Ower it | aied P |  |

Resistance Factor - $\pi_{R}$
(Characteristic G (Inductive Winding) of MIL-R-18546 and

| Siyto | Rated Power (W) | Resistance Range (ohms) |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{aligned} & U_{p} \\ & 10 \\ & 500 \end{aligned}$ | $\begin{aligned} & >500 \\ & 10 \\ & 1 K \end{aligned}$ | $\begin{aligned} & \hline 21 \mathrm{~K} \\ & 10 \\ & 5 \mathrm{~K} \end{aligned}$ | $\begin{gathered} 25 \mathrm{~K} \\ 10 \\ 10 \mathrm{~K} \end{gathered}$ | $\begin{aligned} & \mathbf{2 1 0 K} \\ & \text { 10 } \\ & 20 \mathrm{~K} \end{aligned}$ | 20K |
| RE 60 RER60 | 5 | 1.0 | 1.2 | 1.2 | 1.6 | NA | NA |
| RE 65 RER65 | 10 | 1.0 | 1.0 | 1.2 | 1.6 | NA | NA |
| $\begin{aligned} & \text { RE } 70 \\ & \text { RER70 } \end{aligned}$ | 20 | 1.0 | 1.0 | 1.2 | 1.2 | 1.6 | NA |
| $\text { RE } 75$ RER75 | 30 | 1.0 | 1.0 | 1.0 | 1.1 | 1.2 | 1.6 |
| RE 77 | 75 | 1.0 | 1.0 | 1.0 | 1.0 | 1.2 | 1.6 |
| RE 80 | 120 | 1.0 | 1.0 | 1.0 | 1.0 | 1.2 | 1.6 |

Resistance Factor - $\pi_{\mathrm{R}}$
(Characteristic N (Noninductive Winding) of MIL-R-18546 and Noninductively Wound Styles of MIL-R-39009)

| Siyte | Rated Power (w) | Resistance Range (ohms) |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\begin{aligned} & \mathrm{Up}_{\mathrm{p}} \\ & \text { to } \\ & 500 \end{aligned}$ | $\begin{aligned} & \mathbf{2 5 0 0} \\ & \text { to } \\ & \text { ik } \end{aligned}$ | $\begin{aligned} & \text { sk } \\ & \text { to } \\ & \text { SK } \end{aligned}$ | $\begin{array}{r} 350 \\ 10 \\ 100 \end{array}$ | $\begin{gathered} 210 \\ 10 \\ 20 \mathrm{~K} \end{gathered}$ | 20K |
| RE 60 RER40 | 5 | 1.0 | 1.2 | 1.6 | NA | NA | NA |
| RE 65 RER45 | 10 | 1.0 | 1.2 | 1.6 | NA | NA | NA |
| RE 70 RER50 | 20 | 1.0 | 1.0 | 1.2 | 1.6 | NA | NA |
| RE 75 RER55 | 30 | 1.0 | 1.0 | 1.1 | 1.2 | 1.4 | NA |
| RE 77 | 75 | 1.0 | 1.0 | 1.0 | 1.2 | 1.6 | NA |
| RE 80 | 120 | 1.0 | 1.0 | 1.0 | 1.1 | 1.4 | NA |



| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment $\pi_{E}$ <br> $G_{B}$ 1.0 <br> $G_{F}$ 2.0 <br> $G_{M}$ 10 <br> $N_{S}$ 5.0 <br> $N_{U}$ 16 <br> $A_{I C}$ 4.0 <br> $A_{I F}$ 8.0 <br> $A_{U C}$ 9.0 <br> $A_{U F}$ 18 <br> $A_{R W}$ 23 <br> $S_{F}$ .50 <br> $M_{F}$ 13 <br> $M_{L}$ 34 <br> $C_{L}$ 610 |  |

MIL-HDBK-217F

### 9.8 RESISTORS, THERMISTOR

SPECIFICATION
MII-T-23648

Style RTH

DESCRIPTION Thermally Sensitive Resistor, Insulated, Bead, Disk and Rod Types

$$
\lambda_{\mathrm{P}}=\lambda_{\mathrm{b}} \pi_{\mathrm{O}} \pi_{\mathrm{E}} \text { Failures } / 10^{6} \text { Hours }
$$

| Base Faikure Rate $-\lambda_{b}$ |  |
| :--- | :--- |
| Type | $\lambda_{b}$ |
| Bead <br> (Styles 24, 26, 28, 30, 32, <br> 34, 36, 38, 40) | .021 |
| Disk <br> (Styles 6, 8, 10) |  |
| Rod <br> (Styles 12, 14, 16, 18, <br> 20, 22, 42) | .065 |


| Quality Factor $-\pi_{\mathrm{Q}}$ |  |
| :---: | :---: |
| Quality | $\pi_{\mathrm{Q}}$ |
| MilL-SPEC | 1 |
| Lower | 15 |

### 9.9 RESISTORS, VARIABLE, WIREWOUND



| Base Faiure Rate $-\lambda_{D}$ |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $T_{A}\left({ }^{\circ} C\right)$ | .1 | .3 | .5 | .7 | .9 |
| 0 | .0089 | .011 | .013 | .016 | .020 |
| 10 | .0094 | .012 | .014 | .017 | .021 |
| 20 | .010 | .012 | .015 | .019 | .024 |
| 30 | .011 | .013 | .017 | .021 | .026 |
| 40 | .012 | .015 | .018 | .023 | .029 |
| 50 | .013 | .016 | .020 | .026 | .033 |
| 60 | .014 | .018 | .023 | .029 | .037 |
| 70 | .016 | .020 | .026 | .033 | .043 |
| 80 | .018 | .023 | .03 | .039 | .050 |
| 90 | .021 | .027 | .035 | .046 | .060 |
| 100 | .024 | .032 | .042 | .055 |  |
| 110 | .029 | .038 | .051 |  |  |
| 120 | .035 | .047 |  |  |  |
| 130 | .044 | .059 |  |  |  |
| 140 | .056 |  |  |  |  |

Resistance Factor $-\pi_{R}$

| Resistance Range (ohms) | $\pi_{\mathrm{R}}$ |
| :--- | :---: |
| 10 to 2 K | 1.0 |
| $>2 \mathrm{~K}$ to 5 K | 1.4 |
| $>5 \mathrm{~K}$ to 20 K | 2.0 |


| Voltage Factor - $\pi_{V}$ |  |  |
| :---: | :---: | :---: |
| $\frac{\text { Applied }}{\text { Rated }}$ | $\begin{aligned} & \text { Voltage* } \\ & \hline \text { Voltage } \end{aligned}$ | $\pi_{V}$ |
| 0 to 0.1 |  | 1.10 |
| $>0.1$ to 0.2 |  | 1.05 |
| $>0.2$ to 0.6 |  | 1.00 |
| $>0.6$ to 0.7 |  | 1.10 |
| $>0.7$ to 0.8 |  | 1.22 |
| $>0.8$ to 0.9 |  | 1.40 |
| $>0.9$ to 1.0 |  | 2.00 |
| $*^{\text {Applied }}$ | $=\sqrt{R P}$ |  |
|  | - Nomin Resist |  |
| $\mathrm{P}_{\text {Applied }}$ | = Power |  |
| $V_{\text {Rated }}$ | 40 Volts |  |
| $V_{\text {Rated }}$ | $\begin{aligned} & =90 \text { Votts } \\ & \text { and } 22 \end{aligned}$ | d 24; |

## MIL-HDBK-217F

9.9 RESISTORS, VARIABLE, WIREWOUND

| Quality Factor $-\pi_{Q}$ |  |
| :--- | :---: |
| Quality | $\pi_{\mathrm{Q}}$ |
| S | .020 |
| R | .060 |
| P | .20 |
| M | .60 |
| MIL-R-27208 | 3.0 |
| Lower | 10 |


| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\boldsymbol{\pi}_{\mathrm{E}}$ |
| $\mathrm{G}_{\mathrm{B}}$ | 1.0 |
| $\mathrm{G}_{\mathrm{F}}$ | 2.0 |
| $\mathrm{G}_{\mathrm{M}}$ | 12 |
| $\mathrm{~N}_{\mathrm{S}}$ | 6.0 |
| $\mathrm{~N}_{\mathrm{U}}$ | 20 |
| $\mathrm{~A}_{\mathrm{IC}}$ | 5.0 |
| $\mathrm{~A}_{\mathrm{IF}}$ | 8.0 |
| $\mathrm{~A}_{\mathrm{UC}}$ | 9.0 |
| $\mathrm{~A}_{\mathrm{UF}}$ | 15 |
| $\mathrm{~A}_{\mathrm{RW}}$ | 33 |
| $\mathrm{~S}_{\mathrm{F}}$ | .50 |
| $\mathrm{M}_{\mathrm{F}}$ | 18 |
| $M_{\mathrm{L}}$ | 48 |
| $\mathrm{C}_{\mathrm{L}}$ | 870 |



## MIL-HDBK-217F

9.10 RESISTORS, VARIABLE, WIREWOUND, PRECISION

| Vortage Factor - $\pi V$ |  |  |
| :---: | :---: | :---: |
| Applied Voltage* <br> Rated Voltage |  | $\pi V$ |
| 0 to 0.1 |  | 1.10 |
| $>0.1$ to 0.2 |  | 1.05 |
| $>0.2$ to 0.6 |  | 1.00 |
| $>0.6$ to 0.7 |  | 1.10 |
| $>0.7$ to 0.8 |  | 1.22 |
| $>0.8$ to 0.9 |  | 1.40 |
| $>0.9$ to 1.0 |  | 2.00 |
| $V_{\text {Applied }}=\sqrt{R_{P} P_{\text {Applied }}}$ |  |  |
|  | - Nomina <br> Resista |  |
| $P_{\text {Appliod }}$ | - Power Dissipation |  |
| $V_{\text {Rated }}$ | $=2$ | 1100. |
|  | RR1300, RR2000, RR3000, RR3100, RR3200, RR3300, RR3400, RR3500 |  |
| $V_{\text {Rated }}$ | = 423 Volts for RR3600, RR3700 |  |
| $V_{\text {Rated }}$ | - 500 Volts for RR1000. RR1400, <br> RR2100, RR3800. RR3900 |  |


| Quality Factor $-\pi_{\mathrm{Q}}$ |  |
| :---: | :---: |
| Quality | $\pi_{\mathrm{Q}}$ |
| MIL-SPEC | 2.5 |
| Lower | 5.0 |


| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment $\pi_{E}$ <br> $G_{B}$ 1.0 <br> $G_{F}$ 2.0 <br> $G_{M}$ 18 <br> $N_{S}$ 8.0 <br> $N_{U}$ 30 <br> $A_{I C}$ 8.0 <br> $A_{I F}$ 12 <br> $A_{U C}$ 13 <br> $A_{U F}$ 18 <br> $A_{R W}$ 53 <br> $S_{F}$ .50 <br> $M_{F}$ 29 <br> $M_{L}$ 76 <br> $C_{L}$ 1400 |  |

## MIL-HDBK-217F

### 9.11 RESISTORS, VARIABLE, WIREWOUND, SEMIPRECISION

## SPECIFICATION

MIL-R-19
MIL-R-39002

STYLE
RA
RK

DESCRIPTION
Variable, Wirewound, Semiprecision (Low Operating Temperature)
Variable, Wirewound, Semiprecision

$$
\lambda_{p}=\lambda_{b} \pi_{T A P S} \pi_{R} \pi_{V} \pi_{Q} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

| $T_{A}\left({ }^{\circ} C\right)$ | .1 | .3 | .5 | .7 | .9 |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 0 | .055 | .063 | .072 | .083 | .095 |
| 10 | .058 | .069 | .081 | .095 | .11 |
| 20 | .063 | .076 | .092 | .11 | .13 |
| 30 | .069 | .086 | .11 | .13 | .17 |
| 40 | .076 | .098 | .13 | .16 | .21 |
| 50 | .085 | .11 | .15 | .20 | .27 |
| 60 | .096 | .13 | .19 | .26 | .37 |
| 70 | .11 | .16 | .24 | .35 | .52 |
| 80 | .13 | .20 | .31 | .48 | .75 |
| 90 | .16 | .26 | .42 | .69 | 1.1 |
| 100 | .19 | .34 | .59 | 1.0 |  |
| 110 | .24 | .45 | .85 |  |  |
| 120 | .31 |  |  |  |  |
| 130 | .42 |  |  |  |  |

$$
\begin{aligned}
\lambda_{b}= & .0398 \exp \left(.514\left(\frac{T+273}{313}\right)^{5.28}\right) \times \\
& \exp \left(\frac{S}{1.44}\left(\frac{T+273}{273}\right)^{4.46}\right) \\
T= & \text { Ambient Temperature }\left({ }^{\circ} \mathrm{C}\right) \\
S= & \text { Ratio of Operating Power to Rated Power. } \\
& \text { See Section } 9.16 \text { for } S \text { Calculation. }
\end{aligned}
$$

NOTE: Do not use MIL-R-19 below the line. Points below are overstressed.

| $N_{\text {TAPS }}$ | ${ }^{\text {TAPS }}$ | $N_{\text {taps }}$ | ${ }^{\text {TAPS }}$ | ${ }^{\text {TAPS }}$ | ${ }^{\text {T TAPS }}$ |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 3 | 1.0 | 13 | 2.7 | 23 | 5.2 |
| 4 | 1.1 | 14 | 2.9 | 24 | 5.5 |
| 5 | 1.2 | 15 | 3.1 | 25 | 5.8 |
| 6 | 1.4 | 16 | 3.4 | 26 | 6.1 |
| 7 | 1.5 | 17 | 3.6 | 27 | 6.4 |
| 8 | 1.7 | 18 | 3.8 | 28 | 6.7 |
| 9 | 1.9 | 19 | 4.1 | 29 | 7.0 |
| 10 | 2.1 | 20 | 4.4 | 30 | 7.4 |
| 11 | 2.3 | 21 | 4.6 | 31 | 7.7 |
| 12 | 2.5 | 22 | 4.9 | 32 | 8.0 |
| $\frac{\left(N_{\text {TAPS }}\right)^{\frac{3}{2}}}{25}+0.792$ |  |  |  |  |  |
| $\mathrm{N}_{\text {TAP }}$ | Number of Potentiometer Taps, including the Wiper and Terminations. |  |  |  |  |



| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\pi_{E}$ |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 2.0 |
| $G_{M}$ | 16 |
| $N_{S}$ | 7.0 |
| $N_{U}$ | 28 |
| $A_{I C}$ | 8.0 |
| $A_{I F}$ | 12 |
| $A_{U C}$ | $N / A$ |
| $A_{U F}$ | $N / A$ |
| $A_{R W}$ | 38 |
| $S_{F}$ | .50 |
| $M_{F}$ | $N / A$ |
| $M_{L}$ | $N / A$ |
| $C_{L}$ | $N / A$ |


| Quality Factor $-\pi_{\mathrm{Q}}$ |  |
| :--- | :---: |
| Quality | $\pi_{\mathrm{Q}}$ |
| MIL-SPEC | 2.0 |
| Lower | 4.0 |

## MIL-HDBK-217F

9.12 RESISTORS, VARIABLE, WIREWOUND, POWER

SPECIFICATION
MIL-R-22

$$
\begin{array}{ll}
\text { STYLE } & \begin{array}{l}
\text { DESCRIPTION } \\
\text { VP }
\end{array} \\
\lambda_{p}=\lambda_{b} \pi_{T A P S} \pi_{R} \pi_{V} \pi_{C} \pi_{Q} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
\end{array}
$$

| Base Failure Rate - $\lambda_{B}$ |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{T}_{\mathrm{A}}\left({ }^{\circ} \mathrm{C}\right)$ | Stress |  |  |  |  |
|  | . 1 | . 3 |  | . 7 | . 9 |
| 0 | . 064 | . 074 | . 084 | . 097 | . 11 |
| 10 | . 067 | . 078 | . 091 | . 11 | . 12 |
| 20 | . 071 | . 084 | . 099 | . 12 | . 14 |
| 30 | . 076 | . 091 | . 11 | . 13 | . 16 |
| 40 | 081 | . 099 | . 12 | . 15 |  |
| 50 | . 087 | . 11 | . 14 | . 17 |  |
| 60 | . 095 | . 12 | . 15 |  |  |
| 70 | . 10 | . 14 | . 18 |  |  |
| 80 | . 12 | . 15 |  |  |  |
| 90 | . 13 | . 18 |  |  |  |
| 100 | . 15 |  |  |  |  |
| 110 | . 17 |  |  |  |  |
| 120 | . 20 |  |  |  |  |
| $\begin{aligned} & \lambda_{\mathrm{b}}= .0481 \exp \left(.334\left(\frac{T+273}{298}\right)^{4.66}\right) \times \\ & \exp \left(\frac{\mathrm{S}}{1.47}\left(\frac{\mathrm{~T}+273}{273}\right)^{2.83}\right) \\ & T= \text { Ambient Temperature ( }{ }^{\circ} \mathrm{C} \text { ) } \\ & \mathrm{S}= \text { Ratio of Operating Power to Rated Power. } \\ & \text { See Section } 9.16 \text { for } S \text { Calculation. } \end{aligned}$ |  |  |  |  |  |
|  |  |  |  |  |  |
|  |  |  |  |  |  |
|  |  |  |  |  |  |


| Resistance Factor $-\pi_{R}$ |  |
| :--- | :---: |
| Resistance Range (ohms) $\pi_{R}$ <br> 1 to 2 K 1.0 <br> $>2 \mathrm{~K}$ to 5 K 1.4 <br> $>5 \mathrm{~K}$ to 10 K 2.0 |  |


| Potentiometer Taps Factor $-\pi_{\text {TAPS }}$ |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{N}_{\text {TAPS }}$ | ${ }_{\text {TAPS }}$ | $N_{\text {TAPS }}$ | ${ }^{\mathrm{T} \text { TAPS }}$ | $\mathrm{N}_{\text {TAPS }}$ | ${ }^{\text {T }}$ TAPS |
| 3 | 1.0 | 13 | 2.7 | 23 | 5.2 |
| 4 | 1.1 | 14 | 2.9 | 24 | 5.5 |
| 5 | 1.2 | 15 | 3.1 | 25 | 5.8 |
| 6 | 1.4 | 16 | 3.4 | 26 | 6.1 |
| 7 | 1.5 | 17 | 3.6 | 27 | 6.4 |
| 8 | 1.7 | 18 | 3.8 | 28 | 6.7 |
| 9 | 1.9 | 19 | 4.1 | 29 | 7.0 |
| 10 | 2.1 | 20 | 4.4 | 30 | 7.4 |
| 11 | 2.3 | 21 | 4.6 | 31 | 7.7 |
| 12 | 2.5 | 22 | 4.9 | 32 | 8.0 |
| $\pi_{\text {TAPS }}=\frac{\left(N_{\text {TAPS }}\right)^{\frac{3}{2}}}{25}+0.792$ |  |  |  |  |  |
|  |  |  |  |  |  |
| $\mathrm{N}_{\text {TAPS }}$ |  | Number of Potentiometer Taps, including the Wiper and Terminations |  |  |  |

## MIL-HDBK-217F

9.12 RESISTORS, VARIABLE, WIREWOUND, POWER

| Vohtage Factor - $\pi$, |  |
| :---: | :---: |
| Applied Voltago* Rated Voltage | $\pi_{V}$ |
| 0 to 0.1 | 1.10 |
| >0.1 to 0.2 | 1.05 |
| $>0.2$ to 0.6 | 1.00 |
| $>0.6$ to 0.7 | 1.10 |
| $>0.7$ to 0.8 | 1.22 |
| >0.8 to 0.9 | 1.40 |
| $>0.9$ to 1.0 | 2.00 |
| $\nabla^{\text {Applied }}$ $=\sqrt{R_{P} P_{\text {Applied }}}$ |  |
| $\begin{aligned} R_{P} \quad=\quad & \begin{array}{l}\text { Nominal Total Potentiometer } \\ \\ \text { Resistance }\end{array}\end{aligned}$ |  |
| $\mathrm{P}_{\text {Applied }}=$ Power Dissipation |  |
| $V_{\text {Rated }}=250$ Volts for RP06, RP10 |  |
| $=500$ Votts for Others |  |


| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment $\pi_{E}$ <br> $G_{B}$ 1.0 <br> $G_{F}$ 3.0 <br> $G_{M}$ 16 <br> $N_{S}$ 7.0 <br> $N_{U}$ 28 <br> $A_{I C}$ 8.0 <br> $A_{I F}$ 12 <br> $A_{U C}$ $N / A$ <br> $A_{U F}$ $N / A$ <br> $A_{R W}$ 38 <br> $S_{F}$ .50 <br> $M_{F}$ N/A <br> $M_{L}$ $N / A$ <br> $C_{L}$ $N / A$ |  |

Construction Class Factor $-\pi_{\mathrm{C}}$

| Construction <br> Class | Style | $\pi_{\mathrm{C}}$ |
| :--- | :--- | :---: |
| Enclosed | RP07, RP11, RP16 | 2.0 |
| Unenclosed | All Other Styles are <br> Unenclosed | 1.0 |


$\lambda_{b}=.019 \exp \left(.445\left(\frac{T+273}{358}\right)^{7.3}\right) x$ $\exp \left(\frac{S}{2.69}\left(\frac{T+273}{273}\right)^{2.46}\right)$
$\mathrm{T}=$ Ambient Temperature $\left({ }^{\circ} \mathrm{C}\right)$
$S=$ Ratio of Operating Power to Rated Power. See Section 9.16 for $S$ Calculation.

DESCRIPTION
Variable, Nonwirewound (Adjustment Types)
Variable, Nonwirewound (Adjustment Types),
Established Reliability
Failures $/ 10^{6}$ Hours

Potentiometer Taps Factor $-\pi_{\text {TAPS }}$

| ${ }^{\text {TAPS }}$ | ${ }^{\text {T TAPS }}$ | ${ }^{\text {N TAPS }}$ | ${ }^{\pi}$ TAPS | ${ }^{\text {T TAPS }}$ | ${ }^{\text {T TAPS }}$ |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 3 | 1.0 | 13 | 2.7 | 23 | 5.2 |
| 4 | 1.1 | 14 | 2.9 | 24 | 5.5 |
| 5 | 1.2 | 15 | 3.1 | 25 | 5.8 |
| 6 | 1.4 | 16 | 3.4 | 26 | 6.1 |
| 7 | 1.5 | 17 | 3.6 | 27 | 6.4 |
| 8 | 1.7 | 18 | 3.8 | 28 | 6.7 |
| 9 | 1.9 | 19 | 4.1 | 29 | 7.0 |
| 10 | 2.1 | 20 | 4.4 | 30 | 7.4 |
| 11 | 2.3 | 21 | 4.6 | 31 | 7.7 |
| 12 | 2.5 | 22 | 4.9 | 32 | 8.0 |
| $\pi_{\text {TAPS }}=\frac{\left(\mathrm{N}_{\text {TAPS }}\right)}{25}+0.792$ |  |  |  |  |  |
| $\begin{aligned} N_{\text {TAPS }}= & \text { Number of Potentiometer Taps. } \\ & \text { including the Wiper and Terminations. } \end{aligned}$ |  |  |  |  |  |


Environment Factor $-\pi_{E}$

| Environment | $\pi_{E}$ |
| :---: | :---: |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 3.0 |
| $G_{M}$ | 14 |
| $N_{S}$ | 6.0 |
| $N_{U}$ | 24 |
| $A_{I C}$ | 5.0 |
| $A_{I F}$ | 7.0 |
| $A_{U C}$ | 12 |
| $A_{U F}$ | 18 |
| $A_{R W}$ | 39 |
| $S_{F}$ | .50 |
| $M_{F}$ | 22 |
| $M_{L}$ | 57 |
| $C_{L}$ | 1000 |


| Quality Factor $-\pi_{\mathrm{Q}}$ |
| :--- |
| Quality $\pi_{\mathrm{Q}}$ <br> S .020 <br> R .060 <br> P .20 <br> M .60 <br> MIL-R-22097 3.0 <br> Lower 10 |

### 9.14 RESISTORS, VARIABLE, COMPOSITION

| SPECIFICATION | STYLE | DESCRIPTION |
| :--- | :--- | :--- |
| MIL-R-94 | RV | Variable, Composition, Low Precision |
|  | $\lambda_{p}=\lambda_{b} \pi_{\text {TAPS }} \pi_{R} \pi_{V} \pi_{Q} \pi_{E}$ Failures $/ 10^{6}$ Hours |  |


| Base Faiture Rate - $\lambda_{t}$ |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | Stress |  |  |  |  |
| $T_{A}\left({ }^{\circ} \mathrm{C}\right)$ | . 1 | . 3 | . 5 | . 7 | . 9 |
| 0 | . 027 | . 030 | . 032 | . 035 | . 038 |
| 10 | . 028 | . 031 | . 034 | . 038 | . 042 |
| 20 | . 029 | . 033 | . 037 | . 042 | . 048 |
| 30 | . 031 | . 036 | . 041 | . 048 | . 056 |
| 40 | . 033 | . 039 | . 047 | . 056 | . 067 |
| 50 | . 036 | . 044 | . 054 | . 067 | . 082 |
| 60 | . 039 | . 050 | . 065 | 083 | . 11 |
| 70 | . 045 | . 060 | . 08 | . 11 | . 14 |
| 80 | . 053 | . 074 | . 10 | . 15 |  |
| 90 | . 065 | . 096 | . 14 |  |  |
| 100 | . 084 | . 13 |  |  |  |
| 110 | . 11 |  |  |  |  |
| $\begin{aligned} \lambda_{b}= & .0246 \exp \left(.459\left(\frac{T+273}{343}\right)^{9.3}\right) x \\ & \exp \left(\frac{S}{2.32}\left(\frac{T+273}{273}\right)^{5.3}\right) \\ T= & \text { Ambient Temperature ( } \left.{ }^{\circ} \mathrm{C}\right) \\ S= & \begin{array}{l} \text { Ratio of Operating Power to Rated Power. } \\ \text { See Section } 9.16 \text { for S Calculation. } \end{array} \end{aligned}$ |  |  |  |  |  |
|  |  |  |  |  |  |
|  |  |  |  |  |  |
|  |  |  |  |  |  |


| Resistance Factor $-\pi_{R}$ |  |
| :--- | :---: |
| Resistance Range (ohms) | $\pi_{R}$ |
| 50 to 50 K | 1.0 |
| $>50 \mathrm{~K}$ to 100 K | 1.1 |
| $>100 \mathrm{~K}$ to 200 K | 1.2 |
| $>200 \mathrm{~K}$ to 500 K | 1.4 |
| $>500 \mathrm{~K}$ to 1 M | 1.8 |


| Potentiometer Taps Factor - $\pi_{\text {TAPS }}$ |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| ${ }^{\mathrm{N}}$ TAPS | ${ }^{\text {TAPS }}$ | ${ }^{\text {TAPS }}$ | ${ }^{\text {T TAPS }}$ | ${ }^{\text {TAPS }}$ | ${ }^{\text {T TAPS }}$ |
| 3 | 1.0 | 13 | 2.7 | 23 | 5.2 |
| 4 | 1.1 | 14 | 2.9 | 24 | 5.5 |
| 5 | 1.2 | 15 | 3.1 | 25 | 5.8 |
| 6 | 1.4 | 16 | 3.4 | 26 | 6.1 |
| 7 | 1.5 | 17 | 3.6 | 27 | 6.4 |
| 8 | 1.7 | 18 | 3.8 | 28 | 6.7 |
| 9 | 1.9 | 19 | 4.1 | 29 | 7.0 |
| 10 | 2.1 | 20 | 4.4 | 30 | 7.4 |
| 11 | 2.3 | 21 | 4.6 | 31 | 7.7 |
| 12 | 2.5 | 22 | 4.9 | 32 | 8.0 |
| $\begin{aligned} & \pi_{\text {TAPS }}=\frac{\left(N_{\text {TAPS }}\right)^{\frac{3}{2}}}{25}+0.792 \\ & N_{\text {TAPS }}=\begin{array}{l} \text { Number of Potentiometer Taps, } \\ \text { including the Wiper and Terminations. } \end{array} \end{aligned}$ |  |  |  |  |  |
|  |  |  |  |  |  |

## MIL-HDBK-217F



| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment $\pi_{E}$ <br> $G_{B}$ 1.0 <br> $G_{F}$ 2.0 <br> $G_{M}$ 19 <br> $N_{S}$ 8.0 <br> $N_{U}$ 29 <br> $A_{I C}$ 40 <br> $A_{i F}$ 65 <br> $A_{U C}$ 48 <br> $A_{U F}$ 78 <br> $A_{R W}$ 46 <br> $S_{F}$ .50 <br> $M_{F}$ 25 <br> $M_{L}$ 66 <br> $C_{L}$ 1200 |  |


| Quality Factor $-\pi_{\mathrm{Q}}$ |  |
| :--- | :---: |
| Quality | $\pi_{\mathrm{Q}}$ |
| MIL-SPEC | 2.5 |
| Lower | 5.0 |


|  |  |  |
| :--- | :--- | :--- |
| SPECIFICATION | STYLE | DESCRIPTION |
| MIL-R-39023 | RQ | Variable, Nonwirewound, Film, Precision |
| MIL-R-23285 | RVC |  |
|  |  |  |
|  | $\lambda_{p}=\lambda_{b} \pi_{\text {TAPS }} \pi_{R} \pi^{2} \pi_{Q} \pi_{E}$ Failures $/ 10^{6}$ Hours |  |


| Base Failure Rate $-\lambda_{D}$ (RQ Style Only) |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Stress |  |  |  |  |  |
| $\left.T_{A}{ }^{(0}{ }^{\circ}\right)$ | . 1 | . 3 | . 5 | . 7 | . 9 |
| 0 | . 023 | . 024 | . 026 | . 028 | . 031 |
| 10 | . 024 | . 026 | . 029 | . 031 | . 034 |
| 20 | . 026 | . 029 | . 032 | . 035 | . 039 |
| 30 | . 028 | . 032 | . 036 | . 040 | . 045 |
| 40 | . 032 | . 036 | . 041 | . 047 | . 053 |
| 50 | . 037 | . 042 | . 049 | . 057 | . 065 |
| 60 | . 044 | . 051 | . 060 | . 070 | . 083 |
| 70 | . 053 | . 064 | . 076 | . 091 | . 11 |
| 80 | . 068 | . 083 | . 10 | . 12 |  |
| 90 | . 092 | . 11 | . 14 |  |  |
| 100 | . 13 | . 17 |  |  |  |
| 110 | . 20 |  |  |  |  |
| $\begin{aligned} \lambda_{\mathrm{b}} & =.018 \exp \left(\frac{T+273}{343}\right)^{7.4} \mathrm{x} \\ & \exp \left(\left(\frac{\mathrm{~S}}{2.55}\right)\left(\frac{\mathrm{T}+273}{273}\right)^{3.6}\right) \end{aligned}$ |  |  |  |  |  |
|  |  |  |  |  |  |
| $T=$ Ambient Temperature ( ${ }^{\circ} \mathrm{C}$ ) |  |  |  |  |  |
|  | - Ratio of Operating Power to Rated Power. See Section 9.16 for $S$ Calculation. |  |  |  |  |


| Resistance Factor - $\pi_{R}$ |  |
| :--- | :--- |
| Resistance Range (Ohms) | $\pi_{R}$ |
| Up to 10 K | 1.0 |
| $>10 \mathrm{~K}$ to 50 K | 1.1 |
| $>50 \mathrm{~K}$ to 200 K | 1.2 |
| $>200 \mathrm{~K} 101 \mathrm{M}$ | 1.4 |
| $>1 \mathrm{M}$ | 1.8 |


| Base Failure Rate - $\lambda_{D}$ (RVC Style Only) |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | Stress |  |  |  |  |
| $T_{\hat{A}}\left({ }^{(0}\right)$ | . 1 | . 3 | 5 | . 7 | 9 |
| 0 | . 028 | . 031 | . 033 | . 036 | . 039 |
| 10 | . 029 | . 032 | . 035 | . 038 | . 042 |
| 20 | . 030 | . 033 | . 037 | . 041 | . 046 |
| 30 | . 031 | . 035 | . 040 | . 045 | . 051 |
| 40 | . 032 | . 037 | . 043 | . 050 | . 058 |
| 50 | . 034 | . 040 | . 047 | . 056 | . 066 |
| 60 | . 036 | . 044 | . 053 | . 064 | . 078 |
| 70 | . 039 | . 049 | . 060 | . 075 | . 093 |
| 80 | . 043 | . 055 | . 070 | . 09 | . 11 |
| 90 | . 048 | . 063 | . 083 | . 11 | . 15 |
| 100 | . 055 | . 075 | . 10 | . 14 | . 19 |
| 110 | . 064 | . 091 | . 13 | . 18 | . 26 |
| 120 | . 077 | . 11 | . 17 | . 25 | . 37 |
| 130 | . 096 | . 15 | . 23 | . 36 | . 55 |
| 140 | . 12 | . 20 | . 33 | . 53 |  |
| 150 | . 17 | . 29 | . 50 |  |  |
| 160 | . 24 | . 44 |  |  |  |
| 170 | . 37 |  |  |  |  |
| $\begin{aligned} \lambda_{b}= & .0257 \exp \left(\frac{T+273}{398}\right)^{7.9} \times \\ & \exp \left(\left(\frac{S}{2.45}\right)\left(\frac{T+273}{273}\right)^{4.3}\right) \end{aligned}$ |  |  |  |  |  |
|  |  |  |  |  |  |
| T $=$ Ambient Temperature ( ${ }^{\circ} \mathrm{C}$ ) |  |  |  |  |  |
|  | Ratio of Operating Power to Rated Power. See Section 9.16 for $S$ Calculation. |  |  |  |  |

MIL-HDBK-217F

| Potentiometer Taps Factor - $\pi_{\text {TAPS }}$ |  |  |  |  |  | Quality Factor $\pi_{Q}$ |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{N}_{\text {TAPS }}$ | ${ }_{\text {Taps }}$ | $N_{\text {TAPS }}$ | ${ }_{\text {TAPS }}$ | $N_{\text {taps }}$ | ${ }_{\text {TAPS }}$ | Quality | $\pi_{\mathrm{Q}}$ |
| 3 | 1.0 | 13 | 2.7 | 23 | 5.2 | MIL-SPEC | 2 |
| 4 | 1.1 | 14 | 2.9 | 24 | 5.5 | Lower | 4 |
| 5 | 1.2 | 15 | 3.1 | 25 | 5.8 |  |  |
| 6 | 1.4 | 16 | 3.4 | 26 | 6.1 | Environment Factor - $\pi_{E}$ |  |
| 7 | 1.5 | 17 | 3.6 | 27 | 6.4 |  |  |
| 8 | 1.7 | 18 | 3.8 | 28 | 6.7 |  | ${ }^{\text {n }}$ E |
|  |  |  |  |  |  | $\mathrm{G}_{\mathrm{B}}$ | 1.0 |
| 9 | 1.9 | 19 | 4.1 | 29 | 7.0 | $\mathrm{G}_{\mathrm{F}}$ | 3.0 |
| 10 | 2.1 | 20 | 4.4 | 30 | 7.4 | $G_{M}$ | 14 |
| 11 | 2.3 | 21 | 4.6 | 31 | 7.7 | $\mathrm{N}_{S}$ | 7.0 |
| 12 | 2.5 | 22 | 4.9 | 32 | 8.0 | $\mathrm{N}_{\mathrm{u}}$ | 24 |
| $\begin{aligned} & \pi_{\text {TAPS }}=\frac{\left(N_{\text {TAPS }}\right)^{\frac{3}{2}}}{25}+0.792 \\ & N_{\text {TAPS }}=\begin{array}{l} \text { Number of Potentiometer Taps, } \\ \text { including the Wiper and Terminations. } \end{array} \end{aligned}$ |  |  |  |  |  | $A_{1 C}$ | 6.0 |
|  |  |  |  |  |  | AIF | 12 |
|  |  |  |  |  |  | ${ }^{\text {A }}$ UC | 20 |
|  |  |  |  |  |  | A UF | 30 |
|  |  |  |  |  |  | $A_{\text {RW }}$ | 39 |
| Vottage Factor - $\pi$, |  |  |  |  |  | $S_{F}$ | . 50 |
|  |  |  |  |  |  | $M_{F}$ | 22 |
| $\frac{\text { Applied Voltage }}{\text { Rated Voltage }}$ |  |  |  | $\pi \mathrm{V}$ |  | $\mathrm{M}_{\mathrm{L}}$ | 57 |
| 0.00 |  |  |  |  |  |  | 1000 |


| $\cdot V_{\text {Appliod }}$ | $=\sqrt{R_{P} P_{\text {Applied }}}$ |
| ---: | :--- |
| $R_{P}$ | $=$Nominal Total Potentiometer <br>  <br> Resistance |
| $P_{\text {Applied }}=$ | Power Dissipation |
| $V_{\text {Rated }}=$ | 250 Volts for RQ090, 110, 150, 200, |
|  | 300 |
| $=$ | 500 Volts for RQ100, 160. 210 |
| $=$ | 350 Vots for RVC5, 6 |

Stress Ratio (S) Calculation for Rheostats


Stress Ratio (S) Calculation for Potentiometers Connected Conventionally

$P_{\text {Applied }}=$ Equivalent powor input to the potentiometer when in is not loaded (i.e., wiper lead disconnected). Calculate as follows:
$P_{\text {Applied }}=\frac{v_{i n}{ }^{2}}{R_{p}}$
$v_{\text {in }}=$ Input Voltage
$\mathrm{f}_{\mathrm{P}}=$ Nominal Totâl Potentiometer Resistance

PRATED $=$ Power Rating of Potentiometer
$\pi_{\text {GANGED }}=$ Factor to correct for the reduction in effective rating of the potentiometer due te the close proximity of two or more potentiometers when they are ganged togather on a common shatt. Soo below.

KEff

- Correction factor for the electrical loading effiect on the wiper confact of the potentiometer. He value is a function of the type of potentiometer, its resistance. and the hoad resistance. Ses next page.

Ganged-Potentiometer Factor - $\pi_{\text {GANGED }}$

| Number of Sections | First Potentiometer Next to Mount | Second in Gang | Third in Gang | Fourth in Gang | Fith in Gang | Sixth in Gang |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Singlo | 1.0 | Alot Applicable |  |  |  |  |
| Two | 0.75 | 0.60 | Not Applicable |  |  |  |
| Three | 0.75 | 0.50 | 0.60 | Not Applicable |  |  |
| Four | 0.75 | 0.50 | 0.50 | 0.60 | Not | Applicablo |
| Five | 0.75 | 0.50 | 0.40 | 0.50 | 0.60 | Aot Ápolicáblo |
| Six | 0.75 | 0.50 | 0.40 | 0.40 | 0.50 | 0.60 |


|  | $\mathrm{K}_{\mathrm{H}}$ |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
| $\mathrm{R}_{\text {L }} / R_{P}$ | 0.2 | 0.3 | 0.5 | 1.0 |
| 0.1 | . 04 | . 03 | . 02 | . 01 |
| 0.2 | . 13 | . 09 | . 05 | . 03 |
| 0.3 | . 22 | . 16 | . 10 | . 05 |
| 0.4 | . 31 | . 23 | . 15 | . 08 |
| 0.5 | . 38 | . 29 | . 20 | . 11 |
| 0.8 | . 45 | . 35 | . 25 | . 14 |
| 0.7 | . 51 | . 40 | . 29 | . 17 |
| 0.8 | . 55 | . 45 | . 33 | . 20 |
| 0.9 | . 59 | . 49 | . 37 | . 22 |
| 1.0 | . 63 | . 53 | . 40 | . 25 |
| 1.5 | . 74 | . 65 | . 53 | . 36 |
| 2.0 | . 80 | . 73 | . 62 | . 44 |
| 3.0 | . 87 | . 81 | . 72 | . 56 |
| 4.0 | . 90 | . 86 | . 78 | . 64 |
| 5.0 | . 92 | . 88 | . 82 | . 69 |
| 10.0 | . 96 | . 94 | . 90 | . 83 |
| 100.0 | 1.00 | . 99 | . 99 | . 98 |
|  |  |  |  |  |
| $\pi_{\text {EFF }}$ |  |  |  |  |
|  |  |  |  | variable he total |
|  |  | $\begin{aligned} & \operatorname{tance} \\ & \text { one er } \end{aligned}$ | $\begin{aligned} & \text { een th } \\ & \text { the po } \end{aligned}$ | per arm ometer |
| $R_{p}$ | - | Nominal Total Potentiometer |  |  |
|  |  | istanc |  |  |
| $K_{H}$ | - | Cons | See | Table. |


| Potentiometer MK-SPEC | Style Type | $\mathrm{K}_{\mathrm{H}}$ |
| :---: | :---: | :---: |
| MIL-R-19 | RA | 0.5 |
| MIL-R-22 | RP | 1.0 |
| Mr-R-94 | RV | 0.5 |
| MIL-R-12934 | RR1000, 1001, | 0.3 |
|  | 1003. 1400, |  |
|  | 2100, 2101, |  |
|  | 2102, 2103 |  |
| MIL-R-12934 | All Oher Types | 0.2 |
| MIL-R-22097 | Rل111, RJ12 | 0.3 |
| MIL-R-22097 | All Other Types | 0.2 |
| MIL-R-23285 | RVC | 0.5 |
| MIL-R-27208 | RT22, 24, 26, 27 | 0.2 |
| MHL-R-27208 | AH Other Types | 0.3 |
| MIL-R-39002 | RK | 0.5 |
| MIL-R-39015 | RTR 22, 24 | 0.2 |
| MIL-R-39015 | RTR12 | 0.3 |
| MIL-R-39023 | RO | 0.3 |
| MIL-R-39035 | RJR | 0.3 |

## MIL-HDBK-217F

## Example

Given: Type RV1SAYSA505A variable 500K ohm resistor procured per MIL-R-94, rated at 0.2 watts is being used in a fixed ground environment. The resistor ambient temperature is $40^{\circ} \mathrm{C}$ and is dissipating 0.06 watts. The resistance connected to the wiper contact varies between 1 megohm and 3 megohms. The potentiometer is connected conventionally without ganging.

The appropriate model for RV style variable resistors is given in Section 9.14. Based on the given information the following model factors are determined from the tables shown in Section 9.14 and by following the procedure for determining electrical stress for potentiometers as described in Section 9.16.

From Section 9.16
P $_{\text {APPLIED }}=.06 \mathrm{~W}$
$\pi_{\text {EFF }}=.62$
$\pi_{\text {GANGED }}=1.0$
$\pi_{\text {RATED }}=.2 \mathrm{~W}$
$\mathrm{K}_{\mathrm{H}}=.5$ for MIL-R-94 (Section 9.16 Table)
Not Ganged (Section 9.16 Table, Single Section, First Potentiometer)
$\pi_{\text {RATED }}=.2 \mathrm{~W}$
$\mathrm{S}=\frac{\text { PaPPLIED }}{\pi_{\text {EFF }} \times \pi_{\text {GANGED }} \times \pi_{\text {RATED }}}=\frac{.06}{(.62)(1.0)(.2)}=.48$

From Section 9.14

| $\lambda_{b}$ | $=$ | .047 |
| :--- | :--- | :--- |
| $\pi_{R}$ | $=$ | 1.4 |
| $\pi_{\text {TAPS }}$ | $=1.0$ |  |
| $\pi_{V}$ | $=1.0$ |  |

$T_{A}=40^{\circ} \mathrm{C}$, $S$ Rounded to .5
500 K ohms
3 Taps, Basic Single Potentiometer
$V_{\text {RATED }}=250$ Volts for RV1 prefix
$V_{\text {APPLIED }}=\sqrt{(500,000)(.06)}=173$ volts
$V_{\text {APPLIED }} N_{\text {RATED }}=\frac{173}{250}=.69$

| $\pi_{Q}$ | $=2.5$ |
| :--- | :--- |
| $\pi_{E}$ | $=2.0$ |

$\lambda_{\mathrm{P}} \quad=\quad \lambda_{\mathrm{B}} \pi_{\mathrm{TAPS}} \pi_{R} \pi_{V} \pi_{\mathrm{Q}} \pi_{E}$
$=(.047)(1.0)(1.4)(1.0)(2.5)(2.0)=.33$ Failures $/ 10^{6}$ Hours

## SPECIFICATION

MIL-C-25
MIL-C-12889

## STYLE

CP
CA

DESCRIPTION
Paper, By-pass, Filter, Blocking, DC
Paper, By-pass, Radio Interference Reduction AC and DC

$$
\lambda_{\mathrm{P}}=\lambda_{\mathrm{b}} \pi_{C V^{\pi} Q} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

Base Failure Rate $-\lambda_{b}$
$\left(T=85^{\circ} \mathrm{C}\right.$ Max Rated )
(All MIL-C-12889; MIL-C-25 Styles CP25, 26, 27, 28, 29. $40,41,67,69,70,72,75,76,77,78,80,81,82$;

Characteristics E, F)

| $T_{A}\left({ }^{\circ} \mathrm{C}\right)$ | .1 | .3 | .5 | .7 | .9 |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 0 | .00088 | .0011 | .0036 | .015 | .051 |
| 10 | .00089 | .0011 | .0036 | .016 | .052 |
| 20 | .00092 | .0011 | .0037 | .016 | .054 |
| 30 | .00097 | .0012 | .0039 | .017 | .057 |
| 40 | .0011 | .0013 | .0044 | .019 | .063 |
| 50 | .0013 | .0016 | .0052 | .022 | .075 |
| 60 | .0017 | .0021 | .0069 | .030 | .10 |
| 70 | .0027 | .0034 | .011 | .048 | .16 |
| 80 | .0060 | .0074 | .024 | .10 | .35 |

$\lambda_{b}=.00086\left[\left(\frac{S}{.4}\right)^{5}+1\right] \exp \left(2.5\left(\frac{T+273}{358}\right)^{18}\right)$
$T=$ Ambient Temperature $\left({ }^{\circ} \mathrm{C}\right)$
$S=$ Ratio of Operating to Rated Voltage
Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage.

Base Failure Rate $-\lambda_{D}$
( $\mathrm{T}=125^{\circ} \mathrm{C}$ Max Rated)
(MIL-C-25 Styies CP 4. 5, 8, 9, 10, 11, 12 13;
Characteristic K)

| $\mathrm{T}_{\mathrm{A}}\left({ }^{\circ} \mathrm{C}\right)$ | .1 | .3 | .5 | .7 | .9 |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 0 | .00086 | .0011 | .0035 | .015 | .051 |
| 10 | .00087 | .0011 | .0035 | .015 | .051 |
| 20 | .00087 | .0011 | .0035 | .015 | .051 |
| 30 | .00088 | .0011 | .0035 | .015 | .051 |
| 40 | .00089 | .0011 | .0036 | .015 | .052 |
| 50 | .00091 | .0011 | .0037 | .016 | .053 |
| 60 | .00095 | .0012 | .0039 | .017 | .056 |
| 70 | .0010 | .0013 | .0041 | .018 | .060 |
| 80 | .0011 | .0014 | .0046 | .020 | .067 |
| 90 | .0014 | .0017 | .0056 | .024 | .081 |
| 100 | .0019 | .0023 | .0076 | .033 | .11 |
| 110 | .0030 | .0037 | .012 | .052 | .18 |
| 120 | .0063 | .0078 | .026 | .11 | .37 |

$\lambda_{b}=.00086\left[\left(\frac{S}{4}\right)^{5}+1\right] \exp \left(2.5\left(\frac{T+273}{398}\right)^{18}\right)$
$T=$ Ambient Temperature ( ${ }^{\circ} \mathrm{C}$ )
S - Ratio of Operating to Rated Voltage
Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage.

## MIL-HDBK-217F

10.1 CAPACITORS, FIXED, PAPER, BY-PASS

| Capacitance Factor $-\pi_{\mathrm{CV}}$ |  |
| :--- | :--- |
| Capacitance, $\mathrm{C}(\mu \mathrm{F})$ | $\pi_{\mathrm{CV}}$ |
| MIL-C-25 |  |
| .0034 | 0.7 |
| .15 | 1.0 |
| 2.3 | 1.3 |
| 16. | 1.6 |
| MIL-C-12889 | 1.0 |
| All |  |
|  |  |


| Quality Factor $-\pi_{\mathrm{Q}}$ |  |
| :--- | :---: |
| Quality | $\pi_{\mathrm{Q}}$ |
| MIL-SPEC | 3.0 |
| Lower | 7.0 |


| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment $\pi_{E}$ <br> $G_{B}$ 1.0 <br> $G_{F}$ 2.0 <br> $G_{M}$ 9.0 <br> $N_{S}$ 5.0 <br> $N_{U}$ 15 <br> $A_{I C}$ 6.0 <br> $A_{i F}$ 8.0 <br> $A_{U C}$ 17 <br> $A_{U F}$ 32 <br> $A_{R W}$ 22 <br> $S_{F}$ .50 <br> $M_{F}$ 12 <br> $M_{L}$ 32 <br> $C_{L}$ 570 |  |

10.2 CAPACITORS, FIXED, PAPER, FEED-THROUGH

| SPECIFICATION MIL-C-11693 |  |  | STYLE <br> CZR and CZ |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  |  |
| $\begin{gathered} \text { Base Failure Rate }-\lambda_{\mathrm{b}} \\ \left(T=85^{\circ} \mathrm{C}\right. \text { Max Rated) } \\ (\text { Characteristics } \mathrm{E}, \mathrm{~W}) \end{gathered}$ |  |  |  |  |  |
|  |  |  |  |  |  |
| Stress |  |  |  |  |  |
| $T_{A}\left({ }^{\circ} \mathrm{C}\right)$ | . 1 | . 3 | . 5 | . 7 | . 9 |
| 0 | . 0012 | . 0014 | . 0047 | . 020 | . 069 |
| 10 | . 0012 | . 0015 | . 0048 | . 021 | . 070 |
| 20 | . 0012 | . 0015 | . 0050 | . 021 | . 072 |
| 30 | . 0013 | . 0016 | . 0053 | . 023 | . 076 |
| 40 | . 0014 | . 0018 | . 0058 | . 025 | . 084 |
| 50 | . 0017 | . 0021 | . 0069 | . 030 | . 10 |
| 60 | . 0023 | . 0028 | . 0092 | . 039 | . 13 |
| 70 | . 0037 | . 0045 | . 015 | . 064 | . 21 |
| 80 | . 0080 | . 0099 | . 032 | . 14 | . 47 |
| $\lambda_{b}=.00115\left[\left(\frac{S}{.4}\right)^{5}+1\right] \exp \left(2.5\left(\frac{T+273}{358}\right)^{18}\right)$ <br> $T=$ Ambient Temperature $\left({ }^{\circ} \mathrm{C}\right)$ <br> $S=$ Ratio of Operating to Rated Voltage <br> Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage. |  |  |  |  |  |
|  |  |  |  |  |  |
|  |  |  |  |  |  |

Base Failure Rate - $\lambda_{b}$
( $T=125^{\circ} \mathrm{C}$ Max Rated)
(Characteristic K)

| $T_{A}\left({ }^{\circ} \mathrm{C}\right)$ | Stress |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | 1 | 3 | . 5 | . 7 | . 9 |
| 0 | . 0012 | . 0014 | . 0047 | . 020 | . 068 |
| 10 | . 0012 | . 0014 | . 0047 | . 020 | . 068 |
| 20 | . 0012 | . 0014 | . 0047 | . 020 | . 068 |
| 30 | . 0012 | . 0014 | . 0047 | . 020 | . 069 |
| 40 | . 0012 | . 0015 | . 0048 | . 021 | . 070 |
| 50 | . 0012 | . 0015 | . 0049 | . 021 | . 072 |
| 60 | . 0013 | . 0016 | . 0052 | . 022 | . 075 |
| 70 | . 0014 | . 0017 | . 0055 | . 024 | . 08 |
| 80 | . 0015 | . 0019 | . 0062 | . 027 | . 09 |
| 90 | . 0019 | . 0023 | . 0075 | . 032 | . 11 |
| 100 | . 0025 | . 0031 | . 010 | . 044 | . 15 |
| 110 | . 0040 | . 005 | . 016 | . 07 | . 24 |
| 120 | . 0084 | . 010 | . 034 | . 15 | 49 |

$\lambda_{b}=.00115\left[\left(\frac{S}{.4}\right)^{5}+1\right] \exp \left(2.5\left(\frac{T+273}{398}\right)^{18}\right)$
$\mathrm{T}=$ Ambient Temperature ( ${ }^{\circ} \mathrm{C}$ )
$S=$ Ratio of Operating to Rated Voltage
Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage.

DESCRIPTION
Paper, Metallized Paper, Metallized Plastic, RFI
Feed-Through Established Reliability and Non-Established Reliability

Failures $/ 10^{6}$ Hours
Base Failure Rate - $\lambda_{b}$ ( $\mathrm{T}=150^{\circ} \mathrm{C}$ Max Rated) (Characteristic P)

| $T_{A}\left({ }^{\circ} \mathrm{C}\right)$ | .1 | .3 | .5 | .7 | .9 |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 0 | .0012 | .0014 | .0047 | .020 | .068 |
| 10 | .0012 | .0014 | .0047 | .020 | .068 |
| 20 | .0012 | .0014 | .0047 | .020 | .068 |
| 30 | .0012 | .0014 | .0047 | .020 | .068 |
| 40 | .0012 | .0014 | .0047 | .020 | .068 |
| 50 | .0012 | .0015 | .0048 | .020 | .069 |
| 60 | .0012 | .0015 | .0048 | .021 | .070 |
| 70 | .0012 | .0015 | .0049 | .021 | .079 |
| 80 | .0013 | .0016 | .0051 | .022 | .074 |
| 90 | .0013 | .0017 | .0055 | .023 | .079 |
| 100 | .0015 | .0018 | .0060 | .026 | .087 |
| 110 | .0017 | .0022 | .0071 | .03 | .10 |
| 120 | .0022 | .0028 | .0091 | .039 | .13 |
| 130 | .0033 | .0040 | .013 | .057 | .19 |
| 140 | .0058 | .0072 | .024 | .10 | .34 |
| 150 | .014 | .017 | .057 | .24 | .82 |

$$
\lambda_{b}=.00115\left[\left(\frac{S}{4}\right)^{5}+1\right] \exp \left(2.5\left(\frac{T+273}{423}\right)^{18}\right)
$$

$T=$ Ambient Temperature ( ${ }^{\circ} \mathrm{C}$ )
$S=$ Ratio of Operating to Rated Voltage
Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage.


| Quality Factor $-\pi_{\mathrm{Q}}$ |  |
| :--- | :---: |
| Quality $\pi_{\mathrm{Q}}$ <br> $M$ 1.0 <br> Non-Established Reliability 3.0 <br> Lower 10 |  |


| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment $\pi_{E}$ <br> $G_{B}$ 1.0 <br> $G_{F}$ 2.0 <br> $G_{M}$ 9.0 <br> $N_{S}$ 7.0 <br> $N_{U}$ 15 <br> $A_{I C}$ 6.0 <br> $A_{I F}$ 8.0 <br> $A_{U C}$ 17 <br> $A_{U F}$ 28 <br> $A_{R W}$ 22 <br> $S_{F}$ .50 <br> $M_{F}$ 12 <br> $M_{L}$ 32 <br> $C_{L}$ 570 |  |

### 10.3 CAPACITORS, FIXED, PAPER AND PLASTIC FILM

SPECIFICATION
MIL-C-14157
MIL-C-19978

STYLE
CPV
CQR and CO

DESCRIPTION
Paper and Plastic Film, Est. Rel.
Paper and Plastic Film, Est. Rel. and Non-Est. Red.

$$
\lambda_{\mathrm{P}}=\lambda_{\mathrm{b}} \pi_{C V^{\pi}} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

Base Failure Rate - $\lambda_{\mathrm{t}}$
( $T=65^{\circ} \mathrm{C}$ Max Rated )
(MIL-C-14157 Style CPV07;
MIL-C-19978 Characteristics P, L)

| $\left.T_{A}{ }^{\circ} \mathrm{C}\right)$ | .1 | .3 | .5 | .7 | .9 |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 0 | .00053 | .00065 | .0021 | .0092 | .031 |
| 10 | .00055 | .00069 | .0022 | .0096 | .032 |
| 20 | .00061 | .00075 | .0025 | .011 | .036 |
| 30 | .00071 | .00088 | .0029 | .012 | .042 |
| 40 | .00094 | .0012 | .0038 | .016 | .055 |
| 50 | .0015 | .0019 | .0061 | .026 | .088 |
| 60 | .0034 | .0042 | .014 | .059 | .20 |

$\lambda_{b}=.0005\left[\left(\frac{S}{.4}\right)^{5}+1\right] \exp \left(2.5\left(\frac{T+273}{338}\right)^{18}\right)$
$T=A m b i e n t$ Temperature ( ${ }^{\circ} \mathrm{C}$ )
$S$ - Ratio of Operating to Rated Vohage
Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage.

Base Failure Rate - $\lambda_{b}$
( $\mathrm{T}=125^{\circ} \mathrm{C}$ Max Rated)
(MIL-C-14157 Style CPV09 and MIL-C-19978
Characteristics K, Q, S)

| $T_{A}\left({ }^{\circ} \mathrm{C}\right)$ | .1 | .3 | .5 | .7 | .9 |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 0 | .00050 | .00062 | .0020 | .0087 | .029 |
| 10 | .00050 | .00062 | .0020 | .0088 | .029 |
| 20 | .00051 | .00062 | .0020 | .0088 | .030 |
| 30 | .00051 | .00063 | .0021 | .0089 | .030 |
| 40 | .00052 | .00064 | .0021 | .009 | .030 |
| 50 | .00053 | .00066 | .0021 | .0092 | .031 |
| 60 | .00055 | .00068 | .0022 | .0096 | .032 |
| 70 | .00059 | .00073 | .0024 | .010 | .035 |
| 80 | .00067 | .00083 | .0027 | .012 | .039 |
| 90 | .00081 | .0010 | .0033 | .014 | .047 |
| 100 | .0011 | .0013 | .0044 | .019 | .064 |
| 110 | .0018 | .0022 | .0071 | .030 | .10 |
| 120 | .0037 | .0045 | .015 | .064 | .21 |

$\lambda_{b}=.0005\left[\left(\frac{S}{.4}\right)^{5}+1\right] \exp \left(2.5\left(\frac{T+273}{398}\right)^{18}\right)$
$\mathrm{T}=$ Ambient Temperature $\left({ }^{\circ} \mathrm{C}\right)$
$S=$ Ratio of Operating to Rated Voltage
Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage.

## Base Faikure Rate - $\lambda_{b}$

(T = $85^{\circ} \mathrm{C}$ Max Rated)
(MIL-C-14157 Style CPV17;
MIL-C-19978 Characteristics E, F, G, M)

| $\left.T_{A}{ }^{( }{ }^{( } \mathrm{C}\right)$ | Stress |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | . 1 | . 3 | 5 | . 7 | . 9 |
| 0 | . 00051 | . 00063 | . 0021 | . 0089 | . 030 |
| 10 | . 00052 | . 00064 | . 0021 | . 0090 | . 030 |
| 20 | . 00054 | . 00066 | . 0022 | . 0093 | . 031 |
| 30 | . 00057 | . 00070 | . 0023 | . 0099 | . 033 |
| 40 | . 00063 | . 00077 | . 0025 | . 011 | . 037 |
| 50 | . 00074 | . 00092 | . 0030 | . 013 | . 043 |
| 60 | . 00099 | . 0012 | . 0040 | . 017 | . 058 |
| 70 | . 0016 | . 0020 | . 0064 | . 028 | . 093 |
| 80 | . 0035 | . 0043 | . 014 | . 061 | . 20 |
| $\lambda_{b}=.0005\left[\left(\frac{S}{4}\right)^{5}+1\right] \exp \left(2.5\left(\frac{T+273}{358}\right)^{18}\right)$ |  |  |  |  |  |

$T=A m b i e n t$ Temperature $\left({ }^{\circ} \mathrm{C}\right)$
$S=$ Ratio of Operating to Rated Voltage
Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage.

Base Failure Rate - $\lambda_{b}$
( $\mathrm{T}=170^{\circ} \mathrm{C}$ Max Rated)
(MIL-C-19978 Characteristic T)

| $T_{A}\left({ }^{\circ} \mathrm{C}\right)$ | .1 | .3 | .5 | .7 | .9 |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 0 | .00050 | .00062 | .0020 | .0087 | .029 |
| 10 | .00050 | .00062 | .0020 | .0087 | .029 |
| 20 | .00050 | .00062 | .0020 | .0087 | .029 |
| 30 | .00050 | .00062 | .0020 | .0087 | .029 |
| 40 | .00050 | .00062 | .0020 | .0087 | .029 |
| 50 | .00050 | .00062 | .0020 | .0088 | .030 |
| 60 | .00051 | .00063 | .0021 | .0088 | .030 |
| 70 | .00051 | .00063 | .0021 | .0089 | .030 |
| 80 | .00052 | .00065 | .0021 | .0091 | .031 |
| 90 | .00054 | .00066 | .0022 | .0093 | .031 |
| 100 | .00056 | .00069 | .0023 | .0097 | .033 |
| 110 | .00060 | .00074 | .0024 | .010 | .035 |
| 120 | .00067 | .00083 | .0027 | .012 | .039 |
| 130 | .00079 | .00098 | .0032 | .014 | .046 |
| 140 | .0010 | .0013 | .0041 | .018 | .060 |
| 150 | .0015 | .0018 | .006 | .026 | .087 |
| 160 | .0026 | .0032 | .011 | .046 | .15 |
| 170 | .0061 | .0075 | .025 | .11 | .36 |

$\lambda_{b}=.0005\left[\left(\frac{S}{4}\right)^{5}+1\right] \exp \left(2.5\left(\frac{T+273}{443}\right)^{18}\right)$
$T=$ Ambient Temperature ( ${ }^{\circ} \mathrm{C}$ )
S - Ratio of Operating to Rated Voltage
Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage.

## MIL-HDBK-217F



## MIL-HDBK-217F

10.4 CAPACITORS, FIXED, METALLIZED PAPER, PAPER-PLASTIC AND PLASTIC

## SPECIFICATION

MIL-C-18312
MIL-C-39022

STYLE
CH
CHR

DESCRIPTION
Metallized Paper, Paper-Plastic, Plastic
Metallized Paper, Paper-Plastic, Plastic, Established Reliability

$$
\lambda_{p}=\lambda_{b} \pi_{C V} \pi_{Q} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

Base Faikre Rate - $\lambda_{b}$
( T - $85^{\circ} \mathrm{C}$ Max Rated)
(MIL-C-39022 Charactoristic 9 and 12 ( 50 Vohs rated), Characteristic 49; and MIL-C-18312 Characteristic R)

| $T_{A}\left({ }^{\circ} \mathrm{C}\right)$ | .1 | .3 | .5 | .7 | .9 |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 0 | .00070 | .00087 | .0028 | .012 | .041 |
| 10 | .00072 | .00089 | .0029 | .012 | .042 |
| 20 | .00074 | .00091 | .0030 | .013 | .043 |
| 30 | .00078 | .00097 | .0032 | .014 | .046 |
| 40 | .00086 | .0011 | .0035 | .015 | .051 |
| 50 | .0010 | .0013 | .0041 | .018 | .06 |
| 60 | .0014 | .0017 | .0055 | .024 | .08 |
| 70 | .0022 | .0027 | .0089 | .038 | .13 |
| 80 | .0048 | .0059 | .019 | .084 | .28 |

$\lambda_{b}=.00069\left[\left(\frac{S}{.4}\right)^{5}+1\right] \exp \left(2.5\left(\frac{T+273}{358}\right)^{18}\right)$
$T=A m b i e n t$ Temperature $\left({ }^{\circ} \mathrm{C}\right)$
S - Ratio of Operating to Rated Voltage
Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage.

## Base Failure Rate $-\lambda_{b}$

( $\mathrm{T}=125^{\circ} \mathrm{C}$ Max Rated)
(MIL-C-39022 Characteristic 9 and 12 (above 50 Volts rated), Characteristics 1, 10, 19, 29, 59; and MIL-C-18312 Characteristic N)

| $T_{A}\left({ }^{\circ} C\right)$ | .1 | .3 | .5 | .7 | .9 |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 0 | .00069 | .00086 | .0028 | .012 | .041 |
| 10 | .00069 | .00086 | .0028 | .012 | .041 |
| 20 | .00070 | .00086 | .0028 | .012 | .041 |
| 30 | .00070 | .00087 | .0028 | .012 | .041 |
| 40 | .00071 | .00088 | .0029 | .012 | .042 |
| 50 | .00073 | .00090 | .003 | .013 | .043 |
| 60 | .00076 | .00094 | .0031 | .013 | .045 |
| 70 | .00082 | .0010 | .0033 | .014 | .048 |
| 80 | .00092 | .0011 | .0037 | .016 | .054 |
| 90 | .0011 | .0014 | .0045 | .019 | .065 |
| 100 | .0015 | .0019 | .0061 | .026 | .088 |
| 110 | .0024 | .0030 | .0098 | .042 | .14 |
| 120 | .0051 | .0063 | .020 | .088 | .30 |

$\lambda_{b}=.00069\left[\left(\frac{S}{4}\right)^{5}+1\right] \exp \left(2.5\left(\frac{T+273}{398}\right)^{18}\right)$
$T=$ Ambient Temperature $\left({ }^{\circ} \mathrm{C}\right)$
S = Ratio of Operating to Rated Voltage
Operating voltage is the sum of applied D.C. voltage and poak A.C. voltage.

## MIL-HDBK-217F

10.4 CAPACITORS, FIXED, METALLIZED PAPER, PAPER-PLASTIC AND PLASTIC
Capacitañee Façór - $\pi_{\mathrm{CV}}$

| Capacitance, $\mathrm{C}(\mu \mathrm{F})$ | $\pi_{\mathrm{CV}}$ |
| :--- | :---: |
| 0.0029 | .70 |
| 0.14 | 1.0 |
| 2.4 | 1.3 |
| $\pi_{\mathrm{CV}}=1.2 \mathrm{C}^{0.092}$ |  |


| Quaiity Factor $-\pi_{\mathrm{Q}}$ |  |
| :--- | :---: |
| Quality $\pi_{\mathrm{Q}}$ <br> S 0.03 <br> R .10 <br> P .30 <br> M 1.0 <br> L 3.0 <br> MIL-C-18312. Non-Est. Rel. 7.0 <br> Lower 20 |  |


| Environment Factor $-\pi_{E}$ |
| :---: |
| Environment $\pi_{E}$ <br> $G_{B}$ 1.0 <br> $G_{F}$ 2.0 <br> $G_{M}$ 8.0 <br> $N_{S}$ 5.0 <br> $N_{U}$ 14 <br> $A_{I C}$ 4.0 <br> $A_{I F}$ 6.0 <br> $A_{U C}$ 11.0 <br> $A_{U F}$ 20 <br> $A_{R W}$ 20 <br> $S_{F}$ .50 <br> $M_{F}$ 11 <br> $M_{L}$ 29 <br> $C_{L}$ 530 |

10.5 CAPACITORS, FIXED, PLASTIC AND METALLIZED PLASTIC


$$
\lambda_{p}=\lambda_{b} \pi_{C V} \pi_{Q} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

| $\begin{aligned} & \text { Base Failure Rate }-\lambda_{\mathrm{b}} \\ & \left(T=85^{\circ} \mathrm{C}\right. \text { Max Rated ) } \\ & (\text { Characteristics } M, N) \end{aligned}$ |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | ress |  |  |
| $T_{A}\left({ }^{\circ} \mathrm{C}\right)$ | . 1 | . 3 | . 5 | . 7 | . 9 |
| 0 | . 0010 | . 0012 | . 0041 | . 018 | . 059 |
| 10 | . 0010 | . 0013 | . 0042 | . 018 | . 060 |
| 20 | . 0011 | 0013 | . 0043 | . 018 | . 062 |
| 30 | . 0011 | . 0014 | . 0045 | . 020 | . 066 |
| 40 | . 0012 | . 0015 | . 0050 | . 022 | . 073 |
| 50 | . 0015 | . 0018 | . 0059 | . 026 | . 086 |
| 60 | . 0020 | . 0024 | . 0079 | . 034 | . 11 |
| 70 | . 0032 | . 0039 | . 013 | . 055 | . 18 |
| 80 | . 0069 | . 0085 | . 028 | . 12 | . 40 |
| $\lambda_{b}=.00099\left[\left(\frac{S}{.4}\right)^{5}+1\right] \exp \left(2.5\left(\frac{T+273}{358}\right)^{18}\right)$ |  |  |  |  |  |
|  | Amb | Tempe | ture ( ${ }^{\circ} \mathrm{C}$ ) |  |  |
|  | Ratio | Operat | to Rate | Voltag |  |

Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage.

Base Failure Rate - $\lambda_{D}$
( $\mathrm{T}=125^{\circ} \mathrm{C}$ Max Rated)
(Characteristics Q, R, S)

| $\mathrm{T}_{\mathrm{A}}\left({ }^{\circ} \mathrm{C}\right)$ | .1 | .3 | .5 | .7 | .9 |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 0 | .00099 | .0012 | .0040 | .017 | .058 |
| 10 | .0010 | .0012 | .0040 | .017 | .058 |
| 20 | .0010 | .0012 | .0041 | .017 | .059 |
| 30 | .0010 | .0012 | .0041 | .018 | .059 |
| 40 | .0010 | .0013 | .0041 | .018 | .060 |
| 50 | .0011 | .0013 | .0043 | .018 | .062 |
| 60 | .0011 | .0014 | .0044 | .019 | .064 |
| 70 | .0012 | .0015 | .0048 | .020 | .069 |
| 80 | .0013 | .0016 | .0054 | .023 | .077 |
| 90 | .0016 | .0020 | .0065 | .028 | .094 |
| 100 | .0022 | .0027 | .0087 | .038 | .13 |
| 110 | .0035 | .0043 | .014 | .06 | .20 |
| 120 | .0073 | .0090 | .029 | .13 | .43 |

$\lambda_{b}=.00099\left[\left(\frac{S}{.4}\right)^{5}+1\right] \exp \left(2.5\left(\frac{T+273}{398}\right)^{18}\right)$
$T=$ Ambient Temperature ( ${ }^{\circ} \mathrm{C}$ )
$S$ = Ratio of Operating to Rated Voltage
Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage.

## MIL-HDBK-217F

10.5 CAPACITORS, FIXED, PLASTIC AND METALLIZED PLASTIC

| Capacitance Factor $-\pi_{\mathrm{CV}}$ |  |
| :--- | :---: |
| Capacitanco, $\mathrm{C}(\mu \mathrm{P})$ | $\pi_{\mathrm{CV}}$ |
| 0.0049 | .70 |
| 0.33 | 1.0 |
| 7.1 | 1.3 |
| 38. | 1.5 |
| $\pi_{\mathrm{CV}}=1.1 \mathrm{C}^{0.085}$ |  |


| Quality Factor $-\pi_{Q}$ |  |
| :--- | :---: |
| Quality | $\pi_{Q}$ |
| S | .030 |
| R | .10 |
| P | .30 |
| M | 1.0 |
| Lower | 10 |


| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment $\pi_{E}$ <br> $G_{B}$ 1.0 <br> $G_{F}$ 2.0 <br> $G_{M}$ 10 <br> $N_{S}$ 5.0 <br> $N_{U}$ 16 <br> $A_{I C}$ 6 <br> $A_{I F}$ 11 <br> $A_{U C}$ 18 <br> $A_{U F}$ 30 <br> $A_{R W}$ 23 <br> $S_{F}$ .50 <br> $M_{F}$ 13 <br> $M_{L}$ 34 <br> $C_{L}$ 610 |  |

## MIL-HDBK-217F

10.6 CAPACITORS, FIXED, SUPER-METALLIZED PLASTIC

SPECIFICATION MIL-C-83421

## STYLE CRH

## DESCRIPTION

Super-Metallized Plastic, Est. Rel.

$$
\lambda_{p}=\lambda_{b} \pi_{C V} \pi_{Q} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

| Base Faikure Rate $-\lambda_{D}$ ( $\mathrm{T}=125^{\circ} \mathrm{C}$ Max Rated) |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | Stress |  |  |  |  |
| $T_{A}\left({ }^{\circ} \mathrm{C}\right)$ | . 1 | . 3 | . 5 | . 7 | . 9 |
| 0 | . 00055 | . 00068 | . 0022 | . 0096 | . 032 |
| 10 | . 00055 | . 00068 | . 0022 | . 0096 | . 032 |
| 20 | . 00056 | . 00069 | . 0023 | . 0097 | . 033 |
| 30 | . 00056 | . 00069 | . 0023 | . 0098 | . 033 |
| 40 | . 00057 | . 00070 | . 0023 | . 0099 | . 033 |
| 50 | . 00058 | . 00072 | . 0024 | . 010 | . 034 |
| 60 | . 00061 | . 00075 | . 0025 | . 011 | . 036 |
| 70 | . 00065 | . 00081 | . 0026 | . 011 | . 038 |
| 80 | . 00073 | . 00091 | . 0030 | . 013 | . 043 |
| 90 | . 00089 | . 0011 | . 0036 | . 015 | . 052 |
| 100 | . 0012 | . 0015 | . 0049 | . 021 | . 07 |
| 110 | . 0019 | . 0024 | . 0078 | . 033 | . 11 |
| 120 | . 0040 | . 0050 | . 016 | . 070 | . 24 |
| $\lambda_{b}=.00055\left[\left(\frac{S}{4}\right)^{5}+1\right] \exp \left(2.5\left(\frac{T+273}{398}\right)^{18}\right)$ |  |  |  |  |  |

$T=A m b i e n t$ Temperature ( ${ }^{\circ} \mathrm{C}$ )
$S=$ Ratio of Operating to Rated Voltage
Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage.

| Quality Factor $-\pi_{\mathrm{Q}}$ |  |
| :--- | :---: |
| Quality | $\pi_{\mathrm{Q}}$ |
| S | .020 |
| R | .10 |
| P | .30 |
| M | 1.0 |
| Lower | 10 |



| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\pi_{E}$ |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 4.0 |
| $G_{M}$ | 8.0 |
| $N_{S}$ | 5.0 |
| $N_{U}$ | 14 |
| $A_{l}$ | 4.0 |
| $A_{I F}$ | 6.0 |
| $A_{U C}$ | 13.0 |
| $A_{U F}$ | 20 |
| $A_{R W}$ | 20 |
| $S_{F}$ | .50 |
| $M_{F}$ | 11 |
| $M_{L}$ | 29 |
| $C_{L}$ | 530 |

## SPECIFICATION

MIL-C-5
MIL-C-39001

## styLe <br> CM <br> CMR

DESCRIPTION
MICA (Dipped or Molded)
MICA (Dipped), Established Reliability

$$
\lambda_{\mathrm{P}}=\lambda_{\mathrm{b}} \pi_{C V} \pi_{\mathrm{Q}} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

| Base Failure Rate - $\lambda_{b}$ (T. $70^{\circ} \mathrm{C}$ Max Reted) (MIL-C-5, Tomp. Range M) |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\frac{(M 1 L-C-5, ~ T o m p . ~ R a n g e ~ M) ~}{\text { Stross }}$ |  |  |  |  |  |
| 0 | . 00030 | . 00041 | . 00086 | 0019 | 0036 |
| 10 | . 00047 | . 00066 | . 0014 | . 0030 | . 0058 |
| 20 | . 00075 | . 0011 | . 0022 | . 0047 | . 0092 |
| 30 | . 0012 | . 0017 | . 0035 | . 0075 | . 015 |
| 40 | . 0019 | . 0027 | . 0056 | . 012 | . 023 |
| 50 | . 0031 | . 0043 | . 0089 | . 019 | . 037 |
| 60 | . 0049 | . 0068 | . 014 | . 030 | . 059 |
| 70 | . 0078 | . 011 | . 023 | . 049 | . 095 |
| $\lambda_{b}=8.6 \times 10^{-10}\left[\left(\frac{S}{4}\right)^{3}+1\right] \exp \left(16\left(\frac{T+273}{343}\right)\right)$ |  |  |  |  |  |
| $T=$ Ambient Temperature ( ${ }^{\circ} \mathrm{C}$ ) <br> $S=$ Ratio of Operating to Rated Voltage |  |  |  |  |  |
| Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage. |  |  |  |  |  |

Base Faikure Rate - $\lambda_{b}$
( $\mathrm{T}=125^{\circ} \mathrm{C}$ Max Rated)
(MIL-C-5, Temp. Range O; MIL-C-39001 Temp. Range O)

| $T_{A}\left({ }^{\circ} \mathrm{C}\right)$ | Stress |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | 1 | 3 | . 5 | . 7 | 9 |
| 0 | . 00005 | . 00007 | . 00015 | 00032 | . 00062 |
| 10 | . 00008 | . 00011 | . 00022 | . 00048 | . 00093 |
| 20 | . 00011 | . 00016 | . 00033 | . 00071 | . 0014 |
| 30 | . 00017 | . 00024 | . 00050 | . 0011 | . 0021 |
| 40 | . 00025 | . 00036 | . 00074 | . 0016 | . 0031 |
| 50 | . 00038 | . 00053 | . 0011 | . 0024 | . 0046 |
| 60 | . 00057 | . 0008 | . 0017 | . 0036 | . 0069 |
| 70 | . 00085 | . 0012 | . 0025 | . 0053 | . 010 |
| 80 | . 0013 | . 0018 | . 0037 | . 008 | . 016 |
| 90 | . 0019 | . 0027 | . 0055 | . 012 | . 023 |
| 100 | . 0028 | . 0040 | . 0083 | . 018 | . 035 |
| 110 | . 0042 | . 0059 | . 012 | . 027 | . 052 |
| 120 | 0063 | . 0089 | . 018 | . 040 | . 077 |
| $\lambda_{b}=8.6 \times 10^{-10}\left[\left(\frac{S}{.4}\right)^{3}+1\right] \exp \left(16\left(\frac{T+273}{398}\right)\right)$ |  |  |  |  |  |
| $\dot{s}$ | Amb Rati | t Tem Op | $\text { ature } 1^{\circ} \mathrm{C}$ $\mathrm{g} \text { to } \mathrm{Ra}$ | Voltag |  |
| Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage. |  |  |  |  |  |


| Base Failure Rate $-\lambda_{b}$$\left(T=85^{\circ} \mathrm{C}\right.$ Max Rated)(MiL-C-5, Temp. Range N) |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Stress |  |  |  |  |  |
| $\mathrm{T}_{\mathrm{A}}\left({ }^{\circ} \mathrm{C}\right)$ | . 1 | . 3 | . 5 | . 7 | . 9 |
| 0 | . 00017 | . 00024 | . 00051 | . 0011 | . 0021 |
| 10 | . 00027 | . 00038 | . 00079 | . 0017 | . 0033 |
| 20 | . 00042 | . 00059 | . 0012 | . 0027 | . 0052 |
| 30 | . 00066 | . 000093 | . 0018 | . 0042 | . 0081 |
| 40 | . 0010 | . 0015 | . 003 | . 0065 | . 013 |
| 50 | . 0016 | . 0023 | . 0047 | . 010 | . 020 |
| 60 | . 0025 | . 0036 | . 0074 | . 016 | . 031 |
| 70 | . 0040 | . 0056 | . 012 | . 025 | . 048 |
| 80 | 0062 | . 0087 | . 018 | 039 | 076 |
| $\lambda_{b}=8.6 \times 10^{-10}\left[\left(\frac{S}{.4}\right)^{3}+1\right] \exp \left(16\left(\frac{T+273}{358}\right)\right)$ <br> $T=$ Ambient Temperature ( ${ }^{\circ} \mathrm{C}$ ) <br> $S=$ Ratio of Operating to Rated Voltage <br> Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage. |  |  |  |  |  |
|  |  |  |  |  |  |
|  |  |  |  |  |  |

Base Failure Rate - $\lambda_{b}$
( $\mathrm{T}=150^{\circ} \mathrm{C}$ Max Rated)
(MIL-C-5, Temp. Range P; MIL-C-39001, Temp. Range P)

| $T_{A}\left({ }^{\circ} \mathrm{C}\right)$ | .1 | .3 | .5 | .7 | .9 |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 0 | .00003 | .00004 | .00008 | .00017 | .00033 |
| 10 | .00004 | .00005 | .00011 | .00024 | .00047 |
| 20 | .00006 | .00008 | .00017 | .00036 | .00069 |
| 30 | .00008 | .00012 | .00024 | .00052 | .0010 |
| 40 | .00012 | .00017 | .00035 | .00076 | .0015 |
| 50 | .00018 | .00025 | .00051 | .0011 | .0022 |
| 60 | .00026 | .00036 | .00075 | .0016 | .0031 |
| 70 | .00038 | .00053 | .0011 | .0024 | .0046 |
| 80 | .00055 | .00077 | .0016 | .0034 | .0067 |
| 90 | .0008 | .0011 | .0023 | .0050 | .0098 |
| 100 | .0012 | .0016 | .0034 | .0073 | .014 |
| 110 | .0017 | .0024 | .0050 | .011 | .021 |
| 120 | .0025 | .0035 | .0073 | .016 | .030 |
| 130 | .0036 | .0051 | .011 | .023 | .044 |
| 140 | .0053 | .0074 | .15 | .033 | .065 |
| 150 | .0078 | .011 | .023 | .049 | .095 |

$\lambda_{b}=8.6 \times 10^{-10}\left[\left(\frac{S}{4}\right)^{3}+1\right] \exp \left(16\left(\frac{T+273}{423}\right)\right)$
$T$ - Ambient Temperature ( ${ }^{\circ} \mathrm{C}$ )
$s=$ Ratio of Operating to Rated Voltage
Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage.

MIL-HDBK-217F
10.7 CAPACITORS, FIXED, MICA

| Capacitance Factor $-\pi_{\mathrm{CV}}$ |  |
| :---: | :---: |
| Capacitance, C (pF) | $\pi_{\mathrm{CV}}$ |
| 2 | .50 |
| 38 | .75 |
| 300 | 1.0 |
| 2000 | 1.3 |
| 8600 | 1.6 |
| 29000 | 1.9 |
| 84000 | 2.2 |


| Quality Factor - $\pi_{Q}$ |  |
| :---: | :---: |
| Quality | $\pi_{Q}$ |
| T | . 010 |
| S | . 030 |
| R | . 10 |
| P | . 30 |
| M | 1.0 |
| L | 1.5 |
| Mill-C-5, Non-Est. Rel. Dipped | 3.0 |
| MiL-C-5, Non-Est. Rel. Molded | 6.0 |
| Lower | 15 |


| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\pi_{E}$ |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 2.0 |
| $G_{M}$ | 10 |
| $N_{S}$ | 6.0 |
| $N_{U}$ | 16 |
| $A_{I C}$ | 5.0 |
| $A_{I F}$ | 7.0 |
| $A_{U C}$ | 22 |
| $A_{U F}$ | 28 |
| $A_{R W}$ | 23 |
| $S_{F}$ | .50 |
| $M_{F}$ | 13 |
| $M_{L}$ | 34 |
| $C_{L}$ | 610 |

## MIL-HDBK-217F

$10 . \overline{8}$ CĀPACITŌ̄S, FIXED, MICA, BUTTON

SPECIFICATION MIL-C-10950

## STYLE CB

## DESCRIPTION MICA, Button Style

$$
\lambda_{p}=\lambda_{b} \pi_{C V} \pi_{Q} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

| Base Failure Rate - $\lambda_{t}$ ( $\mathrm{T}=85^{\circ} \mathrm{C}$ Max Rated) (Style CB50) |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | Stress |  |  |  |  |
| $T_{A}\left({ }^{\circ} \mathrm{C}\right)$ | . 1 | . 3 | . 5 | . 7 | . 9 |
| 0 | . 0067 | . 0094 | . 019 | . 042 | . 082 |
| 10 | . 0071 | . 0099 | . 021 | . 044 | . 086 |
| 20 | . 0076 | . 011 | . 022 | . 047 | . 092 |
| 30 | . 0082 | .011 | . 024 | . 051 | . 10 |
| 40 | . 009 | . 013 | . 026 | . 056 | . 11 |
| 50 | . 010 | . 014 | . 029 | . 063 | 12 |
| 60 | . 012 | . 016 | . 033 | . 072 | . 14 |
| 70 | . 013 | . 019 | . 039 | . 084 | . 16 |
| 80 | . 016 | . 023 | . 047 | . 10 | . 20 |
| $\begin{aligned} \lambda_{b} & =.0053\left[\left(\frac{S}{.4}\right)^{3}+1\right] \exp \left(1.2\left(\frac{T+273}{358}\right)^{6.3}\right) \\ T & =\text { Ambient Temperature }\left({ }^{\circ} \mathrm{C}\right) \\ S & =\text { Ratio of Operating to Rated Voltage } \end{aligned}$ <br> Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage. |  |  |  |  |  |
|  |  |  |  |  |  |
|  |  |  |  |  |  |
|  |  |  |  |  |  |


| $\begin{gathered} \text { Base Faihure Rate }-\lambda_{b} \\ \text { ( } T=150^{\circ} \mathrm{C} \text { Max Rated) } \\ \text { (All Types Except CB50) } \end{gathered}$ |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | Stress |  |  |  |  |
| $T_{A}\left({ }^{\circ} \mathrm{C}\right)$ | . 1 | . 3 | . 5 | . 7 | . 9 |
| 0 | . 0058 | . 0081 | . 017 | . 036 | . 071 |
| 10 | . 0059 | . 0083 | . 017 | . 037 | . 072 |
| 20 | . 0061 | . 0085 | . 018 | . 038 | . 074 |
| 30 | 0062 | . 0087 | . 018 | . 039 | . 076 |
| 40 | . 0064 | . 009 | . 019 | . 040 | . 079 |
| 50 | . 0067 | . 0094 | . 019 | . 042 | . 082 |
| 60 | . 0070 | . 0098 | . 020 | . 044 | . 086 |
| 70 | . 0074 | . 010 | . 022 | . 046 | . 090 |
| 80 | . 0079 | . 011 | . 023 | . 049 | . 096 |
| 30 | . 0085 | . 012 | . 025 | . 053 | . 10 |
| 100 | . 0093 | . 013 | . 027 | . 058 | . 11 |
| 110 | . 010 | . 014 | . 03 | . 064 | . 12 |
| 120 | . 011 | . 016 | . 033 | . 072 | . 14 |
| 130 | . 013 | . 018 | . 038 | . 082 | . 16 |
| 140 | . 015 | 021 | . 044 | . 095 | . 18 |
| 150 | . 018 | . 025 | . 052 | . 11 | . 22 |
| $\lambda_{b}=.0053\left[\left(\frac{S}{4}\right)^{3}+1\right] \exp \left(1.2\left(\frac{T+273}{423}\right)^{6.3}\right)$ |  |  |  |  |  |
| $\begin{aligned} T & =\text { Ambient Temperature }\left({ }^{\circ} \mathrm{C}\right) \\ S & =\text { Ratio oi Operating to Raied Voïage } \end{aligned}$ |  |  |  |  |  |
|  |  |  |  |  |  |

Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage.
10.8 CAPACITORS, FIXED, MICA, BUTTON
Quality Factor $-\pi_{\mathrm{Q}}$

| Quality | $\pi_{\mathrm{Q}}$ |
| :--- | :---: |
| MIL-C-10950 | 5.0 |
| Lower | 15 |

Capacitance Factor $-\pi_{\mathrm{CV}}$

| Capacitance, C (pF) | $\pi_{\mathrm{CV}}$ |
| :---: | :---: |
| 8 | .50 |
| 50 | .76 |
| 160 | 1.0 |
| 500 | 1.3 |
| 1200 | 1.6 |
| 2600 | 1.9 |
| 5000 | 2.2 |
|  |  |
| $\pi_{\mathrm{CV}}=.31 C^{0.23}$ |  |


| Environment Factor - $\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\pi_{E}$ |
| $\mathrm{G}_{\mathrm{B}}$ | 1.0 |
| $\mathrm{G}_{\mathrm{F}}$ | 2.0 |
| $\mathrm{G}_{\mathrm{M}}$ | 10 |
| $\mathrm{N}_{S}$ | 5.0 |
| $\mathrm{N}_{\mathrm{U}}$ | 16 |
| $A_{1 C}$ | 5.0 |
| $A_{\text {IF }}$ | 7.0 |
| ${ }^{\text {A }}$ UC | 22 |
| ${ }^{\text {A }}$ UF | 28 |
| $A_{\text {RW }}$ | 23 |
| $S_{F}$ | . 50 |
| $M_{F}$ | 13 |
| $M_{L}$ | 34 |
| $C_{L}$ | 610 |

$\pi_{C V}=.31 C^{0.23}$

MIL-HDBK-217F
$10 . \overline{9}$ CAPACITOFS, FIXED, GLASS

| SPECIFICATION |  |  |
| :--- | :--- | :--- |
| MIL-C-11227 | STYLE | DESCRIPTION |
| MLL-C-23269 | CYR | Glass |
|  |  | Glass, Established Reliability |
|  | $\lambda_{p}=\lambda_{b} \pi_{C V} \pi_{Q} \pi_{E}$ | Failures $/ 10^{6}$ Hours |

Base Faiture Rate $-\lambda_{b}$
( $T=125^{\circ} \mathrm{C}$ Max Rated)
(All MIL-C-23296 and MIL-C-11272 Temp. Range C)

| $T_{A}\left({ }^{\circ} \mathrm{C}\right)$ | .1 | .3 | Stress | .5 | .7 |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 0 | .00005 | .00005 | .00010 | .00023 | .00055 |
| 10 | .00007 | .00008 | .00014 | .00035 | .00083 |
| 20 | .00011 | .00012 | .00022 | .00052 | .0012 |
| 30 | .00016 | .00018 | .00032 | .00078 | .0018 |
| 40 | .00024 | .00027 | .00048 | .0012 | .0028 |
| 50 | .00036 | .00041 | .00072 | .0017 | .0041 |
| 60 | .00054 | .00061 | .0011 | .0026 | .0062 |
| 70 | .0008 | .00091 | .0016 | .0039 | .0092 |
| 80 | .0012 | .0014 | .0024 | .0058 | .014 |
| 90 | .0018 | .0020 | .0036 | .0087 | .021 |
| 100 | .0027 | .0030 | .0054 | .013 | .031 |
| 110 | .0040 | .0045 | .0080 | .019 | .046 |
| 120 | .0060 | .0068 | .012 | .029 | .063 |

$\lambda_{\mathrm{b}}=8.25 \times 10^{-10}\left[\left(\frac{\mathrm{~S}}{5}\right)^{4}+1\right] \exp \left(16\left(\frac{T+273}{398}\right)\right)$
$T=$ Ambient Temperature $\left({ }^{\circ} \mathrm{C}\right)$
$S=$ Ratio of Operating to Rated Voltage
Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage.

Base Failure Rate - $\lambda_{b}$
( $\mathrm{T}=200^{\circ} \mathrm{C}$ Max Rated)
(MIL-C-11272 Temp. Range D)

| $T_{A}\left({ }^{\circ} \mathrm{C}\right)$ | .1 | .3 | Stress |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 0 | .00001 | .00001 | .00002 | .00004 | .00010 |  |  |
| 10 | $.0000 \overline{1} 1$ | .000001 | .00002 | .00006 | .000014 |  |  |
| 20 | .00002 | .00002 | .00003 | .00008 | .00019 |  |  |
| 30 | .00002 | .00003 | .00005 | .00011 | .00027 |  |  |
| 40 | .00003 | .00004 | .00007 | .00016 | .00038 |  |  |
| 50 | .00005 | .00005 | .00009 | .00022 | .00053 |  |  |
| 60 | .00006 | .00007 | .00013 | .00031 | .00074 |  |  |
| 70 | .00009 | .00010 | .00018 | .00044 | .0010 |  |  |
| 80 | .00013 | .00014 | .00025 | .00061 | .0015 |  |  |
| 90 | .00018 | .00020 | .00035 | .00086 | .0020 |  |  |
| 100 | .00025 | .00028 | .00050 | .0012 | .0029 |  |  |
| 110 | .00035 | .00039 | .00070 | .0017 | .0040 |  |  |
| 120 | .00049 | .00055 | .00098 | .0024 | .0056 |  |  |
| 130 | .00069 | .00078 | .0014 | .0033 | .0079 |  |  |
| 140 | .00096 | .0011 | .0019 | .0047 | .011 |  |  |
| 150 | .0014 | .0015 | .0027 | .0065 | .016 |  |  |
| 160 | .0019 | .0021 | .0038 | .0092 | .022 |  |  |
| 170 | .0027 | .0030 | .0053 | .013 | .031 |  |  |
| 180 | .0037 | .0042 | .0075 | .018 | .043 |  |  |
| 190 | .0052 | .0059 | .010 | .025 | .060 |  |  |
| 200 | .0073 | .0083 | .015 | .035 | .084 |  |  |

$\lambda_{b}=8.25 \times 10^{-10}\left[\left(\frac{S}{5}\right)^{4}+1\right] \exp \left(16\left(\frac{T+273}{473}\right)\right)$
$\mathrm{T}=$ Ambient Temperature $\left({ }^{\circ} \mathrm{C}\right)$
$S=$ Ratio of Operating to Rated Voltage
Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage.

## MIL-HDBK-217F

10.9 CAPACITŌ̄S, FIXED, GLASSS

| Capacitance Factor - $\pi_{\text {CV }}$ |  | Environment Factor - $\pi_{E}$ |  |
| :---: | :---: | :---: | :---: |
| Capacitance, C ( pF ) | ${ }^{\pi} \mathrm{CV}$ | Environmem | $\pi_{\text {E }}$ |
| 1 4 | .62 .75 | $\begin{aligned} & \mathrm{G}_{\mathrm{B}} \\ & \mathrm{G}_{\mathrm{F}} \\ & \mathrm{G}_{\mathrm{M}} \end{aligned}$ | $\begin{gathered} 1.0 \\ 2.0 \\ 10 \end{gathered}$ |
| 30 200 | 1.0 1.3 | $\begin{aligned} & \mathrm{N}_{\mathrm{S}} \\ & \mathrm{~N}_{\mathrm{U}} \end{aligned}$ | $\begin{aligned} & 6.0 \\ & 16 \end{aligned}$ |
| 900 | 1.6 | $A_{1}$ | 5.0 |
| 3000 | 1.9 | $\mathrm{A}_{\mathrm{iF}}$ | 7.0 |
|  |  | ${ }^{\text {A }}$ UC | 22 |
| 8500 | 2.2 | $A_{\text {UF }}$ | 28 |
| $\pi_{C V}=0.62 C^{0.14}$ |  | $A_{\text {RW }}$ | 23 |
|  |  | $S_{F}$ | . 50 |
| Quality Factor $-\pi_{\mathrm{Q}}$ |  | $M_{F}$ | 13 |
|  |  | $M_{L}$ | 34 |
| Quality | $\pi_{\mathrm{Q}}$ | $C_{L}$ | 610 |
| S | . 030 |  |  |
| R | . 10 |  |  |
| P | . 30 |  |  |
| M | 1.0 |  |  |
| L | 3.0 |  |  |
| MIL-C-11272, Non-Est. Rel. | 3.0 |  |  |
| Lower | 10 |  |  |

## MIL-HDBK-217F

10.10 CAPACITORS, FIXED, CERAMIC, GENERAL PURPOSE

## SPECIFICATION

MIL-C-11015
MIL-C-39014

## STYLE <br> CK <br> CKR

DESCRIPTION
Ceramic, General Puppose
Ceramic, General Purpose, Est. Rel.

$$
\lambda_{p}=\lambda_{b} \pi_{C V} \pi_{Q} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

Base Failure Rate - $\lambda_{b}$
( $\mathrm{T}=85^{\circ} \mathrm{C}$ Max Rated)
(MIL-C-39014 Styles CKR13, 48, 64, 72;
MIL-C-11015 Type A Rated Tomperature)

| $\mathrm{T}_{\mathrm{A}}\left({ }^{\circ} \mathrm{C}\right)$ | Stress |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | 1 | . 3 | . 5 | . 7 | . 9 |
| $\begin{array}{r} 0 \\ 10 \end{array}$ | . 00067 | . 0013 | . 0036 | . 0088 | . 018 |
|  | . 00069 | . 0013 | . 0037 | . 0091 | . 019 |
| 20 | . 00071 | . 0014 | . 0038 | . 0093 | . 019 |
| 30 | 00073 | . 0014 | . 0039 | . 0096 | . 020 |
| 40 | . 00075 | . 0014 | . 004 | . 0099 | . 020 |
| 50 | . 00077 | . 0015 | . 0042 | . 010 | . 021 |
| 60 | . 00079 | . 0015 | . 0043 | . 010 | . 021 |
| 70 | . 00081 | . 0016 | . 0044 | . 011 | . 022 |
| 80 | . 00083 | 0016 | . 0045 | 011 | . 023 |
| $\lambda_{\mathrm{b}}=.0003$ |  | $\left(\frac{5}{3}\right)^{3}$ | $1] \exp$ | (273 |  |
|  | Ambie <br> Ratio | Tempe Operat | ure ( $^{\circ} \mathrm{C}$ ) to Rated | Voltage |  |
| Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage. |  |  |  |  |  |

Base Failure Rate - $\lambda_{b}$
( $\mathrm{T}=125^{\circ} \mathrm{C}$ Max Rated)
(MIL-C-39014 Styles CKR05-12, 14-19, 73, 74; MIL-C-11015 Type B Rated Temperature)

| $\mathrm{T}_{\mathrm{A}}\left({ }^{\circ} \mathrm{C}\right)$ | Stress |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | 1 | . 3 | 5 | . 7 | . 9 |
| 0 | . 00062 | 0012 | 0033 | 0082 | . 017 |
| 10 | . 00063 | . 0012 | . 0034 | . 0084 | . 017 |
| 20 | . 00065 | . 0013 | . 0035 | . 0086 | . 018 |
| 30 | . 00067 | . 0013 | . 0036 | . 0088 | . 018 |
| 40 | . 00068 | . 0013 | . 0037 | . 0090 | . 018 |
| 50 | . 00070 | . 0014 | . 0038 | . 0093 | . 019 |
| 60 | . 00072 | . 0014 | . 0039 | . 0095 | . 019 |
| 70 | . 00074 | . 0014 | . 0040 | . 0097 | . 020 |
| 80 | . 00076 | . 0015 | . 0041 | . 010 | . 020 |
| 90 | . 00077 | . 0015 | . 0042 | . 010 | . 021 |
| 100 | . 00079 | . 0015 | . 0043 | . 010 | . 021 |
| 110 | . 00081 | . 0016 | . 0044 | . 011 | . 022 |
| 120 | 00084 | . 0016 | . 0045 | . 011 | . 023 |
| $\lambda_{b}=.0003\left[\left(\frac{S}{.3}\right)^{3}+1\right] \exp \left(\frac{T+273}{398}\right)$ |  |  |  |  |  |
| $T=$ Ambient Temperature $\left({ }^{\circ} \mathrm{C}\right)$ <br> $S=$ Ratio of Operating to Rated Voltage |  |  |  |  |  |
| Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage. |  |  |  |  |  |

Base Failure Rate - $\lambda_{0}$
( $T=150^{\circ} \mathrm{C}$ Max Rated)
(MIL-C-11015 Type C Rated Temperature)

| $T_{A}\left({ }^{\circ} C\right)$ | .1 | .3 | .5 | .7 | .9 |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 0 | .00059 | .0011 | .0032 | .0078 | .016 |
| 10 | .00061 | .0012 | .0033 | .008 | .016 |
| 20 | .00062 | .0012 | .0034 | .0082 | .017 |
| 30 | .00064 | .0012 | .0035 | .0084 | .017 |
| 40 | .00065 | .0013 | .0035 | .0086 | .018 |
| 50 | .00067 | .0013 | .0036 | .0088 | .018 |
| 60 | .00068 | .0013 | .0037 | .009 | .018 |
| 70 | .00070 | .0013 | .0038 | .0092 | .019 |
| 80 | .00072 | .0014 | .0039 | .0095 | .019 |
| 90 | .00073 | .0014 | .0040 | .0097 | .020 |
| 100 | .00075 | .0014 | .0041 | .0099 | .020 |
| 110 | .00077 | .0015 | .0042 | .010 | .021 |
| 120 | .00079 | .0015 | .0043 | .010 | .021 |
| 130 | .00081 | .0016 | .0044 | .011 | .022 |
| 140 | .00083 | .0016 | .0045 | .011 | .022 |
| 150 | .00085 | .0016 | .0046 | .011 | .023 |

$\lambda_{b}=.0003\left[\left(\frac{S}{3}\right)^{3}+1\right] \exp \left(\frac{T+273}{423}\right)$
$T=$ Ambient Temperature ( ${ }^{\circ} \mathrm{C}$ )
$S=$ Ratio of Operating to Rated Voltage
Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage.

NOTE: The rated temperature designation (type $A$. B , or C ) is shown in the part number, e.g.,
CKG1AW22M).

## MIL-HDBK-217F

10.10 CAPACITORS, FIXED, CERAMIC, GENERAL PURPOSE
Capacitance Factor $-\pi_{\mathrm{CV}}$

| Capacitance, $\mathrm{C}(\mathrm{pF})$ | $\pi_{\mathrm{CV}}$ |
| :---: | :---: |
| 6.0 | .50 |
| 240 | .75 |
| 3300 | 1.0 |
| 36,000 | 1.3 |
| 240,000 | 1.6 |
| $1,100,000$ | 1.9 |
| $4,300,000$ | 2.2 |
| $\pi_{\mathrm{CV}}=.41 \mathrm{C}^{0.11}$ |  |


| Environment Factor $-\pi_{E}$ |
| :--- |
| Environment $\pi_{\mathrm{E}}$ <br> $\mathrm{G}_{\mathrm{B}}$ 1.0 <br> $\mathrm{G}_{\mathrm{F}}$ 2.0 <br> $\mathrm{G}_{\mathrm{M}}$ 9.0 <br> $\mathrm{~N}_{\mathrm{S}}$ 5.0 <br> $\mathrm{~N}_{\mathrm{U}}$ 15 <br> $\mathrm{~A}_{\mathrm{K}}$ 4.0 <br> $\mathrm{~A}_{\mathrm{IF}}$ 4.0 <br> $\mathrm{~A}_{\mathrm{UC}}$ 8.0 <br> $\mathrm{~A}_{\mathrm{UF}}$ 12 <br> $\mathrm{~A}_{\mathrm{RW}}$ 20 <br> $\mathrm{~S}_{\mathrm{F}}$ .40 <br> $M_{\mathrm{F}}$ 13 <br> $\mathrm{M}_{\mathrm{L}}$ 34 <br> $\mathrm{C}_{\mathrm{L}}$ 610 |

Quality Factor $-\pi_{\mathrm{Q}}$

| Quality | $\pi_{\mathrm{Q}}$ |
| :--- | :---: |
| S | .030 |
| R | .10 |
| P | .30 |
| M | 1.0 |
| L | 3.0 |
| MIL-C-11015, Non-Est. Rel. | 3.0 |
| Lower | 10 |

MIL-HDBK-217F
10.11 CAPACITORS, FIXED, CERAMIC, TEMPERATURE COMPENSATING AND CHIP

SPECIFICATION
MIL-C-20
MIL-C-55681

STYLE CCR and CC CDR

## DESCRIPTION

Ceramic. Temperature Compensating, Est. and Non Est. Rel.
Ceramic, Chip, Est. Rel.

$$
\lambda_{\mathrm{p}}=\lambda_{\mathrm{b}} \pi_{C V} \pi_{\mathrm{Q}} \pi_{E}
$$

Base Failure Rate - $\lambda_{b}$
( $\mathrm{T}=85^{\circ} \mathrm{C}$ Max Rated)
(MIL-C-20 Styles CC 20, 25, 30, 32, 35, 45, 85, 95-97)

| $\mathrm{T}_{\mathbf{A}}{ }^{\circ} \mathrm{C}$ C) | Strese |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | 1 | . 3 | . 5 | 7 | 9 |
| 0 | . 00015 | . 00028 | . 00080 | 001 | 0040 |
| 10 | . 00022 | . 00042 | . 0012 | . 0029 | . 0059 |
| 20 | . 00033 | . 00063 | . 0018 | . 0043 | . 0088 |
| 30 | . 00049 | . 00094 | . 0026 | . 0064 | . 013 |
| 40 | . 00073 | . 0014 | . 0039 | . 0096 | . 020 |
| 50 | . 0011 | . 0021 | . 0059 | . 014 | . 029 |
| 60 | . 0016 | . 0031 | . 0088 | . 021 | . 044 |
| 70 | . 0024 | . 0046 | . 013 | . 032 | . 065 |
| 80 | . 0036 | . 0069 | . 019 | . 047 | . 097 |
| $\lambda_{b}=2.6 \times 10^{-9}\left[\left(\frac{S}{.3}\right)^{3}+1\right] \exp \left(14.3\left(\frac{T+273}{358}\right)\right)$ |  |  |  |  |  |
| $T=$ Ambient Temperature ( ${ }^{\circ} \mathrm{C}$ ) <br> S = Ratio of Operating to Rated Voltage |  |  |  |  |  |
| Operating voltage is the sum of applied D.C. voltage and poak A.C. voltage. |  |  |  |  |  |

Base Failure Rate - $\lambda_{b}$
( $\mathrm{T}=125^{\circ} \mathrm{C}$ Max Rated)
(MIL-C-20 Styles CC 5-9,13-19, 21, 22, 26, 27, 31, 33,
36, 37, 47, 50-57, 75-79, 81-83, CCR 05-09,13-19, 54-
57, 75-79, 81-83, 90; MIL-C-55681 All CDR Styles)

| $T_{A}\left({ }^{\circ} \mathrm{C}\right)$ | .1 | .3 | .5 | .7 | .9 |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 0 | .00005 | .00009 | .00027 | .00065 | .0013 |
| 10 | .00007 | .00014 | .00038 | .00093 | .0019 |
| 20 | .00010 | .00019 | .00055 | .0013 | .0027 |
| 30 | .00014 | .00028 | .00078 | .0019 | .0039 |
| 40 | .00021 | .00040 | .0011 | .0027 | .0056 |
| 50 | .00030 | .00057 | .0016 | .0039 | .008 |
| 60 | .00042 | .00082 | .0023 | .0056 | .011 |
| 70 | .00061 | .0012 | .0033 | .008 | .016 |
| 80 | .00087 | .0017 | .0047 | .011 | .023 |
| 90 | .0012 | .0024 | .0068 | .016 | .034 |
| 100 | .0018 | .0034 | .0097 | .024 | .048 |
| 110 | .0026 | .0049 | .014 | .034 | .069 |
| 120 | .0037 | .0071 | .020 | .048 | .099 |

$\lambda_{b}=2.6 \times 10^{-9}\left[\left(\frac{S}{3}\right)^{3}+1\right] \exp \left(14.3\left(\frac{T+273}{398}\right)\right.$
$T=$ Ambient Temperature ( ${ }^{\circ} \mathrm{C}$ )
$S=$ Ratio of Operating to Rated Voltage
Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage.

Capacitance Factor $-\pi_{C V}$

| Capacitance, $\mathrm{C}(\mathrm{pF})$ | $\pi_{\mathrm{CV}}$ |
| :---: | :---: |
| 1 | .59 |
| 7 | .75 |
| 81 | 1.0 |
| 720 | 1.3 |
| 4,100 | 1.6 |
| 17,000 | 1.9 |
| 58,000 | 2.2 |
| $\pi_{\mathrm{CV}}=.59 \mathrm{C}^{0.12}$ |  |



Environment Factor $-\pi_{E}$

| Environment | $\pi_{E}$ |
| :---: | :---: |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 2.0 |
| $G_{M}$ | 10 |
| $N_{S}$ | 5.0 |
| $N_{U}$ | 17 |
| $A_{I C}$ | 4.0 |
| $A_{I F}$ | 8.0 |
| $A_{U C}$ | 16 |
| $A_{U F}$ | 35 |
| $A_{R W}$ | 24 |
| $S_{F}$ | .50 |
| $M_{F}$ | 13 |
| $M_{L}$ | 610 |
| $C_{L}$ |  |

## MIL-HDBK-217F

## SPECIFICATION

STYLE
CSR

## DESCRIPTION

Tantalum Electrolytic (Solid), Est. Rel.

$$
\lambda_{p}=\lambda_{b} \pi_{C V} \pi_{S R} \pi_{Q} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

| Base Failure Rate - $\lambda_{b}$ |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $T_{A}\left({ }^{\circ} \mathrm{C}\right)$ | Stress |  |  |  |  |
|  | . 1 | . 3 | . 5 | . 7 | . 9 |
| 0 | . 0042 | . 0058 | . 012 | . 026 | . 051 |
| 10 | . 0043 | . 0060 | . 012 | . 027 | . 052 |
| 20 | . 0045 | . 0063 | . 013 | . 028 | . 055 |
| 30 | . 0048 | . 0067 | . 014 | . 030 | . 058 |
| 40 | . 0051 | . 0072 | . 015 | . 032 | . 083 |
| 50 | . 0057 | . 0079 | . 016 | . 035 | . 069 |
| 60 | . 0064 | . 009 | . 019 | . 040 | . 078 |
| 70 | . 0075 | . 011 | . 022 | . 047 | . 092 |
| 80 | . 0092 | . 013 | . 027 | . 058 | . 11 |
| 90 | . 012 | . 017 | . 034 | . 074 | . 14 |
| 100 | . 016 | . 023 | . 047 | . 10 |  |
| 110 | . 024 | . 034 | . 07 | . 15 |  |
| 120 | . 039 | . 054 | . 11 | . 24 |  |
| $\lambda_{b}=.00375\left[\left(\frac{S}{4}\right)^{3}+1\right] \exp \left(2.6\left(\frac{T+273}{398}\right)^{9}\right)$ |  |  |  |  |  |
| $T=$ Ambient Temperature ( ${ }^{\circ} \mathrm{C}$ ) <br> $S=$ Ratio of Operating to Rated Voltage |  |  |  |  |  |
| Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage. |  |  |  |  |  |

Series Resistance Factor - $\pi_{\text {SR }}$

| Circuit Resistance, CR (ohms/volt) | $\pi_{\text {SR }}$ |
| :--- | :--- |
| $>0.8$ | .066 |
| $>0.6$ to 0.8 | .10 |
|  | $>0.4$ to 0.6 |
| $>0.2$ to 0.4 | .13 |
|  | $>0.1$ to 0.2 |
| 0 to 0.1 | .20 |
| CR | $=\frac{.27}{\|c\|}$ Ett. Res. Between Cap. and Pwr. Supply |
| Voltage Applied to Capacitor |  |


| Capacitance Factor $-\pi_{\mathrm{CV}}$ |  |
| :---: | :---: |
| Capacitance, $\mathrm{C}(\mu \mathrm{F})$ | $\pi_{\mathrm{CV}}$ |
| .003 | 0.5 |
| .091 | .75 |
| 1.0 | 1.0 |
| 8.9 | 1.3 |
| 50 | 1.6 |
| 210 | 1.9 |
| 710 | 2.2 |
|  |  |
| $\pi_{\mathrm{CV}}=1.0 \mathrm{C}^{0.12}$ |  |


| Quality Factor $-\pi_{\mathrm{Q}}$ |  |
| :--- | :---: |
| Quality $\pi_{\mathrm{Q}}$ <br> D 0.0010 <br> S 0.010 <br> B 0.030 <br> R 0.030 <br> P 0.10 <br> M 0.30 <br> Lower 1.0 | 1.5 |


| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment $\pi_{E}$ <br> $G_{B}$ 1.0 <br> $G_{F}$ 2.0 <br> $G_{M}$ 8.0 <br> $N_{S}$ 5.0 <br> $N_{U}$ 14 <br> $A_{1 C}$ 4.0 <br> $A_{I F}$ 5.0 <br> $A_{U C}$ 12 <br> $A_{U F}$ 20 <br> $A_{R W}$ 24 <br> $S_{F}$ .40 <br> $M_{F}$ 11 <br> $M_{L}$ 29 <br> $C_{L}$ 530 |  |

## MIL-HDBK-217F

10.13 CAPACITORS, FIXED, ELECTROLYTIC, TANTALUM, NON-SOLID

| SPECIFICATION | STYLE | DESCRIPTION |
| :--- | :--- | :--- |
| MIL-C-3965 | CL | Tantalum, Electrolytic (Non-Solid) |
| MIL-C-39006 | CLR | Tamalum, Electrolytic (Non-Solid), Est. Rel. |

$$
\lambda_{p}=\lambda_{b} \pi_{C V} \pi_{C} \pi_{Q} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

Base Failure Rate - $\lambda_{b}$
(T $=85^{\circ} \mathrm{C}$ Max Rated)
(MIL-C-3965 Styles CL24-27, 34-37)

| $T_{A}\left({ }^{\circ} \mathrm{C}\right)$ | .1 | .3 | .5 | .7 | .9 |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 0 | .0021 | .0029 | .0061 | .013 | .026 |
| 10 | .0023 | .0032 | .0067 | .014 | .028 |
| 20 | .0026 | .0036 | .0075 | .016 | .031 |
| 30 | .0030 | .0042 | .0087 | .019 | .036 |
| 40 | .0036 | .0051 | .011 | .023 | .044 |
| 50 | .0047 | .0066 | .014 | .029 | .057 |
| 60 | .0065 | .0091 | .019 | .041 | .079 |
| 70 | .0098 | .014 | .029 | .062 | .12 |
| 80 | .017 | .023 | .048 | .10 | .20 |

Operating voltege is the sum of applied D.C. voltage and peak A.C. voltage.

Base Failure Rate - $\lambda_{b}$
( $T=125^{\circ} \mathrm{C}$ Max Rated)
(MIL-C-3965 Styles CL20-23, 30-33, 40-43, 46-56, 6467. 70-73; and all MIL-C-39006 Styles)

| $T_{A}\left({ }^{\circ} \mathrm{C}\right)$ | Stress |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | 1 | 3 | 5 | 7 | 9 |
| 0 | . 0018 | . 0026 | . 0053 | . 011 | 022 |
| 10 | . 0019 | . 0026 | . 0055 | . 012 | . 023 |
| 20 | . 0020 | . 0028 | . 0057 | . 012 | . 024 |
| 30 | . 0021 | . 0029 | . 0061 | 013 | 026 |
| 40 | . 0023 | . 0032 | . 0066 | . 014 | . 028 |
| 50 | . 0025 | . 0035 | . 0072 | . 016 | . 030 |
| 60 | . 0028 | . 0040 | . 0082 | . 018 | . 034 |
| 70 | . 0033 | . 0046 | . 0096 | . 021 | . 040 |
| 80 | . 0041 | . 0057 | . 012 | . 025 | . 049 |
| 90 | . 0052 | . 0073 | . 015 | . 033 | . 084 |
| 100 | . 0071 | . 010 | . 021 | . 045 |  |
| 110 | . 011 | . 015 | . 031 | . 066 |  |
| 120 | . 017 | . 024 | . 050 | . 11 |  |
| $\lambda_{b}=.00165\left[\left(\frac{S}{4}\right)^{3}+1\right] \exp \left(2.6\left(\frac{T+273}{398}\right)^{9.0}\right)$ |  |  |  |  |  |

$\mathrm{T}=$ Ambient Temperature $\left({ }^{\circ} \mathrm{C}\right)$
$S=$ Ratio of Operating to Rated Voltage
Operating vottage is the sum of applied D.C. vottage and peak A.C. voltage.

Base Failure Rate - $\lambda_{b}$
( $\mathrm{T}=175^{\circ} \mathrm{C}$ Max Rated)
(MIL-C-3965 Styles CL10, 13, 14, 16-18)

| $T_{A}\left({ }^{\circ} \mathrm{C}\right)$ | Stress |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | . 1 | . 3 | . 5 | . 7 | . 9 |
| 0 | . 0017 | . 0024 | . 0050 | . 011 | . 021 |
| 10 | . 0017 | . 0024 | . 0051 | . 011 | . 021 |
| 20 | . 0018 | . 0025 | . 0052 | . 011 | . 022 |
| 30 | . 0018 | . 0025 | . 0053 | . 011 | . 022 |
| 40 | . 0019 | . 0026 | . 0054 | . 012 | . 023 |
| 50 | . 0019 | . 0027 | . 0056 | 012 | . 023 |
| 60 | . 002 | . 0028 | . 0058 | . 013 | . 024 |
| 70 | . 0021 | . 0030 | . 0062 | . 013 | .026 |
| 80 | . 0023 | . 0032 | . 0066 | . 014 | . 028 |
| 90 | . 0025 | . 0035 | . 0072 | . 016 | . 030 |
| 100 | . 0028 | . 0039 | . 0080 | . 017 | . 034 |
| 110 | . 0032 | . 0044 | . 0092 | . 020 | . 039 |
| 120 | . 0037 | . 0052 | . 011 | . 023 |  |
| 130 | . 0046 | . 0064 | . 013 | . 029 |  |
| 140 | . 0059 | . 0082 | . 017 | . 037 |  |
| 150 | . 0079 | . 011 | . 023 | . 049 |  |
| 160 | . 011 | . 016 | . 033 | . 071 |  |
| 170 | . 018 | . 025 | . 051 |  |  |
| $\lambda_{b}=.00165\left[\left(\frac{S}{4}\right)^{3}+1\right] \exp \left(2.6\left(\frac{T+273}{448}\right)^{9.0}\right)$ |  |  |  |  |  |
| $\begin{aligned} & \mathrm{T}=\text { Ambient Temperature }\left({ }^{\circ} \mathrm{C}\right) \\ & \mathrm{S}=\text { Ratio of Operating to Rated Vottage } \end{aligned}$ |  |  |  |  |  |
|  |  |  |  |  |  |

Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage


$$
\pi_{\mathrm{CV}}=.82 \mathrm{C}^{0.066}
$$

| Construction Factor $-\pi_{\mathrm{C}}$ |
| :--- |
| Construction Type $\pi_{\mathrm{C}}$ <br> Slug, All Tantalum .30 <br> Foil, Hemetic * <br> Sug, Hermetic 1.0 <br> Foil, Non-Hermetic * 2.0 <br> Slug, Non-Hermetic * 2.5 |

*Type of Seal Identified as Follows:

1) MIL-C-3965 (CL) - Note Last Letter in Part Number: G - Hermetic E - Non-Hermetic

Example: CL10BC700TPG is Hermetic
2) MIL-C-39006 (CLR) - Consult Individual Part Specification Sheet (slash sheet) NOTE:

Foil Types - CL 20-25, 30-33, 40, 41, 51-54, 70-73
CLR 25, 27, 35, 37, 53, 71, 73
Slug Types - CL 10, 13, 14, 16, 17, 18, 55, 56,
64-66, 67
CLR 10, 14, 17, 65, 69, 89
All Tantalum - CL 26, 27, 34-37, 42, 43, 46-49 CLR 79
Quality Factor $-\pi_{\mathrm{Q}}$

| Quality | $\pi_{\mathrm{Q}}$ |
| :--- | :---: |
| S | .030 |
| R | .10 |
| P | .30 |
| M | 1.0 |
| L | 1.5 |
| MIL-C-3965, Non-Est. Rel. | 3.0 |
| Lower | 10 |

Environment Factor $-\pi_{E}$

| Environment | $\pi_{E}$ |
| :---: | :---: |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 2.0 |
| $G_{M}$ | 10 |
| $N_{S}$ | 6.0 |
| $N_{U}$ | 16 |
| $A_{1 C}$ | 4.0 |
| $A_{I F}$ | 8.0 |
| $A_{U C}$ | 14 |
| $A_{U F}$ | 30 |
| $A_{R W}$ | 23 |
| $S_{F}$ | .50 |
| $M_{F}$ | 13 |
| $M_{L}$ | 34 |
| $c_{L}$ | 610 |

## MIL-HDBK-217F

SPECIFICATION
MIL-C-39018

STYLE DESCRIPTION CUR and CU

Electrolytic, Aluminum Oxide, Est. Rel. and Non-Est. Rel.

$$
\lambda_{p}=\lambda_{b} \pi_{C V} \pi_{Q} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

Base Failure Rate $-\lambda_{b}$
( $\mathrm{T}=85^{\circ} \mathrm{C}$ Max Rated)
(MIL-C-39018 Style 71)

|  | Stress |  |  |  |  |
| :---: | :--- | :--- | :--- | :--- | :--- |
| $T_{A}\left({ }^{\circ} \mathrm{C}\right)$ | .1 | .3 | .5 | .7 | .9 |
| 0 | .0095 | .011 | .019 | .035 | .064 |
| 10 | .012 | .015 | .024 | .046 | .084 |
| 20 | .017 | .020 | .033 | .062 | .11 |
| 30 | .023 | .028 | .046 | .087 | .16 |
| 40 | .034 | .042 | .068 | .13 | .23 |
| 50 | .054 | .065 | .11 | .20 | .36 |
| 60 | .089 | .11 | .18 | .33 | .60 |
| 70 | .16 | .19 | .31 | .58 | 1.1 |
| 80 | .29 | .35 | .58 | 1.1 | 2.0 |

$\lambda_{b}=.00254\left[\left(\frac{S}{.5}\right)^{3}+1\right] \exp \left(5.09\left(\frac{T+273}{358}\right)^{5}\right)$
$\mathbf{T}=$ Ambient Temperature $\left({ }^{\circ} \mathrm{C}\right)$
$S \quad=\quad$ Ratio of Operating to Rated Voltage
Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage.

Base Faikure Rate $-\lambda_{b}$
( $\mathrm{T}=105^{\circ} \mathrm{C}$ Max Rated)
(MIL-C-39018 Styles 16 and 17)

| (MIL-C-39018 Styles 16 and 17) |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $T_{A}\left({ }^{\circ} \mathrm{C}\right)$ | .1 | .3 | .5 | .7 | .9 |
| 0 | .0070 | .0084 | .014 | .026 | .047 |
| 10 | .0085 | .010 | .017 | .031 | .057 |
| 20 | .011 | .013 | .021 | .040 | .072 |
| 30 | .014 | .017 | .027 | .051 | .094 |
| 40 | .019 | .022 | .037 | .069 | .13 |
| 50 | .026 | .031 | .052 | .097 | .18 |
| 60 | .038 | .046 | .076 | .14 | .26 |
| 70 | .059 | .071 | .12 | .22 | .40 |
| 80 | .095 | .11 | .19 | .35 | .64 |
| 90 | .16 | .20 | .32 | .61 | 1.1 |
| 100 | .30 | .36 | .59 | 1.1 | 2.0 |

$\lambda_{b}=.00254\left[\left(\frac{S}{5}\right)^{3}+1\right] \exp \left(5.09\left(\frac{T+273}{378}\right)^{5}\right)$
$\mathrm{T}=$ Ambient Temperature $\left({ }^{\circ} \mathrm{C}\right)$
$S=$ Ratio of Operating to Rated Voltage
Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage.

Base Failure Rate $-\lambda_{\mathrm{t}}$
( $T=125^{\circ} \mathrm{C}$ Max Rated)
(All MIL-C-39018 Styles Except 71, 16 and 17)

| $\mathrm{T}_{\mathrm{A}}\left({ }^{\circ} \mathrm{C}\right)$ | Stress |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | . 1 | . 3 | . 5 | . 7 | . 9 |
| 0 | . 0055 | . 0067 | . 011 | . 021 | . 038 |
| 10 | . 0065 | . 0078 | . 013 | . 024 | . 044 |
| 20 | . 0077 | . 0093 | . 015 | . 029 | . 052 |
| 30 | . 0094 | . 011 | . 019 | . 035 | . 064 |
| 40 | . 012 | . 014 | . 023 | . 044 | . 080 |
| 50 | . 015 | . 019 | . 030 | 057 | . 10 |
| 60 | . 021 | . 025 | . 041 | . 077 | . 14 |
| 70 | . 029 | . 035 | . 057 | . 11 | . 20 |
| 80 | . 042 | . 050 | . 083 | . 16 | . 28 |
| 90 | . 064 | . 077 | . 13 | . 24 | . 43 |
| 100 | . 10 | . 12 | . 20 | . 38 |  |
| 110 | . 17 | . 21 | . 34 | . 63 |  |
| 120 | . 30 | . 37 | . 60 | 1.1 |  |
| $\lambda_{b}=.00254\left[\left(\frac{S}{.5}\right)^{3}+1\right] \exp \left(5.09\left(\frac{T+273}{398}\right)^{5}\right)$ |  |  |  |  |  |
| T $=$ Ambient Temperature ( ${ }^{\circ} \mathrm{C}$ ) |  |  |  |  |  |
| S - Ratio of Operating to Rated Voltage |  |  |  |  |  |
| Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage. |  |  |  |  |  |


| Capacitance Factor - $\pi_{\text {ch }} \mathrm{CV}$ |  |
| :---: | :---: |
| Capaciance, C ( $\mu$ F) | ${ }^{\pi} \mathrm{CV}$ |
| 2.5 | 40 |
| 55 | 70 |
| 400 | 1.0 |
| 1700 | 1.3 |
| 5500 | 1.6 |
| 14,000 | 1.9 |
| 32,000 | 2.2 |
| 65,000 | 2.5 |
| 120,000 | 2.8 |
| ${ }^{\pi} C V=34 C^{0.18}$ |  |

Environment Factor $-\pi_{E}$

| Environmeni | $\pi_{E}$ |
| :---: | :---: |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 2.0 |
| $G_{M}$ | 12 |
| $N_{S}$ | 6.0 |
| $N_{U}$ | 17 |
| $A_{I C}$ | 10 |
| $A_{I F}$ | 12 |
| $A_{U C}$ | 28 |
| $A_{U F}$ | 35 |
| $A_{R W}$ | 27 |
| $S_{F}$ | .50 |
| $M_{F}$ | 14 |
| $M_{L}$ | 38 |
| $C_{L}$ | 690 |


| Cuality | $\pi_{\mathrm{Q}}$ |
| :--- | :---: |
| S | .030 |
| R | .10 |
| P | .30 |
| M | 1.0 |
| Non-Est. Rei. | 3.0 |
| Lower | 10 |

### 10.15 CAPACITORS, FIXED, ELECTROLYTIC (DRY), ALUMINUM

## SPECIFICATION

 MIL-C-62StyLE
CE

DESCRIPTION
Aluminum, Dry Electrolyte, Polarized

$$
\lambda_{p}=\lambda_{b} \pi_{C v} \pi_{Q} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

Base Faiture Rate - $\lambda_{t}$
( $T=85^{\circ} \mathrm{C}$ Max Rated)

| $T_{A}\left({ }^{\circ} \mathrm{C}\right)$ | .1 | .3 | .5 | .7 | .9 |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 0 | .0064 | .0074 | .011 | .020 | .034 |
| 10 | .0078 | .009 | .014 | .024 | .042 |
| 20 | .0099 | .011 | .017 | .030 | .053 |
| 30 | .013 | .015 | .023 | .040 | .070 |
| 40 | .018 | .021 | .031 | .055 | .098 |
| 50 | .026 | .030 | .046 | .08 | .14 |
| 60 | .041 | .047 | .071 | .12 | .22 |
| 70 | .068 | .078 | .12 | .21 | .36 |
| 80 | .120 | .14 | .21 | .37 | .65 |
| Stress |  |  |  |  |  |
| $\lambda_{6}=.0028\left[\left(\frac{S}{.55}\right)^{3}+1\right] \exp \left(4.09\left(\frac{T+273}{358}\right)\right.$ | $5.9)$ |  |  |  |  |

$T \quad$ - Ambient Temperature $\left({ }^{\circ} \mathrm{C}\right)$
S - Ratio of Operating to Rated Voltage
Operating voltage is the sum of applied D.C. voltage año peak A.C. voltage.

| Capacitance Factor - $\pi_{\mathrm{CV}}$ |  |
| :---: | :---: |
| Capacitance, C ( $\mu \mathrm{F}$ ) | $\pi_{\text {cV }}$ |
| 3.2 | 40 |
| 62 | 70 |
| 400 | 1.0 |
| 1600 | 1.3 |
| 4800 | 1.6 |
| 12,000 | 1.9 |
| 26,000 | 2.2 |
| 50,000 | 2.5 |
| 91,000 | 2.8 |
| $\pi_{C V}=.32 C^{0.19}$ |  |


| Quality Factor $-\pi_{\mathrm{Q}}$ |  |
| :--- | :---: |
| Quality | $\pi_{\mathrm{Q}}$ |
| MIL-SPEC | 3.0 |
| Lower | 10 |


| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\pi_{E}$ |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 2.0 |
| $G_{M}$ | 12 |
| $N_{S}$ | 6.0 |
| $N_{U}$ | 17 |
| $A_{I C}$ | 10 |
| $A_{I F}$ | 12 |
| $A_{U C}$ | 28 |
| $A_{U F}$ | 35 |
| $A_{R W}$ | 27 |
| $S_{F}$ | .50 |
| $M_{F}$ | 14 |
| $M_{L}$ | 38 |
| $C_{L}$ | 690 |

## SPECIFICATION MIL-C. 81

STYLE CV

DESCRIPTION Variable, Ceramic

$$
\lambda_{P}=\lambda_{b} \pi_{Q} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

Base Failure Rate $-\lambda_{0}$
( $T=85^{\circ} \mathrm{C}$ Max Rated)
(MIL-C-81 Styles CV 11, 14, 21, 31, 32, 34, 40, 41)

| $T_{A}\left({ }^{\circ} \mathrm{C}\right)$ | .1 | .3 | .5 | .7 | .9 |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 0 | .0030 | .016 | .066 | .18 | .37 |
| 10 | .0031 | .017 | .069 | .18 | .39 |
| 20 | .0033 | .018 | .073 | .20 | .41 |
| 30 | .0036 | .020 | .080 | .21 | .45 |
| 40 | .0041 | .022 | .089 | .24 | .50 |
| 50 | .0047 | .026 | .10 | .28 | .59 |
| 60 | .0058 | .031 | .13 | .34 | .72 |
| 70 | .0076 | .041 | .17 | .45 | .94 |
| 80 | .011 | .058 | .24 | .63 | 1.3 |
| $=$ |  |  |  |  |  |
| $\lambda_{b}=.00224\left[\left(\frac{S}{.17}\right)^{3}+1\right]$ exp $\left(1.59\left(\frac{T+273}{358}\right)^{10.1}\right)$ |  |  |  |  |  |
| $T$ | $=$ Ambient Temperature ( $\left.{ }^{\circ} \mathrm{C}\right)$ |  |  |  |  |
| S | $=$ |  |  |  |  |
| Ratio of Operating to Rated Voltage |  |  |  |  |  |
| Operating voltage is the sum of applied D.C. voltage |  |  |  |  |  |
| and peak A.C. voltage. |  |  |  |  |  |

Base Fallure Rate $-\lambda_{b}$
( $\mathrm{T}=125^{\circ} \mathrm{C}$ Max Rated)
(MIL-C-81 Styles CV 35, 36)

| MIL-C-81 Styles CV 35, 36) |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $T_{A}{ }^{\circ}$ C) | .1 | .3 | .5 | .7 | .9 |
| 0 | .0028 | .015 | .061 | .16 | .35 |
| 10 | .0028 | .015 | .062 | .17 | .35 |
| 20 | .0029 | .016 | .064 | .17 | .36 |
| 30 | .0030 | .016 | .066 | .18 | .37 |
| 40 | .0031 | .017 | .068 | .18 | .39 |
| 50 | .0033 | .018 | .072 | .19 | .41 |
| 60 | .0035 | .019 | .077 | .21 | .44 |
| 70 | .0038 | .021 | .084 | .23 | .48 |
| 80 | .0043 | .023 | .095 | .25 | .54 |
| 90 | .0050 | .027 | .11 | .30 | .63 |
| 100 | .0062 | .033 | .14 | .36 | .76 |
| 110 | .0079 | .043 | .17 | .47 | .98 |
| 120 | .011 | .059 | .24 | .64 | 1.4 |

$\lambda_{b}=.00224\left[\left(\frac{S}{.17}\right)^{3}+1\right] \exp \left(1.59\left(\frac{T+273}{398}\right)^{10.1}\right)$
$T=$ Ambient Temperature $\left({ }^{\circ} \mathrm{C}\right)$
$S=$ Ratio of Operating to Rated Voltage
Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage.


| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\pi_{E}$ |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 3.0 |
| $G_{M}$ | 13 |
| $N_{S}$ | 8.0 |
| $N_{U}$ | 24 |
| $A_{1 C}$ | 6.0 |
| $A_{I F}$ | 10 |
| $A_{U C}$ | 37 |
| $A_{U F}$ | 70 |
| $A_{R W}$ | 36 |
| $S_{F}$ | .40 |
| $M_{F}$ | 20 |
| $M_{L}$ | 52 |
| $C_{L}$ | 950 |

MIL-HDBK-217F
10.17 CAPACITORS, VARIABLE, PISTON TYPE

## SPECIFICATION <br> MII-C-14409

Style PC

DESCRIPTION
Variable, Piston Type, Tubular Trimmer

$$
\lambda_{p}=\lambda_{b} \pi_{Q} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

| Base Failure Rate - $\lambda_{0}$ ( $T=125^{\circ} \mathrm{C}$ Max Rated) (MIL-C-14409 Styles G, H, J, L, T) |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | Stress |  |  |  |  |
| $\mathrm{T}_{\mathrm{A}}\left({ }^{\circ} \mathrm{C}\right)$ | . 1 | . 3 | . 5 | . 7 | 9 |
| 0 | . 0030 | . 0051 | . 013 | . 031 | . 063 |
| 10 | . 0041 | . 0070 | . 018 | . 042 | . 085 |
| 20 | . 0055 | . 0094 | . 024 | . 057 | . 11 |
| 30 | . 0075 | . 013 | . 033 | . 077 | . 16 |
| 40 | . 010 | . 017 | . 044 | . 10 | . 21 |
| 50 | . 014 | . 024 | . 060 | . 14 | 29 |
| 60 | . 019 | . 032 | . 082 | . 19 | . 39 |
| 70 | . 025 | . 043 | . 11 | . 26 | . 53 |
| 80 | . 034 | . 059 | . 15 | . 35 | . 71 |
| 90 | . 047 | . 079 | . 20 | . 48 | . 96 |
| 100 | . 063 | . 11 | . 27 | . 65 | 1.3 |
| 110 | . 086 | . 15 | . 37 | . 88 | 1.8 |
| 120 | . 12 | . 20 | . 51 | 1.2 | 2.4 |
| $\begin{aligned} & \lambda_{\mathrm{b}}=7.3 \times 10^{-7}\left[\left(\frac{\mathrm{~S}}{.33}\right)^{3}+1\right] \exp \left(12.1\left(\frac{\mathrm{~T}+273}{398}\right)\right) \\ & \left.\mathrm{T}=\text { Ambient Temperature ( }{ }^{\circ} \mathrm{C}\right) \\ & \mathrm{S}=\text { Ratio of Operating to Rated Voltage } \\ & \text { Operating voltage is the sum of applied D.C. voltage } \\ & \text { and peak A.C. voltage. } \end{aligned}$ |  |  |  |  |  |
|  |  |  |  |  |  |

Base Failure Rate - $\lambda_{b}$
( $T=150^{\circ} \mathrm{C}$ Max Rated)
(MiL-C-14409 Characteristic Q)

|  | Stress |  |  |  |  |
| ---: | :---: | :---: | :---: | :---: | :---: |
| 0 | .1 | .3 | .5 | .7 | .9 |
| 0 | .0019 | .0032 | .0081 | .019 | .038 |
| 10 | .0025 | .0042 | .011 | .025 | .051 |
| 20 | .0033 | .0056 | .014 | .034 | .068 |
| 30 | .0044 | .0074 | .019 | .045 | .09 |
| 40 | .0058 | .0039 | .025 | .060 | .12 |
| 50 | .0077 | .013 | .034 | .079 | .16 |
| 60 | .010 | .018 | .045 | .11 | .21 |
| 70 | .014 | .023 | .060 | .14 | .28 |
| 80 | .018 | .031 | .079 | .19 | .38 |
| 90 | .024 | .041 | .11 | .25 | .50 |
| 100 | .032 | .055 | .14 | .33 | .67 |
| 110 | .043 | .073 | .19 | .44 | .89 |
| 120 | .057 | .097 | .25 | .59 | 1.2 |
| 130 | .076 | .13 | .33 | .78 | 1.6 |
| 140 | .10 | .17 | .44 | 1.0 | 2.1 |
| 150 | .13 | .23 | .59 | 1.4 | 2.8 |

$\lambda_{b}=7.3 \times 10^{-7}\left[\left(\frac{S}{.33}\right)^{3}+1\right] \exp \left(12.1\left(\frac{T+273}{423}\right)\right)$
$T=$ Ambient Temperature ( ${ }^{\circ} \mathrm{C}$ )
$S=$ Ratio of Operating to Rated Vohage
Operating voltage is the sum of applied D.C. vothage and peak A.C. voltage.

## MIL-HDBK-217F

10.18 CAPACITORS, VARIABLE, AIR TRIMMER

SPECIFICATION
M!L-C-92

STYLE
CT

DESCRIPTION
Variable, Air Trimmer

$$
\lambda_{\mathrm{P}}=\lambda_{\mathrm{D}} \pi_{\mathrm{Q}} \pi_{\mathrm{E}} \text { Failures } / 10^{6} \text { Hours }
$$

| Base Failure Rate $-\lambda_{b}$ ( $T=85^{\circ} \mathrm{C}$ Max Rated) |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | Stress |  |  |  |  |
| $T_{A}\left({ }^{\circ} \mathrm{C}\right)$ | . 1 | . 3 | . 5 | . 7 | . 9 |
| 0 | . 0074 | . 013 | . 032 | . 076 | . 15 |
| 10 | . 010 | . 017 | . 044 | . 10 | . 21 |
| 20 | . 014 | . 023 | . 059 | . 14 | . 28 |
| 30 | . 018 | . 031 | . 08 | . 19 | . 38 |
| 40 | . 025 | . 042 | . 11 | . 26 | . 52 |
| 50 | . 034 | . 057 | . 15 | . 35 | . 70 |
| 60 | . 046 | . 078 | . 20 | 47 | 94 |
| 70 | . 062 | . 10 | . 27 | . 63 | 1.3 |
| 80 | . 083 | . 14 | . 36 | . 85 | 1.7 |

$\lambda_{b}=1.92 \times 10^{-6}\left[\left(\frac{\mathrm{~S}}{.33}\right)^{3}+1\right] \exp \left(10.8\left(\frac{T+273}{358}\right)\right)$

| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\pi_{E}$ |
| $G_{B}$ | 1.0 |
| $G_{P}$ | 3.0 |
| $G_{M}$ | 13 |
| $N_{S}$ | 8.0 |
| $N_{U}$ | 24 |
| $A_{I C}$ | 6.0 |
| $A_{I F}$ | 10 |
| $A_{U C}$ | 37 |
| $A_{U F}$ | 70 |
| $A_{p W}$ | 36 |
| $S_{F}$ | .50 |
| $M_{F}$ | 20 |
| $M_{L}$ | 52 |
| $C_{L}$ | 950 |

$T=A \quad$ Ambient Temperature ( ${ }^{\circ} \mathrm{C}$ )
$S=$ Ratio of Operating to Rated Voltage
Operating voltage is the sum of applied D.C. voltage and peak A.C. voltage.

| Quality Factor $-\pi_{\mathrm{Q}}$ |  |
| :--- | :---: |
| Quality | $\pi_{\mathrm{Q}}$ |
| Miil-SPEC | 5 |
| Lower | 20 |

MIL-HDBK-217F
10.19 CAPACITORS, VARIABLE AND FIXED, GAS OR VACUUM

| SPECIFICATION | STYLE | DESCRIPTION |
| :--- | :--- | :--- |
| M!IL-CI 23183 | CG | Gas or Vacium Dielectric, Fixed and Variable, Ceramic or |
| Glass Envelope |  |  |

Base Failure Rate - $\boldsymbol{\lambda}_{\boldsymbol{b}}$

$$
\text { ( } \mathrm{T}=85^{\circ} \mathrm{C} \text { Max Rated) }
$$

(Styles CG 20, 21, 30, 31, 32, 40-44, 51, 60-64,

| $T^{\circ} \mathrm{C}$ | .1 | .3 | Siress |  |  |  |  |  |
| ---: | ---: | ---: | ---: | ---: | ---: | :---: | :---: | :---: |
| 0 | .015 | .081 | .33 | .89 | 1.9 |  |  |  |
| 10 | .016 | .084 | .34 | .92 | 1.9 |  |  |  |
| 20 | .017 | .090 | .37 | .98 | 2.1 |  |  |  |
| 30 | .018 | .098 | .40 | 1.1 | 2.2 |  |  |  |
| 40 | .020 | .11 | .45 | 1.2 | 2.5 |  |  |  |
| 50 | .024 | .13 | .52 | 1.4 | 2.9 |  |  |  |
| 60 | .029 | .16 | .64 | 1.7 | 3.6 |  |  |  |
| 70 | .038 | .20 | .83 | 2.2 | 4.7 |  |  |  |
| 80 | .054 | .29 | 1.2 | 3.2 | 6.6 |  |  |  |

Base Faiture Rate - $\lambda_{b}$
( $\mathrm{T}=100^{\circ} \mathrm{C}$ Max Rated)
(Styles CG 65, 66)

| Siress |  |  |  |  |  |
| ---: | :---: | :---: | :---: | :---: | :---: |
| $T C$ | .1 | .3 | .5 | .7 | .9 |
| 0 | .014 | .078 | .30 | .85 | 1.8 |
| 10 | .015 | .080 | .33 | .87 | 1.8 |
| 20 | .015 | .084 | .34 | .91 | 1.9 |
| 30 | .016 | .088 | .36 | .96 | 2.0 |
| 40 | .018 | .095 | .39 | 1.0 | 2.2 |
| 50 | .020 | .11 | .43 | 1.2 | 2.4 |
| 60 | .022 | .12 | .49 | 1.3 | 2.8 |
| 70 | .027 | .14 | .59 | 1.6 | 3.3 |
| 80 | .034 | .18 | .74 | 2.0 | 4.2 |
| 90 | .045 | .24 | .99 | 2.7 | 5.6 |
| 100 | .066 | .36 | 1.5 | 3.9 | 8.2 |
|  |  |  |  |  |  |
| $\lambda_{b}=.0112\left[\left(\frac{S}{.17}\right)^{3}+1\right] \exp \left(1.59\left(\frac{T+273}{373}\right) 10.1\right)$ |  |  |  |  |  |

$T=A m b i e n t$ Temperature $\left({ }^{\circ} \mathrm{C}\right)$
$S=$ Patio of Operating to Rated Vohage
Operating voltage is the sum of applied D.C. voltage and peak A.C. voliage.


| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment $\pi_{E}$ <br> $G_{B}$ 1.0 <br> $G_{F}$ 3.0 <br> $G_{M}$ 14 <br> $N_{S}$ 8.0 <br> $N_{U}$ 27 <br> $A_{I C}$ 10 <br> $A_{I F}$ 18 <br> $A_{U C}$ 70 <br> $A_{U F}$ 108 <br> $A_{R W}$ 40 <br> $S_{F}$ .50 <br> $M_{F}$ N/A <br> $M_{L}$ N/A <br> $C_{L}$ N/A |  |

## MIL-HDBK-217F

## Example

Given: A 400 VDC rated capacitor type COO9A1KE153K3 is being used in a fixed ground environment, $55^{\circ} \mathrm{C}$ component ambient temperature, and 200 VDC applied with 50 Vrms @ 60 Hz . The capacitor is being procured in full accordance with the applicable specification.

The letters "CQ" in the type designation indicate that the specification is MIL-C-19978 and that it is a NonEstablished Reliability quality level. The $1 s t$ " $K$ " in the designation indicates characteristic $K$. The " $E$ " in the designation corresponds to a 400 volt DC rating. The " 153 " in the designation expresses the capacitance in picofarads. The first two digits are significant and the third is the number of zeros to follow. Therefore, this capacitor has a capacitance of 15,000 picofarads. (NOTE: Pico $=10^{-12}, \mu=10^{-6}$ )

The appropriate model for CQ style capacitors is given in Section 10.3. Based on the given information the following model factors are determined from the tables shown in Section 10.3. Voltage stress ratio must account for both the applied DC volts and the peak AC voltage, hence,

$$
\begin{array}{ll}
S=.68 & S=\frac{D C \text { Volts Applied }+\sqrt{2(A C ~ V}}{\text { DC Rated Voltage }} \\
\lambda_{b}=.0082 & \frac{200+\sqrt{2}(50)}{400}=.68 \\
\pi_{C V}=.94 & \begin{array}{l}
\text { Substitute } S=.68 \text { and } T_{A}=55^{\circ} \mathrm{C} \text { into } \\
\text { with Characteristic } K \lambda_{b} \text { Table. }
\end{array} \\
\pi_{\mathrm{Q}}=10 & \text { Use Table Equation (Note } 15,000 \mathrm{pF}= \\
\pi_{\mathrm{E}}=2.0 & \\
\lambda_{\mathrm{P}}=\lambda_{\mathrm{B}} \pi_{\mathrm{CV}} \pi_{\mathrm{Q}} \pi_{\mathrm{E}}=(.0082)(.94)(10)(2)=.15 \text { Failures } / 10^{6} \text { Hours }
\end{array}
$$

SPECIFICATION
MIL-T-27
MIL-T-21038
MIL-T-55631
STYLE
TF
TP
-

DESCRIPTION<br>Audio, Power and High Power Pulse<br>Low Power Pulse<br>IF, RF and Discriminator

$$
\lambda_{p}=\lambda_{b} \pi_{Q} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

Base Failure Rate - $\lambda_{b}$

|  | Maximum Rated Operating Temperature ( ${ }^{\circ} \mathrm{C}$ ) |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{T}_{\mathrm{HS}}\left({ }^{\circ} \mathrm{C}\right)$ | $85^{1}$ | $105^{2}$ | $130^{3}$ | 1554 | $170^{5}$ | $>170^{6}$ |
| 30 | . 0024 | . 0023 | . 0022 | . 0021 | . 0018 | . 0016 |
| 35 | . 0026 | . 0023 | . 0023 | . 0022 | . 0018 | . 0016 |
| 40 | . 0028 | . 0024 | . 0024 | . 0022 | . 0019 | . 0016 |
| 45 | . 0032 | . 0025 | . 0025 | . 0022 | . 0019 | . 0016 |
| 50 | . 0038 | . 0027 | . 0026 | . 0023 | . 0020 | . 0017 |
| 55 | . 0047 | . 0029 | . 0027 | . 0023 | . 0020 | . 0017 |
| 60 | . 0060 | . 0032 | . 0029 | . 0023 | . 0021 | . 0017 |
| 65 | . 0083 | . 0035 | . 0030 | . 0024 | . 0021 | . 0017 |
| 70 | . 012 | . 0040 | . 0033 | . 0025 | . 0022 | . 0017 |
| 75 | . 020 | . 0047 | . 0035 | . 0026 | . 0023 | . 0017 |
| 80 | . 036 | . 0057 | . 0039 | . 0027 | . 0024 | . 0017 |
| 85 | . 075 | . 0071 | . 0043 | . 0028 | . 0024 | . 0017 |
| 90 |  | . 0093 | . 0048 | . 0029 | . 0025 | . 0018 |
| 95 |  | . 013 | . 0054 | . 0031 | . 0026 | . 0018 |
| 100 |  | . 019 | . 0062 | . 0033 | . 0027 | . 0018 |
| 105 |  | . 030 | . 0072 | . 0035 | . 0028 | . 0018 |
| 110 |  |  | . 0085 | . 0038 | . 0030 | . 0019 |
| 115 |  |  | . 010 | . 0042 | . 0031 | . 0019 |
| 120 |  |  | . 013 | . 0046 | . 0032 | . 0019 |
| 125 |  |  | . 016 | . 0052 | . 0034 | . 0020 |
| 130 |  |  | . 020 | . 0059 | . 0036 | . 0020 |
| 135 |  |  |  | . 0068 | . 0038 | . 0021 |
| 140 |  |  |  | . 0079 | . 0040 | . 0021 |
| 145 |  |  |  | . 0095 | . 0042 | . 0022 |
| 150 |  |  |  | . 011 | . 0044 | . 0023 |
| 155 |  |  |  | . 014 | . 0047 | . 0024 |
| 160 |  |  |  |  | . 0050 | . 0025 |
| 165 |  |  |  |  | . 0053 | . 0026 |
| 170 175 |  |  |  |  | . 0056 | . 0027 |
| 175 180 |  |  |  |  |  | . 0029 |
| 180 185 |  |  |  |  |  | $\begin{array}{r} .0030 \\ .0032 \\ \hline \end{array}$ |

NOTE: The models are valid only if $T_{H S}$ is not above the temperature rating for a given insulation class.
$1 \lambda_{\mathrm{b}}=.0018 \exp \left(\frac{T_{H S}+273}{329}\right)^{155}$
MiL-T-27 Insulation Class Q. MIL-T-21038 insulation Class Q, and MIL-T-55631 insulation Class O.•
$2 \lambda_{b}=.002 \exp \left(\frac{T_{H S}+273}{352}\right)^{14}$
MIL-T-27 Insulation Class R, MIL-T-21038 Insulation Class R, and MIL-T-55631 Insulation Class A.-
$3 \quad \lambda_{b}=.0018 \exp \left(\frac{T_{H S}+273}{364}\right)^{8.7}$
$4 \quad \lambda_{b}=.002 \exp \left(\frac{T_{H S}+273}{400}\right)^{10}$
$5 \lambda_{b}=.00125 \exp \left(\frac{T_{H S}+273}{398}\right)^{38}$
$6 \quad \lambda_{b}=.00150 \exp \left(\frac{T_{H S}+273}{477}\right)^{8.4}$
$T_{H S}=$ Hol Spoi Temperature ( ${ }^{\circ} \mathrm{C}$ ). See Section 11.3.
MIL-T-27 Insulation Class S. MIL-T-21038 Insulation Class S, and MIL-T-55631 Insulation Class B.*
MIL-T-27 Insulation Class V, MIL-T-21038 Insulation Class T, and MIL-T-55631 Insulation Class C.

Mil -T-27 Insulation Class T and MIL-T-21038 Insulation Class U.*

MIL-T-27 Insulation Class $U$ and MIL-T-21038 Insulation Class V.
-Refer to Transformer Applicution Note for Determination of Insulation Class

| Quality Factor - $\pi_{\mathrm{Q}}$ |
| :--- |
| Family Type MIL-SPEC Lower <br> Pulse Transformers 1.5 5.0 <br> Audio Transformers 3.0 7.5 <br> Power Transformers and Filters 8.0 30 <br> RF Transformers 12 30 <br> - Refor to Transformer Appllcation Note for   <br> Determination of Famlly Type   |


| Environment Factor $-\pi_{E}$ |
| :---: | :---: |
| Environment $\pi_{E}$ <br> $G_{B}$ 1.0 <br> $G_{F}$ 6.0 <br> $G_{M}$ 12 <br> $N_{S}$ 5.0 <br> $N_{U}$ 16 <br> $A_{I C}$ 6.0 <br> $A_{I F}$ 8.0 <br> $A_{U C}$ 7.0 <br> $A_{U F}$ 9.0 <br> $A_{R W}$ 24 <br> $S_{F}$ .50 <br> $M_{F}$ 13 <br> $M_{L}$ 34 <br> $C_{L}$ 610 |



Family Type Codes Are:
Power Transformer and Fiter: 01 thru 09, 37 thru 41
Audio Transformer: 10 thru 21, 50 thru 53
Pulse Transformer: 22 thru 36, 54
MIL-T-21038 Example Designation

MIL-T-55631. The Transformers are Designated with the following Types, Grades and Classes.

| Type 1 | Intermediate Frequency Transformer |
| :---: | :---: |
| Type II | Radio Frequency Transformer |
| Type III | Discriminator Transformer |
| Grade 1 | For Use When Immersion and Moisture Resistance Tests are Required |
| Grade 2 | For Use When Moisture Resistance Test is Required |
| Grade 3 | For Use in Sealed Assemblies |
| Class O | - $85^{\circ} \mathrm{C}$ Maximum Operating Temperature |
| Class A | - $105^{\circ} \mathrm{C}$ Maximum Operating Temperature |
| Class B | $125^{\circ} \mathrm{C}$ Maximum Operating Temperature |
| Class C | $>125^{\circ} \mathrm{C}$ Maximum Operating <br> Temperature |

The class denotes the maximum operating temperature (temperature rise plus maximum ambient temperature).

## SPECIFICATION <br> MIL-C-15305

## STYLE <br> - <br> -

$$
\lambda_{p}=\lambda_{b} \pi_{C} \pi_{Q} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

## DESCRIPTION

Fixed and Variable, RF
Molded, RF, Est. Rel.

| Base Failure Rate $-\lambda_{b}$ |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
| $T_{H S}\left({ }^{\circ} \mathrm{C}\right)$ | $85^{1}$ | $105^{2}$ | $125^{3}$ | $150^{4}$ |
| 30 | .00044 | .00043 | .00039 | .00037 |
| 35 | .00048 | .00044 | .0004 | .00037 |
| 40 | .00053 | .00046 | .00042 | .00037 |
| 45 | .0006 | .00048 | .00043 | .00038 |
| 50 | .00071 | .00051 | .00045 | .00038 |
| 55 | .00087 | .00055 | .00048 | .00039 |
| 60 | .0011 | .0006 | .00051 | .0004 |
| 65 | .0015 | .00067 | .00054 | .00041 |
| 70 | .0023 | .00076 | .00058 | .00042 |
| 75 | .0037 | .00089 | .00063 | .00043 |
| 80 | .0067 | .0011 | .00069 | .00044 |
| 85 | .014 | .0013 | .00076 | .00046 |
| 90 |  | .0018 | .00085 | .00047 |
| 95 |  | .0024 | .00096 | .0005 |
| 100 |  | .0036 | .0011 | .00052 |
| 105 |  | .0057 | .0013 | .00055 |
| 110 |  |  | .0015 | .00059 |
| 115 |  |  | .0018 | .00063 |
| 120 |  |  | .0022 | .00068 |
| 125 |  |  | .0028 | .00075 |
| 130 |  |  |  | .00083 |
| 135 |  |  |  | .00093 |
| 140 |  |  |  | .0011 |
| 145 |  |  |  | .0014 |
| 150 |  |  |  |  |

NOTE: The models are valid only if $T_{H S}$ is not above the temperature rating for a given insulation class.

$$
\begin{array}{ll}
\text { 1. } \lambda_{\mathrm{b}}=.000335 \exp \left(\frac{\mathrm{~T}_{\mathrm{HS}}+273}{329}\right)^{15.6} & \begin{array}{l}
\text { MIL.C-15305 } \\
\text { Insulation Class } \mathrm{O} .
\end{array} \\
2 & \lambda_{\mathrm{b}}=.000379 \exp \left(\frac{T_{H S}+273}{352}\right)^{14} \quad \begin{array}{l}
\text { MIL-C-15305 } \\
\text { Insulation Class } A \text { and } \\
\text { MIL-. } \\
\text { Insulaton Class } A .
\end{array}
\end{array}
$$

3

$$
\begin{aligned}
& \lambda_{\mathrm{b}}=.000319 \exp \left(\frac{T_{\mathrm{HS}}+273}{384}\right)^{8.7} \quad \begin{array}{l}
\text { MIL-C. } 15305 \\
\text { Insulation Class B and } \\
\text { MLI-C. } 39010 \\
\text { Insulation Class B. }
\end{array} \\
& \lambda_{\mathrm{b}}=00035 \exp \left(\frac{T_{\mathrm{HS}}+273}{409}\right)^{10} \quad \begin{array}{l}
\text { MLL-C. } 15305 \\
\text { Insulation Class } \mathrm{C} \text { and } \\
\text { MIL-C. } 39010 \\
\text { Insulation Class } \mathrm{F}:
\end{array}
\end{aligned}
$$

$$
T_{H S}=\text { Hot Spol Temperature }\left({ }^{\circ} \mathrm{C}\right) \text {, See Section } 11.3 .
$$

-Refor to Coil Appilication Note tor Dotermination of Insulation Class.

| Quality Factor $-\pi_{\mathrm{Q}}$ |  |
| :---: | :---: |
| Quality | $\pi_{\mathrm{Q}}$ |
| S | .03 |
| R | .10 |
| P | .30 |
| M | 1.0 |
| MIL-C-15305 | 4.0 |
| Lower | 20 |

## MIL-HDBK-217F

Environment Factor - $\pi_{E}$

| Environment | $\pi_{E}$ |
| :---: | :---: |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 4.0 |
| $G_{M}$ | 12 |
| $N_{S}$ | 5.0 |
| $N_{U}$ | 16 |
| $A_{I C}$ | 5.0 |
| $A_{I F}$ | 7.0 |
| $A_{U C}$ | 6.0 |
| $A_{U F}$ | 8.0 |
| $A_{R W}$ | 24 |
| $S_{F}$ | .50 |
| $M_{F}$ | 13 |
| $M_{L}$ | 34 |
| $C_{L}$ | 610 |

COIL APPLICATION NOTE: Insulation Class Datermination From Part Designation
MIL-C-15305. All parts in this specitication are R.F. coils. An example type designation is:


The codes used for the Insulation Class are:

| Class C: | $1,2,3$ |
| :--- | :--- |
| Class B: | $4,5,6$ |
| Class O: | $7,8,9$ |
| Class A: | $10,11,12$ |

MIL-C-39010. An example type designation per this specification is:


Hot Spot temperature can be estimated as follows:

$$
T_{H S}=T_{A}+1.1(\Delta T)
$$

where:
$T_{\text {HS }}=$ Hot Spot Temperature $\left({ }^{\circ} \mathrm{C}\right)$
$T_{A}=$ Inductive Device Ambient Operating Temperature $\left({ }^{\circ} \mathrm{C}\right)$
$\Delta T=$ Average Temperature Rise Above Ambient $\left({ }^{\circ} \mathrm{C}\right)$
$\Delta T$ can either be determined by the appropriate "Temperature Rise" Test Method paragraph in the device base specification (e.g., paragraph 4.8.12 for MIL-T-27E), or by approximation using one of the procedures described below.
$\Delta T$ Approximation

| Information Known |  |  |  | $\Delta T$ Approximation |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | 010 Slash <br> -39010/1C <br> -39010/4C <br> ss <br> diating Surfa <br> ss <br> ner Weight <br> er <br> ner Weight <br> 80\% Effici | mber <br> 7C, 9A <br> 11,12 | $14$ | $\Delta T=$ $\Delta T=$ $\Delta T=$ $\Delta T=$ | A $\text { (Wt.). } 6766$ $\text { Nt.). } 6766$ |
|  | Loss (W) <br> ting Surface <br> former Weig <br> Power (W) <br> are listed in <br> $s$ with suria <br> m 3 in 2 to | Case (in <br> d order less tha Do not | below for <br> st to least Equations he mounting | Case A <br> MIL-C pplicabl when | microwith g radiating |
| MIL-T-27 Case Radiating Areas (Excludes Mounting Surface) |  |  |  |  |  |
| Case | Area $\left(\mathrm{in}^{2}\right)$ | Case | Area ( $\mathrm{in}^{2}$ ) | Case | Area $\left(\mathrm{in}^{2}\right)$ |
| AF AG AH AJ EB EA FB FA | $\begin{array}{r} 4 \\ 7 \\ 11 \\ 18 \\ 21 \\ 23 \\ 25 \\ 31 \end{array}$ | $\begin{aligned} & \text { GB } \\ & \text { GA } \\ & H B \\ & H A \\ & \text { JB } \\ & \text { JA } \\ & \text { KB } \\ & \text { KA } \end{aligned}$ | 33 43 42 53 58 71 72 84 | $\begin{aligned} & \text { LB } \\ & \mathrm{LA} \\ & M B \\ & M A \\ & N B \\ & N A \\ & O A \end{aligned}$ | 82 98 98 115 117 139 146 |

The following failure-rate model applies to motors with power ratings below one horsepower. This model is applicable to polyphase, capacitor start and run and shaded pole motors. It's application may be extended to other types of fractional horsepower motors utilizing rolling element grease packed bearings. The model is dictated by two tailure modes, bearing failures and winding failures. Application of the model to D.C. brush motors assumes that brushes are inspected and replaced and are not a failure mode. Typical applications include fans and blowers as woll as various other motor applications. The model is based on Reference 4, which contains a more comprehensive treatment of motor life prediction methods. The reference should be reviewed when bearing loads exceed 10 percent of rated load, speeds exceed 24,000 rpm or motor loads include motor speed slip of greater than 25 percent.

The instantaneous fallure rates, or hazard rates, experienced by motors are not constant but increase with time. The failure rate model in this section is an average failure rate for the motor operating over time period " 7 ". The motor operating time period ( $t$-hours) is selected by the analyst. Each motor must be replaced when it reaches the end of this period to make the calculated $\lambda_{p}$ valid. The average failure rate, $\lambda_{p}$, has been obtained by dividing the cumulative hazard rate by $i$. and can be treated as a constant failure rate and added to other part fallure rates from this Handbook.

$$
\lambda_{p}=\left[\frac{t^{2}}{\alpha_{B}^{3}}+\frac{1}{\alpha_{W}}\right] \times 10^{6} \text { Failures/10 } 0^{6} \text { Hours }
$$

Bearing \& Winding Characteristic Lite $-\alpha_{B}$ and $\alpha_{W}$


NOTE: See next page for method to calculate $\alpha_{B}$ and $\alpha_{W}$ when temperature is not constant.
$\alpha_{\text {Calculation }}$ for Cycled Temperature
The following equation can be used to cakulate a weighted characteristic life for both bearings and windings (e.g., for bearings substitute $\alpha_{B}$ for all $\alpha^{\prime}$ s in equation).

$$
\alpha=\frac{\left(h_{1}+h_{2}+h_{3}+\cdots \cdot \cdot h_{m}\right)}{\frac{h_{1}}{\alpha_{1}}+\frac{h_{2}}{\alpha_{2}}+\frac{h_{3}}{\alpha_{3}}+\cdots \cdots \cdot \frac{h_{m}}{\alpha_{m}}}
$$

where:
$\alpha=$ either $\alpha_{B}$ or $\alpha_{W}$
$h_{1}=$ Time at Temperature $T_{1}$
$n_{2}=$ Time to Cycle From Temperature $T_{1}$ to $T_{3}$
$h_{3}=$ Time at Temperature $T_{3}$
$h_{m}=$ Time at Temperature $T_{m}$
$\alpha_{1}=$ Bearing (or Winding) Life at $T_{1}$
$\alpha_{2}=$ Bearing (or Winding) Life at $T_{2}$
NOTE: $\quad T_{2}=\frac{T_{1}+T_{3}}{2}, \quad T_{4}=\frac{T_{3}+T_{1}}{2}$


Hours (h)
Thermal Cycle

## DESCRIPTION

Rotating Synchros and Resolvers

$$
\lambda_{p}=\lambda_{b} \pi_{S} \pi_{N} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

NOTE: Synchros and resolvers are predominately used in service requiring only slow and infrequent motion. Mechanical wearout problems are infrequent so that the electrical failure mode dominates, and no mechanical mode failure rate is required in the model above.

| Base Failure Rate - $\lambda_{B}$ |  |  |  |
| :---: | :---: | :---: | :---: |
| $T_{F}\left({ }^{\circ} \mathrm{C}\right)$ | $\lambda_{b}$ | $\mathrm{T}_{\mathrm{F}}\left({ }^{\circ} \mathrm{C}\right)$ | $\lambda_{b}$ |
| 30 | . 0083 | 85 | . 032 |
| 35 | . 0088 | 90 | . 041 |
| 40 | . 0095 | 95 | . 052 |
| 45 | . 010 | 100 | . 069 |
| 50 | . 011 | 105 | . 094 |
| 55 | . 013 | 110 | . 13 |
| 60 | . 014 | 115 | . 19 |
| 65 | 016 | 120 | . 29 |
| 70 | . 019 | 125 | 45 |
| 75 | . 022 | 130 | 74 |
| 80 | . 027 | 135 | 1.3 |
| $\lambda_{b}=.00535 \exp \left(\frac{T+273}{334}\right)^{8.5}$ |  |  |  |
| $\mathrm{T}_{\mathrm{F}}=$ Frame Temperature ( ${ }^{\circ} \mathrm{C}$ ) |  |  |  |
| If Frame Temperature is Unknown Assume $T_{F}=40^{\circ} \mathrm{C}+$ Ambient Temperature |  |  |  |


| Size Factor $-\pi_{S}$ |  |  |  |
| :---: | :---: | :---: | :---: |
|  | $\pi_{S}$ |  |  |
|  | Size 8 or <br> Smaller | Size $10-16$ | Size 18 or <br> Larger |
| Synchro | 2 | 1.5 | 1 |
| Resolver | 3 | 2.25 | 1.5 |

DESCRIPTION

## Elapsed Time Meters

$$
\lambda_{p}=\lambda_{b} \pi_{T} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

| Base Failure Rate $-\lambda_{\mathrm{b}}$ |  |
| :--- | :--- |
| Type | $\lambda_{\mathrm{b}}$ |
| A.C. | 20 |
| Inverter Driven | 30 |
| Commutator D.C. | 80 |

Temperature Stress Factor $-\pi_{\mathrm{T}}$

| Operating $\mathrm{T}\left({ }^{\circ} \mathrm{C}\right) /$ Rated $\mathrm{T}\left({ }^{\circ} \mathrm{C}\right)$ |  |
| :---: | :---: |
| 0 to .5 | .5 |
| .6 | .6 |
| .8 | .8 |
| 1.0 | 1.0 |

Environment Factor $-\pi_{E}$

| Environment | $\pi_{E}$ |
| :---: | :---: |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 2.0 |
| $G_{M}$ | 12 |
| $N_{S}$ | 7.0 |
| $N_{U}$ | 18 |
| $A_{I C}$ | 5.0 |
| $A_{I F}$ | 8.0 |
| $A_{U C}$ | 16 |
| $A_{U F}$ | 25 |
| $A_{R W}$ | 26 |
| $S_{F}$ | .50 |
| $M_{F}$ | 14 |
| $M_{L}$ | 38 |
| $C_{L}$ | $N / A$ |

## MIL-HDBK-217F

12.4 ROTATING DEVICES, EXAMPLE

## Example

Given: Fractional Horsepower Mctor operating at a thermal duty cycle of: 2 hours at $100^{\circ} \mathrm{C}, 8$ hours at $20^{\circ} \mathrm{C}, 0.5$ hours from $100^{\circ} \mathrm{C}$ to $20^{\circ} \mathrm{C}$, and 0.5 hours from $20^{\circ} \mathrm{C}$ back to $100^{\circ} \mathrm{C}$. Find the average failure rate for 4000 hours operating time.

The basic procedure is to first determine operating temperature at each time interval (or averge temperature when traversing from one temperature to another, e.g. $T_{2}=(100+20) / 2=60^{\circ} \mathrm{C}$. Determine $\alpha_{B}$ and $\alpha_{W}$ at each temperature and then use these vakues to determine a weighted average $\alpha_{B}$ and $\alpha_{W}$ to use in the $\lambda_{p}$ equation.

$$
\begin{aligned}
& h_{1}=2 \mathrm{hr} . \quad T_{1}=100^{\circ} \mathrm{C} ; \alpha_{B}=6100 \text { hours; } \quad \alpha_{W}=31000 \text { hours } \\
& h_{2}=h_{4}=0.5 \mathrm{hr} . \quad T_{2}=60^{\circ} \mathrm{C} ; \quad \alpha_{B}=35000 \text { hours; } \alpha_{W}=180000 \text { hours } \\
& h_{3}=8 \mathrm{hr} . \quad T_{3}=20^{\circ} \mathrm{C} ; \quad \alpha_{B}=39000 \text { hours; } \alpha_{W}=1600000 \text { hours } \\
& \alpha_{B}=\frac{2+0.5+8+0.5}{\frac{2}{6100}+\frac{0.5}{35000}+\frac{8}{39000}+\frac{0.5}{35000}}=19600 \text { nours } \\
& \alpha_{W}=\frac{2+0.5+8+0.5}{\frac{2}{31000}+\frac{0.5}{180000}+\frac{8}{1600000}+\frac{0.5}{180000}}=146000 \text { hours } \\
& \lambda_{p}=\left(\frac{t^{2}}{\alpha_{B}{ }^{3}}+\frac{1}{\alpha_{w}}\right) \times 10^{6} \\
& \lambda_{p}=\left(\frac{(4000)^{2}}{(19600)^{3}}+\frac{1}{146000}\right) \times 10^{6} \\
& \lambda_{p}=9.0 \text { Faihres } / 10^{6} \text { Hours }
\end{aligned}
$$

SPECIFICATION
MIL-R-5757
MIL-R-6106
MIL-R-19523
MIL-R-39016

DESCRIPTION
Mechanical Relay

MIL-R-19648
MIL-R-83725
MIL-R-83726 (Except Class C, Solid State Type)

$$
\lambda_{\mathrm{P}}=\lambda_{\mathrm{b}} \pi_{\mathrm{L}} \pi_{\mathrm{C}} \pi_{\mathrm{CYC}} \pi_{\mathrm{F}} \pi_{\mathrm{O}} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

Base Failure Rate - $\lambda_{D}$

| $\mathrm{T}_{\mathrm{A}}\left({ }^{\circ} \mathrm{C}\right)$ | Rated Temperature |  |
| :---: | :---: | :---: |
|  | $85^{\circ} \mathrm{C}^{1}$ | $125^{\circ} \mathrm{C}^{2}$ |
| 25 | .0060 | .0059 |
| 30 | .0061 | .0060 |
| 35 | .0063 | .0061 |
| 40 | .0065 | .0082 |
| 45 | .0068 | .0064 |
| 50 | .0072 | .0066 |
| 55 | .0077 | .0068 |
| 60 | .0084 | .0071 |
| 65 | .0094 | .0074 |
| 70 | .011 | .0079 |
| 75 | .013 | .0083 |
| 80 | .020 | .0089 |
| 85 |  | .0097 |
| 90 |  | .011 |
| 95 |  | .012 |
| 100 |  | .013 |
| 105 |  | .015 |
| 110 |  | .021 |
| 115 |  | .025 |
| 120 |  | .031 |

1. $\lambda_{B}=.00555 \exp \left(\frac{T_{A}+273}{352}\right)^{15.7}$
2. $\lambda_{b}=.0054 \exp \left(\frac{T_{A}+273}{377}\right)^{10.4}$
$T_{A}=$ Ambient Temperature $\left({ }^{\circ} \mathrm{C}\right)$

Load Stress Factor $-\pi_{L}$

| S | Load Type |  |  |
| :---: | :---: | :---: | :---: |
|  | Resistive ${ }^{1}$ | Inductive ${ }^{2}$ | Lamp ${ }^{3}$ |
| . 05 | 1.00 | 1.02 | 1.06 |
| . 10 | 1.02 | 1.06 | 1.28 |
| . 20 | 1.06 | 1.28 | 2.72 |
| . 30 | 1.15 | 1.78 | 9.49 |
| . 40 | 1.28 | 2.72 | 54.6 |
| . 50 | 1.48 | 4.77 |  |
| . 60 | 1.76 | 9.49 |  |
| . 70 | 2.15 | 21.4 |  |
| . 80 | 2.72 |  |  |
| . 90 | 3.55 |  |  |
| 1.00 | 4.77 |  |  |
|  | $\left(\frac{S}{.8}\right)^{2}$ | 3. $\pi_{L}=$ | $\left(\frac{S}{2}\right)^{2}$ |
| $\pi_{L}$ | $\left(\frac{S}{4}\right)^{2}$ | $\frac{\text { Operating }}{\text { Rated Resis }}$ | Current |

For single devices which switch two different load types, evaluate $\pi_{L}$ for each possible stress load type combination and use the worse case (largest $\pi_{\mathrm{L}}$ ).


Contact Form Factor - $\pi_{C}$
(Applies to Active Conducting Contacts)

| Contact Form | $\pi_{C}$ |
| :---: | :---: |
| SPST | 1.00 |
| DPST | 1.50 |
| SPDT | 1.75 |
| 3PST | 2.00 |
| 4PST | 2.50 |
| DPDT | 3.00 |
| 3PDT | 4.25 |
| 4PDT | 5.50 |
| 6PDT | 8.00 |


| Cycle Rate <br> (Cycles per Hour) | $\pi_{\text {CYC }}$ <br> (Lower Quality) |
| :---: | :---: |
| $>1000$ | $\left(\frac{\text { Cycles per Hour }}{100}\right)^{2}$ |
| $10-1000$ | $\frac{\text { Cycles per Hour }}{10}$ |
| $<10$ | 1.0 |
| NOTE:Values of $\pi_{\text {CYC }}$ for cycling rates beyond the <br> basic design limitations of the relay are not valid. <br> Design specitications should be consulted prior to <br> evaluation of $\pi_{\text {CYC }}$ |  |


| Quality Fectior $-\mathrm{R}_{\mathrm{O}}$ |  |
| :--- | :---: |
| Oualiny | 0 |
| R | .10 |
| P | .30 |
| X | .35 |
| M | .60 |
| L | 1.0 |
| Non-Est. Rel. | 1.5 |
|  | 3.0 |


| Application and Corstruction Factor - If |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
| Contact Reting | Application Type | Construction Type | ${ }^{*} F$ |  |
|  |  |  | $\begin{aligned} & \text { MML- } \\ & \text { SPEC } \end{aligned}$ | $\begin{aligned} & \text { Lower } \\ & \text { Quality } \end{aligned}$ |
| Signe Current (low mw and ma) | Dry Circui | Armature (Long) Dry Reed Mercury Wetted Magnetic Latching Balanced Armature Solenoid | $\begin{aligned} & 4 \\ & 6 \\ & 1 \\ & 4 \\ & 7 \\ & 7 \end{aligned}$ | $\begin{array}{r} 8 \\ 18 \\ 3 \\ 8 \\ 14 \\ 14 \end{array}$ |
| $0-6$ Anp | $\begin{aligned} & \text { Ceneral } \\ & \text { Purpose } \end{aligned}$ | Frimiture (Long) Balanced Armature Solenoid | $\begin{aligned} & 3 \\ & 5 \\ & 6 \end{aligned}$ | $\begin{array}{r} 8 \\ 10 \\ 12 \end{array}$ |
|  | $\begin{aligned} & \text { Sensitive } \\ & (0-100 \mathrm{mw}) \end{aligned}$ | Armative (Long and Short) <br> Movoury Wimed Mmonevic Letching Meter Movement Batanced Armature | $\begin{array}{r} 5 \\ 2 \\ 6 \\ 100 \\ 10 \end{array}$ | $\begin{array}{r} 10 \\ 6 \\ 12 \\ 100 \\ 20 \end{array}$ |
|  | Polarized | Armailure (Short) Meter Movement | $\begin{array}{r} 10 \\ 100 \\ \hline \end{array}$ | $\begin{array}{r} 20 \\ 100 \\ \hline \end{array}$ |
|  | Vibrating Reed | Dry Reed Mercury Wetted | $\begin{aligned} & 6 \\ & 1 \end{aligned}$ | $\begin{array}{r} 12 \\ 3 \end{array}$ |
|  | High Speed | $\begin{aligned} & \text { Armature (Balanced } \\ & \text { and Short) } \\ & \text { Dry Reed } \end{aligned}$ | 25 6 | $\begin{aligned} & M A \\ & M A \end{aligned}$ |
|  | $\begin{aligned} & \text { Therma } \\ & \text { Time Doley } \end{aligned}$ | Bimetal | 10 | 20 |
|  | Electronic True Delay. Nor Thermal |  | 9 | 12 |
|  | Latching. Magnetic | Dry Reed Morcury Wetted Balanced Aramture | $\begin{array}{r} 10 \\ 5 \\ 5 \\ \hline \end{array}$ | $\begin{aligned} & 20 \\ & 10 \\ & 10 \\ & \hline \end{aligned}$ |
| $\begin{aligned} & 5-20 \\ & \text { Anp } \end{aligned}$ | $\begin{aligned} & \text { Han } \\ & \text { Voluere } \end{aligned}$ | Vacuum (Glass) Vacum (Ceramic) | $\begin{array}{r} 20 \\ 5 \end{array}$ | $\begin{aligned} & 40 \\ & 10 \end{aligned}$ |
|  | $\begin{aligned} & \text { Madium } \\ & \text { Power } \end{aligned}$ | Armature (Long and Short) <br> Mercury Wetted Magnetic Lathing Mechanical Latching Balanced Armature Solencid | $\begin{aligned} & 3 \\ & 1 \\ & 2 \\ & 3 \\ & 2 \\ & 2 \end{aligned}$ | $\begin{aligned} & 6 \\ & 3 \\ & 6 \\ & 6 \\ & 6 \\ & 6 \end{aligned}$ |
| 25-600 ATp | $\begin{aligned} & \text { Contactors } \\ & \text { (high } \\ & \text { Current) } \end{aligned}$ | Armature (Short) Mechanical Letching Balanced Armature Solenoid | $\begin{array}{r} 7 \\ 12 \\ 10 \\ 5 \\ \hline \end{array}$ | $\begin{aligned} & 14 \\ & 24 \\ & 20 \\ & 10 \end{aligned}$ |

## SPECIFICATION

MIL-R-28750
MIL-R-83726

## DESCRIPTION

Relay, Solid State
Relay, Time Delay, Hybrid and Solid State

The most accurate method for predicting the failure rate of solid state (and solid state time delay) relays is to sum the failure rates for the individual components which make up the relay. The individual component failure rates can either be calculated from the models provided in the main body of this Handbook (Parts Stress Method) or from the Parts Count Method shown in Appendix A, depending upon the depth of knowledge the analyst has about the components being used. If insufficient information is available, the following default model can be used:

$$
\lambda_{p}=\lambda_{b} \pi_{Q} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

| Base Failure Rate $-\lambda_{\mathrm{b}}$ |  |
| :--- | :--- |
| Relay Type | $\lambda_{\mathrm{b}}$ |
| Solid State | .40 |
| Solid State Time Delay | .50 |
| Hybrid | .50 |


| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\pi_{E}$ |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 3.0 |
| $G_{M}$ | 12 |
| $N_{S}$ | 6.0 |
| $N_{U}$ | 17 |
| $A_{I C}$ | 12 |
| $A_{I F}$ | 19 |
| $A_{U C}$ | 21 |
| $A_{U F}$ | 32 |
| $A_{R W}$ | 23 |
| $S_{F}$ | .40 |
| $M_{F}$ | 12 |
| $M_{L}$ | 33 |
| $C_{L}$ | 590 |

## SPECIFICATION

MIL-S-3350
MIL-S-8805
MIL-S-8834

MIL-S-22885
MIL-S-83731

## DESCRIPTION

Snap-action, Toggle or Pushbutton, Single Body

$$
\lambda_{\mathrm{p}}=\lambda_{\mathrm{b}} \pi_{\mathrm{CYC}} \pi_{\mathrm{L}} \pi_{C} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

Base Failure Rate $-\lambda_{\mathrm{b}}$

| Description | MIL-SPEC | Lower Quality |
| :--- | :---: | :---: |
| Snap-action | .00045 | .034 |
| Non-snap Action | .0027 | .040 |


| Cycling Factor $-\pi_{\mathrm{CYC}}$ |  |
| :---: | :---: |
| Switching Cycles <br> per Hour | $\pi_{\mathrm{CYC}}$ |
| $\leq 1$ Cycle/Hour | 1.0 |
| $>1$ Cycle/Hour | Number of Cycles/Hour |


| Load Stress Factor - $\pi_{\mathrm{L}}$ |  |  |  |
| :---: | :---: | :---: | :---: |
| $\begin{gathered} \hline \text { Stress } \\ S \\ \hline \end{gathered}$ | Load Type |  |  |
|  | Resistive | Inductive | Lamp |
| 0.05 | 1.00 | 1.02 | 1.06 |
| 0.1 | 1.02 | 1.06 | 1.28 |
| 0.2 | 1.06 | 1.28 | 2.72 |
| 0.3 | 1.15 | 1.76 | 9.49 |
| 0.4 | 1.28 | 2.72 | 54.6 |
| 0.5 | 1.48 | 4.77 |  |
| 0.6 | 1.76 | 9.49 |  |
| 0.7 | 2.15 | 21.4 |  |
| 0.8 | 2.72 |  |  |
| 0.9 | 3.55 |  |  |
| 1.0 | 4.77 |  |  |
| $S=\frac{\text { Operating Load Current }}{\text { Rated Resistive Load Current }}$ |  |  |  |
|  |  |  |  |
| $\pi_{\mathrm{L}}=\exp (S / .8)^{2} \quad$ for Resistive Load |  |  |  |
| $\pi_{\mathrm{L}}=\exp (\mathrm{S} / .4)^{2} \quad$ for Inductive Load |  |  |  |
| $\pi_{L}=\exp (S / 2)^{2}$ for Lamp Load |  |  |  |

Contact Form and Quantity Factor $-\pi_{\mathrm{C}}$

| Contact Form | $\pi_{\mathrm{C}}$ |
| :--- | :---: |
| SPST | 1.0 |
| DPST | 1.5 |
| SPDT | 1.7 |
| 3PST | 2.0 |
| 4PST | 2.5 |
| SPDT | 3.0 |
| 3PDT | 4.2 |
| 6PDT | 5.5 |


| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\pi_{E}$ |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 3.0 |
| $G_{M}$ | 18 |
| $N_{S}$ | 8.0 |
| $N_{U}$ | 29 |
| $A_{I C}$ | 10 |
| $A_{I F}$ | 18 |
| $A_{U C}$ | 13 |
| $A_{U F}$ | 22 |
| $A_{R W}$ | 46 |
| $S_{F}$ | .50 |
| $M_{F}$ | 25 |
| $M_{L}$ | 67 |
| $C_{L}$ | 1200 |

NOTE: When the switch is rated by inductive load, then use resistive $\pi_{\mathrm{L}}$.

## MIL-HDBK-217F

### 14.2 SWITCHES, BASIC SENSITIVE

## SPECIFICATION

MIL-S-8805

## DESCRIPTION Basic Sensitive

$$
\lambda_{p}=\lambda_{b} \pi_{C Y C} \pi_{L} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

| $\begin{array}{ll} \lambda_{\mathrm{b}}=\lambda_{\mathrm{bE}}+n \lambda_{\mathrm{bC}} & \begin{array}{l} \text { (if Actuation Differential is } \\ >0.002 \text { inches) } \end{array} \\ \lambda_{\mathrm{b}}=\lambda_{\mathrm{bE}}+n \lambda_{\mathrm{bO}} & \begin{array}{l} \text { (if Actuation Differential is } \\ \\ \leq 0.002 \text { inches) } \end{array} \end{array}$ <br> $\mathrm{n}=$ Number of Active Contacts |  |  |
| :---: | :---: | :---: |
| Description | MIL-SPEC | Lower Quality |
| $\lambda_{\text {b }}$ | . 10 | . 10 |
| $\lambda_{\text {b }}$ | 00045 | . 23 |
| $\lambda_{\text {b } 0}$ | . 0009 | . 63 |


| Load Stress Factor - $\pi_{L}$ |  |  |  |
| :---: | :---: | :---: | :---: |
| $\begin{gathered} \hline \text { Stress } \\ S \end{gathered}$ | Load Type |  |  |
|  | Resistive | Inductive | Lamp |
| 0.05 | 1.00 | 1.02 | 1.06 |
| 0.1 | 1.02 | 1.06 | 1.28 |
| 0.2 | 1.06 | 1.28 | 2.72 |
| 0.3 | 1.15 | 1.76 | 9.49 |
| 0.4 | 1.28 | 2.72 | 54.6 |
| 0.5 | 1.48 | 4.77 |  |
| 0.6 | 1.76 | 9.49 |  |
| 0.7 | 2.15 | 21.4 |  |
| 0.8 | 2.72 |  |  |
| 0.9 | 3.55 |  |  |
| 1.0 | 4.77 |  |  |
| $S=\frac{\text { Operating Load Curren! }}{\text { Rated Resistive Load Current }}$ |  |  |  |
|  |  |  |  |
|  | $\exp (\mathrm{S} / .8)^{2}$ | for Re | e Load |
|  | $\exp (S / .4)^{2}$ | for Ind | e Load |
|  | $\exp (S / .2)^{2}$ | for Lam |  |


| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\pi_{\mathrm{E}}$ |
| $\mathrm{G}_{\mathrm{B}}$ | 1.0 |
| $\mathrm{G}_{\mathrm{F}}$ | 3.0 |
| $\mathrm{G}_{\mathrm{M}}$ | 18 |
| $\mathrm{~N}_{\mathrm{S}}$ | 8.0 |
| $\mathrm{~N}_{\mathrm{U}}$ | 29 |
| $\mathrm{~A}_{1 \mathrm{l}}$ | 10 |
| $A_{I F}$ | 18 |
| $A_{U C}$ | 13 |
| $A_{U F}$ | 22 |
| $A_{R W}$ | 46 |
| $\mathrm{~S}_{\mathrm{F}}$ | .50 |
| $M_{\mathrm{F}}$ | 25 |
| $M_{\mathrm{L}}$ | 67 |
| $C_{L}$ | 1200 |

NOTE: When the Switch is Rated by Inductive Load, then use Resistive $\pi_{\mathrm{L}}$.

SPECIFICATION
MIL-S-3786

## DESCRIPTION

Rotary, Ceramic or Glass Water, Silver Alloy Contacts

$$
\lambda_{p}=\lambda_{b} \pi_{C Y C} \pi_{L} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

| Base failure rate model ( $\lambda_{\text {b }}$ ): |  |  |
| :---: | :---: | :---: |
| $\lambda_{b}=\lambda_{B E}+n \lambda_{B G} \quad$ (for Rotary Switch Medium Power Wafers) |  |  |
| $n=$ Number of Active Contacts |  |  |
| Description | MIL-SPEC | Lower Quality |
| $\lambda_{b E}$ | . 0067 | . 10 |
| $\lambda_{b F}$ | . 00003 | . 02 |
| $\lambda_{b G}$ | . 00003 | . 06 |


| Load Stress Factor $-\pi_{\mathrm{L}}$ |  |  |  |
| :---: | :---: | :---: | :---: |
| Stress | Load Type |  |  |
| $S$ | Resistive | Inductive | Lamp |
| 0.05 | 1.00 | 1.02 | 1.06 |
| 0.1 | 1.02 | 1.06 | 1.28 |
| 0.2 | 1.06 | 1.28 | 2.72 |
| 0.3 | 1.15 | 1.76 | 9.49 |
| 0.4 | 1.28 | 2.72 | 54.6 |
| 0.5 | 1.48 | 4.77 |  |
| 0.6 | 1.76 | 9.49 |  |
| 0.7 | 2.15 | 21.4 |  |
| 0.8 | 2.72 |  |  |
| 0.9 | 3.55 |  |  |
| 1.0 | 4.77 |  |  |

$S=\frac{\text { Operating Load Current }}{\text { Rated Resistive Load Current }}$

| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\pi_{E}$ |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 3.0 |
| $G_{M}$ | 18 |
| $N_{S}$ | 8.0 |
| $N_{U}$ | 29 |
| $A_{I C}$ | 10 |
| $A_{I F}$ | 18 |
| $A_{U C}$ | 13 |
| $A_{U F}$ | 22 |
| $A_{R W}$ | 46 |
| $S_{F}$ | .50 |
| $M_{F}$ | 67 |
| $M_{L}$ | 1200 |
| $C_{L}$ |  |

$\pi_{\mathrm{L}}=\exp (\mathrm{S} / .8)^{2} \quad$ for Resistive Load
$\pi_{\mathrm{L}}=\exp (\mathrm{S} / .4)^{2} \quad$ for Inductive Load
$\pi_{L}=\exp (S / .2)^{2} \quad$ for Lamp Load
NOTE: When the Switch is Rated by Inductive Load, then use Resistive $\pi_{L}$.

## SPECIFICATION

MIL-S-22710
Line

DESCRIPTION
Switches, Rotary (Printed Circuit) (Thumbwheel, Inand Pushbutton)

$$
\lambda_{p}=\left(\lambda_{b 1}+\pi_{N} \lambda_{b 2}\right) \pi_{C Y C} \pi_{L} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

CAUTION: This model applies to the switching function only. The model does not consider the contribution of any discrete components (e.g., resistors, diodes, lamp) which may be mounted on the switch. If signiticant (relative to the switch failure rate), the failure rate of these devices must be calculated using the appropriate section of this Handbook and added to the failure rate of the switch.

This model applies to a single switch section. This type of switch is frequently ganged to provide the required function. The model must be applied to each section individually.


Number of Active Contacts Factor $-\pi_{N}$
$\pi_{N}=$ Number of Active Contacts

| Load Stress Factor $-\pi_{L}$ |  |  |  |
| :---: | :---: | :---: | :---: |
| Stress | Load Type |  |  |
| $S$ | Resistive | Inductive | Lamp |
| 0.05 | 1.00 | 1.02 | 1.06 |
| 0.1 | 1.02 | 1.06 | 1.28 |
| 0.2 | 1.06 | 1.28 | 2.72 |
| 0.3 | 1.15 | 1.76 | 9.49 |
| 0.4 | 1.28 | 2.72 | 54.6 |
| 0.5 | 1.48 | 4.77 |  |
| 0.6 | 1.76 | 9.49 |  |
| 0.7 | 2.15 | 21.4 |  |
| 0.8 | 2.72 |  |  |
| 0.9 | 3.55 |  |  |
| 1.0 | 4.77 |  |  |

$S=\frac{\text { Operating Load Current }}{\text { Rated Resistive Load Current }}$
$\pi_{L}=\exp (S / .8)^{2} \quad$ for Resistive Load
$\pi_{L}=\exp (S / .4)^{2} \quad$ for Inductive Load
$\pi_{L}=\exp (S / .2)^{2} \quad$ for Lamp Load

NOTE: When the Switch is Rated by Inductive
Load, then use Resistive $\pi_{\mathrm{L}}$.

Cycting Factor - $\pi_{\mathrm{CYC}}$

| Switching Cycles <br> per Hour | $\pi_{\mathrm{CYC}}$ |
| :---: | :---: |
| $\leq 1$ Cycle/Hour | 1.0 |
| $>1$ Cycle/Hour | Number of Cycles/Hour |

Environment Factor - $\pi_{E}$

| Environment | $\pi_{\mathrm{E}}$ |
| :---: | :---: |
| $\mathrm{G}_{\mathrm{B}}$ | 1.0 |
| $\mathrm{G}_{\mathrm{F}}$ | 3.0 |
| $\mathrm{G}_{M}$ | 18 |
| $\mathrm{~N}_{\mathrm{S}}$ | 8.0 |
| $\mathrm{~N}_{\mathrm{U}}$ | 29 |
| $\mathrm{~A}_{I C}$ | 10 |
| $A_{I F}$ | 18 |
| $A_{U C}$ | 13 |
| $A_{U F}$ | 22 |
| $A_{R W}$ | 46 |
| $\mathrm{~S}_{\mathrm{F}}$ | 25 |
| $M_{F}$ | 67 |
| $M_{L}$ | 1200 |
| $C_{L}$ |  |

## SPECIFICATION

MIL-C-55629
MIL-C-83383
MIL-C-39019
W-C-375

## DESCRIPTION

Circuit Breakers, Magnetic, Unsealed, Trip-Free
Circuit Breakers, Remote Control, Thermal, Trip-Free
Circuit Breakers, Magnetic, Low Power, Sealed, Trip-Free Service
Circuit Breakers, Molded Case, Branch Circuit and Service

$$
\lambda_{p}=\lambda_{b} \pi_{C} \pi_{U} \pi_{Q} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

Base Failure Rate $-\lambda_{\mathrm{b}}$

| Description | $\lambda_{\mathrm{b}}$ |
| :--- | :---: |
| Magnetic | .020 |
| Thermal | .038 |
| Thermal-Magnetic | .038 |


| Quality Factor $-\pi_{\mathrm{Q}}$ |  |
| :--- | :---: |
| Quality | $\pi_{\mathrm{Q}}$ |
| MIL-SPEC | 1.0 |
| Lower | 8.4 |


| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\pi_{E}$ |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 2.0 |
| $G_{M}$ | 15 |
| $N_{S}$ | 8.0 |
| $N_{U}$ | 27 |
| $A_{I C}$ | 7.0 |
| $A_{I F}$ | 9.0 |
| $A_{U C}$ | 11 |
| $A_{U F}$ | 12 |
| $A_{R W}$ | 46 |
| $S_{F}$ | .50 |
| $M_{F}$ | 25 |
| $M_{L}$ | 66 |
| $C_{L}$ | $N / A$ |


| SPECIFICATION* | DESCRIPTION | SPECIFICATION* | DESCRIPTION |
| :---: | :---: | :---: | :---: |
| MIL-C-24308 | Rack and Panel | MIL-C-3607 | Coaxial, RF |
| MIL-C-28748 |  | MIL-C-3643 |  |
| MIL-C-28804 |  | MIL-C-3650 |  |
| MIL-C-83513 |  | MIL-C-3655 |  |
| M11-C83733 |  | MIL-C-25516 |  |
| MIL-C-5015 | Circular | MIL-C-39012 |  |
| MIL-C-26482 |  | MIL-C-55235 |  |
| ML-C28840 |  | MIL-C-55339 |  |
| MIL-C-38999 |  | MIL-C-3767 | Power |
| MIL-C-81511 |  | MIL-C-22992 |  |
| MIL-C83723 |  |  |  |
| *NOTE: See following | e for connector configurations. | MIL-C-49142 | Triaxial, RF |

APPLICATION NOTE: The failure rate model is for a mated pair of connectors. It is sometimes desirable to assign half of the overall mated pair connector (i.e., single connector) failure rate to the line replaceable unit and half to the chassis (or backplane). An example of when this would be beneficial is for input to maintainability prediction to allow a failure rate weighted repair time to be estimated for both the LRU and chassis. This accounting procedure could be significant if repair times for the two halves of the connector are substantially different. For a single connector divide $\lambda_{p}$ by two.

| $\mathrm{T}_{0}\left({ }^{\circ} \mathrm{C}\right)$ | $\frac{\text { Base Failure Rate }-\lambda_{D}}{\text { Insert Material* }}$ |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  | $A^{1}$ | $\mathrm{B}^{2}$ | $c^{3}$ | $D^{4}$ |
| 0 | . 00006 | . 00025 | . 0021 | . 0038 |
| 10 | . 00008 | . 00033 | . 0026 | . 0048 |
| 20 | . 00009 | . 00044 | . 0032 | . 0062 |
| 30 | . 00011 | . 00057 | . 0040 | . 0078 |
| 40 | . 00014 | . 00073 | . 0048 | . 0099 |
| 50 | . 00016 | . 00093 | . 0059 | . 013 |
| 60 | . 00020 | . 0012 | . 0071 | . 016 |
| 70 | . 00023 | . 0015 | . 0087 | . 020 |
| 80 | . 00027 | . 0019 | . 011 | . 026 |
| 90 | . 00032 | . 0023 | . 013 | . 033 |
| 100 | . 00037 | . 0029 | . 016 | . 043 |
| 110 | . 00043 | . 0036 | . 020 | . 056 |
| 120 | . 00050 | . 0045 | . 024 | . 074 |
| 130 | . 00059 | . 0056 |  |  |
| 140 | . 00069 | . 0070 |  |  |
| 150 | . 00080 | . 0087 |  |  |
| 160 | . 00094 | . 011 |  |  |
| 170 | . 0011 | . 014 |  |  |
| 180 | . 0013 | . 018 |  |  |
| 190 | . 0016 | . 022 |  |  |
| 200 | . 0019 | . 029 |  |  |
| 210 | . 0023 |  |  |  |
| 220 | . 0028 |  |  |  |
| 230 | . 0034 |  |  |  |
| 240 | . 0042 |  |  |  |
| 250 | . 0053 |  |  |  |

Base Failure Rate $-\lambda_{b}$ ( $\infty$ nt'd)

1. $\lambda_{b}=.020 \exp \left(\left(\frac{-1592.0}{T_{0}+273}\right)+\left(\frac{T_{0}+273}{473}\right)^{5.36}\right)$
2. $\lambda_{b}=.431 \exp \left(\left(\frac{-2073.6}{T_{0}+273}\right)+\left(\frac{T_{0}+273}{423}\right)^{4.66}\right)$
3. $\lambda_{b}=.190 \exp \left(\left(\frac{-1298.0}{T_{0}+273}\right)+\left(\frac{T_{0}+273}{373}\right)^{4.25}\right)$
4. $\lambda_{\mathrm{b}}=.770 \exp \left(\left(\frac{-1528.8}{T_{0}+273}\right)+\left(\frac{T_{0}+273}{358}\right)^{4.72}\right)$
$T_{0}=$ Internal Contact Operating Temperature $\left({ }^{\circ} \mathrm{C}\right)$
$\begin{aligned} T_{0}= & \text { Connector Ambient Temperature + Insert } \\ & \text { Temperature Rise }\end{aligned}$
See following page for Insert Temperature Rise Determination.

[^0]

Insert Temperature Rise ( $\Delta \mathrm{T}^{\circ} \mathrm{C}$ ) Determination

| Amperes Per Contact | Comact Gauga |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  | 22 | 20 | 16 | 12 |
| 2 | 4 | 2 | 1 | 0 |
| 3 | 8 | 5 | 2 | 1 |
| 4 | 13 | 8 | 4 | 1 |
| 5 | 19 | 13 | 5 | 2 |
| 6 | 27 | 18 | 8 | 3 |
| 7 | 36 | 23 | 10 | 4 |
| 8 | 46 | 30 | 13 | 5 |
| 9 | 57 | 37 | 16 | 6 |
| 10 | 70 | 45 | 19 | 7 |
| 15 |  | 96 | 41 | 15 |
| 20 |  |  | 70 | 26 |
| 25 |  |  | 106 | 39 |
| 30 |  |  |  | 54 |
| 35 |  |  |  | 72 |
| 40 |  |  |  | 92 |
| $\Delta T=0.9$ |  |  | Gaug | tacts |
| $\Delta T=0.6$ | (i) ${ }^{1}$ |  | Gauge | tacts |
| $\Delta T=0.27$ | (i) ${ }^{1}$ |  | Gauge | tacts |
| $\Delta T=0.1$ | (i) ${ }^{1 .}$ |  | Gauge | tacts |

$\Delta T=$ Insen Temperature Rise
$1=$ Amperes per Contact

RF Coaxial Connectors $\quad \Delta T=5^{\circ} \mathrm{C}$
RF Coaxial Connectors (High Power Applications) $\quad \Delta T=50^{\circ} \mathrm{C}$

| Mating/Unmating Facior $-\pi_{\mathrm{K}}$ |  |
| :--- | :---: |
| Mating/Unmating Cycles* <br> (per 1000 hours) $\pi_{\mathrm{K}}$ <br>   <br> 0 to 05 1.0 <br> $>.05$ to .5 1.5 <br> $>.5$ to 5 2.0 <br> $>5$ to 50 3.0 <br> $>50$ 4.0 |  |

- One cycle includes both connect and disconnect.



## SPECIFICATION

MIL-C-21097
MIL-C-55302

## DESCRIPTION

One-Piece Connector
Two-Piece Connector

$$
\lambda_{p}=\lambda_{b} \pi_{K} \pi_{P} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

|  |  |  |  |
| :---: | :---: | :---: | :---: |
| $\mathrm{T}_{0}\left({ }^{\circ} \mathrm{C}\right)$ | $\lambda_{b}$ | $\mathrm{T}_{0}\left({ }^{\circ} \mathrm{C}\right)$ | $\lambda_{b}$ |
| 0 | . 00012 | 110 | . 0018 |
| 10 | . 00017 | 120 | . 0022 |
| 20 | 00022 | 130 | . 0028 |
| 30 | 00028 | 140 | . 0035 |
| 40 | 00037 | 150 | . 0044 |
| 50 | 00047 | 160 | . 0055 |
| 60 | 00059 | 170 | . 0069 |
| 70 | . 00075 | 180 | . 0088 |
| 80 | . 00093 | 190 | . 011 |
| 90 | . 0012 | 200 | . 015 |
| 100 | . 0015 |  |  |
| $\lambda_{b}=.216 \exp \left(\left(\frac{-2073.6}{T_{0}+273}\right)+\left(\frac{T_{0}+273}{423}\right)^{4.66}\right)$ |  |  |  |
| $\mathrm{T}_{0}=$ Internal Contact Operating Temperature ( ${ }^{\circ} \mathrm{C}$ ) |  |  |  |

Connector Temperature Rise ( $\Delta \mathrm{T}^{\circ} \mathrm{C}$ ) Determination

| Amperes | Contact Guage |  |  |
| :---: | ---: | ---: | ---: |
| Per Contact | 26 | 22 | 20 |
| 1 | 2 | 1 | 1 |
| 2 | 8 | 4 | 2 |
| 3 | 16 | 8 | 5 |
| 4 | 27 | 13 | 8 |
| 5 | 41 | 19 | 13 |
|  |  |  |  |
| $\Delta T=2.100$ (i) 1.85 | 26 Guage Contacts |  |  |
| $\Delta T=0.989$ (i) 1.85 | 22 Guage Contacts |  |  |
| $\Delta T=0.640$ (i) 1.85 | 20 Guage Contacts |  |  |
| $\Delta T=$ Contact Temperature Rise |  |  |  |
| $i \quad=$ Amperes per Contact |  |  |  |


| Mating/Unmating Factor $-\pi_{\mathrm{K}}$ |
| :--- |
| Mating/Unmating Cycles* $\pi_{\mathrm{K}}$ <br> (Per1000 Hours)  |
| 0 to .05 |
| $>.05$ to .5 |
| $>.5$ to |
| $>5$ to 50 |
| $>50$ |

## MIL-HDBK-217F

15.2 CONNECTORS, PRINTED CIRCUIT BOARD

| Active Pins Factor - $\pi_{p}$ |  |  |  |
| :---: | :---: | :---: | :---: |
| Number of Active Contacts | $\pi_{P}$ | Number of Active Contacts | $\pi_{p}$ |
| 1 | 1.0 | 65 | 13 |
| 2 | 1.4 | 70 | 15 |
| 3 | 1.6 | 75 | 16 |
| 4 | 1.7 | 80 | 18 |
| 5 | 1.9 | 85 | 19 |
| 6 | 2.0 | 90 | 21 |
| 7 | 2.2 | 95 | 23 |
| 8 | 2.3 | 100 | 25 |
| 9 | 2.4 | 105 | 27 |
| 10 | 2.6 | 110 | 30 |
| 11 | 2.7 | 115 | 32 |
| 12 | 2.9 | 120 | 35 |
| 13 | 3.0 | 125 | 37 |
| 14 | 3.1 | 130 | 40 |
| 15 | 3.3 | 135 | 43 |
| 16 | 3.4 | 140 | 46 |
| 17 | 3.6 | 145 | 50 |
| 18 | 3.7 | 150 | 53 |
| 19 | 3.9 | 155 | 57 |
| 20 | 4.0 | 160 | 61 |
| 25 | 4.8 | 165 | 65 |
| 30 | 5.6 | 170 | 69 |
| 35 | 6.5 | 175 | 74 |
| 40 | 7.4 | 180 | 78 |
| 45 | 8.4 | 185 | 83 |
| 50 | 9.5 | 190 | 89 |
| 55 | 11 | 195 | 94 |
| 60 | 12 | 200 | 100 |
| $\pi_{P}=\exp \left(\frac{N-1}{10}\right)^{q}$ |  |  |  |
| $q=0.51064$ |  |  |  |
| $N=$ Number of Active Pins |  |  |  |
| An active contact is the conductive element which mates with another element for the purpose of transferring electrical energy. |  |  |  |


| Environment Factor $-\pi_{E}$ |  |  |
| :--- | :---: | :---: |
|  $\pi_{E}$  <br> Environment MIL-SPEC Lower Quality <br> $G_{B}$ 1.0 2.0 <br> $G_{F}$ 3.0 7.0 <br> $G_{M}$ 8.0 17 <br> $N_{S}$ 5.0 10 <br> $N_{U}$ 13 26 <br> $A_{I C}$ 6.0 14 <br> $A_{I F}$ 11 22 <br> $A_{U C}$ 6.0 14 <br> $A_{U F}$ 11 22 <br> $A_{R W}$ 19 37 <br> $S_{F}$ .50 .80 <br> $M_{F}$ 10 20 <br> $M_{L}$ 27 54 <br> $C_{L}$ 490 970 |  |  |

### 15.3 CONNECTORS, INTEGRATED CIRCUIT SOCKETS

 -
## SPECIFICATION

MIL-S-83734

## DESCRIPTION <br> IC Sockets, Plug-in

$$
\lambda_{p}=\lambda_{b} \pi_{P} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$



## MIL-HDBK-217F

16.1 INTERCONNECTION ASSEMBLIES WITH PLATED THROUGH HOLES

DESCRIPTION
Circuit Boards, Printed (PCBs) and Discrete Wiring
$\lambda_{p}=\lambda_{b}\left[N_{1} \pi_{C}+N_{2}\left(\pi_{C}+13\right)\right] \pi_{Q} \pi_{E}$ Failures $/ 10^{6}$ Hours

APPLICATION NOTE: For assemblies not using Plated Through Holes (PTH), use Section 17, Connections. A discrete wiring assembly with electroless deposit plated through holes is basically a pattern of insulated wires laid down on an adhesive coated substrate. The primary cause of failure for both printed wiring and discrete wiring assemblies is associated with plated through hole problems (e.g., barrel cracking).

| Base Faikure Rate $-\lambda_{\mathrm{b}}$ |  |
| :--- | :---: |
| Technology | $\lambda_{\mathrm{b}}$ |
| Printed Wiring Assembly/Printed <br> Circuit Boards with PTHs | .000041 |
| Discrete Wiring with Electroless <br> Deposited PTH $(\leq 2$ Levels of Circuitry) | .00026 |


| Quality Factor $-\pi_{\mathrm{Q}}$ |  |
| :---: | :---: |
| Quality | $\pi_{\mathrm{Q}}$ |
| MIL-SPEC or Comparable Institute for <br> Interconnecting, and Packaging <br> Electronic Circuits (IPC) Standards | 1 |
| Lower | 2 |

Number of PTHs Factor $-N_{1}$ and $N_{2}$

| Factor | Quantity |
| :---: | :--- |
| $N_{1}$ | Quantity of Wave Soldered Functional <br> $N_{2}$ |

Complexity Factor $-\pi_{C}$

| Number of Circuit Planes, $P$ | $\pi_{\mathrm{C}}$ |
| :---: | :---: |
| $\leq 2$ | 1.0 |
| 3 | 1.3 |
| 4 | 1.6 |
| 5 | 1.8 |
| 6 | 2.0 |
| 7 | 2.2 |
| 8 | 2.4 |
| 9 | 2.6 |
| 10 | 2.8 |
| 11 | 2.9 |
| 12 | 3.1 |
| 13 | 3.3 |
| 14 | 3.4 |
| 15 | 3.7 |
| 16 | 1 |
|  |  |
| $\pi_{\mathrm{C}}=.65 \mathrm{P} .63$ | $2 \leq \mathrm{P} \leq 16$ |


| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\pi_{E}$ |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 2.0 |
| $G_{M}$ | 7.0 |
| $N_{S}$ | 5.0 |
| $N_{U}$ | 13 |
| $A_{I C}$ | 5.0 |
| $A_{I F}$ | 8.0 |
| $A_{U C}$ | 16 |
| $A_{U F}$ | 28 |
| $A_{R W}$ | 19 |
| $S_{F}$ | .50 |
| $M_{F}$ | 10 |
| $M_{L}$ | 27 |
| $C_{L}$ | 500 |

## DESCRIPTION <br> Connections Used on All Assemblies Except Those Using Plated Through Holes (PTH)

APPLICATION NOTE: The failure rate model in this section applies to connections used on all assemblies except those using plated through holes. Use the Interconnection Assembly Model in Section 16 to account for connections to a circuit board using plated through hole technology. The failure rate of the structure which supports the connections and parts, e.g., non-plated-through hole boards and terminal straps, is considered to be zero. Solderless wrap connections are characterized by solid wire wrapped under tension around a post, whereas hand soldering with wrapping does not depend on a tension induced connection. The following model is for a single connection.

$$
\lambda_{P}=\lambda_{B} \pi_{Q} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

| Base Failure Rate $-\lambda_{\mathrm{D}}$ |  |
| :---: | :---: |
| Connection Type $\lambda_{\mathrm{D}}\left(F / 10^{6} \mathrm{hrs}\right)$ <br> Hand Solder, w/o Wrapping .0026 <br> Hand Solder, w/Wrapping .00014 <br> Crimp .00026 <br> Weld .00005 <br> Solderless Wrap .0000035 <br> Clip Termination .00012 <br> Reflow Solder .000069 |  |


| Quality Factor - $\pi_{Q}$ |  |  |
| :---: | :---: | :---: |
| Quality Grade | $\pi_{Q}$ | Comments |
| Crimp Types |  |  |
| Automated | 1.0 | Daily pull tests recommended. |
| Manual |  |  |
| Upper | 1.0 | Only MIL-SPEC or equivalent tools and terminals, pull test at beginning and end of each shift, color coded tools and terminations. |
| Standard | 2.0 | MIL-SPEC tools, pull test at beginning of each shift. |
| Lower | 20.0 | Anything less than standard criteria. |
| All Types Except Crimp | 1.0 |  |

## MIL-HDBK-217F

SPECIFICATION MIL-M-10304

## DESCRIPTION

Meter, Electrical Indicating, Panel Type, Ruggedized

$$
\lambda_{p}=\lambda_{b} \pi_{A} \pi_{F} \pi_{Q} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

Base Failure Rate $-\lambda_{\mathrm{b}}$

| Type | $\lambda_{\mathrm{b}}$ |
| :---: | :---: |
| All | .090 |


| Quality Factor $-\pi_{\mathrm{Q}}$ |  |
| :---: | :---: |
| Quality | $\pi_{\mathrm{Q}}$ |
| MIL-M-10304 | 1.0 |
| Lower | 3.4 |


| Application Factor $-\pi_{\mathrm{A}}$ |  |
| :--- | :---: |
| Application | $\pi_{\mathbf{A}}$ |
| Direct Current | 1.0 |
| Alternating Current | 1.7 |


| Function Factor $-\pi_{F}$ |  |
| :--- | :---: |
| Function | $\pi_{F}$ |
| Ammeter | 1.0 |
| Voltmeter | 1.0 |
| Other* | 2.8 |

- Meters whose basic meter movement construction is an ammeter with associated conversion elements.

| Environment Factor $-\pi_{E}$ |  |
| :---: | :---: |
| Environment | $\pi_{E}$ |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 4.0 |
| $G_{M}$ | 25 |
| $N_{S}$ | 12 |
| $N_{U}$ | 35 |
| $A_{I C}$ | 28 |
| $A_{I F}$ | 42 |
| $A_{U C}$ | 58 |
| $A_{U F}$ | 73 |
| $A_{R W}$ | 60 |
| $S_{F}$ | 1.1 |
| $M_{F}$ | 60 |
| $M_{L}$ | $N / A$ |
| $C_{L}$ | $N / A$ |

## MIL-HDBK-217F

```
SPECIFICATION
MIL-C-3098
```


## DESCRIPTION

Crystal Units, Quartz

$$
\lambda_{p}=\lambda_{b} \pi_{Q} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

| Base Failure Rate $-\lambda_{\mathrm{b}}$ |  |
| :---: | :---: |
| Frequency, $\mathrm{f}(\mathrm{MHz})$ | $\lambda_{\mathrm{b}}$ |
| 0.5 | .011 |
| 1.0 | .013 |
| 5.0 | .019 |
| 10 | .022 |
| 15 | .024 |
| 20 | .026 |
| 25 | .027 |
| 30 | .028 |
| 35 | .029 |
| 40 | .031 |
| 45 | 032 |
| 50 | .033 |
| 55 | .033 |
| 60 | .034 |
| 65 | .035 |
| 70 | .036 |
| 75 | .036 |
| 80 | .037 |
| 85 | .037 |
| 90 | .038 |
| 95 |  |
| 100 |  |
| 105 |  |


| Environment Factor $-\pi_{\mathrm{E}}$ |  |
| :---: | :---: |
| Environment | $\pi_{\mathrm{E}}$ |
| $\mathrm{G}_{\mathrm{B}}$ | 1.0 |
| $\mathrm{G}_{\mathrm{F}}$ | 3.0 |
| $\mathrm{G}_{\mathrm{M}}$ | 10 |
| $\mathrm{~N}_{\mathrm{S}}$ | 6.0 |
| $\mathrm{~N}_{\mathrm{U}}$ | 16 |
| $\mathrm{~A}_{\mathrm{I}}$ | 12 |
| $\mathrm{~A}_{\mathrm{IF}}$ | 17 |
| $\mathrm{~A}_{\mathrm{UC}}$ | 22 |
| $\mathrm{~A}_{\mathrm{UF}}$ | 28 |
| $\mathrm{~A}_{\mathrm{RW}}$ | 23 |
| $\mathrm{~S}_{\mathrm{F}}$ | .50 |
| $M_{\mathrm{F}}$ | 13 |
| $M_{\mathrm{L}}$ | 32 |
| $\mathrm{C}_{\mathrm{L}}$ | 500 |


| Quality Factor $-\pi_{\mathrm{O}}$ |  |
| :--- | :---: |
| Ouality | $\pi_{\mathrm{Q}}$ |
| MIL-SPEC | 1.0 |
| Lower | 2.1 |

MIL-HDBK-217F

## SPECIFICATION

## DESCRIPTION

MIL-L-6363
Lamps, Incandescent, Aviation Service
W-L-111

$$
\lambda_{p}=\lambda_{b} \pi_{U} \pi_{A} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

APPLICATION NOTE: The data used to develop this model included randomly occurring catastrophic failures and failures due to tungsten filament wearout.

| Rated Voltage, $\mathrm{V}_{\mathrm{r}}$ (Volts) | $\lambda_{b}$ |
| :---: | :---: |
| $\begin{aligned} & 5 \\ & 6 \\ & 12 \\ & 14 \\ & 24 \\ & 28 \\ & 37.5 \end{aligned}$ | $\begin{array}{r} .59 \\ .75 \\ 1.8 \\ 2.2 \\ 4.5 \\ 5.4 \\ 7.9 \end{array}$ |
| $\lambda_{b}=.074\left(V_{r}\right)^{1.29}$ |  |


| Utiilization Factor $-\pi_{U}$ |  |
| :--- | :--- |
| Utilization (Illuminate Hours/' <br> Equipment Operate Hours) <br> $<0.10$ <br> 0.10 to 0.90 <br> $>0.90$ | 0.10 |


| Environment | $\pi_{\text {E }}$ |
| :---: | :---: |
| $\mathrm{G}_{\mathrm{B}}$ | 1.0 |
| $\mathrm{G}_{\mathrm{F}}$ | 2.0 |
| $G_{M}$ | 3.0 |
| $\mathrm{N}_{S}$ | 3.0 |
| $\mathrm{N}_{\mathrm{U}}$ | 4.0 |
| $A_{1 C}$ | 4.0 |
| $A_{\text {IF }}$ | 4.0 |
| ${ }^{\text {A }}$ UC | 5.0 |
| ${ }^{\text {A }}$ UF | 6.0 |
| $A_{\text {RW }}$ | 5.0 |
| $S_{F}$ | . 70 |
| $M_{F}$ | 4.0 |
| $M_{L}$ | 6.0 |
| $\mathrm{C}_{\mathrm{L}}$ | 27 |

Application Factor $-\pi_{\mathrm{A}}$

| Application | $\pi_{\mathrm{A}}$ |
| :--- | :---: |
| Alternating Current | 1.0 |
| Direct Current | 3.3 |

## SPECIFICATION

MIL-F-15733
MIL-F-18327

## DESCRIPTION

Fitters, Radio Frequency Interference
Fitters, High Pass, Low Pass, Band Pass, Band Suppression, and Dual Functioning (Non-tunable)

The most accurate way to estimate the failure rate for electronic filters is to sum the failure rates tor the individual components which make up the filter (e.g., IC's, diodes, resistors, etc.) using the appropriate models provided in this Handbook. The Parts Stress models or the Parts Count method given in Appendix A can be used to determine individual component failure rates. If insufficient information is available then the following defaut model can be used.

$$
\lambda_{P}=\lambda_{D} \pi_{Q} \pi_{E} \quad \text { Failures } / 10^{6} \text { Hours }
$$

| Type | $\lambda_{b}$ |
| :---: | :---: |
| MIL-F-15733, Ceramic-Ferrite Construction (Styles FL 10-16, 22, 24, 30-32, 34, 35, 38, 41-43, 45, 47-50, 61-65, 70, 81-93, 95, 96) | . 022 |
| MIL-F-15733, Discrete LC Components, (Styles FL 37, 53, 74) | . 12 |
| MIL-F-18327, Discrete LC Components (Composition 1) | . 12 |
| MIL-F-18327, Discrete LC and Crystal Components (Composition 2) | . 27 |
| Quality Factor - $\pi_{\mathrm{Q}}$ |  |
| Quality | $\pi_{0}$ |
| MIL-SPEC | 1.0 |
| Lower | 2.9 |


| Environment Factor $-\pi_{E}$ |
| :--- |
| Environment $\pi_{E}$ <br> $G_{B}$ 1.0 <br> $G_{F}$ 2.0 <br> $G_{M}$ 6.0 <br> $N_{S}$ 4.0 <br> $N_{U}$ 9.0 <br> $A_{I C}$ 7.0 <br> $A_{I F}$ 9.0 <br> $A_{U C}$ 11 <br> $A_{U F}$ 13 <br> $A_{R W}$ 11 <br> $S_{F}$ .80 <br> $M_{F}$ 7.0 <br> $M_{L}$ 15 <br> $C_{L}$ 120 |

MIL-HDBK-217F
22.1 FUSES

## SPECIFICATION

W-F-1726
W-F-1814
MIL-F-5372
ML-F-23419
MiL-F-15160

DESCRIPTION<br>Fuse, Cartridge Class H<br>Fuse, Cartridge, High Interrupting Capacity<br>Fuse, Current Limiter Type, Aircraft<br>Fuse, Instrument Type<br>Fuse, Instrument, Power and Telephone<br>(Nonindicating), Style F01

$$
\lambda_{p}=\lambda_{t} \pi_{E} \text { Failures } / 10^{6} \text { Hours }
$$

APPLICATION NOTE: The reliabiitity modeling of fuses presents a unique problem. Unlike most other components, there is very little correlation between the number of fuse replacements and actual fuse failures. Generally when a fuse opens, or "blows," something else in the circuit has created an overload condition and the fuse is simply functioning as designed. This model is based on life test data and represents fuse open and shorting failure modes due primarily to mechanical fatigue and corrosion. A short faihure mode is most commonty caused by electrically conductive material shorting the fuse terminals logether causing a failure to open condition when rated current is exceeded.


| Environment | $\pi_{\mathrm{E}}$ |
| :---: | :---: |
| $G_{B}$ | 1.0 |
| $G_{F}$ | 2.0 |
| $\mathrm{G}_{\mathrm{M}}$ | 8.0 |
| $\mathrm{N}_{S}$ | 5.0 |
| $\mathrm{N}_{\mathrm{U}}$ | 11 |
| $A_{\text {ic }}$ | 9.0 |
| $A_{\text {IF }}$ | 12 |
| ${ }^{\text {A }}$ UC | 15 |
| A UF | 18 |
| ${ }^{\text {A }}$ RW | 16 |
| $S_{F}$ | . 90 |
| $M_{F}$ | 10 |
| $M_{L}$ | 21 |
| $C_{L}$ | 230 |

$\lambda_{p}$ - Failure Rates for Miscellaneous Parts (Faikures/10 ${ }^{6}$ Hours)

| Pant Type | Failure Rate |
| :---: | :---: |
| Vibrators (MIL=V=95) 60-cycle 120-cycle 400-cycle | 15 20 40 |
| Lamps Neon Lamps | 0.20 |
| Fiber Optic Cables (Single Fiber Types Only) | 0.1 (Per Fiber Km) |
| Single Fiber Optic Connectors* | 0.10 |
| Microwave Elements (Coaxial \& Waveguide) Attenuators (Fixed \& Variable) | See Resistors, Type RD |
| Fixed Elements (Directional Couplers, Fixed Stubs \& Cavities) | Negligible |
| Variable Clements (Tuned Stubs \& Cavities) | 0.10 |
| Microwave Ferrite Devices Isolators \& Circulators ( 5100 W ) | $0.10 \times \pi_{E}$ |
| Isolators \& Circulators ( $>100 \mathrm{~W}$ ) | $0.20 \times \pi_{E}$ |
| Phase Shifter (Latching) | $0.10 \times \pi_{E}$ |
| Dummy Loads < 100W | $0.010 \times \pi_{E}$ |
| 100 W to $\leq 1000 \mathrm{~W}$ | $0.030 \times \pi_{E}$ |
| > 1000 W | $0.10 \times \pi_{E}$ |
| Terminations (Thin or Thick Fitm Loads Used in Stripline and Thin Film Circults) | $0.030 \times \pi{ }_{E}$ |

[^1]
## MIL-HDBK-217F

### 23.1 MISCELLANEOUS

| Environment Factor - $\pi_{E}$ <br> (Microwave Ferrite Devices) |  | Environment Factor $-\pi_{E}$ (Dummy Loads) |  |
| :---: | :---: | :---: | :---: |
| Environment | $\pi_{E}$ | Environment | $\pi_{\mathrm{E}}$ |
| $\mathrm{G}_{\mathrm{B}}$ | 1.0 | $\mathrm{G}_{\mathrm{B}}$ | 1.0 |
| $G_{F}$ | 2.0 | $\mathrm{G}_{\mathrm{F}}$ | 2.0 |
| $G_{M}$ | 8.0 | $\mathrm{G}_{\mathrm{M}}$ | 10 |
| $\mathrm{N}_{S}$ | 5.0 | ${ }^{\mathrm{N}}$ S | 5.0 |
| $\mathrm{N}_{\mathrm{U}}$ | 12 | $\mathrm{N}_{\mathrm{U}}$ | 17 |
| $A_{\text {IC }}$ | 5.0 | $A_{1}$ | 6.0 |
| $A_{\text {IF }}$ | 8.0 | $A_{\text {IF }}$ | 8.0 |
| ${ }^{\text {A }}$ UC | 7.0 | ${ }^{\text {A }}$ UC | 14 |
| ${ }^{\text {A }}$ UF | 11 | ${ }^{\text {A }}$ UF | 22 |
| $A_{\text {RW }}$ | 17 | $A_{\text {RW }}$ | 25 |
| $S_{F}$ | . 50 | $S_{F}$ | . 50 |
| $M_{F}$ | 9.0 | $\mathrm{M}_{\mathrm{F}}$ | 14 |
| $M_{L}$ | 24 | $M_{L}$ | 36 |
| $\mathrm{C}_{\mathrm{L}}$ | 450 | $\mathrm{C}_{\mathrm{L}}$ | 660 |

MIL-HDBK-217F

APPENDIX A: PARTS COUNT RELIABILITY PREDICTION

Parts Coumt Rellabillty Prediction - This prediction method is applicable during bid proposal and earty design phases when insufficient information is avaitable to use the part stress analysis models shown in the main body of this Handbook. The information needed to apply the method is (1) generic part types (including complexity for microcircuits) and quantities, (2) part quality levels, and (3) equipment environment. The equipment failure rate is obtained by looking up a generic failure rate in one of the following tables, multiphying it by a qually factor, and then summing it with failure rates obtained for other components in the equipment. The general mathematical expression for equipment taikre rate with this method is:

$$
\lambda_{\text {EQUIP }}=\sum_{i=1}^{i=n} N_{i}\left(\lambda_{0} \pi^{\alpha_{i}} \quad \quad \text { Equation } 1\right.
$$

for a given equipment ervironment where:
$\lambda_{\text {EQUIP }}=$ Total equipment faikure rate (Failures/10 ${ }^{6}$ Hours)
$\lambda_{g}=$ Generic failure rate for the $i^{\text {th }}$ generic part (Failures $/ 10^{6}$ Hours)
$\pi_{Q} \quad=$ Quality factor for the $i^{\text {th }}$ generic part
$N_{i} \quad=$ Quantity of $i^{\text {th }}$ generic part
$n$

Equation 1 applies if the entire equipment is being used in one environment. If the equipment comprises several units operating in different environments (such as avionics systems with units in airborne inhabited $\left(A_{1}\right)$ and uninhabited ( $A_{U}$ ) environments), then Equation 1 should be applied to the portions of the equipment in each environment. These "environment-equipment" failure rates should be added to determine total equipment failure rate. Environmental symbols are defined in Section 3.

The quality factors to be used with each part type are shown with the applicable $\lambda_{\mathrm{g}}$ tables and are not necessarily the same values that are used in the Part Stress Analysis. Microcircuits have an additional multiplying factor, $\pi_{L}$, which accounts for the maturty of the manufacturing process. For devices in production two years or more, no modification is needed. For those in production less than two years, $\lambda_{g}$ should be multiplied by the appropriate $\pi_{\mathrm{L}}$ factor (See page A-4).

It should be noted that no generic failure rates are shown for hybrid microcircuits. Each hybrid is a fairty unique device. Since none of these devices have been standardized, their complexity cannot be determined from their name or function. Identically or similarty named hybrids can have a wide range of complexity that thwarts categorization for purposes of this prediction method. Hf hybrids are anticipated for a design, their use and construction should be thoroughly investigated on an individual basis with application of the prediction model in Section 5.

The failure rates shown in this Appendix were calculated by assigning model default values to the failure rate models of Section 5 through 23. The spectic default values used for the model parameters are shown with the $\lambda_{g}$ Tables for microcircuits. Defauk parameters for all other part classes are summarized in the tables starting on Page A-12. For parts with characteristics which differ significantly from the assumed defaults, or parts used in large quantities, the underlying models in the main body of this Handbook can be used.

## MIL-HDBK-217F

\begin{tabular}{|c|c|c|c|c|c|c|c|c|c|c|c|c|c|c|c|c|}
\hline Section \& Broclac Iechollogy \& $$
\begin{aligned}
& \text { Emivion. } \rightarrow \\
& T_{J}\left(C_{0}\right) \rightarrow
\end{aligned}
$$ \& $$
\begin{aligned}
& G_{8} \\
& 50 \\
& \hline
\end{aligned}
$$ \& $G_{F}$
60 \& GM
65 \& N

0 \& $\mathrm{N}_{15}$
05 \& $A_{10}$

75 \& | ${ }^{1} 7$ |
| :--- |
| 75 | \& $41 \%$

90 \& $$
\begin{gathered}
A_{1 F} \\
00
\end{gathered}
$$ \& $\left.{ }^{A_{\text {RW }}} \begin{array}{c}75\end{array}\right]$ \& \[

$$
\begin{array}{r}
S_{F} \\
50 \\
\hline
\end{array}
$$

\] \& | 70 |
| :---: |
| 85 | \& M

75 \& $C$
60 <br>

\hline \multirow[t]{7}{*}{5.1} \& \multirow[t]{7}{*}{| Gatelopic Arrays, Digital (Ea - .4) |
| :--- |
| 1-100 Galin |
| 101-1000 Gales |
| 1001 it 3010 Gatios |
| 3001 to 10,000 Gates |
| 10,000 to 30,000 Gates |
| 30,000 to 00,000 Gapes |} \& \multirow[t]{7}{*}{} \& \multirow[t]{7}{*}{\[

$$
\begin{aligned}
& .0036 \\
& .0060 \\
& .11 \\
& .033 \\
& .52 \\
& .075
\end{aligned}
$$

\]} \& \multirow[t]{7}{*}{\[

$$
\begin{aligned}
& .012 \\
& .020 \\
& .035 \\
& .12 \\
& .17 \\
& .23 \\
& \hline
\end{aligned}
$$

\]} \& \multirow[t]{7}{*}{\[

$$
\begin{aligned}
& .024 \\
& .008 \\
& .086 \\
& .22 \\
& .33 \\
& .44 \\
& \hline
\end{aligned}
$$

\]} \& \multirow[t]{7}{*}{\[

$$
\begin{aligned}
& .024 \\
& .037 \\
& .085 \\
& .22 \\
& .33 \\
& .43 \\
& \hline
\end{aligned}
$$

\]} \& \multirow[t]{7}{*}{\[

$$
\begin{aligned}
& .035 \\
& .055 \\
& .097 \\
& .33 \\
& .48 \\
& .83 \\
& \hline
\end{aligned}
$$

\]} \& \multirow[t]{7}{*}{\[

$$
\begin{aligned}
& .025 \\
& .029 \\
& .070 \\
& .23 \\
& .34 \\
& .48 \\
& \hline
\end{aligned}
$$

\]} \& \multirow[t]{7}{*}{\[

$$
\begin{aligned}
& .030 \\
& .048 \\
& .085 \\
& .28 \\
& .42
\end{aligned}
$$

\]} \& \multirow[t]{7}{*}{\[

$$
\begin{aligned}
& .032 \\
& .051 \\
& .061 \\
& .30 \\
& .45
\end{aligned}
$$

\]} \& \multirow[t]{7}{*}{\[

$$
\begin{aligned}
& .049 \\
& .017 \\
& .14 \\
& .48 \\
& .68 \\
& .90
\end{aligned}
$$

\]} \& \multirow[t]{7}{*}{\[

$$
\begin{aligned}
& .017 \\
& .074 \\
& .13 \\
& .41 \\
& .85
\end{aligned}
$$

\]} \& \multirow[t]{7}{*}{\[

$$
\begin{aligned}
& .0038 \\
& .0060 \\
& .011 \\
& .033 \\
& .075
\end{aligned}
$$
\]} \& \multirow[t]{7}{*}{.030

.046
.082
.28
.41

53} \& \multirow[t]{7}{*}{$$
\begin{aligned}
& .080 \\
& .11 \\
& .10 \\
& .85 \\
& 1.25 \\
& \hline
\end{aligned}
$$} \& \multirow[t]{7}{*}{\[

$$
\begin{aligned}
& 1.2 \\
& 1.0 \\
& 3.3 \\
& 12 \\
& 17 \\
& 71
\end{aligned}
$$
\]} <br>

\hline \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& <br>
\hline \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& <br>
\hline \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& <br>
\hline \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& <br>
\hline \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& <br>
\hline \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& <br>
\hline \multirow[t]{5}{*}{5.1} \& Gateloglic Array , Linaer (Ea = . 85 ) \& \multirow[t]{5}{*}{} \& \multirow[t]{5}{*}{.0095
.017
.033

.050} \& \multirow[t]{5}{*}{$$
\begin{aligned}
& .024 \\
& .041 \\
& .074 \\
& .12 \\
& \hline
\end{aligned}
$$} \& \multirow[t]{5}{*}{\[

$$
\begin{aligned}
& .039 \\
& .085 \\
& .11 \\
& .18 \\
& \hline
\end{aligned}
$$

\]} \& \multirow[t]{5}{*}{\[

$$
\begin{array}{r}
.034 \\
.054 \\
.092 \\
.15 \\
\hline
\end{array}
$$

\]} \& \multirow[t]{5}{*}{\[

$$
\begin{aligned}
& .048 \\
& .078 \\
& .13 \\
& .21 \\
& \hline
\end{aligned}
$$

\]} \& \multirow[t]{5}{*}{\[

$$
\begin{aligned}
& .057 \\
& .10 \\
& .19 \\
& .29 \\
& \hline
\end{aligned}
$$

\]} \& \multirow[t]{5}{*}{\[

$$
\begin{aligned}
& .062 \\
& .11 \\
& .19 \\
& .30 \\
& \hline
\end{aligned}
$$

\]} \& \multirow[t]{5}{*}{\[

$$
\begin{aligned}
& .12 \\
& .22 \\
& .41 \\
& .63 \\
& \hline
\end{aligned}
$$

\]} \& \multirow[t]{5}{*}{\[

$$
\begin{aligned}
& .13 \\
& .24 \\
& .44 \\
& .67 \\
& \hline
\end{aligned}
$$

\]} \& \multirow[t]{5}{*}{\[

$$
\begin{aligned}
& .076 \\
& .13 \\
& .22 \\
& .35 \\
& \hline
\end{aligned}
$$

\]} \& \multirow[t]{5}{*}{\[

$$
\begin{aligned}
& .0095 \\
& .017 \\
& .033 \\
& .050 \\
& \hline
\end{aligned}
$$

\]} \& \multirow[t]{5}{*}{\[

$$
\begin{aligned}
& .044 \\
& .072 \\
& .12 \\
& .19
\end{aligned}
$$

\]} \& \multirow[t]{5}{*}{\[

$$
\begin{aligned}
& .098 \\
& .15 \\
& .20 \\
& .41
\end{aligned}
$$
\]} \& \multirow[t]{5}{*}{1.1

1.4
2.0
3.4} <br>

\hline \& | 1-100 Tremisiators |
| :--- |
| 101-300 Transistora | \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& <br>

\hline \&  \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& <br>

\hline \& | 301-1000 Transietiors |
| :--- |
| 1001-10,000 Trensistora | \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& <br>

\hline \& \multirow[t]{4}{*}{} \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& <br>
\hline \multirow[t]{3}{*}{5.1} \& \& (16 Pin DIP) \& . 0061 \& 016 \& 029 \& \& \& \& \& \& \& \& \& \& \& <br>
\hline \& \& (24 Pin DIP) \& . 011 \& . 028 \& . 048 \& . 04.4 \& . 04 \& . 032 \& . 037 \& . 044 \& . 081 \& . 054 \& . 0081 \& . 034 \& . 076 \& 1.2 <br>
\hline \& \& 140 Pin DIP \& . 022 \& . 052 \& . 087 \& \& \& . 054 \& . 063 \& . 077 \& . 10 \& . 039 \& 011 \& . 057 \& . 12 \& 1.9 <br>

\hline \multirow[t]{8}{*}{5.1} \& \multirow[t]{8}{*}{} \& \multirow[t]{8}{*}{| (16 Pin DIP) $(24$ Pin DIP (40 Pin DIP) |
| :--- |
| ( 120 Piri PGA) |
| (100 Pin PGA) |
| (224 Pin PGA) |} \& \multirow[t]{8}{*}{.0057

.010
.019
.049

.13} \& \multirow[t]{8}{*}{$$
\begin{aligned}
& .015 \\
& .028 \\
& .047 \\
& .14 \\
& .22 \\
& .31 \\
& \hline
\end{aligned}
$$} \& \multirow[t]{8}{*}{\[

$$
\begin{aligned}
& .027 \\
& .045 \\
& .850 \\
& .25 \\
& .39
\end{aligned}
$$

\]} \& \multirow[t]{8}{*}{\[

$$
\begin{aligned}
& .027 \\
& .043 \\
& .077 \\
& .24 \\
& .51
\end{aligned}
$$

\]} \& \multirow[t]{8}{*}{\[

$$
\begin{aligned}
& .039 \\
& .062 \\
& .11 \\
& .36 \\
& .54 \\
& .73 \\
& \hline
\end{aligned}
$$

\]} \& \multirow[t]{8}{*}{\[

$$
\begin{aligned}
& .029 \\
& .040 \\
& .088 \\
& .27 \\
& .42 \\
& .59 \\
& \hline
\end{aligned}
$$
\]} \& . 11 \& . 14 \& . 18 \& . 13 \& 022 \& . 10 \& 22 \& 3.3 <br>

\hline \& \& \& \& \& \& \& \& \& \multirow[t]{7}{*}{$$
\begin{aligned}
& .035 \\
& .057 \\
& .10 \\
& .32 \\
& .49 \\
& .69 \\
& \hline
\end{aligned}
$$} \& \multirow[t]{7}{*}{\[

$$
\begin{aligned}
& .030 \\
& .006 \\
& .12 \\
& .36 \\
& .56 \\
& .82 \\
& \hline
\end{aligned}
$$

\]} \& \multirow[t]{7}{*}{\[

$$
\begin{gathered}
.058 \\
.092 \\
.17 \\
.51 \\
.79 \\
1.1 \\
\hline
\end{gathered}
$$

\]} \& \multirow[t]{7}{*}{\[

$$
\begin{aligned}
& .052 \\
& .033 \\
& .15 \\
& .48 \\
& .72
\end{aligned}
$$

\]} \& \multirow[t]{8}{*}{\[

$$
\begin{aligned}
& .0057 \\
& .010 \\
& .019 \\
& .048 \\
& .084 \\
& .13 \\
& \hline
\end{aligned}
$$
\]} \& \multirow[t]{8}{*}{.033

.053
.095
.30
.46

.83} \& \multirow[t]{8}{*}{$$
\begin{gathered}
.074 \\
.12 \\
.21 \\
.00 \\
1.0 \\
1.4 \\
\hline
\end{gathered}
$$} \& \multirow[t]{7}{*}{1.2

1.9
3.3
12
17
21} <br>
\hline \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& <br>
\hline \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& <br>
\hline \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& <br>
\hline \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& <br>
\hline \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& <br>
\hline \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& <br>

\hline \multirow[t]{5}{*}{5.1} \& \multirow[t]{5}{*}{| Gaimiogic Arragi, Lhear (EA $=$. .B5 |
| :--- |
| 10100 Translitions 101 yo 300 Trandictors 301 to 1,000 Tranciation 1001 bo 10,000 Trandiesora |} \& \multirow[t]{5}{*}{} \& \multirow[t]{5}{*}{\[

$$
\begin{aligned}
& .0095 \\
& .017 \\
& .033 \\
& .05 \\
& \hline
\end{aligned}
$$

\]} \& \multirow[t]{5}{*}{\[

$$
\begin{array}{r}
.024 \\
.041 \\
.074 \\
.12 \\
\hline
\end{array}
$$

\]} \& \multirow[t]{5}{*}{\[

$$
\begin{aligned}
& .038 \\
& .065 \\
& .11 \\
& .18 \\
& \hline
\end{aligned}
$$

\]} \& \multirow[t]{5}{*}{\[

$$
\begin{array}{r}
.034 \\
.054 \\
.092 \\
.15 \\
\hline
\end{array}
$$

\]} \& \multirow[t]{5}{*}{\[

$$
\begin{aligned}
& .043 \\
& .073 \\
& .13 \\
& .21 \\
& \hline
\end{aligned}
$$

\]} \& \multirow[t]{5}{*}{\[

$$
\begin{aligned}
& .057 \\
& .10 \\
& .19 \\
& .29 \\
& \hline
\end{aligned}
$$

\]} \& \multirow[t]{5}{*}{\[

$$
\begin{aligned}
& .062 \\
& .11 \\
& .30 \\
& .30 \\
& \hline
\end{aligned}
$$

\]} \& \multirow[t]{5}{*}{\[

$$
\begin{array}{r}
.12 \\
.22 \\
.41 \\
.63 \\
\hline
\end{array}
$$

\]} \& \& \multirow[t]{5}{*}{\[

$$
\begin{aligned}
& .076 \\
& .13 \\
& .22 \\
& .35
\end{aligned}
$$
\]} \& \& \& \& <br>

\hline \& \& \& \& \& \& \& \& \& \& \& \multirow[t]{4}{*}{$$
\begin{array}{r}
131 \\
.24 \\
.44 \\
.67 \\
\hline
\end{array}
$$} \& \& \multirow[t]{5}{*}{\[

$$
\begin{aligned}
& .0095 \\
& .017 \\
& .033 \\
& \hline
\end{aligned}
$$

\]} \& \multirow[t]{4}{*}{\[

$$
\begin{aligned}
& .044 \\
& .072 \\
& .12 \\
& .10
\end{aligned}
$$
\]} \& \multirow[t]{5}{*}{.098

.15
.20
.4} \& \multirow[t]{5}{*}{1.1
1.4
2.0
3.4} <br>
\hline \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& <br>
\hline \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& <br>
\hline \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& <br>

\hline \multirow[t]{5}{*}{5.1} \& \multirow[t]{5}{*}{| 1001 to 10,000 Trandicxars |
| :--- |
| Floaing (sate Progrerninestive Logic Arty, AIOS (Ee m36) Up to 16K Ciols 16K io 84K Colls 64K to 256 K Colla 256K of 1 MCCl |} \& \multirow[t]{6}{*}{} \& \multirow[t]{6}{*}{\[

$$
\begin{array}{r}
.0048 \\
.0058 \\
.0081 \\
.0095 \\
\hline
\end{array}
$$

\]} \& \multirow[t]{6}{*}{\[

$$
\begin{aligned}
& .018 \\
& .021 \\
& .022 \\
& .033 \\
& \hline
\end{aligned}
$$

\]} \& \multirow[t]{6}{*}{\[

$$
\begin{aligned}
& .035 \\
& .042 \\
& .043 \\
& .044 \\
& \hline
\end{aligned}
$$

\]} \& \multirow[t]{6}{*}{\[

$$
\begin{aligned}
& .035 \\
& .042 \\
& .042 \\
& .063
\end{aligned}
$$
\]} \& \& \& \& \& \& \& \& \& \& <br>

\hline \& \& \& \& \& \& \& \multirow[t]{5}{*}{$$
\begin{array}{r}
.052 \\
.062 \\
.083 \\
.094 \\
\hline
\end{array}
$$} \& \multirow[t]{5}{*}{\[

$$
\begin{array}{r}
.035 \\
.042 \\
.043 \\
.085 \\
\hline
\end{array}
$$

\]} \& \multirow[t]{5}{*}{\[

$$
\begin{array}{r}
.044 \\
.052 \\
.054 \\
.080 \\
\hline
\end{array}
$$

\]} \& \multirow[t]{5}{*}{| .044 |
| ---: |
| .053 |
| .055 |
| .083 |} \& \multirow[t]{5}{*}{.070

.084
.086

.13} \& \multirow[t]{5}{*}{$$
\begin{aligned}
& .070 \\
& .013 \\
& .013 \\
& .13 \\
& \hline
\end{aligned}
$$} \& \multirow[t]{5}{*}{\[

$$
\begin{array}{r}
.0048 \\
.0058 \\
.0061 \\
.0095 \\
\hline
\end{array}
$$

\]} \& \multirow[t]{5}{*}{\[

$$
\begin{array}{r}
.044 \\
.052 \\
.053 \\
.079 \\
\hline
\end{array}
$$

\]} \& \multirow[t]{5}{*}{\[

$$
\begin{array}{r}
.10 \\
12 \\
.13 \\
.19 \\
\hline
\end{array}
$$

\]} \& \multirow[t]{5}{*}{| 1.9 |
| :--- |
| 2.3 |
| 2.3 |
| 3.3 |} <br>

\hline \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& <br>
\hline \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& <br>
\hline \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& <br>

\hline \multirow[t]{4}{*}{5.1} \& \multirow[t]{4}{*}{| Microprocesames, Bpoilur (Ell a . .1) |
| :--- |
| Yo to 8 Bits |
| Up of 16 Biss |
| Up to 32 Bins |} \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& <br>

\hline \& \& \multirow[t]{3}{*}{(40 Pin DIP) (64 Pin PGA) (128 Pin PGA)} \& \multirow[t]{3}{*}{$$
\begin{aligned}
& .028 \\
& .052 \\
& .11 \\
& \hline
\end{aligned}
$$} \& \multirow[t]{3}{*}{\[

$$
\begin{aligned}
& .061 \\
& .11 \\
& .23 \\
& \hline
\end{aligned}
$$

\]} \& \multirow[t]{3}{*}{\[

$$
\begin{aligned}
& .098 \\
& .18 \\
& .36
\end{aligned}
$$

\]} \& \multirow[t]{4}{*}{\[

$$
\begin{array}{r}
.091 \\
.16 \\
.33 \\
\hline
\end{array}
$$

\]} \& \multirow[t]{4}{*}{\[

$$
\begin{array}{r}
13 \\
.23 \\
.47 \\
\hline
\end{array}
$$

\]} \& \multirow[t]{4}{*}{\[

$$
\begin{aligned}
& .12 \\
& .21 \\
& .44 \\
& \hline
\end{aligned}
$$

\]} \& \multirow[t]{4}{*}{\[

$$
\begin{array}{r}
.13 \\
.24 \\
.49 \\
\hline
\end{array}
$$

\]} \& \multirow[t]{4}{*}{\[

$$
\begin{aligned}
& .17 \\
& .32 \\
& .65 \\
& \hline
\end{aligned}
$$

\]} \& \multirow[t]{4}{*}{\[

$$
\begin{array}{r}
.22 \\
.38 \\
.81 \\
\hline
\end{array}
$$

\]} \& \multirow[t]{4}{*}{\[

$$
\begin{aligned}
& .114 \\
& .31 \\
& .65 \\
& \hline
\end{aligned}
$$

\]} \& \multirow[t]{4}{*}{\[

$$
\begin{aligned}
& .028 \\
& .052 \\
& .11 \\
& \hline
\end{aligned}
$$

\]} \& \multirow[t]{4}{*}{\[

$$
\begin{array}{r}
.11 \\
.20 \\
.42 \\
\hline
\end{array}
$$

\]} \& \multirow[t]{4}{*}{\[

$$
\begin{array}{r}
.24 \\
.41 \\
.86 \\
\hline
\end{array}
$$
\]} \& \multirow[t]{4}{*}{${ }^{3.3}{ }^{5.6}$} <br>

\hline \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& <br>
\hline \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& <br>

\hline \multirow[t]{4}{*}{5.1} \& \multirow[t]{4}{*}{} \& \multirow[t]{4}{*}{(40 Pin DIP) ( 64 Pin PGA) (128 Pin PGA)} \& \multirow[t]{4}{*}{$$
\begin{aligned}
& .048 \\
& .093 \\
& .10 \\
& \hline
\end{aligned}
$$} \& \multirow[t]{4}{*}{\[

$$
\begin{array}{r}
.089 \\
.17 \\
.34 \\
\hline
\end{array}
$$
\]} \& \& \& \& \& \& \& \& \& \& \& \& <br>

\hline \& \& \& \& \& \multirow[t]{3}{*}{$$
\begin{array}{r}
.13 \\
.24 \\
.49 \\
\hline
\end{array}
$$} \& \multirow[t]{3}{*}{\[

$$
\begin{array}{r}
.12 \\
22 \\
.45
\end{array}
$$
\]} \& \multirow[t]{3}{*}{.16

.29

.60} \& \multirow[t]{3}{*}{| .16 |
| :--- |
| .30 |
| .61 |} \& \multirow[t]{3}{*}{\[

$$
\begin{aligned}
& .17 \\
& .32 \\
& .66
\end{aligned}
$$

\]} \& \multirow[t]{3}{*}{\[

$$
\begin{aligned}
& .24 \\
& .45 \\
& .90 \\
& \hline
\end{aligned}
$$
\]} \& \multirow[t]{3}{*}{.28

.52

1.1} \& \multirow[t]{3}{*}{$$
\begin{array}{r}
.2 \% \\
.40 \\
.8 \% \\
\hline
\end{array}
$$} \& \multirow[t]{3}{*}{\[

$$
\begin{aligned}
& .048 \\
& .093 \\
& .19
\end{aligned}
$$
\]} \& \multirow[t]{3}{*}{.15

.27

.54} \& \multirow[t]{3}{*}{$$
\begin{array}{r}
.28 \\
.50 \\
\hline
\end{array}
$$} \& \multirow[t]{3}{*}{\[

$$
\begin{array}{r}
3.4 \\
5.8 \\
12 \\
\hline
\end{array}
$$
\]} <br>

\hline \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& <br>
\hline \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& \& <br>
\hline
\end{tabular}

MIL-HDBK-217F
APPENDIX A: PARTS COUNT


APPENDIX A: PARTS COUNT


| Qubiry Fectors - $0_{0}$ |  |
| :---: | :---: |
| Description | ${ }_{0}$ |
| cimes Gangorme: <br>  <br>  <br>  | . 25 |
| ChmBCitesorte: <br> 1. Procured in IUlli sccondencer with MiL-M-38510, Clasa 8 requiremerta. <br> 2. Procured in full accordenos with Mil. +39536, (Clase Q ). <br>  | 1.0 |
| Chamelcarmoct <br>  ML trawng. DESC dranthg or ather covermmore approved documummaiton. (Doee not <br>  | 2.0 |


Generlc Fallure Rate - $\lambda_{\text {g }}$ (Fallurea/10 ${ }^{15}$ Hours) for Discrete Semiconductors


| Soction | Pan Type | $\left[\begin{array}{l} \text { Env } \rightarrow Q_{B} \\ T_{j}(C) \rightarrow 50 \end{array}\right.$ | $\begin{aligned} & \mathrm{a}_{\mathrm{F}} \\ & 60 \end{aligned}$ | $\begin{aligned} & 9_{M} \\ & 65 \end{aligned}$ | $\begin{aligned} & N_{S} \\ & 60 \end{aligned}$ | $\begin{aligned} & N_{y} \\ & 65 \end{aligned}$ | $A_{K}$ | $\begin{aligned} & A_{\text {IF }} \\ & 75 \end{aligned}$ | $A A_{X C}$ $90$ | $\begin{aligned} & \text { AuF }^{2} \\ & \infty \end{aligned}$ | $\begin{gathered} A_{\text {RW }} \\ 75 \end{gathered}$ | $\begin{aligned} & \delta_{\mathrm{F}} \\ & 50 \end{aligned}$ | $\begin{aligned} & M_{F} \\ & 65 \end{aligned}$ | $\begin{aligned} & M_{L} \\ & 75 \end{aligned}$ | $\begin{aligned} & q_{L} \\ & 60 \end{aligned}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | OPTO-ELECTITONICS |  |  |  |  |  |  |  |  |  |  |  |  |  |  |
| 6.11 | Pholodetector | 011 | . 029 | . 083 | . 059 | . 18 | . 084 | . 11 | 21 | 35 | 34 | . 0057 | . 15 | . 51 | 3.7 |
| 6.11 | Opro-isolutor | . 027 | . 070 | 20 | 14 | . 43 | . 20 | 25 | . 48 | . 83 | . 80 | . 013 | . 35 | 1.2 | 8.7 |
| 6.11 | Emmer | . 00047 | . 0012 | . 0335 | . 0025 | . 0077 | . 0035 | . 0044 | . 0086 | . 015 | . 014 | . 00024 | . 0063 | . 021 | 15 |
| 6.12 | Aphanumeric Dipplay | . 0062 | . 016 | . 045 | . 032 | . 10 | . 046 | . 058 | . 11 | . 18 | . 18 | . 0031 | . 082 | 28 | 2.0 |
| 6.13 | Laser Diosec cranev Cials | 5.1 | 15 | 49 | 32 | 110 | 58 | 72 | 100 | 170 | 230 | 2.6 | 87 | 350 | 2000 |
| 6.13 | Lever Diose. in Canas/n GrAsP | 8.9 | 23 | ${ }_{85}$ | 55 | 190 | 100 | 130 | 180 | 300 | 400 | 4.5 | 150 | 600 | 3500 |
| 7 | tuaes |  | Seation | cindude | Aocolver | CRIT, C | Sess Frok | mpprifers, | Kyratrons, | NT, M | mutrons) |  |  |  |  |
| 8 | Lasers |  | Section | 8 |  |  |  |  |  |  |  |  |  |  |  |



| Section | Peritype | Style | M14.-R. | $\begin{aligned} & \text { Env. } \rightarrow G_{B} \\ & T_{A}(C) \rightarrow 30 \end{aligned}$ | $\begin{aligned} & G_{F} \\ & 40 \end{aligned}$ | $\begin{aligned} & G_{M} \\ & 45 \end{aligned}$ | ${ }_{4}$ | $\begin{aligned} & N_{U} \\ & 45 \end{aligned}$ | $\begin{gathered} A_{1 C} \\ 55 \end{gathered}$ | $\begin{aligned} & A_{i F} \\ & 55 \end{aligned}$ | $\begin{aligned} & A_{u} u \\ & 70 \end{aligned}$ | $\begin{aligned} & A_{4} \\ & 70 \end{aligned}$ | ${ }_{55}^{A_{\text {PW }}}$ | $\begin{aligned} & S_{F} \\ & 30 \end{aligned}$ | $\begin{gathered} M_{F}^{\prime} \\ 45 \end{gathered}$ | $\begin{gathered} \hline M_{1} \\ 55 \end{gathered}$ | $C$ 40 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 0.1 | Composition | Fक्र | 38008 | . 00050 | . 0022 | . 0071 | . 0037 | . 012 | . 0052 | . 0065 | . 016 | . 025 | . 025 | . 00025 | . 0098 | . 035 | . 36 |
| 0.1 | Composition | PC | 11 | . 00050 | . 0022 | . 0071 | . 0037 | . 012 | . 0052 | . 0065 | . 016 | . 025 | . 025 | . 00025 | . 0098 | . 035 | . 36 |
| 9.2 | Fulm, insulated | RLR | 30017 | . 0012 | . 0027 | . 011 | . 0054 | . 020 | . 0063 | . 013 | . 018 | . 033 | . 030 | . 00025 | . 014 | . 044 | . 69 |
| 0.2 | Film, Insulated | RL | 22684 | . 0012 | . 0027 | . 011 | . 0054 | . 020 | . 0063 | . 013 | . 018 | . 033 | . 030 | . 00025 | . 014 | . 044 | . 69 |
| 8.2 | Fim PN(RCOM) | ANA | 55182 | . 0014 | . 0031 | . 013 | . 0061 | . 023 | . 0072 | . 014 | . 021 | . 038 | . 034 | . 00028 | . 018 | . 050 | . 78 |
| 9.2 | Fin | FN | 10509 | . 0014 | . 0031 | . 013 | . 0061 | . 023 | . 0072 | . 014 | . 021 | . 038 | . 034 | . 00028 | . 018 | . 050 | . 78 |
| 9.3 | Film, Power | fo | 11804 | . 012 | . 025 | . 13 | . 082 | . 21 | 078 | . 10 | . 19 | . 24 | . 32 | . 0060 | . 18 | . 47 | 8.2 |
| 9.4 | Fum, Notwork | PR | 83401 | . 0023 | . 0066 | . 031 | . 013 | . 055 | . 022 | . 043 | . 077 | . 15 | . 10 | . 0011 | . 055 | . 15 | 1.7 |
| 9.5 | Wirewound, Accurato | PER | 38005 | . 0085 | . 018 | . 10 | . 045 | . 16 | . 15 | . 17 | . 30 | . 38 | 26 | . 0068 | . 13 | . 37 | 5.4 |
| 9.5 | Wirowound, Accurate | P\% | 93 | . 0085 | . 018 | . 10 | . 045 | . 16 | . 15 | . 17 | . 30 | . 38 | . 26 | . 0088 | . 13 | . 37 | 5.4 |
| 9.6 | Wircwound Power | ANR | 39007 | . 014 | . 031 | . 16 | . 077 | . 28 | . 073 | . 15 | . 19 | . 39 | . 42 | . 0042 | . 21 | . 62 | 0.4 |
| 9.6 | Wrewound, Power | PW | 26 | . 013 | . 028 | . 15 | . 070 | . 24 | . 066 | . 13 | . 18 | . 35 | . 38 | . 0038 | . 10 | . 56 | 8.6 |
| 9.7 | Wrowound, Power, Chassia Mounted | fer | 38009 | . 0080 | . 018 | . 096 | . 045 | . 15 | . 044 | . 088 | . 12 | . 24 | . 25 | . 0040 | . 13 | . 37 | 5.5 |
| 0.7 | Wircwound, Pown. Chassis Mounted | PE | 10546 | . 0080 | . 018 | . 096 | . 045 | . 15 | . 044 | . 088 | . 12 | . 24 | . 25 | . 0040 | . 13 | . 37 | 5.5 |
| 9.8 | Thermistor | RTH | 23648 | . 065 | . 32 | 1.4 | . 71 | 1.6 | . 71 | 1.9 | 1.0 | 2.7 | 2.4 | . 032 | 1.3 | 3.4 | 82 |
| 9.9 | Wirowound, Varieble | FIR | 38015 | . 025 | . 055 | . 35 | . 16 | . 58 | . 16 | . 26 | . 35 | . 50 | 1.1 | . 013 | . 52 | 1.6 | 24 |
| 9.9 | Wirewound, Variable | FT | 27208 | . 025 | . 055 | . 35 | . 16 | . 58 | . 16 | . 26 | . 35 | . 59 | 1.1 | . 013 | . 52 | 1.6 | 24 |
| 9.10 | Wirowound, Veriable, Precision | PR | 12934 | . 33 | . 73 | 7.0 | 2.9 | 12 | 3.5 | 5.3 | 7.1 | 9.8 | 23 | . 16 | 11 | 33 | 510 |
| 9.11 | Wirewound, Variable, Semiprecision | PA | 19 | . 15 | . 35 | 3.1 | 1.2 | 5.4 | 1.8 | 2.8 | - | - | 9.0 | . 075 | - | - | - |
| 9.11 | Wirewound, Variable, Semprocizion | FK | 38002 | . 15 | . 35 | 3.1 | 1.2 | 5.4 | 1.8 | 2.8 | - | - | 9.0 | . 075 | - | - | - |
| 9.12 | Wirewound. Variable, Power | fP | 22 | . 15 | . 34 | 2.9 | 1.2 | 5.0 | 1.6 | 2.4 | - | - | 7.6 | . 076 | - | . | - |
| 9.13 | Norwirewound. | RUR | 38035 | . 033 | . 10 | 50 | . 21 | . 87 | . 19 | . 27 | . 52 | . 79 | 1.5 | . 017 | . 79 | 2.2 | 35 |
| 9.13 | Norwirewound Variable | RJ | 22097 | . 033 | . 10 | . 50 | . 21 | . 87 | . 19 | . 27 | . 52 | . 79 | 1.5 | . 017 | . 78 | 2.2 | 35 |
| 9.14 | Composillon, Variable | RV | 94 | . 050 | . 11 | 1.1 | . 45 | 1.7 | 2.8 | 4.6 | 4.6 | 7.5 | 3.3 | . 025 | 1.5 | 4.7 | 87 |
| 9.15 | Normirewound Veriable Precision | RO | 38023 | . 043 | . 15 | 75 | . 35 | 1.3 | . 39 | . 78 | 1.8 | 2.8 | 25 | . 021 | 1.2 | 3.7 | 49 |
| 9.15 | Flom Varieble | RMC | 23285 | . 048 | . 16 | . 76 | . 36 | 1.3 | . 36 | . 72 | 1.4 | 2.2 | 2.3 | . 024 | 1.2 | 3.4 | 52 |

[^2]
Genorlc Fallure Rato, $\lambda_{g}$ (Fallures $/ 10^{6}$ Hours) for Capectors

| Section | Part Type or Dielectric | Syle | MILC- | $\begin{aligned} & \text { Env. } \rightarrow G_{B} \\ & T_{A}\left({ }^{\circ} \mathrm{C}\right) \rightarrow 30 \end{aligned}$ | $\begin{aligned} & G_{F} \\ & 40 \end{aligned}$ | $G_{M}$ | $\begin{aligned} & N_{S} \\ & 40 \end{aligned}$ | $\begin{aligned} & N_{U} \\ & 45 \end{aligned}$ | $\begin{aligned} & A_{1} C \\ & 55 \end{aligned}$ | $\begin{aligned} & A_{i F} \\ & 55 \end{aligned}$ | $\begin{aligned} & \lambda_{u} \\ & 70 \end{aligned}$ | ${ }_{T 0}^{A_{F}}$ | $\lambda_{50}$ | $\begin{aligned} & S_{F} \\ & 30 \end{aligned}$ | $\begin{aligned} & W_{F} /{ }_{4} \end{aligned}$ | $\begin{aligned} & \hline W L \\ & 55 \end{aligned}$ | $c$ 40 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 10.1 | Paper, ByPass | ${ }^{\text {CP }}$ | 25 | . 0036 | . 0072 | . 033 | . 018 | . 055 | . 023 | . 03 | . 070 | . 13 | . 083 | . 0018 | . 044 | . 12 | 2.1 |
| 10.1 | Paper, By-Pass | CA | 12889 | . 0039 | . 0087 | . 042 | . 022 | . 070 | . 035 | . 047 | . 19 | . 35 | . 13 | . 002 | . 056 | . 10 | 25 |
| 10.2 | Peperflastic. Feedthrough | CRP | 11893 | . 0047 | . 0086 | . 044 | . 034 | . 073 | . 030 | . 040 | . 094 | . 15 | . 11 | . 0024 | . 058 | . 18 | 27 |
| 10.3 | Paperficastc Firm | CPV | 14157 | . 0021 | . 0042 | . 017 | . 010 | . 030 | . 0088 | . 013 | . 026 | . 048 | . 044 | . 0010 | . 023 | . 083 | 1.1 |
| 10.3 | Paparfisatic Fllm | COR | 19978 | . 0021 | . 0042 | . 017 | . 010 | . 030 | . 0088 | . 013 | . 026 | . 048 | . 044 | . 0010 | . 023 | . 063 | 1.1 |
| 10.4 | Motuliced Paper/Plestic | OHR | 39022 | . 0028 | . 0058 | . 023 | . 014 | . 041 | . 012 | . 018 | . 037 | . 066 | . 060 | . 0014 | . 032 | . 088 | 1.5 |
| 10.4 | Metulized Plastiod Plastic | OH | 18312 | . 0029 | . 0058 | . 023 | . 014 | . 041 | . 012 | . 018 | . 037 | . 066 | . 060 | . 0014 | . 032 | . 088 | 1.5 |
| 10.5 | Motalized PaperiPlestic | Cf | 55514 | . 0041 | . 0083 | . 042 | . 021 | . 067 | . 026 | . 048 | . 086 | . 14 | . 10 | . 0020 | . 054 | . 15 | 2.5 |
| 10.6 | Motalized Plestic | CPH | 83421 | . 0023 | . 0092 | . 019 | . 012 | . 033 | . 0096 | . 014 | . 034 | . 053 | . 048 | . 0011 | . 026 | 07 | 1.2 |
| 10.7 | MICA (Dipped or Molded) | CWR | 38001 | . 0005 | . 0015 | . 0081 | . 0044 | . 014 | . 0068 | . 0095 | . 054 | . 069 | . 031 | . 00025 | . 012 | . 046 | . 45 |
| 10.7 | MICA (Dppoed) | OM | 5 | . 0005 | . 0015 | . 0081 | . 0044 | . 014 | . 0068 | . 0095 | . 054 | . 069 | . 031 | . 00025 | . 012 | . 046 | . 45 |
| 10.8 | MICA (Buthon) | C8 | 10850 | . 018 | . 037 | . 19 | . 094 | . 31 | . 10 | . 14 | . 47 | . 80 | . 48 | . 0091 | . 25 | . 68 | 11 |
| 10.9 | Gless | Cra | 23289 | . 00032 | . 00096 | . 0059 | . 0029 | . 0094 | . 0044 | . 0062 | . 035 | . 045 | . 020 | . 00016 | . 0076 | . 030 | 29 |
| 10.9 | Glass | Cr | 11272 | . 00032 | . 00096 | . 0059 | . 0029 | . 0094 | . 0044 | . 0062 | . 035 | . 045 | . 020 | . 00016 | . 0076 | . 030 | . 29 |
| 10.10 | Ceraric (Gent Puppose) | ${ }_{\sim}^{*}$ | 11015 | . 0036 | . 0074 | . 034 | . 019 | . 056 | . 015 | . 015 | . 032 | . 048 | . 077 | . 0014 | . 049 | . 13 | 2.3 |
| 10.10 | Ceranic (Gen. Purpose) | CNP | 30014 | . 0036 | . 0074 | . 034 | . 019 | 056 | . 015 | . 015 | . 032 | . 048 | . 077 | . 0014 | . 049 | . 13 | 2.3 |
| 10.11 | Ceranic (Tema Coma) | CCR | 20 | . 00078 | . 0022 | . 013 | . 0056 | 023 | . 0077 | . 015 | . 053 | . 12 | . 046 | . 00039 | . 017 | . 065 | . 68 |
| 10.11 | Ceranic Crip | COR | 55881 | . 00078 | . 0022 | . 013 | . 0056 | . 023 | . 0077 | . 015 | . 053 | . 12 | . 048 | . 00039 | . 017 | . 065 | . 68 |
| 10.12 | Tantalum, Solld | Csi | 39003 | . 0018 | . 0039 | . 016 | . 0097 | . 028 | . 0091 | . 011 | . 034 | . 057 | . 065 | . 00072 | . 022 | . 086 | 1.0 |
| 10.13 | Tantalum Non-Solid | CLR | 30006 | . 0061 | . 013 | . 069 | . 039 | . 11 | . 031 | . 061 | . 13 | . 29 | . 18 | . 0030 | . 089 | . 26 | 4.0 |
| 10.13 | Tertalum, Non-Solid | $a$ | 3985 | . 0061 | . 013 | . 069 | . 030 | . 11 | . 031 | . 061 | . 13 | . 29 | . 18 | . 0030 | . 080 | . 26 | 4.0 |
| 10.14 | Alurinum Oxide | ar | 39018 | . 024 | . 061 | . 42 | . 18 | . 50 | . 46 | . 55 | 2.1 | 2.8 | 1.2 | . 012 | . 40 | 1.7 | 21 |
| 10.15 | Alumirum Dry | $\boldsymbol{C E}$ | 62 | . 029 | . 081 | . 58 | . 24 | . 83 | . 73 | . 88 | 4.3 | 5.4 | 20 | . 015 | . 68 | 2.8 | 28 |
| 10.16 | Vartabo. Cerenic | CV | 81 | . 08 | . 27 | 1.2 | . 71 | 2.3 | . 69 | 1.1 | 6.2 | 12 | 4.1 | . 032 | 1.0 | 5.9 | 85 |
| 10.17 | Variablo. Pliston | PC | 14009 | . 033 | . 13 | . 62 | . 31 | . 93 | . 21 | . 28 | 2.2 | 3.3 | 2.2 | . 016 | . 93 | 3.2 | 37 |
| 10.18 | Variable, At Trimmer | CT | 92 | . 080 | . 33 | 1.6 | . 87 | 3.0 | 1.0 | 1.7 | 9.9 | 19 | 6.1 | . 032 | 25 | 8.8 | 100 |
| 10.19 | Varieblo, Vecuum | CG | 23183 | 0.4 | 1.3 | 6.7 | 3.6 | 13 | 5.7 | 10 | 56 | 80 | $2{ }^{\text {d }}$ | . 20 | - | - | . $\cdot$ |

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[^3]Gonoric Fallure Rato, $\lambda_{g}$ (Fallures/10 ${ }^{6}$ Hours) for Miscollanoous Parts

| Section | Paritype Dialoctric | MII. | $\begin{aligned} & E n v \rightarrow G_{B} \\ & T_{A}\left({ }^{(C)}()+30\right. \end{aligned}$ | $\begin{aligned} & \sigma_{F} \\ & 40 \end{aligned}$ | $\begin{aligned} & G_{M} \\ & 45 \end{aligned}$ | $\begin{aligned} & \mathrm{N}_{\mathrm{s}} \\ & 40 \end{aligned}$ | $\begin{aligned} & \hline M_{i} \\ & 45 \end{aligned}$ | $\begin{aligned} & A_{1 K} \\ & 55 \end{aligned}$ | $\begin{aligned} & \hline A_{\text {IF }} \\ & 55 \end{aligned}$ | $\begin{aligned} & A_{40} \\ & 70 \end{aligned}$ | $\begin{gathered} \overline{A_{i F}} \\ { }_{70} \end{gathered}$ | $\begin{gathered} A_{5 w 1} \\ { }_{5 N} \end{gathered}$ | $\begin{aligned} & s_{F} \\ & 30 \end{aligned}$ | $\begin{aligned} & M_{F} \\ & 45 \end{aligned}$ | M 5 5 | 9 40 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\begin{aligned} & 17.1 \\ & 17.1 \\ & 17.1 \\ & 17.1 \\ & 17.1 \\ & 17.1 \\ & 17.1 \end{aligned}$ | SNGLE CONNECTIONS Hand Solder, wo Wrepping Hand Solder, wWrapping Crimp <br> Wed <br> Soldertess Wrap <br> Cip Termination <br> Relow Solder $\qquad$ |  | $\begin{array}{r} .0026 \\ .00014 \\ .000026 \\ .000050 \\ .0000035 \\ .00012 \\ .000069 \\ \hline \end{array}$ | $\begin{gathered} .0052 \\ .00028 \\ .00052 \\ .000100 \\ .000007 \\ .00024 \\ .000138 \\ \hline \end{gathered}$ | $\begin{gathered} .018 \\ .00098 \\ .0018 \\ .000350 \\ .000025 \\ .00084 \\ .000483 \end{gathered}$ | $\begin{gathered} .010 \\ .00056 \\ .0010 \\ .000200 \\ .000014 \\ .00048 \\ .000276 \\ \hline \end{gathered}$ | $\begin{gathered} .029 \\ .0015 \\ .0029 \\ .000550 \\ .000089 \\ .0013 \\ .000759 \end{gathered}$ |  | .016 <br> . 00004 .0016 000300 .000021 .00072 <br> 000414 | $\qquad$ | $\begin{gathered} .021 \\ .0011 \\ .0021 \\ .000400 \\ .00028 \\ .00096 \\ .000552 \\ \hline \end{gathered}$ |  | $\qquad$ |  | .062! <br> .0034 <br> .0062 <br> . 101200 <br> . 000084 <br> .028 <br> .001856 | 1.1 <br> .059 <br> .11 <br> .021000 <br> .0015 <br> .050 <br> .02898 |
| $\begin{array}{r} 18.1 \\ 18.1 \\ \hline \end{array}$ | DC Ammater or Votimeter AC Ammeter or Vollemeler | $\begin{aligned} & \begin{array}{l} 1+10304 \\ 4 \\ 4 \end{array} \mathbf{1 0 3 0 4} \end{aligned}$ | $\begin{aligned} & 0.09 \\ & 0.15 \\ & \hline \end{aligned}$ | $\begin{array}{r} 0.36 \\ 0.81 \\ \hline \end{array}$ | $\begin{array}{r} 23 \\ 3.8 \\ \hline \end{array}$ | $\begin{array}{r} 1.1 \\ 1.8 \\ \hline \end{array}$ | $\begin{array}{r} 3.2 \\ 5.4 \\ \hline \end{array}$ |  |  |  |  |  | $\begin{aligned} & 0.098 \\ & 0.17 \\ & \hline \end{aligned}$ | $\begin{aligned} & 5.4 \\ & 0.2 \end{aligned}$ | $\begin{aligned} & N / \\ & N A \end{aligned}$ | N/A |
| 9.1 | Querte Crasale | C.300e | . 032 | 096 | 32 | 19 | 51 | 38 | . 54 | 70 | 80 | 74 | 018 | 42 | 1.0 | 16 |
| $\begin{array}{r} 20.1 \\ 20.1 \\ \hline \end{array}$ | Lampe, mcandocee:ent, AC Lempe, haydorcent, DC |  |  | $\begin{array}{r} 7.8 \\ 26 \\ \hline \end{array}$ | $\begin{array}{r} 12 \\ 38 \\ \hline \end{array}$ | $\begin{array}{r} 12 \\ 38 \\ \hline \end{array}$ | $\begin{array}{r} 16 \\ -51 \\ \hline \end{array}$ | $\begin{array}{r} 16 \\ 51 \\ \hline \end{array}$ | $\begin{array}{r} 16 \\ 51 \\ \hline \end{array}$ | $\begin{array}{r} 19 \\ 64 \\ \hline \end{array}$ | $\begin{aligned} & 23 \\ & n \\ & \hline \end{aligned}$ | $\begin{array}{r} 19 \\ 64 \\ \hline \end{array}$ |  | $\begin{array}{r} 16 \\ .51 \\ \hline \end{array}$ |  | 100 350 |
| $\begin{aligned} & 21.1 \\ & 21.1 \\ & 21.1 \\ & \hline \end{aligned}$ | ELECTRONC: FLITERS <br> Ceramic-Ferrite <br> Discrete LC Comp. <br> Discrete LC \& Cyistal Comp. | $\begin{aligned} & \text { F-15733 } \\ & \text { F-15733 } \\ & \text { F-18327 } \\ & \hline \end{aligned}$ | $\begin{array}{r}.022 \\ .12 \\ .27 \\ \hline\end{array}$ | $\begin{array}{r} .044 \\ .24 \\ .54 \\ \hline \end{array}$ | $\begin{array}{r} .13 \\ .72 \\ 1.6 \\ \hline \end{array}$ | $\begin{array}{r} .088 \\ .48 \\ 1.1 \\ \hline \end{array}$ | $\begin{array}{r} .20 \\ 1.1 \\ 2.4 \\ \hline \end{array}$ | $\begin{array}{r} .15 \\ .84 \\ .1 .9 \\ \hline \end{array}$ | .20 1.1 2.4 | .24 1.3 3.0 | $\begin{array}{r}28 \\ 1.6 \\ \hline .5 \\ \hline\end{array}$ | .24 1.3 3.0 | $\begin{array}{r}.018 \\ .096 \\ .22 \\ \hline\end{array}$ | $\begin{array}{r} .15 \\ .84 \\ .1 .9 \\ \hline \end{array}$ | .33 <br> 1.8 <br> 4.1 | $\begin{aligned} & 2.6 \\ & 14 \\ & 32 \end{aligned}$ |
| 2.1 | fuses |  | 010 | . 020 | . 080 | . 050 | 11 | . 090 | 12 | 15 | 18 | 16 | . 009 | . 10 | 21 | 2.3 |

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* Category applies only to MIL-C-39010 Coils.

MIL-HDBK-217F
APPENDIX A: PARTS COUNT

$\overline{\mathrm{A}-12}$

## MIL-HDBK-217F

Defaull Parameters for Discrute Semiconductors


## MIL-HDBK-217F

| Section $\qquad$ | Part Type | Style | MIL-R-SPEC | ${ }^{*}$ R | $\pi$ | ${ }^{\text {KTAPS }}$ | Comments |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 9.1 9.1 | Composition | ACR | $\begin{array}{r} 39008 \\ 11 \end{array}$ | $\begin{aligned} & \hline 1.1 \\ & 1.1 \end{aligned}$ |  |  | PW. Stress - .5. 1 M काm <br> Pw. Stress =.5, 1 Mohm |
| 9.2 | Film, Insulated | RLA | 39017 | 1.1 |  |  | $\mathrm{P}_{\text {Wr }}$. Stress $=.5,1 \mathrm{Mchm}$ |
| 9.2 | Film, Insulated | RL | 22684 | 1.1 |  |  | Pwr. Stress $=.5 .1 \mathrm{M} \mathrm{ohm}$ |
| 9.2 | Fim, RN ( $\mathrm{P}, \mathrm{Cor}$ ) | PNR | 55182 | 1.1 |  |  | PWr. Stress $=.5,1 \mathrm{Mchm}$ |
| 9.2 | Fim | PN | 10509 | 1.1 |  |  | Pwr. Stress = . 5, 1 M ohm |
| $\begin{aligned} & 9.3 \\ & 9.4 \end{aligned}$ | Film, Power Fxed, Natwork | PD | $\begin{aligned} & 11804 \\ & 83401 \end{aligned}$ | 1.0 |  |  | PWr. Stress = .5, 100 ohm <br> Pwr. Stress $=5 . T_{C}=T_{A}+28^{\circ} \mathrm{C}$, 10 Film Resistors |
| 9.5 | Wirewound. Accurate | RBR | 39005 | 1.7 |  |  | PWr. Strese $=.5,100 \mathrm{~K}$ chms |
| 9.5 | Wrewound, Accurate | RB | 93 | 1.7 |  |  | Pwr. Strese = 5, 100 K chms |
| 9.6 | Wrewound, Power | RWR | 39007 | 1.1 |  |  | Pwr. Stress $=.5,5 \mathrm{~K}$ ohms, RWR 84 |
| 9.6 | Wrewound, Power | FW | 28 | 1.0 |  |  | Pwr. Stress = .5, 5K ohms, RW10 |
| 9.7 | Wrowound, Power, Chassis Mounted | RER | 39009 | 1.1 |  |  | Pwr. Stress = 5. Noninductively Wound, 5K ohm, RER 55 |
| 9.7 | Wrewound, Power, Chassis Mountad | PE | 18546 | 1.1 |  |  | Pwr. Stress = 5, MLL-R-18546, Char. N, 5K ohm, RE75 |
| 9.8 | Thermistor | FTH | 23648 |  |  |  | Disk Type |
| 9.9 9.9 | Wrewound, Variable Wirewound, Variable | RTR | 39015 | 1.4 | 1.1 | 1.0 | Pwr. Stress $=5.5 \mathrm{~K}$ ohms, 3 Teps, Voltage Stiess $=.5$ |
| 9.10 | Wrewound, Variable, Preciston | RT | 27208 12934 | 1.4 1.4 | 1.1 1.1 | 1.0 1.0 | $P_{\text {wr. }}$ Streses $=.5,3$ Tape, Voltage Strese $=.5$ <br> PWr. Stest = .5, Construction Claes $8\left(\pi_{c}=1.5\right)$, |
| 9.11 | Wirewound, Variable, Semipredision | PA | 19 | 1.4 | 1.0 | 1.0 | 50K ohm, 3 Taps, Voltage Stress $=.5$ <br> $P_{w}$. Stress = $=5,5 \mathrm{~K}$ ohms, 3 Teps, Voltage Stress $=.5$ |
| 9.11 9.12 | Wrewound. Semiprecision Wrowound, Variable, Power | PK RP | 39002 22 | $1.4$ | 1.0 | 1.0 | Pwr. Stress = .5, 3 Tape, Voltage Stress $=.5$ |
|  | Norwirewound Varieble | R1R | 22 30035 | 1.4 | 1.0 | 1.0 | Pwr. Stress = $.5,3$ Tape, Voltage Stress $=.5$, <br> Unenclosed ( $x_{c}=1$ ) |
| 9.13 9.13 | Norwirewound, Varieble Norwirewound, Varisble | RNR | 39035 22097 | 1.2 1.2 | 1.0 1.0 | 1.0 | Pwr. Strese = .5, 200K ohm. 3 Tapre, Voltage Stress = . 5 |
| 9.14 | Composilion, Variable | FV | 94 | 1.2 | 1.0 | 1.0 | Pwr. Stuese = . 5 , 200K Chm , 3 Tapa, Voltape Stress = . 5 |
| 9.15 | Nonwirewound, Variable Precision | RO | 39023 | 1.2 | 1.0 | 1.0 | Pwr. Stress $=.5,200 \mathrm{~K}$ ohm, 3 Taps , Voltage Stress $=.5$ |
| 9.15 | Flim, Vartable | FNC | 23285 | 1.2 | 1.0 | 1.0 | Pwr. Stress = .5, 200K ohm, 3 Taps, Vatage Stress = . 5 |


| Section * | Part Typ | MIL-SPEC | ${ }^{\pi_{C}}$ | "CYC | $\pi_{F}$ | Comments |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | INDUCTIVE |  |  |  |  |  |
| 11.1 | Low Pwr. Puised, XFMR | MIL.T. 21038 |  |  |  | Max. Rated Temp. $=130^{\circ} \mathrm{C}, \Delta T=10$ |
| 11.1 | Audio XFMR | MIL-T-27 |  |  |  | Max. Rated Temp. $=130^{\circ} \mathrm{C}, \Delta T=10$ |
| 11.1 | High Pwr. Pulse and Pwr XFMR, Fiter | MIL-T-27 |  |  |  | Max. Rated Temp. $=130^{\circ} \mathrm{C}, \Delta \mathrm{T}=30$ |
| 11.1 | RF Transformers | MIL.T-55631 |  |  |  | Max. Rated Terme. $=130^{\circ} \mathrm{C}, \Delta \mathrm{t}^{T}=10$ |
| 11.2 | RF Colls, Fixed or Malded | MIL.C. 15305 | 1 |  |  | Max. Rated Temp. $=125^{\circ} \mathrm{C}, \Delta \mathrm{t}^{T}=10$ |
| 11.2 | RF Colls, Varlable | MIL-C-15305 | 2 |  |  | Max. Rated Termp., $=125^{\circ} \mathrm{C}, \Delta \mathrm{T}=10$ |
|  | ROTATING DEVICES |  |  |  |  |  |
| 12.1 | Motors |  |  |  |  | $t=15,000$ hours (Assumed Puplacement Time) |
| 12.2 | Synchros |  |  |  |  | $T_{F}=T_{A}+40$, Size 10-16, 3 Brushes |
| 12.2 | Resolvers |  |  |  |  | $T_{F}=T_{A}+40$, Size 10-16, 3 Brushes |
| 12.3 | Elapsed Time Meters (ETM) ETM-AC |  |  |  |  | Op. Temp/Rated Temp. $=.5\left(x_{T}=.5\right)$ |
| 12.3 | ETM-Inviarter Driver |  |  |  |  | Op. Temp/Ratiod Temp. $=.5\left(x_{\top}=.5\right)$ |
| 12.3 | ETM-Cornruiteter DC: |  |  |  |  | Op. Temp/Rated Tomp. $=.5\left(x_{T}=.5\right)$ |
|  | RELAYS |  |  |  |  |  |
| 13.1 | General Purpose |  | 3 | 1 | 5 | Max. Rated Temp. $=125^{\circ} \mathrm{C}$, DPDT, MIL-SPEC, 10 Cycles/Hour, 4 Amp., General Purpose, Balanced Armature, Resiattive Load, $s=.5$ |
| 13.1 | Contactor, High Current |  | 3 | 1 | 5 | Max. Rated Tiemp. $=125^{\circ} \mathrm{C}$, DPDT, MIL-SPEC, 10 C -cles/Hour, 600 Amp., Solenoid, Inductive Load, $8=.5$ |
| 13.1 | Latching |  | 3 | 1 | 5 | Max. Rated Temp. $=125^{\circ} \mathrm{C}$, MILL-SPEC, 4 Amp., Mercury Wetted, 10 Cyles/Hour, DPDT, Resisttve Load, $s=.5$ |
| 13.1 | Reed |  | 1 | 2 | 6 | Max. Rated Timp. $=85^{\circ} \mathrm{C}$, Mil.SPEC, SIgnal Current, Dy Reed, 20 Cycles/Hour, SPST, Reelstive Load, $1=.5$ |
| 13.1 | Thermal Bi-Metal |  | 1 | 1 | 10 | Max. Rated Tomp. $=125^{\circ} \mathrm{C}$, MLL-SPEC, EN-Metal, 10 Cycles/Hour, SPST, Inductive Load, 5 Amp., s = . 5 |
| 13.1 | Meter Moivement |  | 1 | 1 | 100 | Max. Rated Tomp. $=125^{\circ} \mathrm{C}$, MLL-SPEC, Polarized Meter Movement, 10 Cydes/Hour, SPST, Reslative Load, 1 - .5 |
| 13.2 | Solid State | MIL.-R-28750 |  |  |  | No Defaults |
| 19 ? | Time Delay Hybrid and Solid State | MIL.-R-3372.6 |  |  |  | No Dofaults |



## MIL-HDBK-217F

## APPENDIX A: PARTS COUNT



## MIL-HDBK-217F

## APPENDIX B: VHSICNHSIC-LIKE AND VLSI CMOS (DETAILED MODEL)

This appendix contains the detailed version of the VHSICNLSI CMOS model contained in Section 5.3. It is provided to allow more detailed device level design trade-offs to be accomplished for predominate failure modes and mechanisms exhibited in CMOS devices. Reference 30 should be consulted for a detailed derivation of this model.

VHSICNHSIC-LIKE EAILURE RATE MODEL
$\lambda_{P}(t)=\lambda_{O X}(t)+\lambda_{\text {MET }}(t)+\lambda_{\text {HC }}(t)+\lambda_{C O N}(t)+\lambda_{\text {PAC }}+\lambda_{\text {ESD }}+\lambda_{\text {MIS }}(t)$
$\lambda_{P}(t)=$ Predicted Failure Rate as a Function of Time
$\lambda_{O X}(t)=$ Oxide Failure Rate
$\lambda_{\text {MET }}(t)=$ Metallization Fallure Rate
$\lambda_{\text {HC }}(t)=$ Hot Carrier Failure Rate
$\lambda_{C O N}(t)=$ Contamination Failure Rate
$\lambda_{\text {PAC }}=$ Package Failure Rate
$\lambda_{\text {ESD }}=$ EOS/ESD Failure Rate
$\lambda_{\text {MIS }}(t)=$ Miscellaneous Failure Rate

The equations for each of the above failure mechanism failure rates are as follows:

## OXIDE FAILURE RATE EQUATION

$$
\begin{aligned}
\lambda_{o x}\left(\text { in } F / 10^{6}\right)= & \frac{A A_{\text {TYPEOX }}}{A_{R}}\left(\frac{D_{0_{0 x}}}{D_{R}}\right)\left[\left(.0788 e^{-7.7 t_{0}}\right)\left(A_{T_{0 X}}\right)\left(e^{-7.7 A_{O X} t}\right)\right. \\
& \left.+\frac{.399}{(t+t 0) \sigma_{0 x}} \exp \left(\frac{-.5}{\sigma_{0 x}^{2}}\left(\ln \left(t+t_{0}\right)-\ln t_{50}\right)^{2}\right)\right]
\end{aligned}
$$

## A $=$ Total Chip Area (in $\mathrm{cm}^{2}$ )

$A_{\text {TYPE }}^{0 \times}$ = $\quad .77$ for Custom and Logic Devices, 1.23 for Memories and Gate Arrays

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| OXIDE FAILURE RATE EQUATON(CONTINUED) |  |  |
| :---: | :---: | :---: |
| ${ }^{A_{R}}$ | = | . $21 \mathrm{~cm}^{2}$ |
| $\mathrm{D}_{0 \text { ox }}$ |  | Oxide Defect Density (H unknown, use $\left(\frac{x_{0}}{X_{s}}\right)^{2}$ where $X_{0}=2 \mu \mathrm{~m}$ and $X_{s}$ is the feature size of the device) |
| $\mathrm{D}_{\mathrm{R}}$ | = | 1 Defect/cm ${ }^{2}$ |
| $\mathrm{t}_{0}$ | = | Effective Screening Time |
|  | $=$ |  |
| ${ }^{\text {A }}$ Tox | - | $\text { Temperature Acceleration Factor, }=\exp \left[\frac{.3}{8.617 \times 10^{-5}}\left(\frac{1}{T_{J}} \cdot \frac{1}{298}\right)\right]$ |
|  |  | (where $T_{J}=T_{C}+\theta_{J C}{ }^{( }$(in $\left.{ }^{\circ} \mathrm{K}\right)$ ) |
| ${ }^{\text {A }} \mathrm{V}_{\text {OX }}$ |  | $e^{-192\left(\frac{1}{E_{0 x}} \cdot \frac{1}{2.5}\right)}$ |
| $E_{0 x}$ | $=$ | Maximum Power Supply Voltage $\mathrm{V}_{\mathrm{DD}}$. divided by the gate oxide thickness (in MV/cm) |
| ${ }^{\text {t }} 50 \mathrm{ox}$ | $=$ | $\frac{1.3 \times 10^{22}(\mathrm{QML})}{\mathrm{A}_{\mathrm{ox}}{ }^{A} V_{\mathrm{OX}}} \quad \text { (in } 10^{6} \text { hrs.) }$ |
|  |  | (QML) $=2$ if on OML, $.5 \mathrm{ff} \mathrm{not}$. |
| $\sigma_{0 x}$ | = | Sigma obtained from test data of oxide failures from the same or similar process. If not available, use a $\sigma_{0 x}$ value of 1 . |
| $t$ | $=$ | time (in $10^{6}$ Hours) |

## MEIAL FALL URE BATE EQUATION

$$
\begin{aligned}
& \lambda_{\text {MET }}=\left[\frac{A_{T_{T Y E}}}{A_{R E T}} \frac{D_{0_{M E T}}}{D_{R}}\left(.00102 e^{-1.18 t_{0}}\right)\left(A_{T_{M E T}}\right)\left(e^{-1.18 A_{T_{M E T}} t}\right)\right] \\
&+\left[\frac{.399}{\left(t+t_{0}\right) \sigma_{M E T}} \exp \left(\frac{-.5}{\sigma_{\text {MET }} 2}\left(\ln \left(t+t_{0}\right)-\ln t_{50_{M E T}}\right)^{2}\right)\right]
\end{aligned}
$$

A $\quad=$ Total Chip Area (in $\mathrm{cm}^{2}$ )
$A_{\text {TPPE }_{\text {MET }}}=.88$ for Custom and Logic Devices, 1.12 for Memory and Gate Arrays
$A_{R}=.21 \mathrm{~cm}^{2}$
$D_{0_{\text {MET }}}=$ Metal Defect Density (If unknown use $\left(\frac{x_{0}}{X_{S}}\right)^{2}$ where $X_{0}=2 \mu \mathrm{~m}$ and $X_{S}$ is the feature size of the device)
$D_{R}=1$ Defect $/ \mathrm{cm}^{2}$
$A_{\text {TMET }}=$ Temperature Acceleration Factor
$=\exp \left[\frac{-.55}{8.617 \times 10^{-5}}\left(\frac{1}{T_{J}}-\frac{1}{298}\right)\right]\left(T_{J}=T_{C A S E}+\theta_{J C}{ }^{P} \quad\right.$ (in $\left.\left.{ }^{\circ} \mathrm{K}\right)\right)$
${ }^{t_{0}}=$ Effective Screening Time (in $10^{6}$ hrs.)
$=A_{T_{\text {MET }}}$ (at Screening Temp. (in $\left.{ }^{\circ} \mathrm{K}\right)$ ) * (Actual Screening Time (in $10^{6}$ hrs))
$\mathrm{t}_{50_{\text {MET }}}=(\mathrm{QML}) \frac{.388^{*} \text { (Metal Type) }}{J^{2} A_{\text {TMET }}} \quad$ (in $10^{6} \mathrm{hrs}$.)
$(\mathrm{QML})=2$ if on $\mathrm{OML}, .5$ if not.
Metal Type $=1$ for Al, 37.5 for ALCu or for Al-Si-Cu
$\mathrm{J}=$ The mean absolute value of Metal Current Density (in $10^{6} \mathrm{Amps} / \mathrm{cm}^{2}$ )
$\sigma_{\text {MET }} \quad=$ sigma obtained from test data on electromigration failures from the same or a similar process. If this data is not available use $\sigma_{\text {meT }}=1$.
$1=$ time (in $10^{6}$ hrs.)

## APPENDIX B: VHSIC-VHSIC-LIKE AND VLSI CMOS (DETAILED MODEL)

## HOT CARRIER FAILURE RATE EQUATION

$$
\begin{aligned}
& \lambda_{H C}=\frac{.399}{\left(t+t_{0}\right) \sigma_{H C}} \exp \left[\frac{-.5}{\sigma_{H C}^{2}}\left(\ln \left(t+t_{0}\right)-\ln t_{50_{H C}}\right)^{2}\right] \\
& t_{50_{H C}}=\frac{(Q M L) 3.74 \times 10^{-5}}{A_{T_{H C}} I_{d}}\left(\frac{I_{\mathrm{SUb}}}{I_{\mathrm{d}}}\right)^{-2.5} \\
&(\mathrm{OML})=2 \text { it on QML, } 5 \text { it not }
\end{aligned}
$$

$$
A_{T_{H C}}=\exp \left[\frac{.039}{8.617 \times 10^{-5}}\left(\frac{1}{T_{J}}-\frac{1}{298}\right)\right]\left(\text { where } T_{J}=T_{C}+\theta_{J C} P\left(\text { in }{ }^{\circ} K\right)\right)
$$

id $=$ Drain Current at Operating Temperature. If unknown use $I_{d}=3.5 e^{-.00157} \mathrm{~T}_{\mathrm{J}}$ (in $\left.{ }^{\circ} \mathrm{K}\right)(\mathrm{mA})$
$I_{\text {sub }}=$ Substrate Current at Operating Temperature. If unknown use

$$
\mathrm{I}_{\mathrm{sub}}=.0058 \mathrm{e}^{-.00689 \mathrm{~T}_{J}\left(\mathrm{in}{ }^{\circ} \mathrm{K}\right)}(\mathrm{mA})
$$

$\sigma_{\mathrm{HC}} \quad=\quad$ sigma derived from test data, if not available use 1.
$\mathrm{t}_{0} \quad=\mathrm{A}_{\mathrm{T}_{H C}}$ (at Screening Temp.(in $\left.{ }^{\circ} \mathrm{K}\right)$ ) *(Test Duration in $10^{6}$ hours)
$1=$ time (in $10^{6}$ hrs.)

CONTAMINATION FAILUBE BATE EQUATION

$A_{T_{C O N}}=\exp \left[\frac{-1.0}{8.617 \times 10^{-5}}\left(\frac{1}{T_{J}}-\frac{1}{298}\right)\right]$ (where $T_{J}=T_{C}+\theta_{J C} P\left(\right.$ in ${ }^{\circ}$ K) $)$
$t_{0}=$ Effective Screening Time
$={ }^{A} \mathrm{~T}_{\text {con }}$ (at screening junction temperature (in $\left.{ }^{\circ} \mathrm{K}\right)$ ) • (actual screening time in $10^{6} \mathrm{hrs}$.)
$1 \quad=$ time (in $10^{6} \mathrm{hrs}$.)

## MIL-HDBK-217F

## APPENDIX B: VHSIC/VHSIC-LIKE AND VLSI CMOS (DETAILED MODEL)

## PACKAGE FAILURE RATE EQUATION

$\lambda_{P A C}=\left(.0024+1.85 \times 10^{-5}(\#\right.$ Pins $\left.)\right) \pi_{E} \pi_{Q} \pi_{P T}+\lambda_{P H}$
$\pi_{E} \quad=\quad$ See Section 5.10
$\pi_{\mathrm{Q}}=$ See Section 5.10

Package Type Factor ( $\Pi_{\mathrm{P}}$ )

| Package Type | $\bar{\Pi}_{\text {PT }}$ |
| :--- | :---: |
| DIP | 1.0 |
| Pin Grid Array | 2.2 |
| Chip Carrier (Surface Mount Technology) | 4.7 |

$\lambda_{\mathrm{PH}}=$ Package Hermeticity Factor
$\lambda_{\text {PH }}=0$ for Hermetic Packages
$\lambda_{\mathrm{PH}}=\frac{.399}{t_{\mathrm{PH}}} \exp \left[\frac{-.5}{\sigma_{\mathrm{PH}}{ }^{2}}\left(\ln (\mathrm{t})-\ln \left(\mathrm{t}_{50 \mathrm{PH}}\right)^{\prime}\right)^{2}\right]$ tor plastic packages
${ }^{t_{50}}{ }_{P H}=86 \times 10^{-6} \exp \left[\frac{2}{8.617 \times 10^{-5}}\left(\frac{1}{T_{A}}-\frac{1}{298}\right)\right] \exp \left[\frac{2.96}{R H_{E F F}}\right]$
$\mathrm{T}_{\mathrm{A}}=$ Ambient Temp. (in ${ }^{\circ} \mathrm{K}$ )
$R H_{\text {eff }}=(D C)(R H)\left[e^{5230}\left(\frac{1}{T_{J}}-\frac{1}{T_{A}}\right)\right]+(1-D C)(R H)$ where $T_{J}=T_{C}+\theta_{J C} P$ (in $\left.{ }^{\circ} K\right)$
(for example, for $50 \%$ Relative Humidity, use $\mathrm{RH}=.50$ )
$\sigma_{\mathrm{PH}}=.74$
$1=$ time (in $10^{6}$ hrs.)

MIL-HDBK-217F

APPENDIX B: VHSIC-VHSIC-LIKE AND VLSI CMOS (DETAILED MODEL)

## EOSAESD FAULURE PATE EQUATION

$\lambda_{\text {EOS }}=\frac{-\ln \left(1-.00057 e^{-.0002 V_{T H}}\right)}{.00876}$
$V_{T H}=$ ESD Threshold of the device using a $100 \mathrm{pF}, 1500$ ohm discharge model

## MISCELLANEOUS FAILURE BATE EQUATION

$$
\begin{aligned}
& \lambda_{\text {MIS }}=\left(.01 \mathrm{e}^{-2.2 \mathrm{t}_{0}}\right)\left(\text { A }_{\text {M MIS }}\right)\left(\mathrm{e}^{\left.-2.2 A T_{\text {MIS }}{ }^{t}\right)}\right. \\
& { }^{\text {A }} \text { TMIS }=\text { Temperature Acceieration Factor } \\
& =\exp \left[\frac{. .423}{8.6317 \times 10^{-5}}\left(\frac{1}{T_{J}}-\frac{1}{298}\right)\right] \\
& \text { where } T_{J}=T_{C}+\theta_{J C} P \text { (in }{ }^{\circ} K \text { ) } \\
& t_{0}=\text { Effective Screening Time } \\
& =A^{T_{\text {MIS }}} \text { (at Screening Temp. (in }{ }^{\circ} \mathrm{K} \text { )) }{ }^{*} \text { Actual Screening Time (in } 10^{6} \text { hours) } \\
& t=\text { time (in } 10^{6} \text { hrs.) }
\end{aligned}
$$

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The year of publication of the Rome Laboratory (RL) (formerty Rome Air Development Center (RADC)) documents is part of the RADC (or RL) number, e.g., RADC-TR-88-97 was published in 1988.

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[^0]:    - H a mating pair of connectors uses two types of insert materials, use the average of the base failure rates for the two insert material types. See following page for insert material determination.

[^1]:    "Caution: Excessive Mating-Demating Cycies May Seriousiy Degrade Reliabiiity

[^2]:    NOTE: 1) ${ }^{-}$Not Normally used in this Environment
    2) $T_{A}=$ Default Component Amblert Temperature ( ${ }^{\circ} \mathrm{C}$ )

[^3]:    

